AD-A198 305

A TOPICAL WORKSHOP

ORGANIC AND POLYMERIC NONLINEAR OPTICAL MATERIALS

sponsored by

THE DIVISION OF POLYMER CHEMISTRY

AMERICAN CHEMICAL SOCIETY

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MAY 16 - 19, 1988

VIRGINIA BEACH, VIRGINIA

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16 SUPPLEMENTARY NOTATION Workshop on Organic and Polymeric Nonlinear Optical Materials, May 16-19, 1988 at Virginia Beach, VA.	

17. COSATI CODES		
FIELD	GROUP	SUB-GROUP

18. SUBJECT TERMS (Continue on reverse if necessary and identify by block number)
nonlinear optical materials, second order nonlinear optical susceptibility, third order nonlinear optical susceptibility, electro-optic, nonlinear optical devices

19. ABSTRACT (Continue on reverse if necessary and identify by block number)

At this Workshop on Organic and Polymeric Nonlinear Optical Materials, the latest developments in the areas of theory, characterization, synthesis, molecular assemblies, and potential device applications for organic and polymeric materials exhibiting nonlinear optical behavior are discussed. Topics discussed ...

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22a. NAME OF RESPONSIBLE INDIVIDUAL Dr. Donald Ulrich	22b. TELEPHONE (Include Area Code) (202) 767-4960 22c. OFFICE SYMBOL NC

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INTRODUCTION

The objective if the workshop was to provide a forum for the sharing of information and the discussion of device applications in the area of organic and polymeric nonlinear optical materials. The workshop addressed the issues of theory, characterization, synthesis, molecular assemblies, and potential device applications. Multidisciplinary interactions are vital to the addvancement of research in this field, and the seventy-six participants included scientists from the USA, Japan, UK, France, Germany, and Canada and represented academic, industrial and government laboratories.

WORKSHOP FOCUS

The workshop focus was divided into five half-day sessions and addressed the following topics.

Theory: Current theoretical work on nonlinear optical interactions in organic and polymeric materials was reviewed, with a focus on understanding the microscopic properties of these systems and their correspondence to the macroscopic properties. The value of modelling these systems and the usefulness of the theoretical projections for determining structural requirements for enhanced nonlinear optical activity was discussed.

Characterization: Experimental studies to determine the second and third order nonlinear optical susceptibilities of organic and polymeric systems was discussed. Limiting values

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for device applications derived from characterization studies were presented.

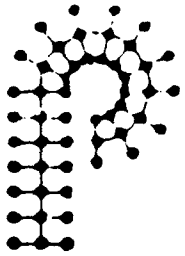
Molecular Assemblies: Characterization measurements have been carried out on many materials in a variety of forms to provide information on structure-property releationships. Molecular order is essential for second order nonlinear optical effects and may enhance third order effects. Therefore, control of molecular orientation in these systems is important. Useful molecular assemblies, including Langmuir-Blodgett films and electrically poled polymer systems were discussed.

Synthesis: The synthesis of organic and polymeric systems is most effective when carried out in conjunction with theoretical development and characterization efforts. Examples of how synthetic efforts can be used to enhance nonlinear optical activity and to improve the physical properties of materials under consideration for use in devices were presented.

Device Applications: Discussions addressed the current status and the future potential of devices utilizing organic and polymeric nonlinear optical materials.

SUMMARY

The Workshop on Organic and Polymeric Nonlinear Optical Materials was very successful. The informal atmosphere encouraged informal discussions, of particular importance in this interdisciplinary field.



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AMERICAN CHEMICAL SOCIETY

May 16-19, 1988

Virginia Beach, VA

Co-Chairmen

Diana Gerbi *Sukant Tripathy*

The generous support of the contributors is gratefully acknowledged: Air Force Office of Scientific Research, Office of Naval Research, Du Pont Company, Hoechst-Celanese and 3M Company.

Monday Evening, May 16, 1988

3:00-9:00 p.m.		REGISTRATION
6:30-9:30 p.m.		WELCOMING RECEPTION

PROGRAM:

Tuesday Morning, May 17, 1988

8:15 A.M.		**Opening Remarks**
8:20-9:10	A.	*"An Overview on Nonlinear Optical Polymer Systems and Devices"* by D.R. Ulrich (Air Force Office of Scientific Research)
9:10-10:00	B.	*"Nonlinear Optical Effects in Polymeric Films"* by P.N. Prasad (State University of New York at Buffalo)
10:00-10:30		**Break**
10:30-11:20	C.	*"Recent Advances in Nonlinear Optical Properties of Organic and Polymer Systems"* by A.F. Garito (University of Pennsylvania)
11:20-12:10	D.	*"Conjugated Polymers and Nonlinear Optics"* by S. Etemad (Bell Communications)
		Lunch

Tuesday Afternoon, May 17, 1988

1:30-2:20	E.	*"Anisotropy of the Third Order Nonlinear Optical Susceptibility in Conjugated Polymers"* by A.J. Heeger (University of California at Santa Barbara)
2:20-3:10	F.	*"Nonlinear Optics in Ordered Molecular Systems"* by K.D. Singer (AT&T)
3:10-3:40		**Break**

3:40-4:30	G.	*"Several Series of Novel Polydiacetylenes for Nonlinear Optics"* by H. Nakanishi (Research Institute for Polymers and Textiles, Japan)
4:30-5:20	H.	*"Resonance Effects in Cubic Hyperpolarisabilities of Conjugated Polymers*, by F. Kajzar (CEN Saclay, France)

Wednesday Morning, May 18, 1988

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9:20-10:10	J.	*"Nonlinear Optical Effects in Conjugated Systems"* by D. J. Gerbi (3M Co.)
10:10-10:40		**Break**
10:40-11:30	K.	*"Optical Nonlinearity: Molecules, Assemblies and Wave Phenomena"* by G. R. Meredith (E.I. DuPont DeNemours and Co.)
10:30-12:20	L.	*"Characterization of Polymeric Nonlinear Optical Materials"* by G. Khanarian (Hoechst-Celanese)

LUNCH

Wednesday Afternoon, May 18, 1988

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2:20-3:10	N.	*"Optical Properties of Organized Assemblies"* by S.K. Tripathy (University of Lowell)
3:10-3:40		**Break**
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8:00 p.m.		BANQUET

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8:30-9:20	P.	*"Advances in Organic Electro-Optic Devices"* by R.S. Lytel (Lockheed Research and Development)
9:20-10:10	Q.	*"Organic Nonlinear Optical Devices and Material Considerations"* by B.K. Nayar (British Telecom Research Laboratories, U.K.)
10:10-10:40		**Break**
10:40-11:30	R.	*"Towards Nonlinear Optical Applications of Polydiacetylenes"* by M. Thakur (AT&T)
11:30-12:20	S.	*"High Resolution Laser Spectroscopy in Polymers" by D. Haarer (Universitat Bayreuth, West Germany)*
12:20		*"Closing Remarks"* byK.J. Wynne(Office of Naval Research)

* *

List of Registrants

"ORGANIC AND POLYMERIC NONLINEAR OPTICAL MATERIALS"

MAY 16 - 19, 1988
Virginia Beach, VA

Gregory L. Baker
Bellcore
331 Newman Springs Road
3X-275
Red Bank, NJ 07701-7020
(201) 756-2932

David N. Beratan
Jet Propulsion Laboratory
4800 Oak Grove Drive
M.S. 67-201
Pasadena, CA 91109
(818) 354-6548

Murrae J. Bowden
Bellcore
331 Newman Springs Rd.
Red Bank, NJ 07701
(201) 758-3360

Michael E. Boyle
Naval Research Laboratory
Polymeric Materials
NRL Code 6123
Washington, D. C. 20375-5000
(202) 767-2472

Eve Chauchard
Dept. of Electrical Engineering
University of Maryland
College Park, MD 20742
(301) 454-6834

Paula Cockerham
Martin Marietta Labs
1450 S. Rolling Rd.
Baltimore, MD 21227
(301) 247-0700

David B. Cotts
KRI International
Advanced Materials Lab.
19-9 Torishima 6-Chome
Konohana-ku
Osaka 554, Japan
(06) 466-2531

Daniel R. Coulter
Jet Propulsion Laboratory
4800 Oak Grove Drive
M.S. 67/201
Pasadena, CA 91109
(818) 354-3638

William Daly
Department of Chemistry
Louisiana State University
Baton Rouge, LA 70803
(504) 388-3237

John Eichelberger
Pennwalt Corporation
900 First Avenue
P.O. Box C
King of Prussia, PA 19406
(215) 337-6729

Susan Erner
Lockheed
0/93-50 B/204
3251 Hanover St.
Palo Alto, CA 94304
(415) 424-3131

Shahab Etemad
Bellcore
Room 3X-291
Red Bank, NJ 07701
(201) 758-2942

Warren T. Ford
Dept. of Chemistry
Oklahoma State University
Stillwater, OK 74078
(405) 624-5946

Robert P. Foss
E.I. du Pont de Nemours & Co.
CR&D
Experimental Station E328/215
Wilmington, DE 19898
(302) 695-4367

Anthony Garito
Dept. of Physics
University of Pennsylvania
Philadelphia, PA 19104

Diana J. Gerbi
3M Company
3M Center Bldg. 201-2E-08
St. Paul, MN 55144
(612) 736-2557

Frederick J. Goetz
Pennwalt Corporation
900 First Avenue
P.O. Box C
King of Prussia, PA 19406
(215) 337-6758

Robert Gulotty
Dow Chemical Co.
CRIMCL Bldg. 1776
Midland, MI 48674
(517) 636-2861

Dietrich Haarer
Experimentalphysik IV
Postfach 101251
University of Bayreuth
Bayreuth D-8580
Federal Republic of Germany
(0921)55-3240

Michael Hayden
Unisys Corp.
P.O. Box 64525
M.S. U1L14
St. Paul, MN 55164
(612) 456-3669

Alan J. Heeger
Polymer Institute
University of California
Santa Barbara, CA 93106
(805) 961-2001

Keith A. Horn
Allied-Signal Co.
Engineered Materials Sector
Box 1087R
Columbia Tpke & Park Ave.
Morristown, NJ 07960
(201) 455-3022

Phelps Johnson
Rohm & Haas
P.O.Box 219
Bristol, PA 19007
(215) 785-8552

Francois Kajzar
CEA IRDI D. LETI
Dept. d'Electronique et
d'Instrumentation Nucleaire -CENIS
91191 Gif Sur Yvette Cedex
France
(33)1-69-08-6810

G. Khanarian
Hoechst-Celanese
86 Morris Ave.
Summit, NJ 07901
(201) 522-7918

Peter Leung
3M
St. Paul, MN 55144

Richard Lytel
Lockheed
R-202 D-9720
3251 Hanover St.
Palo Alto, CA 94304
(415) 424-2363

Robert J. McMahon
Dept. of Chemistry 6-427
M.I.T.
Cambridge, MA 02139
(617) 253-4546

Michael A. Meador
NASA Lewis Research Center
21000 Brookpark Road
M.S. 49-1
Cleveland, OH 44136
(216) 433-3228

Gerald Meredith
E.I. du Pont de Nemours & Co.
Experimental Station
CR&D 356
Wilmington, DE 19898
(302) 695-4984

Joann Milliken
Office of Naval Research
800 N. Quincy St.
Arlington, VA 22217
(202) 696-4409

Jovan Moacanin
Jet Propulsion Laboratory
4800 Oak Grove Drive
M.S. 122-123
Pasadena, CA 91109
(818) 354-3178

Machiro Nakanishi
Research Inst. for Polymers & Textiles
1-1-4 Yatabe-Higashi
Tsukuba 305, Japan
(0298) 54-6310

Piero Nannelli
Pennwalt Corporation
900 First Avenue
P.O. Box C
King of Prussia, PA 19406
(215) 337-6367

B. K. Nayar
British Telecom
R2121
British Telecom Research Labs.
Martlesham Heath
Suffolk IPS TRE, U.K.

Moris K. Niknam
Chemical Abstracts Service
2540 Olentangy River Rd.
P.O. Box 3012
Columbus, OH 43210
(614) 421-3600

Raphael Ottenbrite
Dept. of Chemistry
Virginia Commonwealth University
Richmond, VA 23284
(804) 367-1298

Joseph W. Perry
Jet Propulsion Laboratory
4800 Oak Grove Drive
M.S. 67-201
Pasadena, CA 91109
(818) 354-5794

Ian Peterson
GEC Research Ltd.
Hirst Research Center
Wembley, U.K.

Juergen L. W. Pohlmann
Dept. of the Army, USACECOM
Center for Night Vision
& Electro-Optics
AMSEL-RD-NV-L, Bldg. #317
Fort Belvoir, VA 22060-5677
(703) 664-1432

Pamela Porter
Martin Marietta Labs
1450 S. Rolling Rd.
Baltimore, MD 21227
(301) 247-0700

Richard S. Potember
JHU/Applied Physics Lab.
Johns Hopkins Rd.
Laurel, MD 20707-6099
(310) 953-6251

Paras Prasad
Dept. of Chemistry
SUNY at Buffalo
52 Acheson Hall
Buffalo, NY 14214
(716) 831-3026

Tim Richardson
Oxford University
Dept. of Engineering Science
Parks Road, Oxford OX1 3PJ
England, U.K.
(0865) 273092

Gareth Roberts
Dept. of Engineering Science
University of Oxford
Parks Road
Oxford, OXI 3PJ
England, U.K.

Guerino Sacripante
Xerox Research Center of Canada
2660 Speakman Drive
Mississauga, Ontario
Canada L5K 2L1
(416) 823-7031

Marcia L. Schilling
AT&T Bell Laboratories
600 Mountain Ave.
Rm. 1A-234
Murray Hill, NJ 07974
(201) 582-6434

Paul J. Shannon
Hercules Inc.
Rt 48 & Hercules Rd.
Wilmington, DE 19894
(302) 995-3854

Y. R. Shen
Physics Dept.
University of California, Berkeley
Berkeley, CA 94720
(415) 602-4856

Kenneth Singer
AT&T Engineering Research Center
P.O. Box 900
Pricnceton, NJ 08540

Karen Stetyick
Johns Hopkins University
Applied Physics Lab.
Johns Hopkins Road
Bldg. 2, Rm. 252
Laurel, MD 20707
(301) 953-6242

Albert E. Stiegman
Jet Propulsion Laboratory
4800 Oak Grove Drive
M.S. 67/201
Pasadena, CA 91109
(818) 354-4857

Shao-Tang Sun
Hercules Inc.
Rt. 48 & Hercules Road
Wilmington, DE 19894
(302) 995-3112

Murial Thakur
AT&T Bell Laboratories
600 Mountain Ave.
Rm. #6C-312
Murray Hill, NJ 07974
(201) 582-2522

John M. Torkelson
Dept. of Chemical Engineering
Northwestern University
Evanston, IL 60208
(312) 491-7449

Donald R. Ulrich
Air Force Office of
Scientific Research
Bolling AFB
Washington, D.C. 20332
(202) 767-4963

Maria M. Vida
Chemical Abstracts Service
2540 Olentangy River Rd.
Columbus, OH 43210
(614) 421-3600

Jane C. Vogl
Division of Polymer Chemistry
Polytechnic University
333 Jay St.
Brooklyn, NY 11201
(718) 260-3125

Otto Vogl
Herman F. Mark Prof. of Poly. Sci.
Polytechnic University
333 Jay St.
Brooklyn, NY 11201
(718) 260-3180

Bruce D. Webber
Amoco Technology Co.
P.O. Box 400, F-4
Naperville, IL 60566
(312) 420-4670

James K. Whitesell
Dept. of Chemistry
University of Texas at Austin
Austin, TX 78712
(512) 471-1094

C.C. Winter
British Telecom Research Labs
Rt 2333
Martlesham Heath, Ipswich
England, IP5 7RE, U.K.

Kenneth Wynne
National Science Foundation
Materials Research
1800 G Street N.W.
Washington, D.C. 20550
(202) 696-4410

Frederick C. Zumsteg
E.I. du Pont de Nemours & Co.
Experimental Station
CR&D E356-213
Wilmington, DE 19898
(302) 695-1485

Accompanying Guests

Mrs. G. Khanarian
Mrs. G. Meredith (Leslie)
Mrs. S. Thakur

"ORGANIC AND POLYMERIC NONLINEAR OPTICAL MATERIALS"

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List of Registrants: Addendum

Jan Bartus
H.F. Mark Dept.
Polytechnic University
333 Jay Street
Brooklyn, NY 11201
(718) 260-3403

Michael A. Lee
Dept. of Physics
Kent State University
Kent, OH 44242

T. Mookherji
Teledyne Brown Engineering
M.S. 52
300 Sparkman Dr.
Huntsville, AL 35807
(205) 532-2875

Peter Palffy-Muhoray
Liquid Crystals Institute
Kent State University
Kent, OH 44242

Wei-Fang Su
Westinghouse R&D
Pittsburgh, PA 15235
(412) 256-2096

Laren Tolbert
Georgia Institute of Technology
School of Chemistry
Atlanta, GA 30332
(404) 894-4043

Eric Van Styland
CREOL
University of Central Florida
12424 Research Parkway
Suite 600
Orlando, FL 32826
(407) 658-6814

Francis Wang
Lawrence Livermore National Lab.
L-250, P.O. Box 808
Livermore, CA 94550
(415) 422-7305

"ORGANIC AND POLYMERIC NONLINEAR OPTICAL MATERIALS"

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List of Registrants: Addendum #2

William Krug
Boeing Electronics High Tech Center
P.O. Box 24969
M.S. 7J-27
Seattle, WA
(206) 865-3033

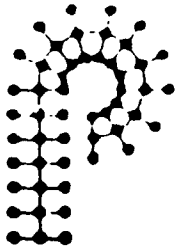
James Le May
Lawrence Livermore National Lab.
P.O. Box 808
Livermore, CA 94550
(415) 422-7305

Edward Miao
Boeing Electronics High Tech Center
P.O. Box 24969
M.S. 7J-27
Seattle, WA 98124
(206) 865-3027

George Rayfield
University of Oregon
Eugene, OR 97403
(503) 382-4100

Nan-Loh Yang
Chemistry Dept.
St. George Campus
CCNY
50 Bay St.
Staten Island, NY 10301
(718) 390-7994

Stanley C. Israel
Dept. of Chemistry
University of Lowell
Lowell, MA 01854
(617) 452-5000



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LUNCH

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12:20		*"Closing Remarks"* byK.J. Wynne(Office of Naval Research)

* *

D. R. Ulrich
Air Force Office of Scientific Research

AN OVERVIEW ON NONLINEAR OPTICAL POLYMER SYSTEMS AND DEVICES

Accession For
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BRIEFER:

Dr. Donald R. Ulrich

Directorate of Chemical & Atmospheric Sciences
AFOSR

NLO Response in Polymers

Molecular Level — Microscopic Polarization Related to Applied Electric Field

$$p(E) = \alpha E + \beta E^2 + \gamma E^3 \ldots$$

Macroscopic NLO — Originates From Polarization Response of Molecular Electrons

$$P(E) = \chi^{(1)}E + \chi^{(2)}E^2 + \chi^{(3)}E^3 + \ldots$$

- $\chi^{(1)}$ — Represents Linear Optics
- $\chi^{(3)}$ — Represents Third Order Nonlinear Process i.e., Third Harmonic Generation, Self-Focusing

First and Third Order Terms of Odd Power of E Common to All Materials — Centrosymmetric

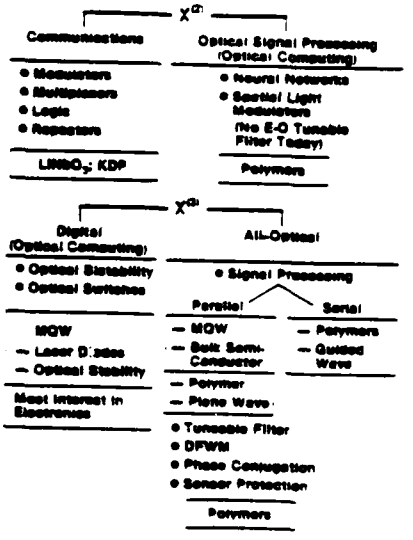
- $\chi^{(2)}$ — Second Order Response i.e., Second Harmonic Generation, Optical Rectification

Only in Noncentrosymmetric Medium — Lacks Center of Inversion Symmetry

Why NLO Polymers?

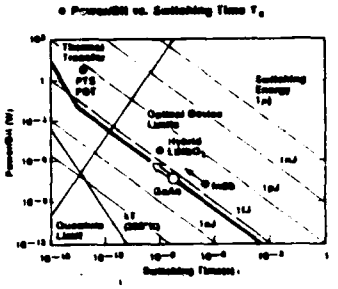
- Subpicosecond Response Times
- Large, Nonresonant Nonlinearities
- Low DC Dielectric Constants
- Low Switching Energy
- Broadband
- Low Absorption
- Absence of Diffusion Problems
- Potential for Resonant Enhancement
- Ease of Processing and Synthesis Modification
- Room Temperature Operation
- Environmental Stability
- Mechanical and Structural Integrity

Where Will NLO Polymers Fit In?



Comparison of Optical Switching Technologies

- Fastest Switches Based on Nonresonant Nonlinearity
- Power Requirements Inversely Proportional to Nonlinearity
- New Organic Polymers May Exceed Optical Device Limits of Resonant Materials
  - Requires Larger n_2 Without Introducing Significant New Absorption
- For $\lambda \geq 0.85$ μm, There are No Alternatives to Organics for Fast Optical Switching

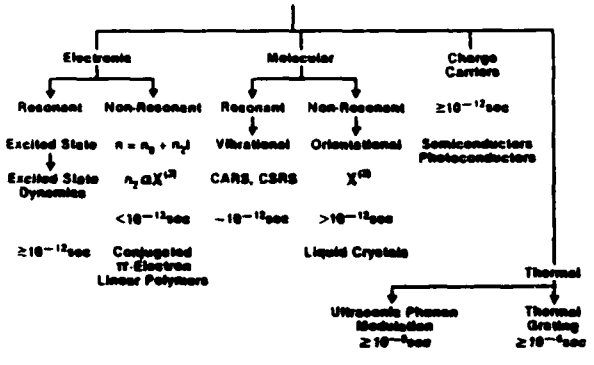


- Extrapolated to λ^2 Cross-Section Devices
- Length Adjusted for Minimum Switching Energy

Optical Performance Comparison

	Polymers	GaAs/GaAlAs
Switch On/ Switch Off, T (Recovery Period)	• Femtoseconds	• Nanoseconds
Energy Required to Induce Switching	• Moderate N_2 • Nonresonant • Not Defined by λ • Broad Band of Response and Light Sources • Shows all NLO Processes	• High N_2 • Resonance Enhanced • Limited by λ • Close to Bandgap • NLO 3D Order, But Not Optical Amplification or THG
Absorption Coefficient, α Associated With Switching	• $\frac{1}{10^4}$ GaAs	• Large
Figure of Merit FOM = $\frac{n_2}{\alpha T}$	• High (1×10^7)	• Moderate (1.5×10^5 on Resonance)

Mechanisms of Four Wave Mixing



Research Directions NLO Polymer Requirements

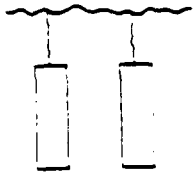
- Nonlinear Susceptibilities $\geq 10^{-6}$ esu
  - *Resonant vs Nonresonant*
- Ease of Processing
  - Solubility
- Thin Films of Reasonable Optical Quality
  - Transparency
  - Surface Smoothness
- Environmental Stability
- Low Switching Energy (PJ, Diode Lasers)
- Characterization and Separation of Electronic, Molecular, Thermal and Charge Carrier Contribution Mechanisms to Response Time

Status NLO Polymer Classes

Class	Examples	NLO Function
ISO Tropic	Glasses Alloys Composites	$\chi^{(2)}$, $\chi^{(3)}$
Bond Alternation	Ladder Polymers PTL, PQL Polyacetylene Polythiophene	$\chi^{(3)}$
Liquid Crystalline Polymers (LCP)	Side Chain LCPs	$\chi^{(2)}$
Rigid Rod Aromatic Heterocyclics	PBT LCPs PBO SBL	$\chi^{(3)}$
Polydiacetylenes		Mostly $\chi^{(3)}$ Some $\chi^{(2)}$

Second Order Polymers for Electrooptical Devices

- Pendant Side Chain Structure



- High Activity

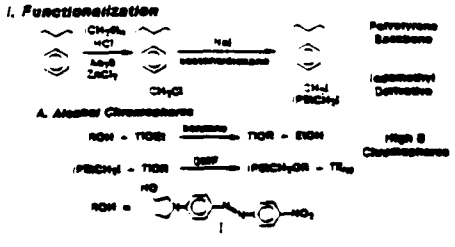
	Polymer	$LiNbO_3$
For SHG	$\chi^{(2)}$ = 120 pm/V	10 pm/V
For Electrooptics	r = 35 pm/V	30 pm/V
FOM = $\frac{r}{\varepsilon}$	10	1

- Excellent Secondary Properties
  - Spin Castable for Thin Film Waveguides, 2-4 Micron
  - Low Dielectric Constant ($\varepsilon_{polymer}$ = 3; ε_{LiNbO_3} = 30)
  - Low Loss (< 1 db/cm at 830 nm)
  - Melt Processable for Optics
  - Tg ~ 120 °C

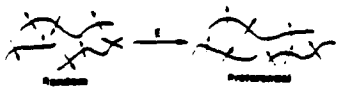
Nonlinear Chromophores Covalently Linked to Glassy Polymer Constructs Noncentrosymmetric Assembly

Synthesis and Poling of Covalently-Functionalized Polymers for Frequency Doubling

I. Functionalization

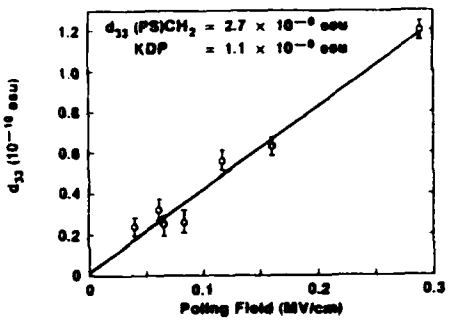


II. Alignment

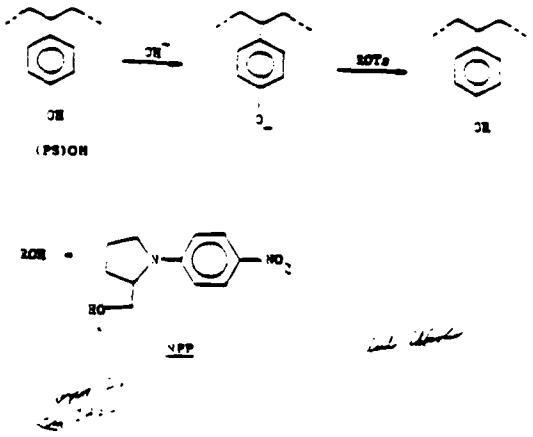


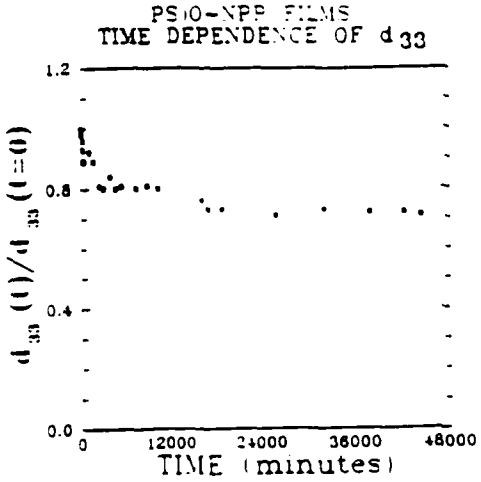
Dependence of SHG On Poling Field

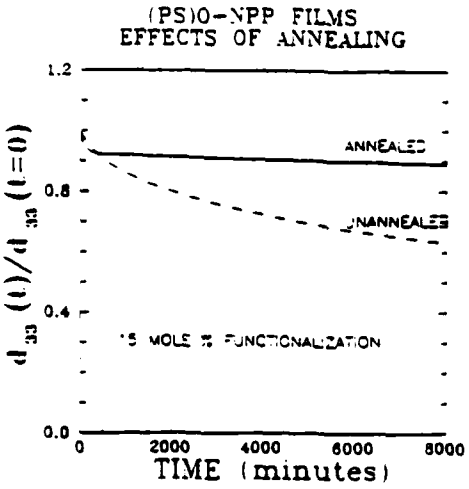
- Significant Non-Random Chromophore Alignment



FUNCTIONALIZATION OF POLY(p-HYDROXY-STYRENE) WITH NLO CHROMOPHORES







Values for $\chi^{(3)}$, Eg, W From Semiempirical Calculations and Experimentally Determined $\gamma(HOMO)^2$ Delocalization Length for Prototype Ladder Polymers and Polyacetylene

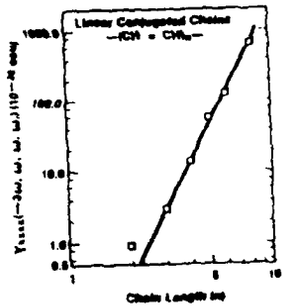
Polymer	Band Gap Eg(eV)	Band Width W(ev)	$\chi^{(3)}$ (esu)	N_d^*
Pristine Trans-PA	1.8	10	6.5×10^{-10}	29
Pristine PXL X = CH Ladder (Chance)	0.7	1.5	5×10^{-10}	26-28
Bipolaron State of PXL X = CH Ladder (Dalton)	0.3	2	10^{-7}	
Protonated PXL	3.8	3	2×10^{-10}	

Implications of $\gamma(HOMO)^2$ Delocalization Experiments For NLO Polymen Synthesis

- Negative Spin Density Confirms Electronic Excitation (Electron Correlation)
- Delocalization Length in Ladder Polymers and Polyacetylene the Same — 26 to 29 Atoms
- Indicates $\chi^{(3)}$ Will Not Increase Beyond 25 Repeat Units (60 Å)
- Ladder Polymers May be Superior to Open Chain Polyanilines Because Improved π-Orbital Overlap Will Lead to Enhanced Delocalization and Reduced Optical Gap

Dependence of $\gamma(-3\omega, \omega, \omega, \omega)$ On Chain Length

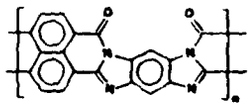
- Finite Chain Limit: $\gamma \propto n^{4.5}$
  - *Decreasing Excitation Energy*
  - Increasing Number of Spin Correlated States
- Polymer Chains: $\chi^{(3)} \sim 10^{-9}$ esu
  - 25 Repeat Units (60 Å)



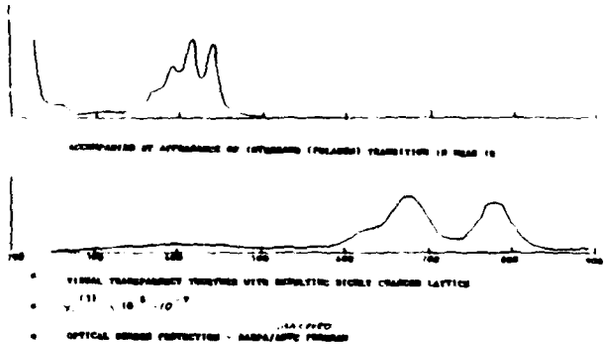
Application of Dalton's Results

- Solubilized Ladder Polymers by Lewis Acid Charge Transfer Complex Forming Agents

Soluble Benzimidazophenanthroline (BBL)



- Soluble in Organic Acids
- Reduces Intermolecular Attractive Forces and Allows Solubilization of Rigid Macromolecules



NONLINEAR OPTICAL AND PHOTOCHROMIC POLYMERS

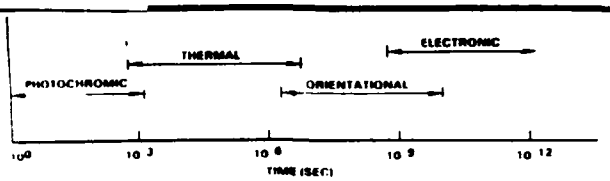
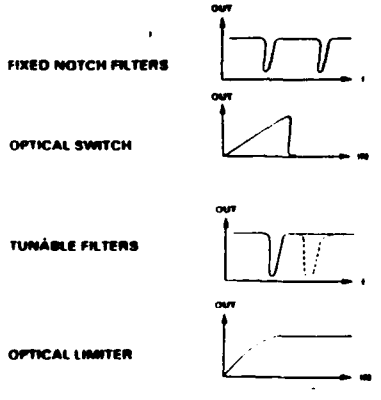


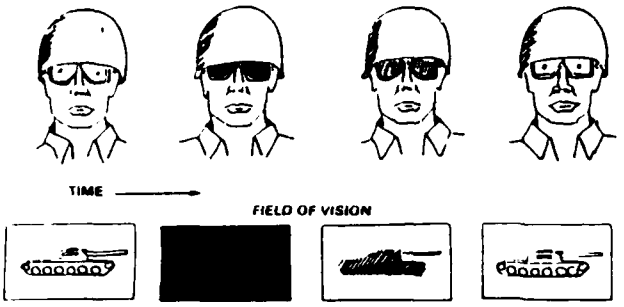
PHOTO-CHROMIC	THERMAL NONLINEARITY	ORIENTATIONAL KERR NONLINEARITY	ELECTRONIC KERR NONLINEARITY
– OPTICAL FUSE	– DYE SENSITIZED THERMAL EFFECT	– LIQUID CRYSTAL POLYMERS	– ELECTRONIC $\chi^{(3)}$ POLYMERS
– 10^3 D.C.	– 10^{-3} - 10^{-7} SEC	– 10^{-7} - 10^{-10} SEC	– 10^{-9} - 10^{-12} SEC
THREAT	**THREAT**	**THREAT**	**THREAT**
– GAS LASERS	– PULSED FLASH LAMP PUMPED LASERS	– Q-SWITCHED SOLID STATE LASERS	– Q-SWITCHED SOLID STATE LASERS
– CW SOLID STATE LASERS	– GAS LASERS	– PULSED FLASH LAMP PUMPED LASERS	– MODE LOCKED LASERS
	– CW SOLID STATE LASERS		

HARDENING TECHNIQUES



- SUB NANOSECOND RESPONSE TIMES
- MILLISECOND RECOVERY SPEEDS (AT LEAST)
- BROADBAND WAVELENGTH RESPONSE (OVER VISIBLE AND NEAR IR)
- REJECTION EFFICIENCY >99% BEFORE AND AFTER SWITCHING
- HIGH DAMAGE THRESHOLDS (J/cm^2)
- LOW INSERTION LOSSES AND MINIMAL RETROFIT COMPLEXITIES

SENSOR PROTECTION



FOCUS IS ON CONCEPTS WHICH CAN:

- PROTECT AGAINST RAPIDLY TUNABLE, PULSED, VISIBLE AND NEAR IR LASER THREATS TO HIGH GAIN OPTICAL SYSTEMS
- USEFUL FOR RANGEFINDERS, VISUAL SENSORS, CAMERAS, AND MOST IMPORTANTLY, THE EYE

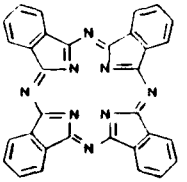
Third Order Polymers for Optical Devices

- Planar Structure With Extended π Orbitals

M = Metal Atom

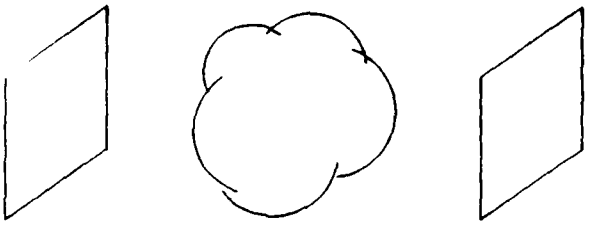
- Shift In Focus From Conjugated Off-Resonance to Systems on Resonance With Narrow Molecular Extinction Coefficients
- High Activity Through Saturable Absorption
  - Effective N_2 Equals AlGaAs MQW Structures
- Excellent Secondary Properties
  - Spin Coatable For Thin Film Structure Applications
    - Optical Bistability
    - Parallel Processing

Phthalocyanines



- Large NLO response discovered by A. Garito
- Numerous variants synthesized to tailor
  - NLO activity
  - Fabrication properties

Basic Structure of an Optical Neural Network



Input Plane of Neurons

N , X (i) 's

Optically Implemented Interconnections

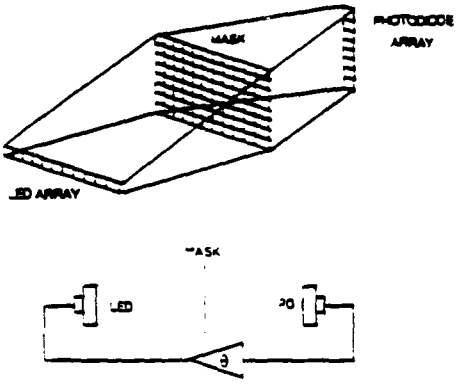
W (i,j) 's

$N^2 \rightarrow N^{3/2}$

Output Plane of Neurons

N , X (j) 's

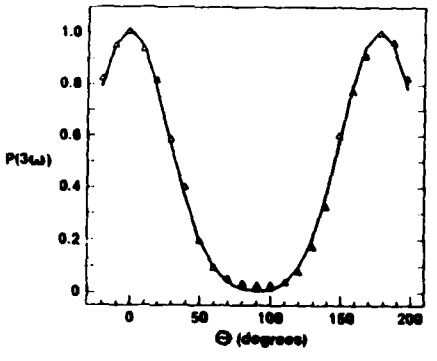
OPTOELECTRONIC IMPLEMENTATION OF A NEURAL NETWORK



ELECTRONIC FEEDBACK

- [illegible] - FIXED OPTICAL BISTABILITY COMPARABLE TO GaAs IN FAMILY - FIXED STATES OF 100nA POLYMER FILM
- [illegible] ARRAY OF OPTICAL BISTABLE ELEMENTS THAT COULD REPLACE PHOTODIODES

Angular Dependence of Reflected $\chi^{(3)}$ for Oriented Trans-Polyacetylene by Third Harmonic Generation

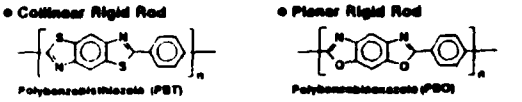


Third Order Response in Polyacetylene

- Resonant Process
  - Photoexcited Nonlinear Excitations
  - Associated Structural Distortions (Solitons, Bipolarons, Polarons) Responsible for Large Shifts of Oscillator Strength Observed With Resonant Pumping Consequence of Electron-Phonon Interaction
  - Electronic Resonant Enhancement
    - Nonradiative Dissipation Produces Slower Responses
- Reflected $\chi^{(3)}$
  - 9×10^{-10} esu Parallel to Polymer Chain
  - For Devices Polymer Must Be Able to Inherently Transmit or Guide Light

Third Order NLO Response of Ordered Polymers

- Collinear Rigid Rod
- Planar Rigid Rod

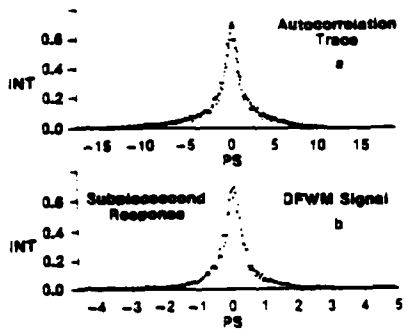


COMPARISON			
Uniaxial PBT	— Third Harmonic Generation	— $\chi^{(3)} \simeq 10^{-10}$ esu	
Biaxial PBT	— Degenerate Four Wave Mixing (DFWM)	— $\chi^{(3)} \simeq 10^{-11}$ esu	
Uniaxial PBO	— Degenerate Four Wave Mixing	— $\chi^{(3)} \simeq 2.5 \times 10^{-11}$ esu	

- Requirement for Film Quality — Avoid Inherently Grain or Fibrous Components Which Scatter Light

Degenerate Four Wave Mixing of Biaxial PBT Ordered Polymer Films

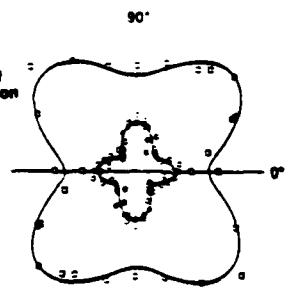
Poly (p-phenylenebenzobisthiazole) (PBT)



Nonresonant Third Order Susceptibility $\chi^{(3)}$ in Biaxial PBT

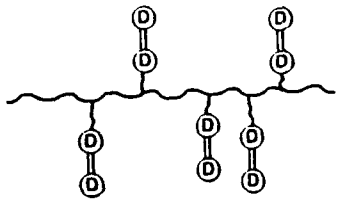
- Degenerate Four Wave Mixing

Polar Plot: $\chi^{(3)}$ As a Function of Film Rotation Angle



- New Feature for Third Order Devices
- Anisotropic $\chi^{(3)}$ Materials for Optically-Activated Birefringent Film Applications

$\chi^{(3)}$ Polymers for Fibers



- $\chi^{(3)}$ units have modest activity but very low absorption
- Polymer backbone confers secondary properties
  - Spinability
- Shear and elongational flow yield alignment

$\chi^{(3)}$ Materials

Thin Limit	Thick Limit
Properties	**Properties**
• Near reasonance	• Non resonant
• High n_2	• Lower n_2
• High absorption (α)	• Very low absorption
Material	**Material**
• Phthalocyanines	• Side chain polymer
Application	**Application**
• Etalons	• NLO fibers
• All optical SLM's	• All optical switching
Advantages	**Advantages**
• Fabrication ease	• Fiber spinning ease
• Room temperature operation	• Potentially highest n_2/α materials
• Potentially highest n_2 materials	

POLYALKYLTHIOPHENE

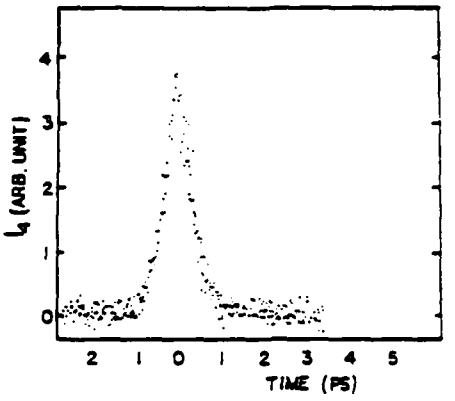
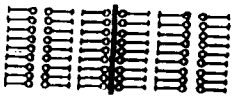


Fig. The degenerate four wave mixing signal obtained for a 20 layer thick Langmuir-Blodgett film of polyalkylthiophene shown as a function of the delay of the backward beam; the wavelength is 602 nm and the excitation pulsewidth is 340 fs.

$\chi^{(3)} \sim 10^{-9}$ esu

POLYMER MULTIPLE QUANTUM WELLS



MOLECULAR ARCHITECTURE ENGINEERING

- o LIQUID CRYSTALLINITY
- o GUEST-HOST BLENDS
- o IN-SITU POLYMERIZATION AND ORDERING
- o RIGID/FLEXIBLE CHAIN CONFORMATIONS

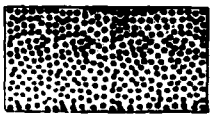
- o NEW HETEROSTRUCTURE ASSEMBLIES
  - GaAs ANALOGS
  - NON GaAs ANALOGS
- o QUANTUM DOT DOMAIN STRUCTURES

CHARGE CARRIER DYNAMICS

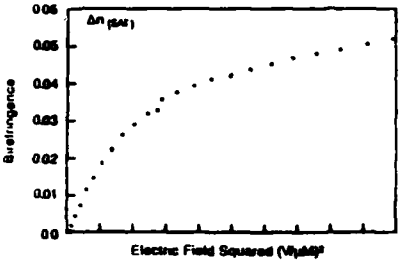
- o CHARGE TRANSFER INTERACTIONS
- o REDUCE DIMENSIONALITY OF CHARGE CARRIERS
- o INTERFACE SHG
- o PICOSECOND TRANSIENT ABSORPTION/GRATING
- o TRANSIENT ETALON EFFECTS/PHONON INDUCED PROCESSES

LCC Composite

New LCC's



- d << λ (Rayleigh scattering regime)
- Randomly oriented LC microdroplets
- Low scattering - hazy blue to transparent
- Kerr material with positive n_2



ADVANCED POLYMER BLENDS AND OPTICS

NLO POLYMERS

GENERATION	SECOND ORDER NLO, $\chi^{(2)}$	THIRD ORDER NLO, $\chi^{(3)}$
I (1985 - 1990)	HOMOPOLYMERS	
	o ISOTROPIC	o BOND ALTERNATION
	o POLED	o LADDER
	o ORIENTED	o ORDERED
II (1990 - ?)	POLYMER - POLYMER INTERACTIONS { BLENDS - ALLOYS / MOLECULAR COMPOSITES }	
	o SELF-INDUCED POLARIZATION	o NEAR-OFF RESONANCE
	o SELF-ORGANIZING	o PLANAR

IMPROVEMENTS IN CALCULATION OF NLO SINGLE-MOLECULE PROPERTIES

PARALLEL COMPUTING

ABSORPTION LINEWIDTHS

MOLECULAR CONFORMATIONS AND DEFECTS

DEVELOPMENT OF ALTERNATIVE METHODOLOGIES, SUCH AS FINITE FIELD APPROACHES

GENERALIZATION OF SINGLE-MOLECULE TO BULK NLO PROPERTIES

STATISTICAL AVERAGING OF ORIENTATION (FROZEN GAS MODEL)

STATISTICAL AVERAGING OF CHAIN LENGTHS

EFFECTS OF INTERMOLECULAR INTERACTIONS ON SINGLE MOLECULE NLO PROPERTIES

EFFECTS OF INTERMOLECULAR INTERACTIONS ON MOLECULAR CONFORMATION AND STRUCTURE

EFFECT OF INTERMOLECULAR INTERACTIONS ON MATERIAL ULTRASTRUCTURE

THE KEY: INTERMOLECULAR INTERACTIONS!

Status of Understanding for Polymer Design

Detailed Mechanism(s) of Nonlinear Optical Activity in Delocalized Electron Polymers Have Yet to Be Defined

- Nonlinear Optical Activity May Not Be Simply Related to Bandgap
- Potential Contributions of D Orbitals to NLO (S-D Cross-Terms)
- Role of Electron-Phonon Interactions
- A Qualitative Correlation Between $\chi^{(3)}$ and Electron Delocalization Length
- Effect of Doping and Intermolecular Charge Transfer Needs to Be Clarified
- Quantitative Theory Lacking to Predict Macromolecules With Large Second Order (Beta) and Third Order (Gamma) Molecular Susceptibilities

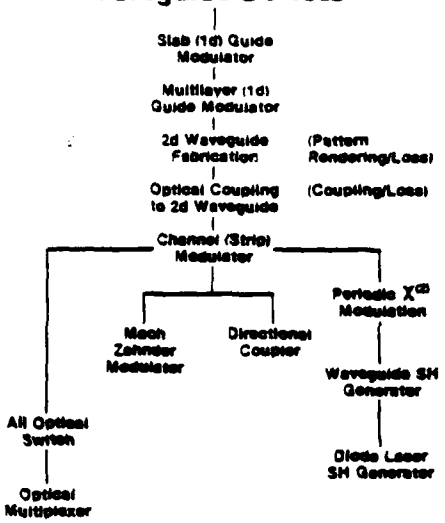
State-of-Art $\chi^{(2)}$ Devices

- Traveling-Wave Electrode Mach-Zehnder Electrooptic Modulator

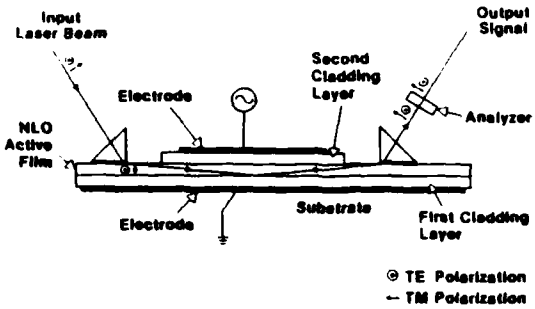
	$LiNbO_3$ Modulator	Polymer Modulator
Switching Voltage (V)	3 1/2 - 10 1/2	1.3 (0.7 With Higher $\chi^{(2)}$)
Power Requirement (W)	0.6 - 5	0.03
Maximum Frequency (GHz)	8 - 24	> 50

  - No Expected Velocity Mismatch Implies Higher Frequency Devices are Possible With Polymers
- Electrooptic Bragg Cell
  - High Speed Radar Signal Processing
  - 20 GHz as a Target
- Second Harmonic Generation
  - High Efficiency Doubling of a Diode Laser

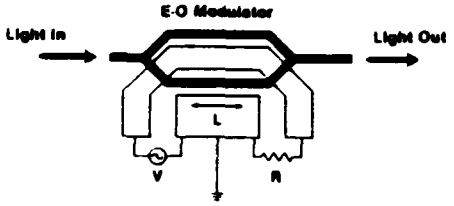
Waveguide Devices



Polymeric Electrooptic Modulator



Traveling-Wave Waveguide

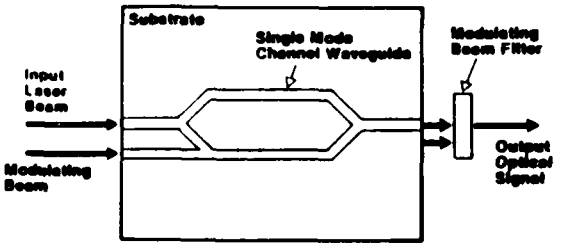


- Voltage Varies Along the Length ($L \geq \lambda$ Electrical)
- Important Device Parameters:
  - Voltage
  - Optical Mode Size
  - Drive Power
  - Speed
  - Length
  - Impedance

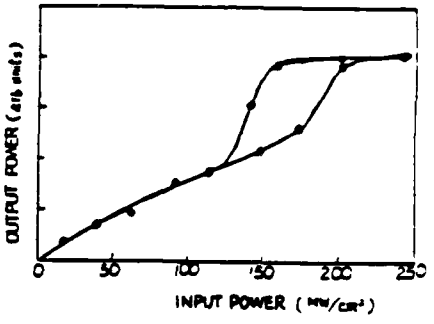
State-of-Art $\chi^{(3)}$ Devices

- Far Less Progress Than $\chi^{(2)}$
- Large Payoff in Multiplexing and Demultiplexing
  - High Speed
  - Handle Many Inputs
  - Very High $\chi^{(3)}$
- Can Lead to:
  - All Optical Interferometer and Optical Switch
  - Optical Bistability and Digital Optical Information Processing
  - Optically Induced Dynamic Grating and Real-Time Holography
- Device Performance Depends on Material Properties in a Complicated Way
  - Determined by Device Architecture
  - Parallel/Analog Processing of 2D Image
  - Phase Conjugate Optics and Image Processing
  - Self Focusing/Defocusing Applications

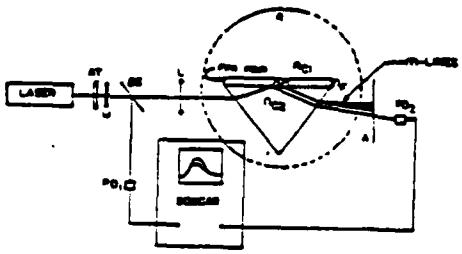
Mach-Zehnder All Optical Modulator



OPTICAL BISTABILITY IN A
NONLINEAR POLYMER
FABRY-PEROT ETALON



OPTICAL BISTABILITY IN A POLYMER
QUASI WAVE GUIDE INTERFEROMETER



MERITS:

(i) Obtain Linear Refractive Index and Film Thickness

(ii) Obtain Both Magnitude and Sign of $\chi^{(3)}$

Ref 28

OPTICAL BISTABILITY IN A
NONLINEAR POLYMER
QUASI-WAVEGUIDE INTERFEROMETER

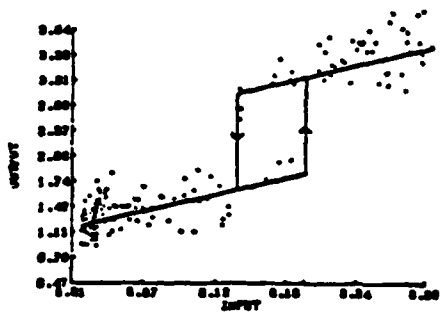


Figure 1. The observed optical bistability behavior in the poly-[DEH] polymer quasi-waveguide interferometer. The detuning angle is 400°.

Summary

Second Order

- Poled Polymer Films
  - Close to Achieving Levels of Response for Electrooptic Device Application
- First Polymers Comparable to Lithium Niobate Reported
- Focus for Research to Achieve Optimum Electrooptic Modulation
  - $\chi^{(2)}$ Parallel to Film Surface

Third Order

- Nonlinearities of 10^{-9} esu Large for Nonresonance but Still Needs to be Larger ($\approx 10^{-7}$ esu) for Broad Device Application
- State-of-Art of 10^{-9} esu Will Find Applications in Optical Wave Guide Devices Such as Optical Switches and Optically Controlled Modulators
- Thin Film Applications Such as Etalons Unlikely Unless Significant Advances in Larger Nonlinearities, Optical Flatness and Optical Clarity

P. N. Prasad
State University of New York at Buffalo

NONLINEAR OPTICAL EFFECTS IN POLYMERIC FILMS

B-2

NONLINEAR OPTICAL EFFECTS

IN

POLYMERIC FILMS

PARAS N. PRASAD

DEPARTMENT OF CHEMISTRY

STATE UNIVERSITY OF NEW YORK AT BUFFALO

BUFFALO, NEW YORK 14214

SECOND ORDER NONLINEAR OPTICAL PROCESSES

CURRENT STATUS

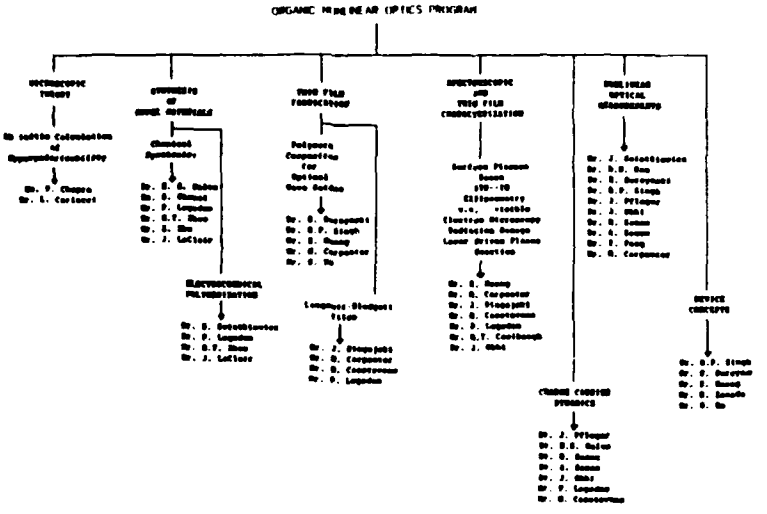
1. PREDICTABILITY OF STRUCTURE FOR MOLECULAR ENGINEERING
   → REASONABLE

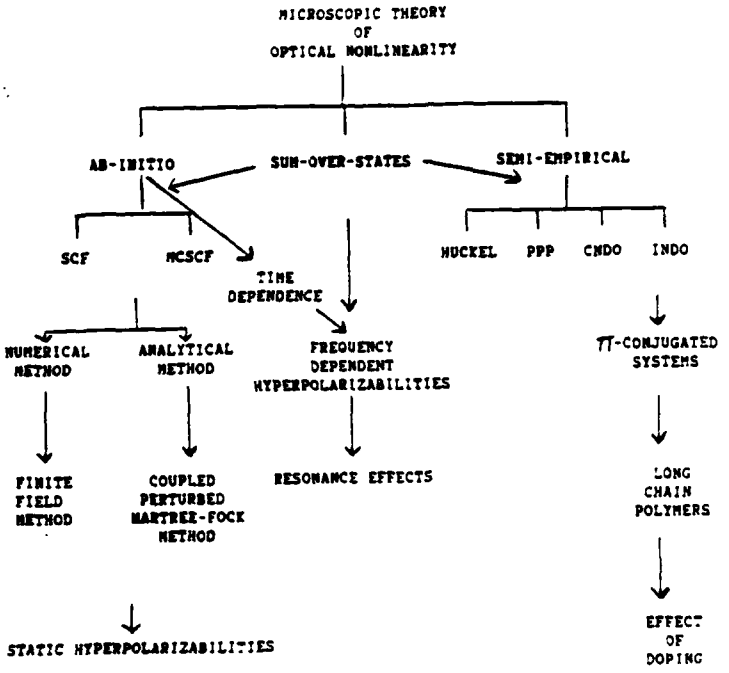
2. LARGE $\chi^{(2)}$
   FAST RESPONSE TIME → ALREADY ACHIEVED
   LOW DC DIELECTRIC CONSTANT

3. GUIDED WAVE PROCESSES - ALREADY DEMONSTRATED

4. POLYMERIC STRUCTURES
   NOT REQUIRED, BUT MAY BE DESIRABLE FOR MATERIALS PROCESSING AND DEVICE APPLICATIONS
   DOPED POLYMERS, LIQUID CRYSTALLINE POLYMERS, ETC.

5. DEVICES (?) : RESTRICTED BY MATERIALS LIMITATION





Ab-initio Calculations of Second Hyperpolarizabilities (γ)

OBJECTIVE: Relative importance of σ and π contributions

Comparison of various π electron structures

π-electron conjugation effect

Sign of γ

Anisotropy of γ tensor

Effect of substituents

Conformational effect

Effect of Structural (conformational) defects such as solitons, polarons and bipolarons

⇩

Identify Structural Parameters for enhancing $\chi^{(3)}$

Ab-initio approach

DEFINE MOLECULAR HAMILTONIAN INCLUDING FIELD DEPENDENT STARK TERM

CONSTRUCT LCAO - MO - SLATER DETERMINANTS WITH A CHOICE OF AO BASIS SET

OPTIMIZE THE GEOMETRY USING SCF

CALCULATE DIPOLE MOMENT AS A FUNCTION OF FIELD

POLYNOMIAL FIT TO GET γ

CHANGE FIELD DIRECTIONS TO CALCULATE DIFFERENT COMPONENTS OF γ

ORBITAL TRANSFORMATION TO SEPARATE σ AND π-CONTRIBUTIONS

CONTOUR PLOTS TO OBTAIN FIELD INDUCED CHARGE REDISTRIBUTION

STATIC SECOND HYPERPOLARIZABILITIES (γ)

NONRESONANT VALUE

MERITS OF THIS APPROACH:

ONLY GROUND STATE PROPERTIES NEED TO BE DEFINED

IN PERTURBATIVE CALCULATIONS INVOLVING EXCITED STATES EXPRESSION, EXCITED STATE PROPERTIES NEED TO BE CALCULATED

B-4

SOME CONCLUSIONS OF THEORETICAL STUDIES OF MICROSCOPIC NONLINEARITY

1. THE CHOICE OF BASIS, PARTICULARLY THE INCLUSION OF DIFFUSE POLARIZATION FUNCTIONS, IS IMPORTANT IN DESCRIBING THE HYPERPOLARIZABILITIES OF CONJUGATED SMALL MOLECULES.

2. γ IS ANISOTROPIC, WITH THE COMPONENT γ_{ZZZZ} ALONG CHAIN GROWING RAPIDLY FOR THE CONJUGATED HYDROCARBONS SERIES POLYENES, POLYYNES AND CUMULENES AS THE CHAIN LENGTH GROWS.

3. FOR POLYENES, CHAIN LENGTH DEPENDENCE OF $N^{3.2}$ IS FOUND. N^{5} AND $N^{5.3}$ FREE ELECTRON MODEL AND HUCKEL MODEL PREDICT RESPECTIVELY.

4. THE CORRESPONDING ORBITAL ANALYSIS SHOWS THAT THE SIGMA AND π-ELECTRON CONTRIBUTIONS TO γ ARE OF OPPOSITE SIGNS.

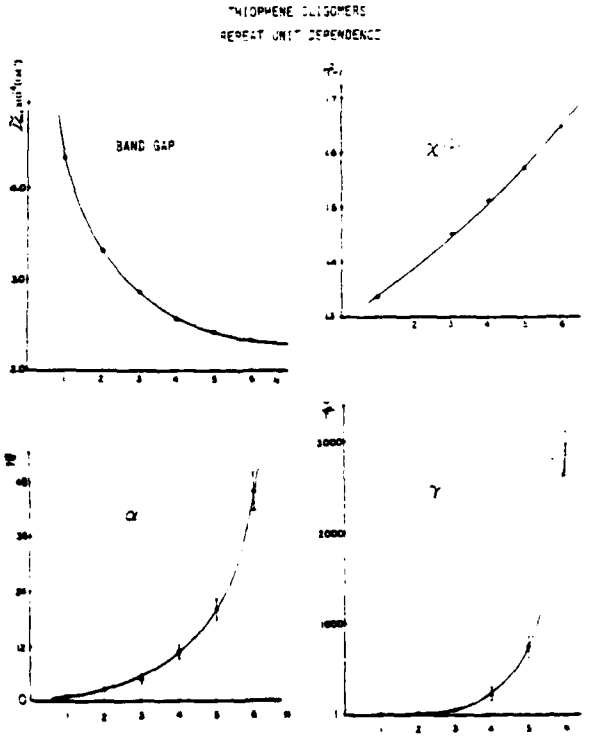
5. CONTOUR MAP OF THIRD DERIVATIVE OF CHARGE DENSITY WITH RESPECT TO FIELD (REGIONAL CONTRIBUTION ANALYSIS OF γ) CONDUCTED FOR POLYYNES, INDICATES THAT THE NONLINEAR ELECTRONIC DISTORTION IS A CO-OPERATIVE EFFECT WITH A SUBSTANTIAL CHARGE TRANSFER ALONG THE ENTIRE LENGTH OF THE CHAIN.

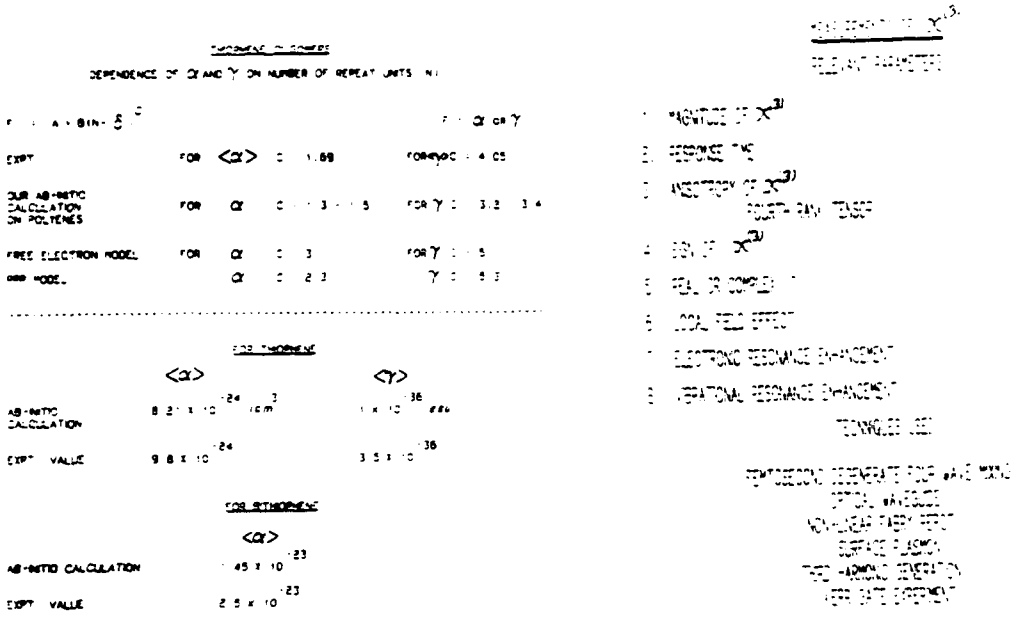
6. OUR SCF CALCULATION RESULTS FOR α COMPARE WELL WITH THOSE OF THE SOS METHOD, BUT γ VALUES DO NOT AGREE.

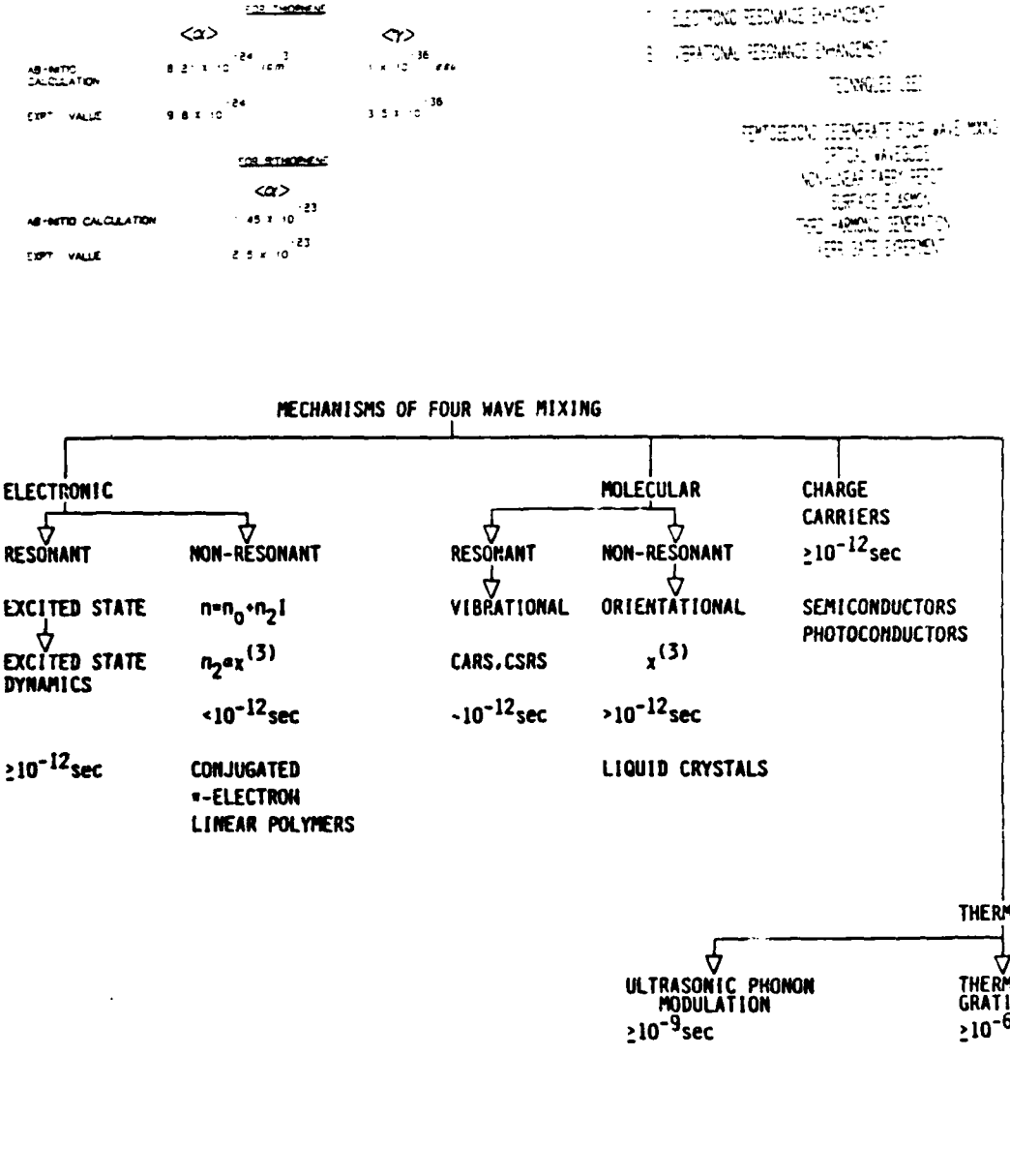
7. IN THE SERIES R1 - C≡C - R2, THE LONGITUDINAL COMPONENT γ_{ZZZZ} INCREASES AS THE ELECTRON WITHDRAWS GROUPS AT R1 OR R2 ARE SUBSTITUTED.

8. A COMPARISON OF γ FOR CIS-BUTADIENE, TRANS-BUTADIENE AND THIOPHENE REVEALS THE FOLLOWING ORDER:

   TRANS-BUTADIENE) THIOPHENE) CIS-BUTADIENE






MECHANISMS OF FOUR WAVE MIXING
ELECTRONIC
RESONANT
EXCITED STATE
EXCITED STATE DYNAMICS
≥10^-12sec
NON-RESONANT
n=n0+n2I
n2αx(3)
<10^-12sec
CONJUGATED π-ELECTRON LINEAR POLYMERS
MOLECULAR
RESONANT
VIBRATIONAL
CARS, CSRS
~10^-12sec
NON-RESONANT
ORIENTATIONAL
x(3)
>10^-12sec
LIQUID CRYSTALS
CHARGE CARRIERS
≥10^-12sec
SEMICONDUCTORS
PHOTOCONDUCTORS
THERMAL
ULTRASONIC PHONON MODULATION
≥10^-9sec
THERMAL GRATING
≥10^-6sec

MEASUREMENTS OF $\chi^{(3)}$

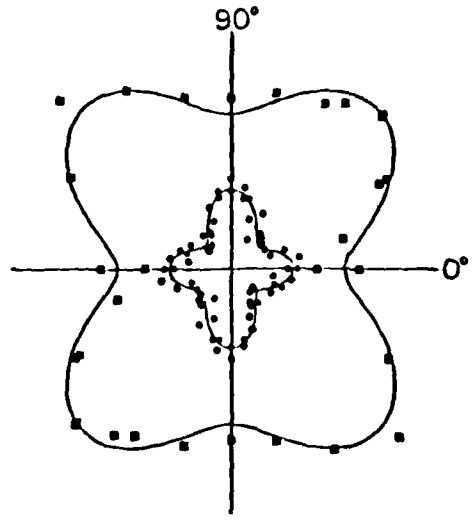
RELEVANT PARAMETERS:

1. MAGNITUDE OF $\chi^{(3)}$
2. RESPONSE TIME
3. ANISOTROPY OF $\chi^{(3)}$
   FOURTH RANK TENSOR
4. SIGN OF $\chi^{(3)}$
5. REAL OR COMPLEX (?)
6. LOCAL FIELD EFFECT
7. ELECTRONIC RESONANCE ENHANCEMENT
8. VIBRATIONAL RESONANCE ENHANCEMENT

TECHNIQUES USED:

FEMTOSECOND DEGENERATE FOUR WAVE MIXING
OPTICAL WAVEGUIDE
NON-LINEAR FABRY PEROT
SURFACE PLASMON
THIRD HARMONIC GENERATION
KERR GATE EXPERIMENT

POLAR PLOT: $\chi^{(3)}$ AS A FUNCTION OF FILM ROTATION ANGLE



RESONANT $\chi^{(3)}$ BY FOUR WAVE MIXING

ELECTRONIC RESONANCES

SYSTEMS	MECHANISM	RESPONSE TIME	$\chi^{(3)}$
PVK THF	CORRELATED ELECTRON-HOLE PAIRS	>100 ps	10^{-11} esu
POLYACETYLENE PMMA	SOLITON POLARON DYNAMICS	fs	10^{-9} esu
PHTHALOCYANINES (LB FILMS)	EXCITON DYNAMICS	ps	10^{-8} esu
POLYTHIOPHENE (ELECTROCHEMICALLY DEPOSITED)	POLARON DYNAMICS	fs	10^{-9} esu
POLYALKYLTHIOPHENE (SOLUTION CAST FILMS) LB FILMS	POLARON DYNAMICS	fs	10^{-9} esu

CAUTION:

$\chi^{(3)}_{\parallel}$ DEPENDENT ON PULSE WIDTH GOING FROM 600 fs TO 6 ps INCREASES $\chi^{(3)}_{\parallel}$ BY A FACTOR OF 5 IN PHTHALOCYANINES

B-7

NONLINEAR OPTICAL EFFECTS
IN
CONJUGATED POLYMERS
WITH
CONFORMATIONAL DEFECTS
(Bond Alternation)

NONRESONANT CASE: Charge on Polymer Backbone can be Varied in a Controlled way - Tune $\chi^{(3)}$

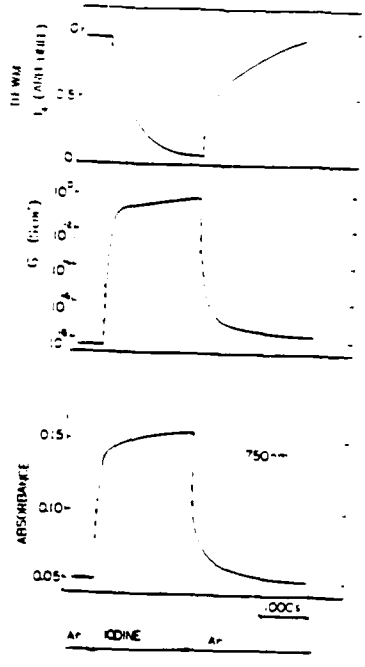
RESONANT CASE: Photoinduced Solitons and Bipolarons create Mid Gap States

Redistribution of Oscillator Strength

Large $\chi^{(3)}$ with Fast Response

A NEW PHENOMENON

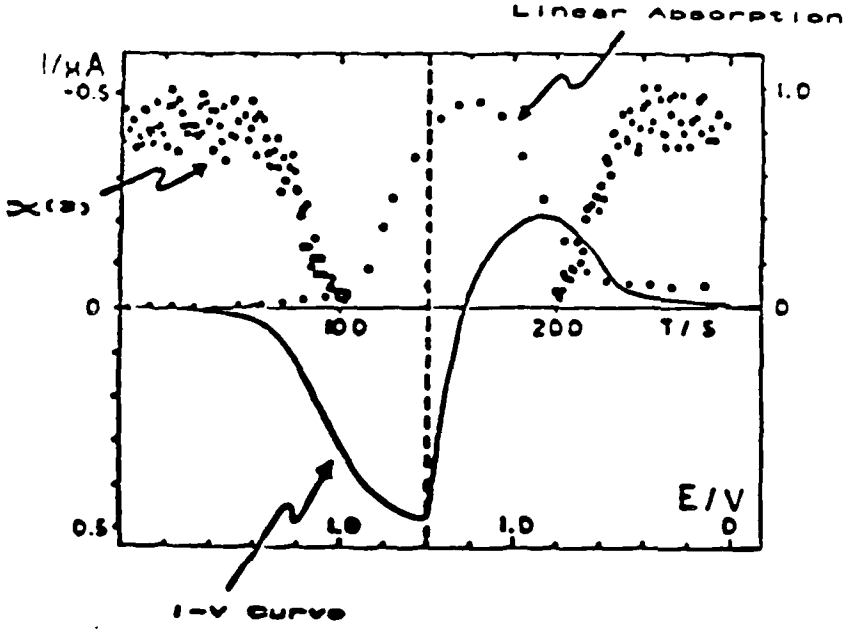
Chemical or Electrochemical Switching of $\chi^{(3)}$ Between High and Low States



POLYALKYLTHIOPHENE - LB FILMS
IODINE DOPING

IN-SITU ELECTROCHEMICAL STUDY OF
$\chi^{(3)}$ IN POLYTHIOPHENE

REDUCED FORM <-> OXIDIZED FORM <-> REDUCED FORM

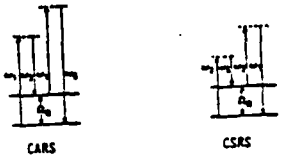


SWIATKIEWICZ, JANISZEWSKA AND PRASAD

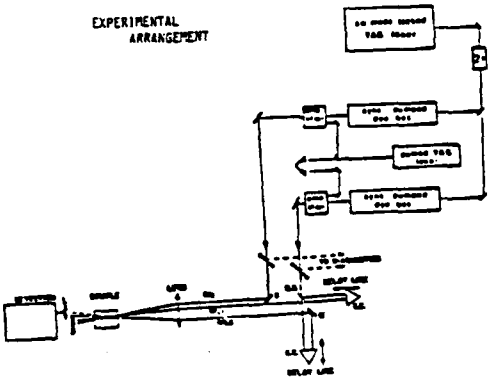
B-8

PICOSECOND TIME-RESOLVED COHERENT
RAMAN SCATTERING

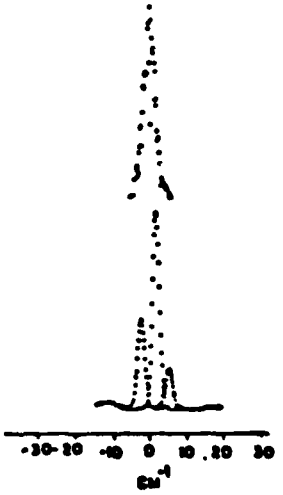
$\chi^{(3)}$

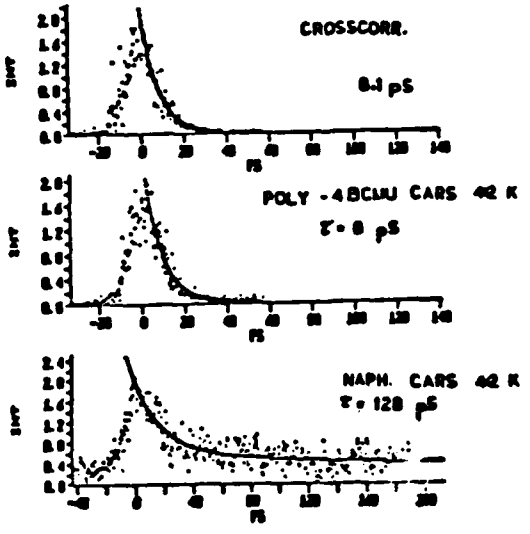


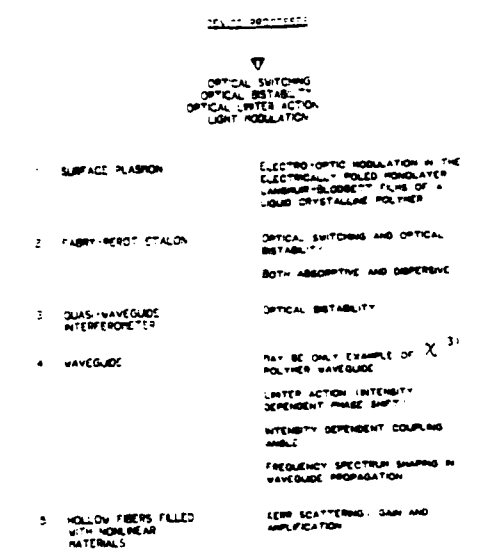
EXPERIMENTAL
ARRANGEMENT

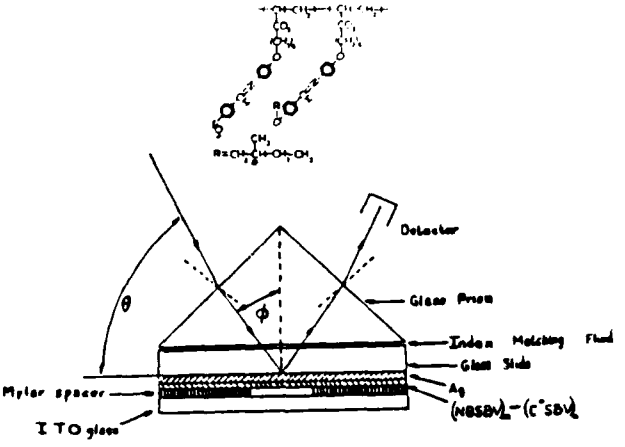


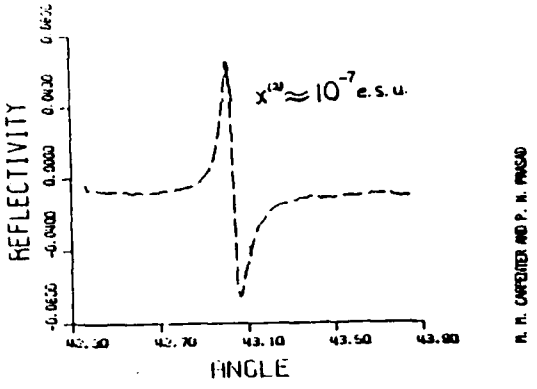
POLY - 4BCMU (LOW MOL. WT), 42 K



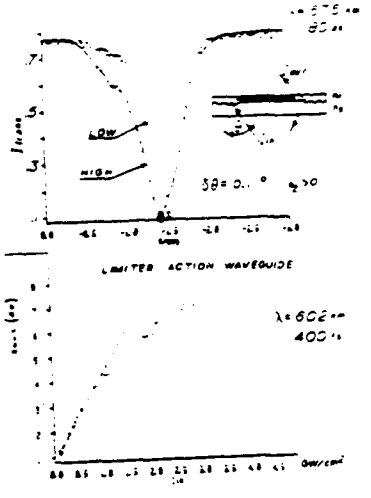


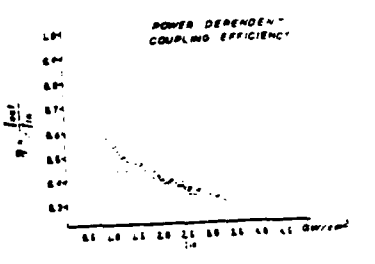






R. R. CARPENTER AND P. N. PRASAD





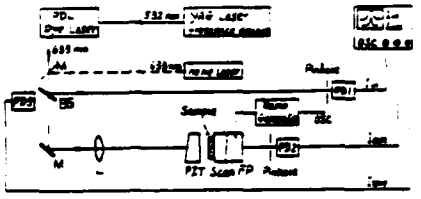


FIG. Experimental setup for the observation of optical instability.

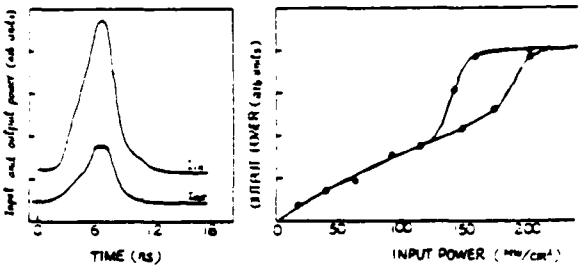


FIG 2 LEFT: INPUT AND OUTPUT PULSES
RIGHT: INPUT-OUTPUT CHARACTERISTICS

ENHANCEMENT OF $\chi^{(3)}$

(A) DO WE NEED EXTENSIVE π = ELECTRON DELOCALIZATION?

BAND GAP REDUCES. PROBLEM WITH NONRESONANT WINDOW

PROBLEM WITH DISTRIBUTION OF CONJUGATION LENGTH

A BROAD DISTRIBUTION OF BAND GAPS.

(B) DO WE NEED A HIGH MOLECULAR WEIGHT POLYMER?

PROBLEM WITH SOLUBILITY

↓

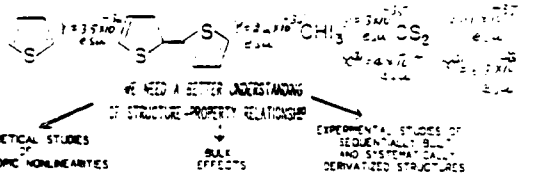
DERIVATIZE WITH LONG ALKYL CHAIN, REDUCES PACKING DENSITY

PROBLEM WITH DISTRIBUTION OF MOLECULAR WEIGHT

↓

REFRACTIVE INDEX INHOMOGENEITIES

(C) DO WE NEED π ELECTRONS?



WE NEED A BETTER UNDERSTANDING OF STRUCTURE-PROPERTY RELATIONSHIPS

THEORETICAL STUDIES OF MICROSCOPIC NONLINEARITIES

BULK EFFECTS

EXPERIMENTAL STUDIES OF SEQUENTIALLY B... AND SYSTEMATICALLY DERIVATIZED STRUCTURES

2 OPTICAL QUALITY MATERIALS

PROCESSABLE MATERIALS

STRUCTURAL CONTROL, CHARACTERIZATION AND MATERIALS PROCESSING FOR LOW OPTICAL LOSS SYSTEMS

3 DEVICE PHYSICS AND DEVICE STRUCTURES

EXPERIMENTS WITH CHANNELED WAVEGUIDES, ETALONS, FIBERS

ACKNOWLEDGEMENT

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MS. P. CHOPRA	MR. X. HUANG
MR. L. CARLACCI	MR. Y. PANG
MS. S. GHOSAL	MR. M. CARPENTER
MR. J. SIEGAJSKI	MR. P. LOGSDON
MR. M.T. COOLBAUGH	MR. M. CASSTEVENS
MR. R. ZAWADA	MR. M.T. ZHAO

DR. DONALD R. ULRICH (AFOSR)

SUPPORT

AIR FORCE OFFICE OF SCIENTIFIC RESEARCH

A. F. Garito
University of Pennsylvania

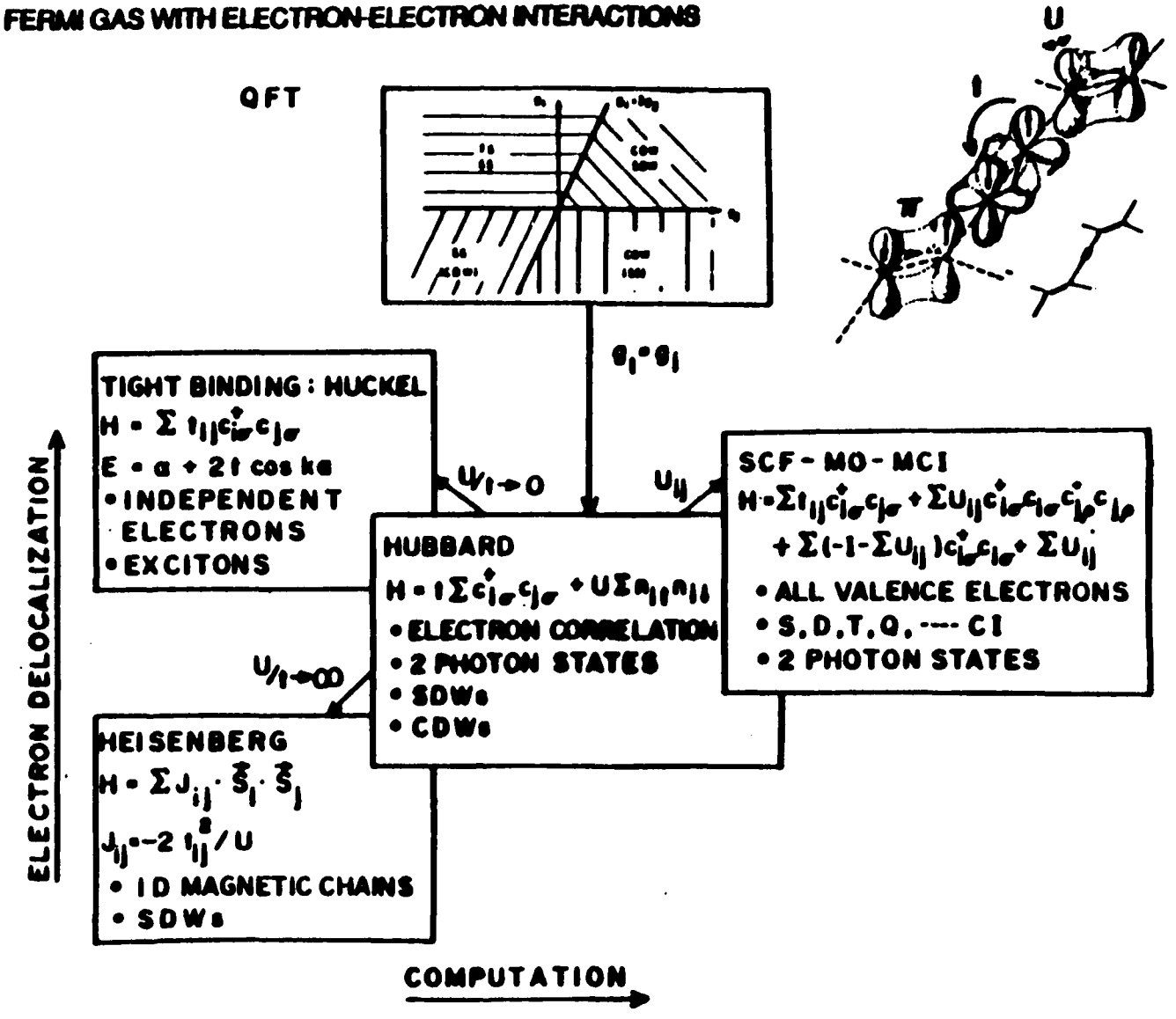
RECENT ADVANCES IN NONLINEAR OPTICAL PROPERTIES OF ORGANIC AND POLYMER SYSTEMS

RECENT ADVANCES IN NONLINEAR OPTICAL PROPERTIES OF ORGANIC AND POLYMER SYSTEMS

A.F. Garito
Department of Physics
University of Pennsylvania
Philadelphia, PA 19104-6396

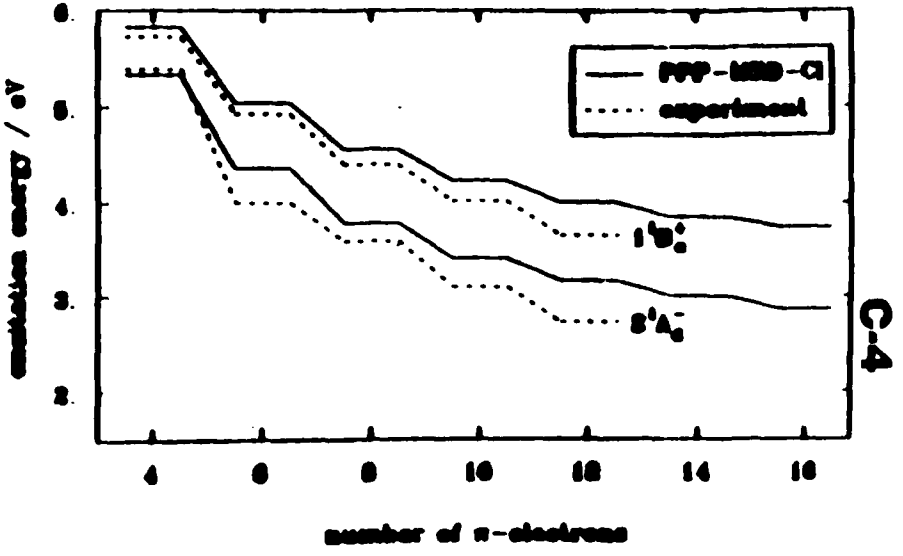
ELECTRON CORRELATED STATES: ORIGIN OF THIRD ORDER NONLINEAR OPTICAL SUSCEPTIBILITY OF CONJUGATED LINEAR CHAINS

FERMI GAS WITH ELECTRON-ELECTRON INTERACTIONS



ELECTRON CORRELATION AND RESONANT PROCESSES

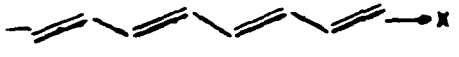
- π-ELECTRON STATES DOMINATED BY ELECTRON CORRELATIONS
- TWO PHOTON 2^1A_g STATE EXISTS BELOW FIRST OPTICALLY ALLOWED 1^1B_u STATE
- PPP AND HUBBARD MODELS OBTAIN CORRECT STATE ORDERING WITH INCLUSION OF AT LEAST DOUBLY EXCITED CONFIGURATIONS (DCI)



FROM TAVAN AND SCHULTEN, J. CHEM. PHYS. 85, 6602 (1986)

ELECTRONIC STATES OF OT

SYMMETRY	ENERGY (eV)	μ_{ag}(D)	$\mu_{1^1B_u,a}$(D)
5^1B_u	7.30	1.14	0.00
6^1A_g	7.16	0.00	•13.24
4^1B_u	7.01	1.11	0.00
3^1B_u	6.47	0.01	0.00
5^1A_g	6.07	0.00	1.11
4^1A_g	6.00	0.00	2.84
3^1A_g	5.19	0.00	0.07
2^1B_u	4.79	0.88	0.00
• 1^1B_u	4.42	•7.81	0.00
• 2^1A_g	4.15	0.00	•2.82
1^1A_g			



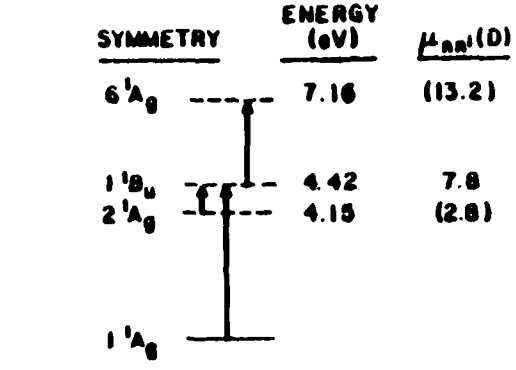
OT (octatetraene)

- DOMINANT 1 PHOTON STATE: ^1B_u
- LOW-LYING 2^1A_g EXCITED STATE: ELECTRON CORRELATION

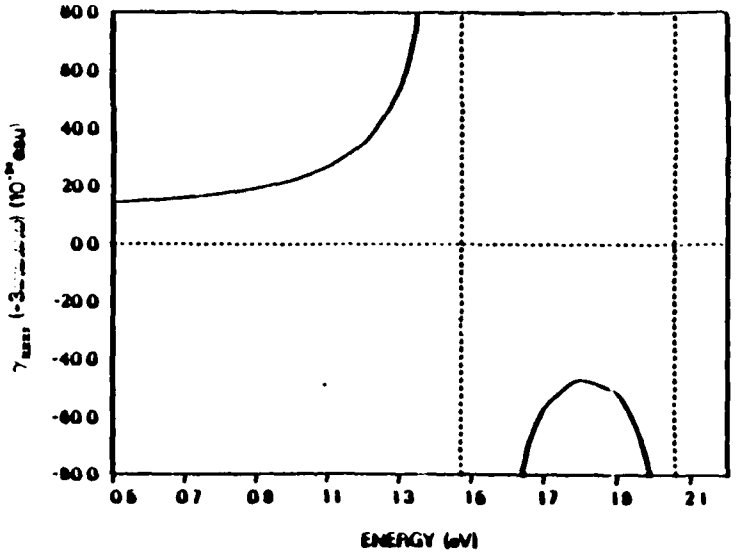
VERTICAL EXCITATION ENERGIES: CHAIN LENGTH

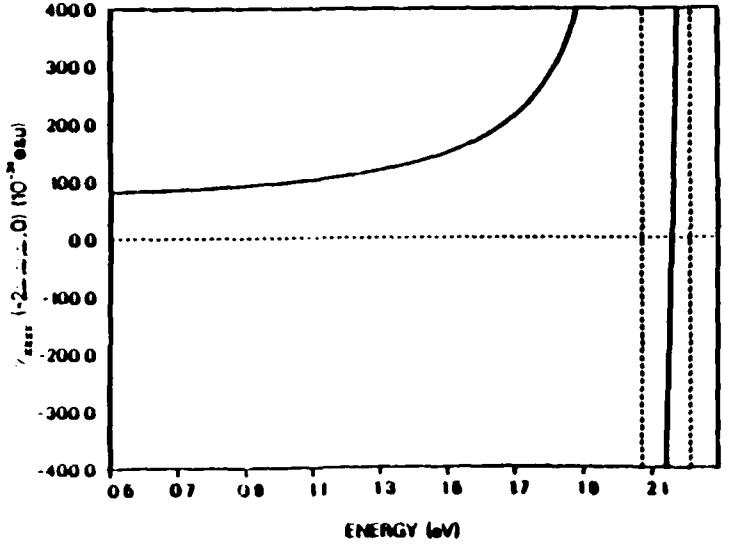
	1^1B_u (eV)		2^1A_g (eV)	
N(sites)	Exp.	Theo.	Exp.	Theo.
4	5.91	5.77	5.4(0-0)	5.31
6	4.93	4.94	4.0(0-0)	4.59
• 8	4.40	4.42	3.97	4.15
10	4.02	4.07	3.48	3.90
12	3.65	3.83	2.91	3.74

MICROSCOPIC ORIGIN OF $\gamma(-3\omega;\omega,\omega,\omega)$ FOR LINEAR CONJUGATED CHAINS



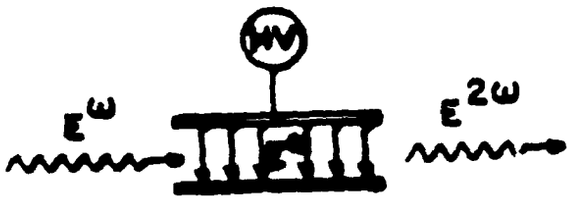
OT





- $\gamma_{xxxx}(-3\omega;\omega,\omega,\omega,\omega) = 15.5 \times 10^{-36}$ esu
  $\gamma_g(-3\omega;\omega,\omega,\omega,\omega) = 3.4 \times 10^{-36}$ esu
  (ω: 0.65 eV/$\hbar$)
- ONLY CONTRIBUTIONS: $g \rightarrow {}^1B_u \rightarrow {}^1A_g \rightarrow {}^1B_u \rightarrow g$
- ^1A_g STATES: THOSE WITH LARGEST $\mu_{nn'}$ WITH DOMINANT ^1B_u STATE
- 2 PHOTON ^1A_g STATES CRITICAL IN THIRD ORDER PROCESSES

DC INDUCED SECOND HARMONIC GENERATION AND γ_g



$$P^{2\omega} = \gamma_g(-2\omega;\omega,\omega,0)\, E^{\omega} E^{\omega} E^{0}$$

$$\gamma_g(-2\omega;\omega,\omega,0) = \frac{1}{5}\left[\sum_i \gamma_{iiii} + \frac{1}{3}\sum_{i\neq j}\left(\gamma_{iiij} + \gamma_{ijij} + \gamma_{ijji}\right)\right] + \frac{1}{5}\frac{\mu}{kT}\beta_x(-2\omega;\omega,\omega)$$

- SECOND ORDER CONTRIBUTION β_x VANISHES BY SYMMETRY

γ_g VALUES (IN UNIT OF 10^{-36} esu) AT 1.787 eV:

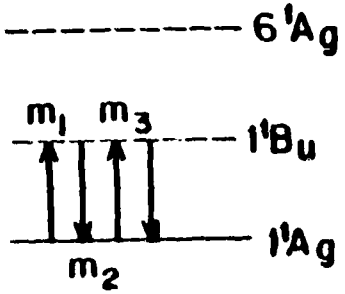
	γ_g (THEORY)	γ_g (EXPERIMENT)
BUTADIENE (N=4)	3.8	3.45 ± 0.2
HEXATRIENE (N=6)	13.9	11.3 ± 1.05
(60% $\perp$ - 40% $\subseteq$)	(12.9)	

- CALCULATED γ_g AGREES WITH EXPERIMENT BOTH FOR THE MAGNITUDE AND SIGN

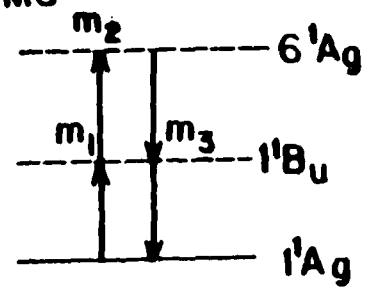
MICROSCOPIC ELECTRONIC ORIGIN OF $\gamma(-3\omega;\omega,\omega,\omega)$

$$\gamma_{ijkl}(-3\omega;\omega,\omega,\omega) = \frac{e^4}{4\hbar^3} \sum_{m_1 m_2 m_3} \frac{\langle g|r_i|m_3\rangle\langle m_3|r_j|m_2\rangle\langle m_2|r_k|m_1\rangle\langle m_1|r_l|g\rangle}{(\omega_{m_1 g}-\omega)(\omega_{m_2 g}-2\omega)(\omega_{m_3 g}-3\omega)} + \cdots$$

- TWO IMPORTANT TYPES OF CONTRIBUTING TERMS

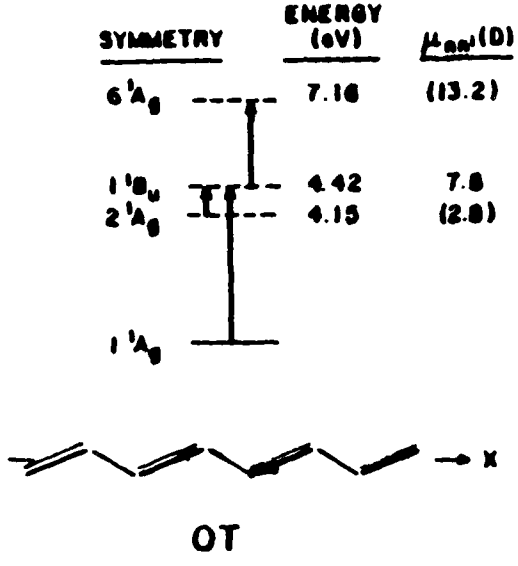


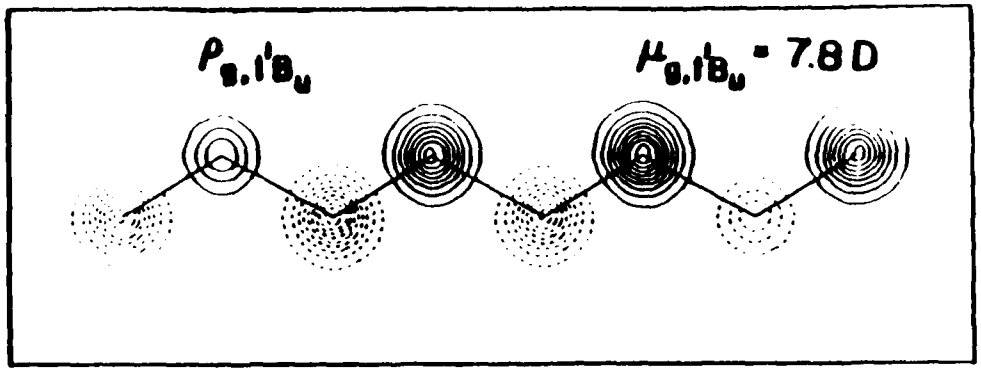
- INTERMEDIATE STATE m_2 IS THE GROUND STATE ITSELF
- NUMERATOR IS POSITIVE
- $(\omega_{gg}-2\omega)$ TERM IN DENOMINATOR IS NEGATIVE
- NEGATIVE CONTRIBUTION TO γ

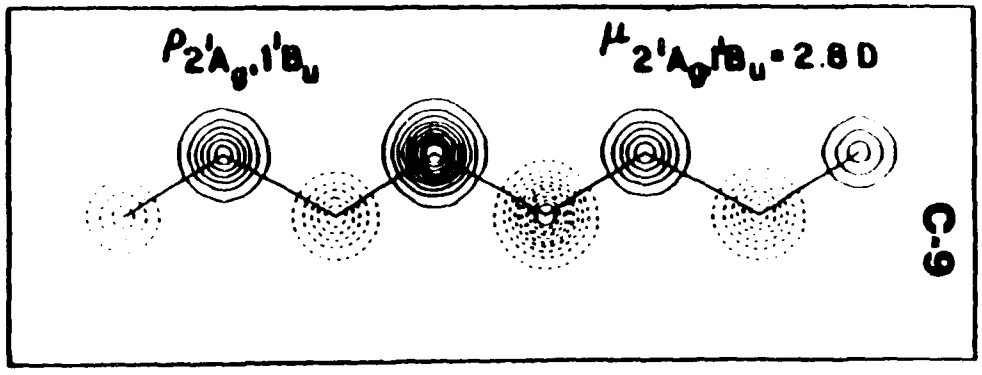


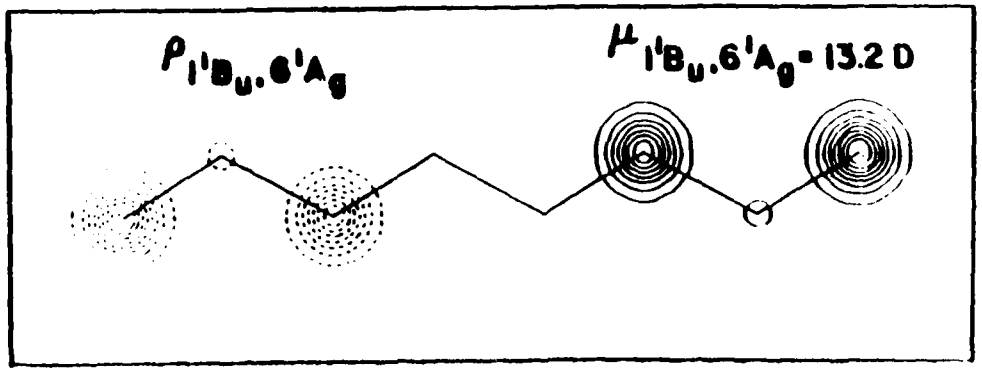
- INTERMEDIATE STATE m_2 IS THE UPPER $6\,^1A_g$ STATE
- NUMERATOR IS POSITIVE
- $(\omega_{m_2 g}-2\omega)$ TERM IN DENOMINATOR IS POSITIVE
- POSITIVE CONTRIBUTION TO γ

TRANSITION DENSITY MATRIX DIAGRAMS









- $\langle \mu_{nn'} \rangle = \int r\, \rho_{nn'}(r)\, dr$
- CORRELATION OCCURS ACROSS ENTIRE CHAIN LENGTH
- $\mu_{1^1B_u,6^1A_g} \gg \mu_{2^1A_g,1^1B_u}$: CHARGE SEPARATION IS LARGEST IN $\rho_{1^1B_u,6^1A_g}$

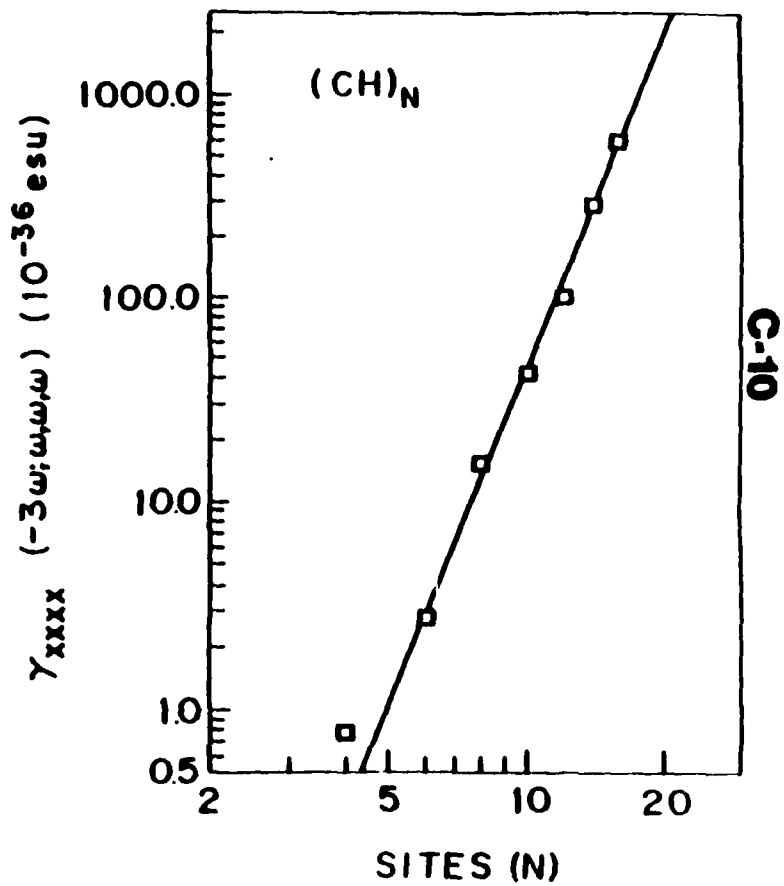
DEPENDENCE OF $\gamma(-3\omega;\omega,\omega,\omega)$ ON NUMBER OF SITES

- FINITE CHAIN LIMIT: POWER LAW DEPENDENCE

$$\gamma_{xxxx} \propto N^{5.4}$$

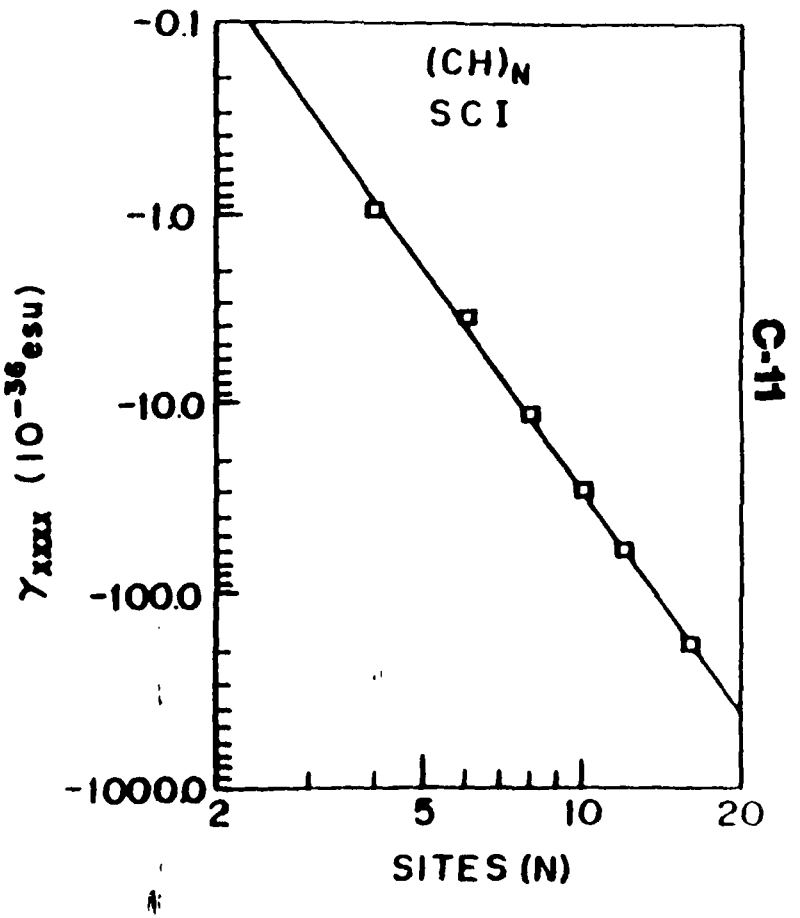
  - DECREASED EXCITATION ENERGY
  - INCREASED TRANSITION MOMENTS
  - INCREASED NUMBER OF CONTRIBUTING EXCITED STATE TERMS

- POLYMER CHAINS: $\chi^{(3)} \sim 10^{-9}$ esu
  - 50 SITES (60Å)

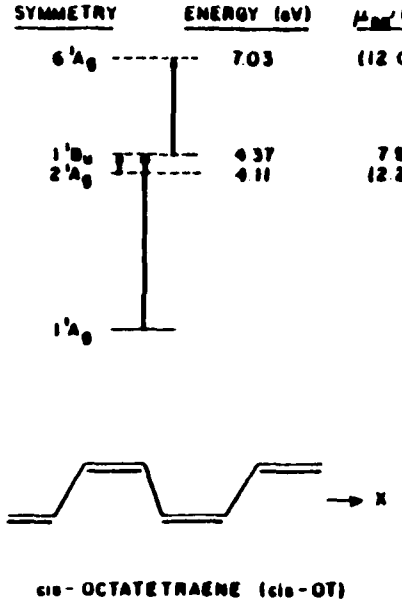


INCOMPLETE DESCRIPTION OF ELECTRON CORRELATION

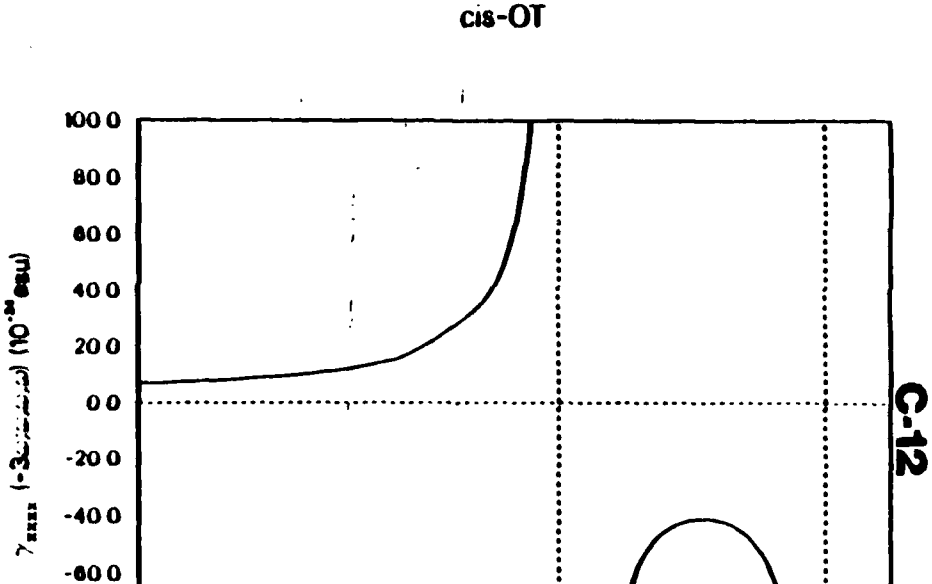
- SCI ONLY; OTHERWISE IDENTICAL TO FULL SDCI
- NEGATIVE SIGN FOR γ_{xxxx} FOR ALL CHAIN LENGTHS
- SCI POWER LAW EXPONENT IS 3.9 AS COMPARED TO 5.4 OF SDCI



MICROSCOPIC ORIGIN OF $\gamma(-3\omega;\omega,\omega,\omega)$ FOR cis - POLYENES



cis - OCTATETRAENE (cis - OT)



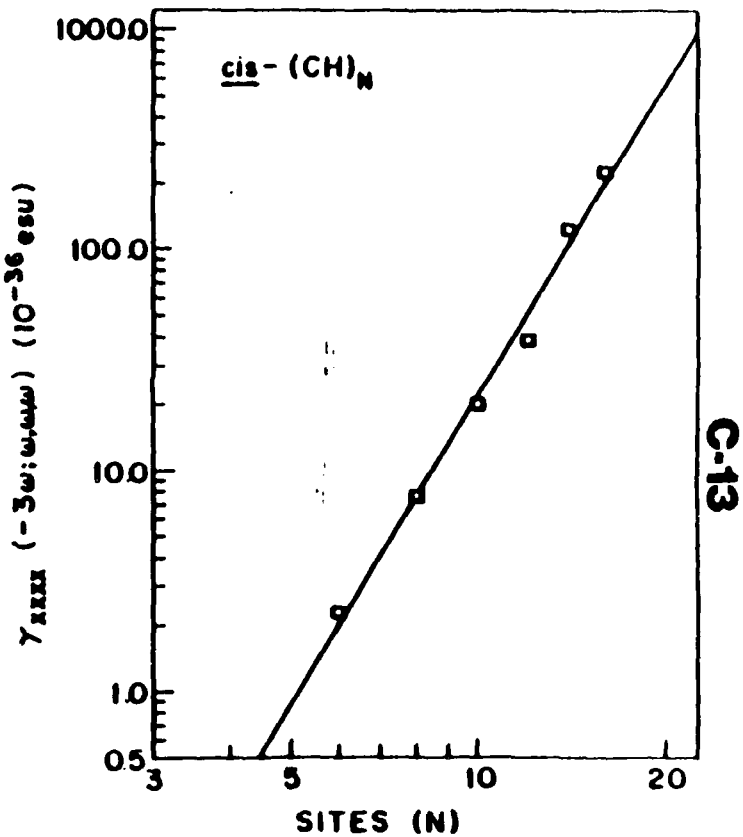
- $\gamma_{xxxx}(-3\omega;\omega,\omega,\omega) = 7.7 \times 10^{-36}$ esu (ω: 0.65 eV/ħ)
  $\gamma_0(-3\omega;\omega,\omega,\omega) = 1.8 \times 10^{-36}$ esu
- ONLY CONTRIBUTIONS: $g \rightarrow {}^1B_u \rightarrow {}^1A_g \rightarrow {}^1B_u \rightarrow g$
- ^1A_g STATES: THOSE WITH LARGEST $\mu_{nn'}$ WITH DOMINANT ^1B_u STATE
- 2 PHOTON ^1A_g STATES CRITICAL IN THIRD ORDER PROCESSES

DEPENDENCE OF $\gamma(-3\omega;\omega,\omega,\omega)$ ON NUMBER OF SITES

- FINITE CHAIN LIMIT: POWER LAW DEPENDENCE

$$\gamma_{xxxx} \propto N^{4.7}$$

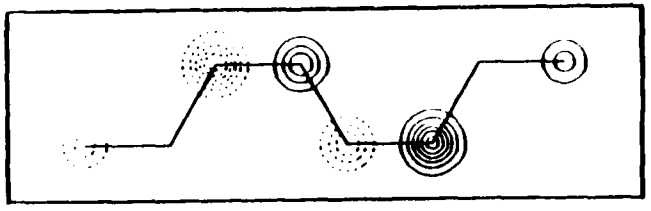
  - DECREASED EXCITATION ENERGY
  - INCREASED TRANSITION MOMENTS
  - INCREASED NUMBER OF CONTRIBUTING EXCITED STATE TERMS



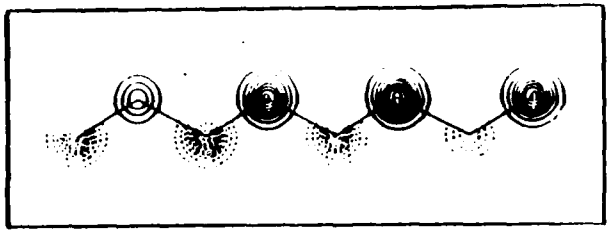
TRANSITION DENSITY MATRIX DIAGRAMS

$\rho_{g,1^1B_u}$

$\mu_{g,1^1B_u} = 7.9D$

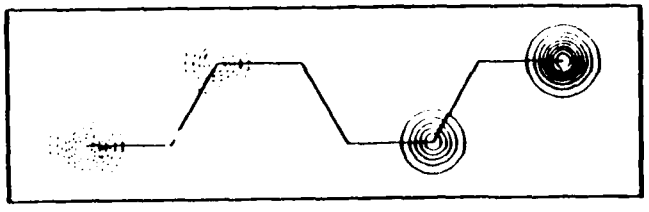


$\mu_{g,1^1B_u} = 7.8D$

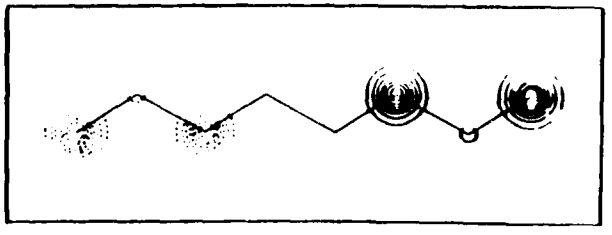


$\rho_{1^1B_u,6^1A_g}$

$\mu_{1^1B_u,6^1A_g} = 12.0D$



$\mu_{1^1B_u,6^1A_g} = 13.2D$



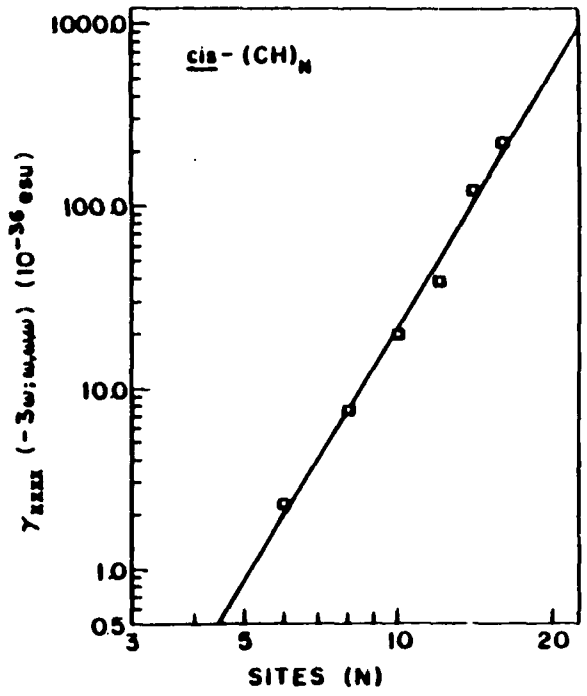
- CHARGE REDISTRIBUTION ESSENTIALLY THE SAME FOR <u>cis</u> AND <u>trans</u> CONFORMATIONS

DEPENDENCE OF $\gamma(-3\omega;\omega,\omega,\omega)$ ON NUMBER OF SITES

- FINITE CHAIN LIMIT: POWER LAW DEPENDENCE

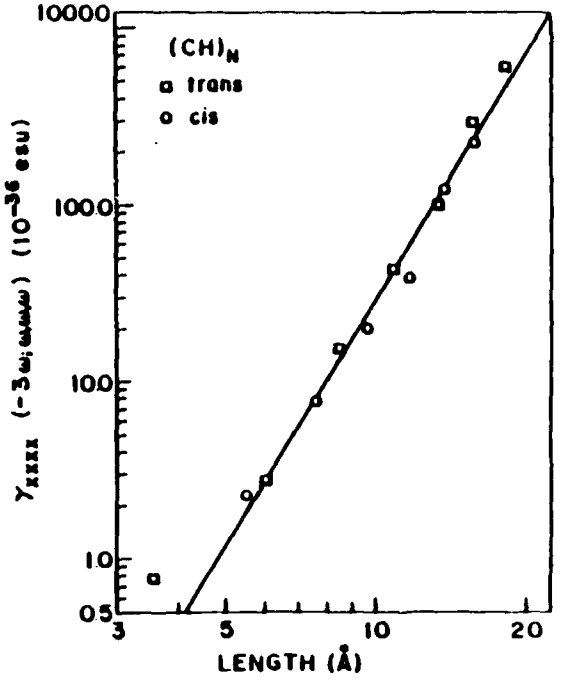
$$\gamma_{xxxx} \propto N^{4.7}$$

- DECREASED EXCITATION ENERGY
- INCREASED TRANSITION MOMENTS
- INCREASED NUMBER OF CONTRIBUTING EXCITED STATE TERMS



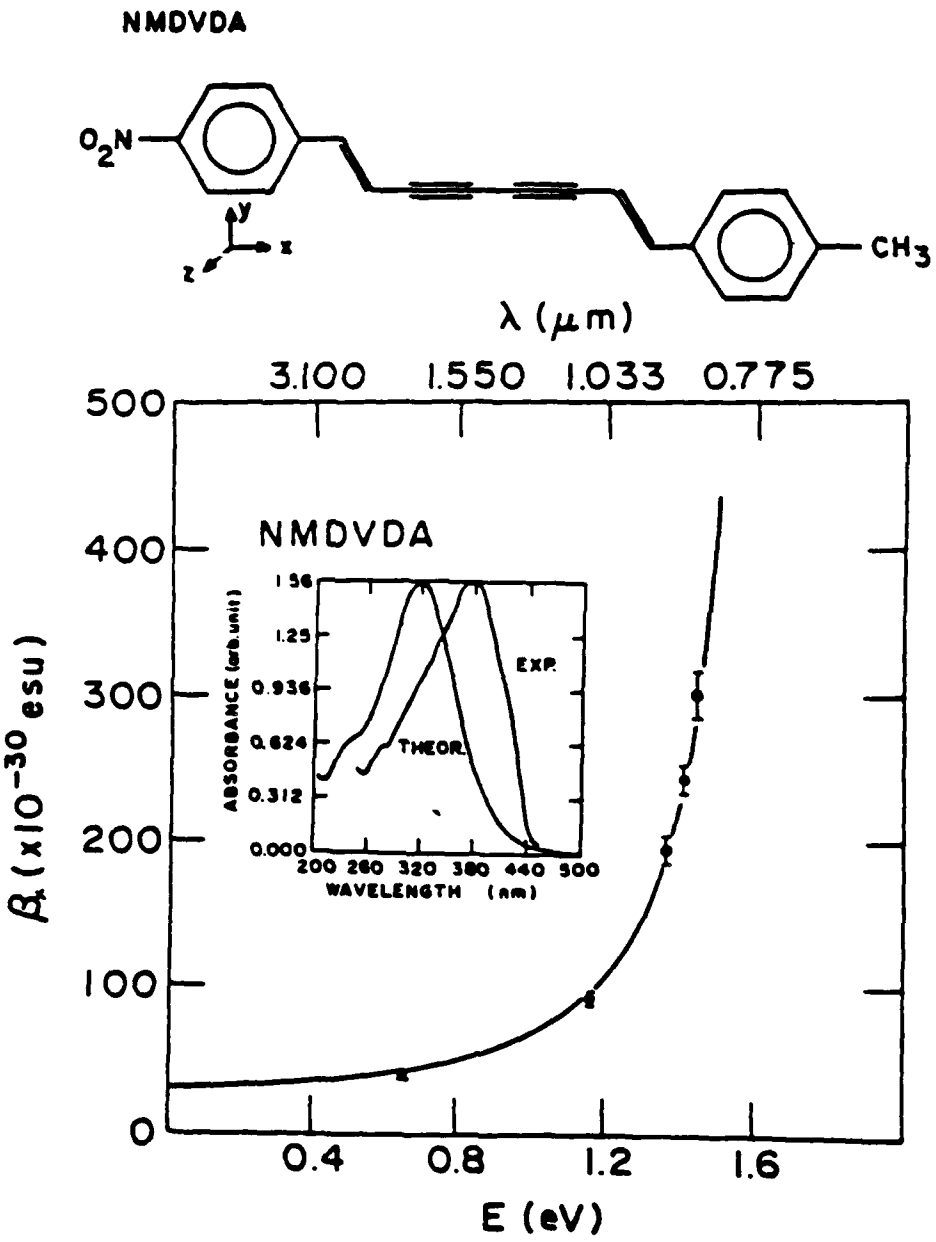
DEPENDENCE OF $\gamma(-3\omega;\omega,\omega,\omega)$ ON CHAIN LENGTH

- FINITE CHAIN LIMIT : $\gamma_{xxxx} \propto L^{4.6}$
- $\gamma_{xxxx}(-3\omega;\omega,\omega,\omega)$ FOR cis IS SMALLER THAN THAT FOR trans OF SAME NUMBER OF SITES
- DIFFERENCE IN $\gamma_{xxxx}(-3\omega;\omega,\omega,\omega)$ IS ACCOUNTED FOR BY DIFFERENCE IN LENGTH IN X-DIRECTION
- $\gamma_{xxxx}(-3\omega;\omega,\omega,\omega)$ MUCH MORE SENSITIVE TO CHAIN LENGTH THAN CONFORMATION

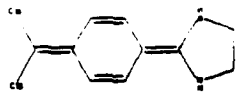


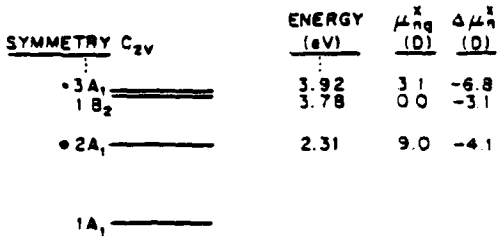
C-17

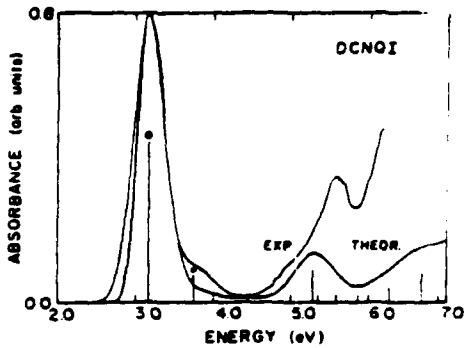
ELECTRON CORRELATED STATES: ORIGIN OF SECOND ORDER NONLINEAR OPTICAL SUSCEPTIBILITY OF CONJUGATED CYCLIC CHAINS

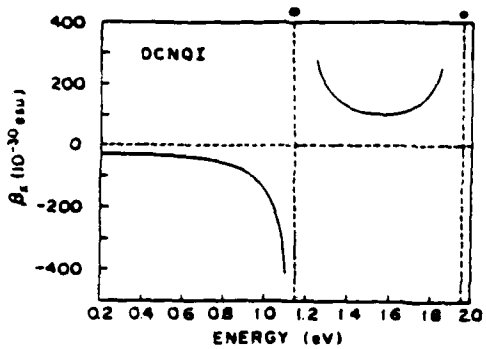


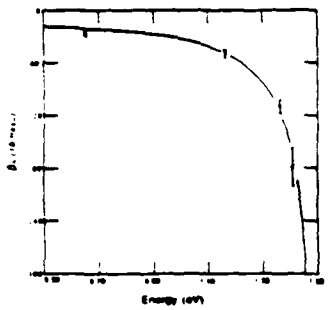
DCNQI











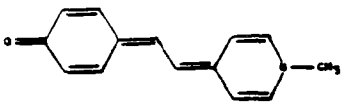
DCNQI	Experimental	SDCI	SCI
μ_z (Debye)	17.5 ±0.8	17	18.4
β_z (10^{-30} esu)	-27 ±3	-19.7	-73.2
$\mu_z \beta_n$ (10^{-48} esu)	-474 ± 52	-335	-1347

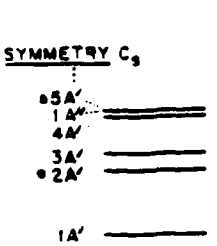
Comparison of Experimental and SDCI,SCI Values of Dipole Moment and the Second Order Microscopic Susceptibility at 0.65 eV.

	SDCI	SCI
β_{zzz}^{NN}	44%	85%
$\beta_{zzz}^{NN'}$	56%	15%

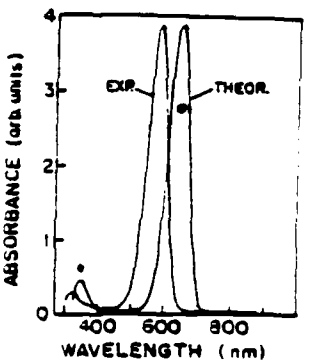
The percentage Contributions of Diagonal Term and Off-diagonal Term.

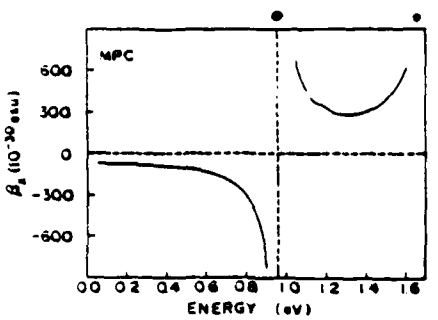
MPC

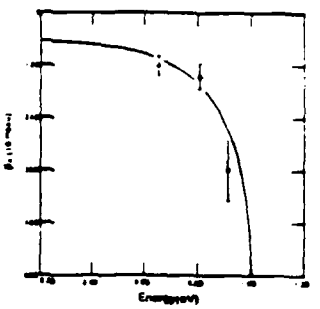




	ENERGY (eV)	μ_{ng}^{x} (D)	$\Delta\mu_{n}^{x}$ (D)
	3.69	4.7	-8.3
	3.69	0	-20.0
	3.54	0.4	-13.8
	2.42	0.1	-14.1
	1.92	12.0	-4.4







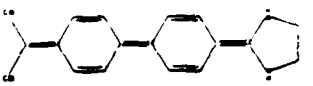
MPC	Experimental	SDCI	SCI
μ_x (Debye)	17.4 ±2.5	21.4	25.1
β_x (10^{-30} esu)	-123 ± 22	-104.7	-236.4
$\mu_x \beta_x$ (10^{-48} esu)	-2140 ± 390	-2240	-5933

Comparison of Experimental and SDCI,SCI Values of Dipole Moment and the Second Order Microscopic Susceptibility at 0.65 eV.

	SDCI	SCI
β_{xxx}^{w}	55.5%	86.4%
β_{xxx}^{w}	44.5%	13.6%

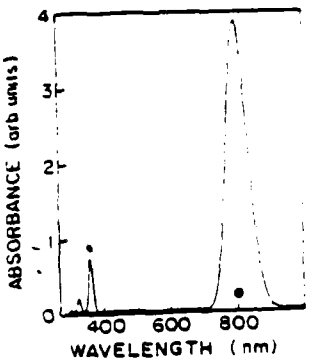
The percentage Contributions of Diagonal Term and Off-diagonal Term.

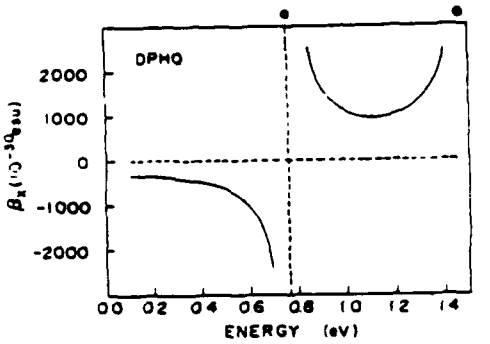
DPHQ



SYMMETRY C_{2v}

	ENERGY (eV)	μ_{ng}^{x} (D)	$\Delta\mu_{n}^{x}$ (D)
	⋮		
$\bullet 3A_1$	3.41	4.2	-8.6
$1B_2$	3.18	0	-9.4
$\bullet 2A_1$	1.54	14.4	-7.7
$1A_1$			





DPHQ	SDCI	SCI
μ_z (Debye)	25.4	30.5
β_z (10^{-30} esu)	-1410	-626
$\mu_z\,\beta_z$ (10^{-48} esu)	-35800	-19100

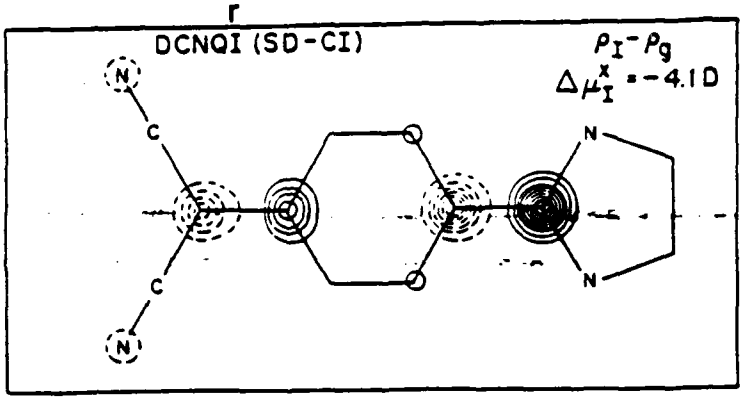
Comparison of Experimental and SDCI,SCI Values of Dipole Moment and the Second Order Microscopic Susceptibility at 0.65 eV.

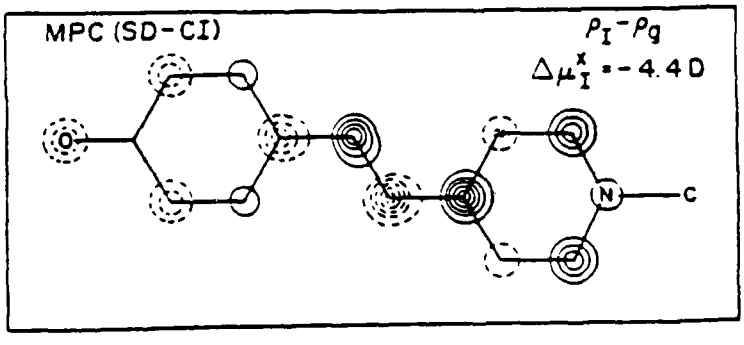
	SDCI	SCI
β_{zzz}^{nn}	72%	85%
$\beta_{zzz}^{nn'}$	28%	15%

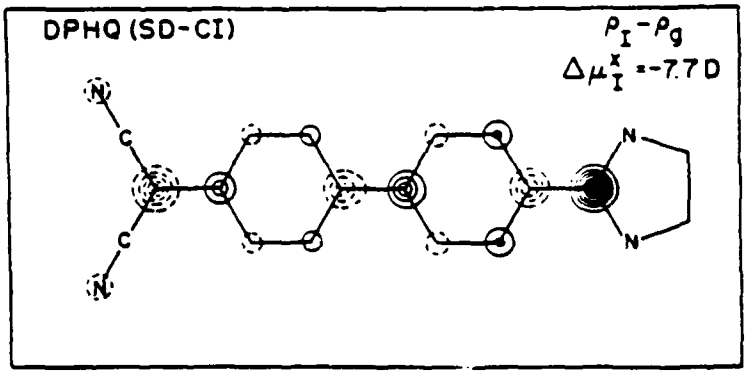
The percentac . Contributions of Diagonal Term and Off-diagonal Term.

ELECTRON DENSITY CORRELATION DIAGRAMS

$$\langle \Delta\mu_n \rangle = e \int_r r\,(\rho_n - \rho_g)\,dr$$

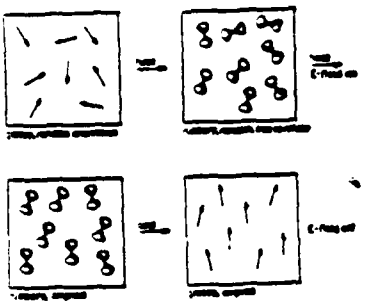


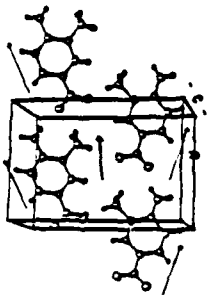




PCLED PCLYMER GLASSES

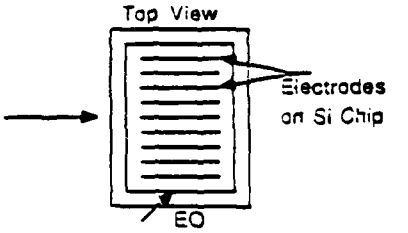
C-22





MNA SINGLE CRYSTAL

TIR SLM DEVICES



Orientational Order

$$\chi^{(2)}_{111} = N \frac{\beta_{xxx} \mu_x E_x}{k_B T} f^{2\omega} (f^{\omega})^2 \left(\frac{1}{5} + \frac{4}{7}\langle P_2 \rangle + \frac{8}{35}\langle P_4 \rangle \right)$$

CLASS	SYSTEM	$\mu_x\beta_x$ (10^{-30}cm^{5}Desu^{-1})	d_{11}(10^{-9}esu) (λ=1.907μm)	r_{11}(10^{-12}m/V) (λ=0.633μm)
RESONANT RING	MNA	66	0.8	0.3
	AZO DYE	530*	6*	2.5
	MNA SINGLE CRYSTAL		230	67
LINEAR CHAIN	NMDVDA	200	2.3	0.9
CYCLIC CHAIN	MPC	2100	24	10
	DCNQI	470	5.3	2.2
	DPHQ	36000	410	170

*Measured at λ=1.58μm

RELATED REFERENCES

1. Third harmonic generation study of orientational order in nematic liquid crystals, Phys. Rev. A34, 5051 (1986).

2. Microscopic origin of second order nonlinear optical properties of organic structures, in Nonlinear Optical and Electroactive Polymers (Plenum, New York, 1988).

3. Recent developments in microscopic descriptions of the nonlinear optical properties of organic and polymer structures, in Proceedings SPIE 825 (1988).

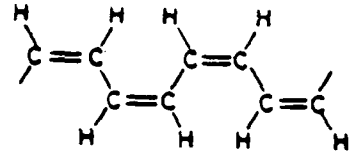
4. Nonlinear optical properties of linear chains and electron correlation effects, Phys. Rev. B - Rapid Communications (in press).

5. Symmetry controlled electron correlation mechanism for third order nonlinear optical properties of conjugated linear chains, in Electroresponsive Polymers, Special Issue, Mol. Cryst. Liq. Cryst. (1988).

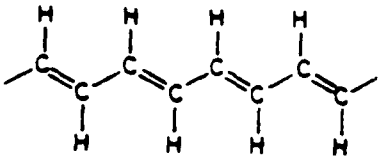
6. Nonlinear optical properties of polyenes: Electron correlation and chain conformation, in Nonlinear Optical Properties of Polymers (Materials Research Society, Boston, 1988) 109, p. 91.

S. Etemad
Bell Communications

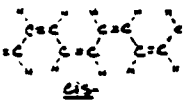
CONJUGATED POLYMERS AND NONLINEAR OPTICS



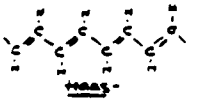
(a)



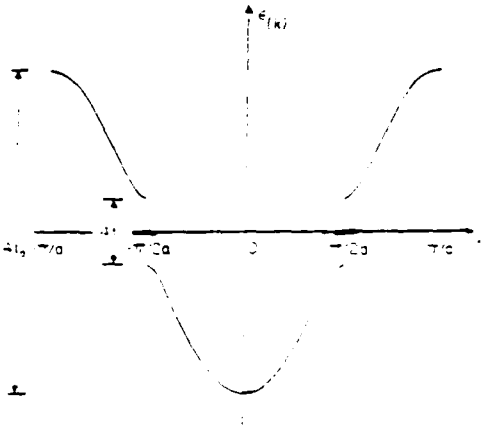
(b)



cis-



trans-

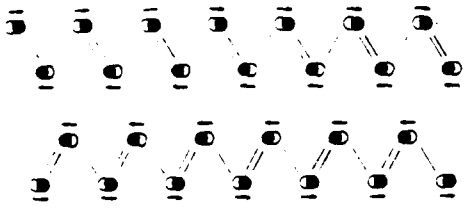


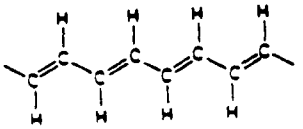
trans - $(CH)_x$

$t_0 = 2.5 - 3.0$ eV

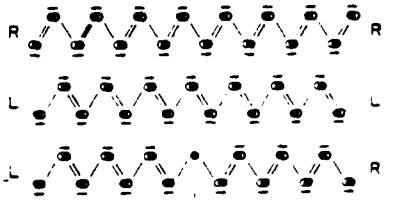
$2\Delta = 4t_1 \approx 1.5$ eV e.f. a-Si

$t_2 \approx .05$ eV

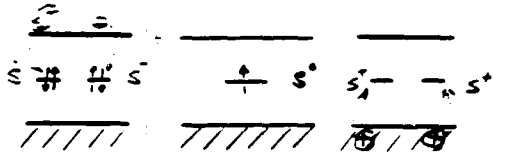




REVERSED CHARGE & SPIN



TRANS - $(CH)_x$



CHEMISTRY VIEW

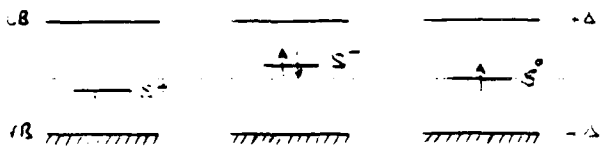
HIGHLY CORRELATED STATES

MANY BODY !

CASE STUDY : FINITE POLYENES

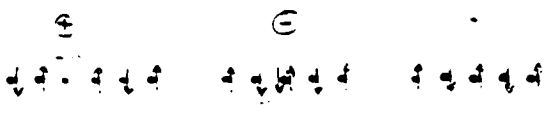
COULOMB INTERACTIONS

PERTURBATION APPROACH



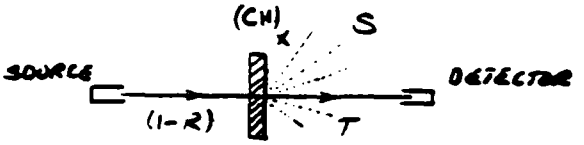
"MID-GAP" TRANSITIONS

HIGHLY CORRELATED STATES



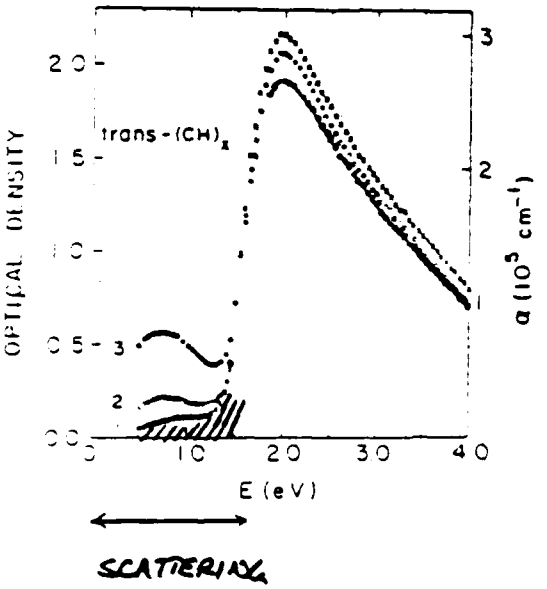
LOWEST ENERGY TRANSITIONS

- S^0 ABSORPTION AT BAND GAP

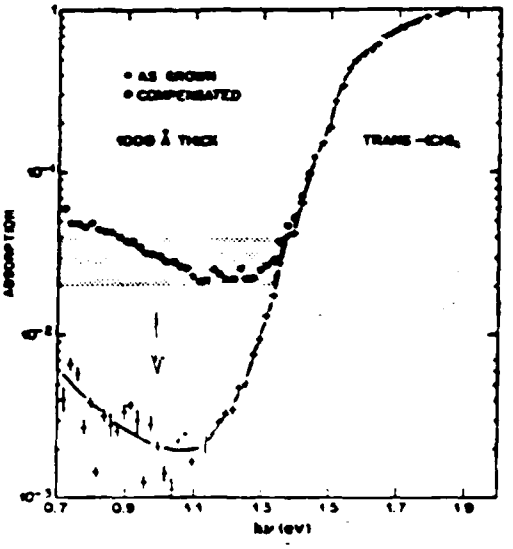


$1-R = T+S+A$

EFFECT OF COMPENSATION WITH NH_3

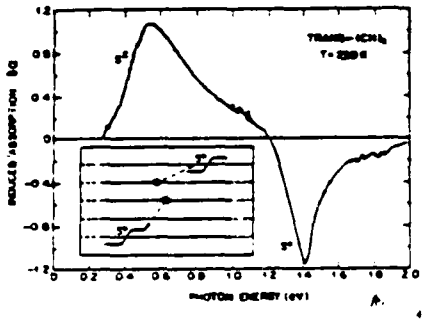


SCATTERING



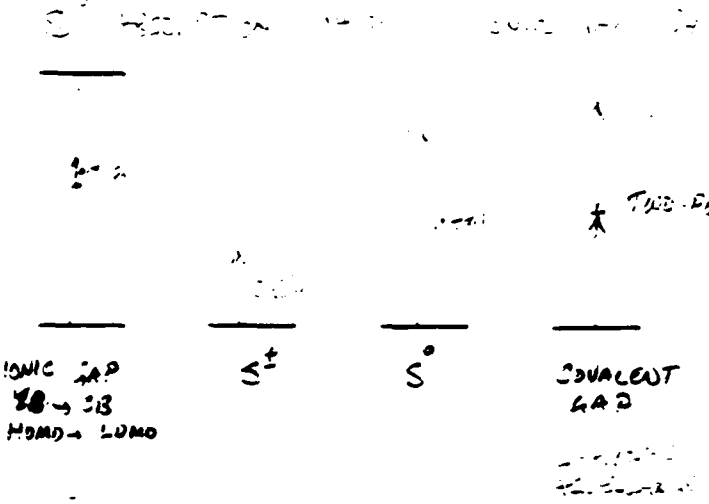
LONG TIME BEHAVIOR

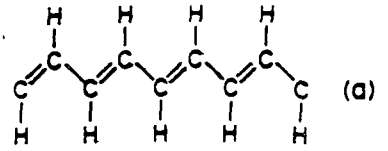
MOL. CRYST. LIQ. CRYST. 117, 275.



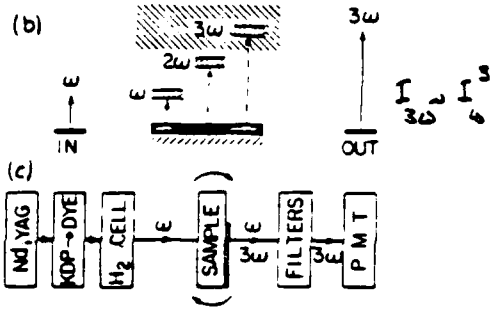
$e/h + 2S^0 \rightarrow 2S^{\pm}$

PRB 30, 786 (84)





WHERE IS THE 2^1A_g ('COVALENT GAP')
WITH RESPECT TO 1^1B_u ('IONIC GAP')



FILM: COMPENSATED $(CH)_x$ Fig 1
700 Å THICK; UNIFORM

THIRD HARMONIC GENERATION

$$\chi^{(3)}(3\omega;\omega,\omega,\omega) = \sum_{nmn} \Omega_{gn}\Omega_{nm}\Omega_{mn}\Omega_{ng}$$

$$\left[\frac{1}{(E_{ng} - 3\omega)(E_{mg} - 2\omega)(E_{ng} - \omega)} \right.$$

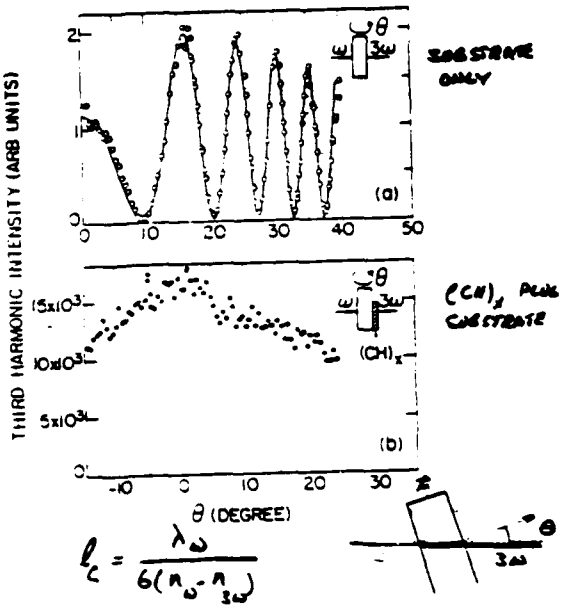
$$+ \frac{1}{(E_{ng} + \omega)(E_{mg} - 2\omega)(E_{ng} - \omega)} +$$

$$\frac{1}{(E_{ng} + \omega)(E_{mg} + 2\omega)(E_{ng} - \omega)}$$

$$\left. + \frac{1}{(E_{ng} + 3\omega)(E_{mg} - 2\omega)(E_{ng} + \omega)} \right]$$

TRANSITIONS BETWEEN ALL STATES
IRRESPECTIVE OF SYMMETRY

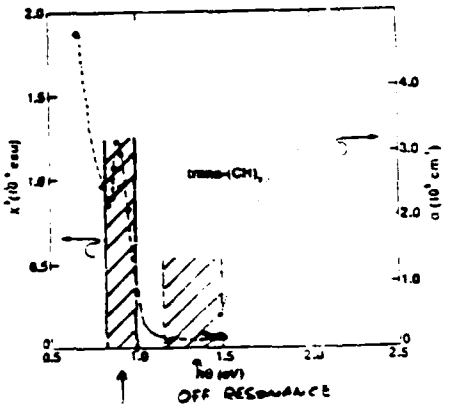
χ^3 OF $(CH)_x$: CALIBRATION



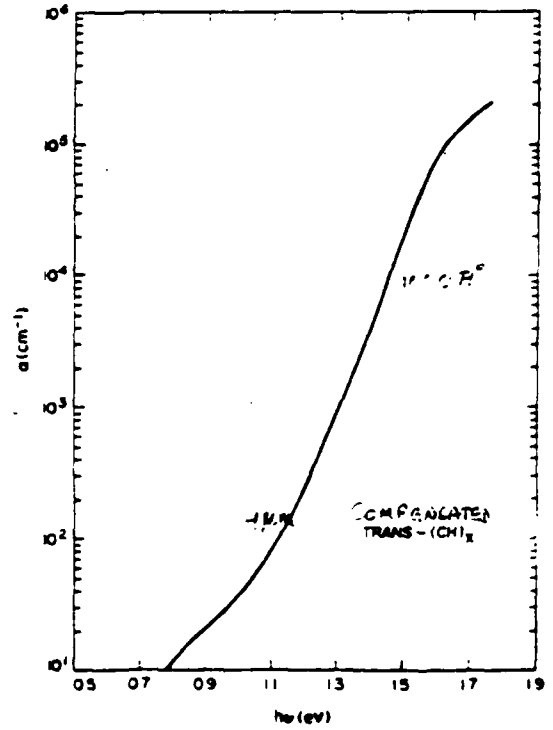
$$l_c = \frac{\lambda_\omega}{6(n_\omega - n_{3\omega})}$$

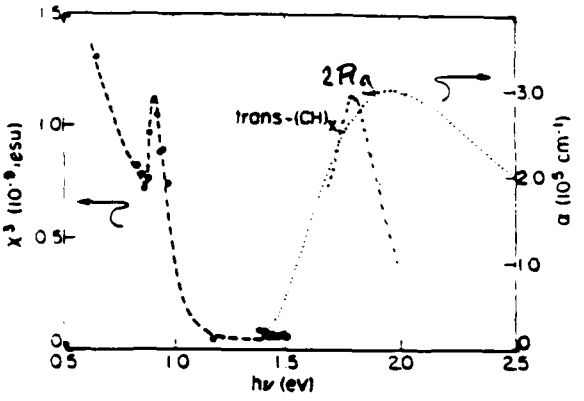
$$I_{3\omega} \sim I_\omega^3 \cdot |\chi^3|^2 \cdot \sin^2\left(\frac{l \cos\theta}{2 l_c}\right)$$

$\chi^{(3)}$ LARGE



2-PHOTON RESONANCE





$2R_g$ STATE IS CLOSE TO $1B_u$ STATE?!

FREE ELECTRON LASER
(FEL)

INTENSE TUNABLE IR RADIATION

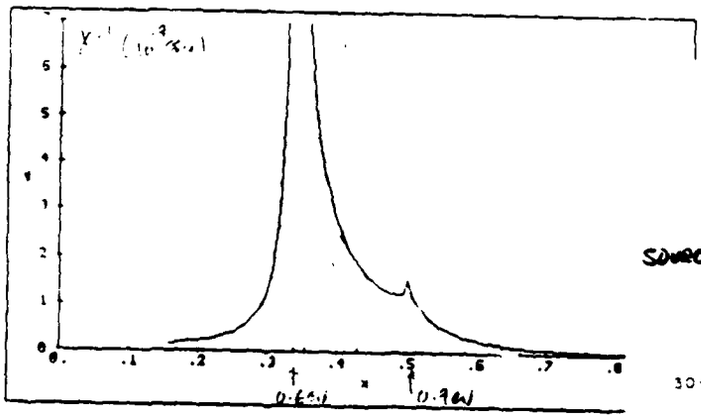
1 → 100 KW IN 2 - 10 μm RANGE

STANFORD → DUKE

< PARTICLE IN A BOX

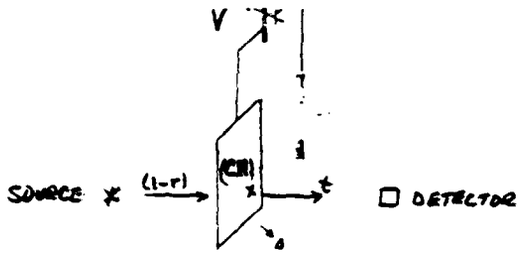
< DIMERIZATION

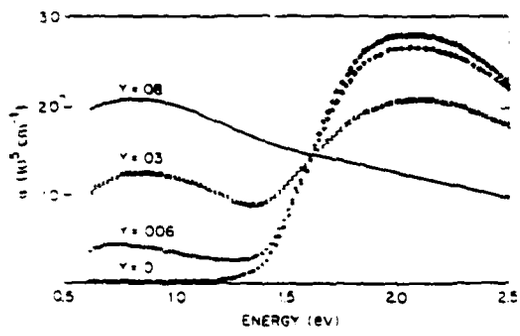
< IONIC & COVALENT STATES



U≠0 CALCULATION

W K Wu

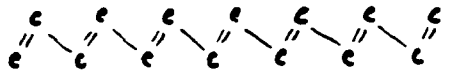




$\int_{EL} \alpha\, dx = 1.1 \times 10^{-17}$ cm^{-1}·eV / injected charge

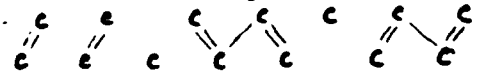
ENHANCED BY ~ ℓ/a

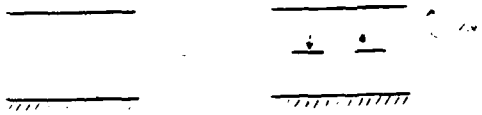
DOPING & SOLITON FORMATION



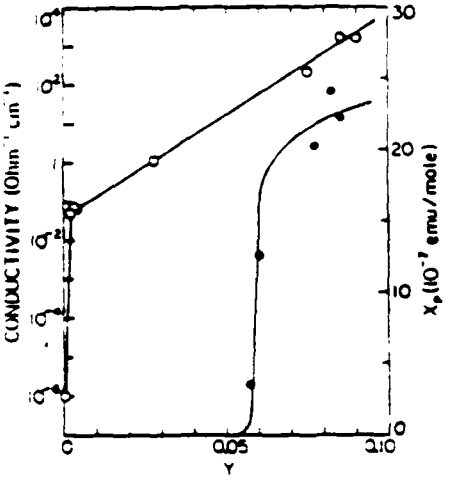
$E = ?\Delta$

$E = 2E_s = 2 \times 2\Delta/\pi$





NO SPIN.



Chiang et al PRB 20, 2341 (1979)

SIGNATURES OF SOLITON DOPING

APPEARANCE OF ABSORPTION BAND NEAR MID GAP

APPEARANCE OF ENHANCED IR ACTIVE LOCAL MODES

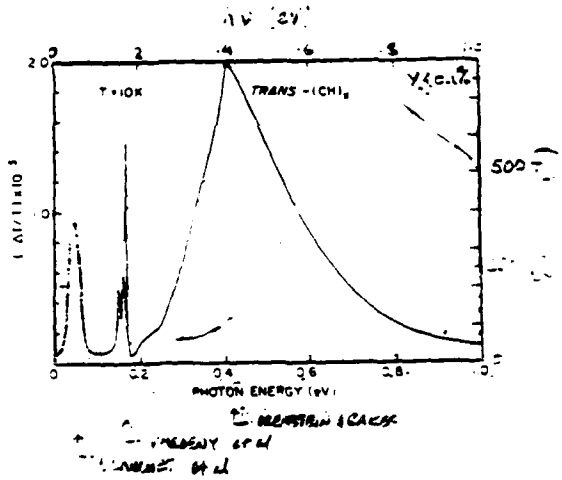
NO INCREASE IN χ

PHOTOEXCITED

SPEED OF RESPONSE (RESONANCE)

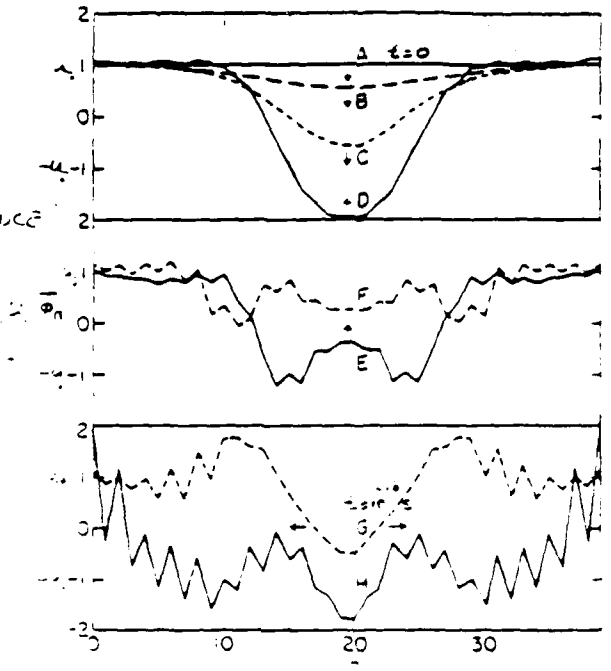
Su & Schrieffer Proc. Nat. Acad Sci USA

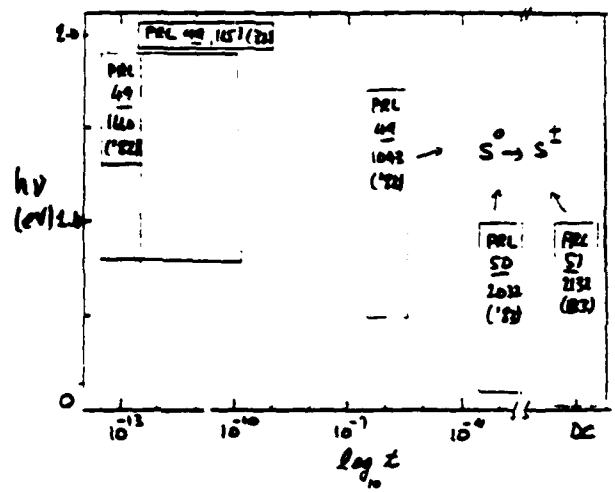
$t > 10^{-2}$ sec.

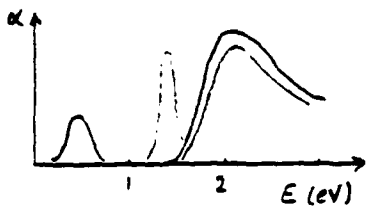


ELECTRONICALLY ENHANCED IR MODES

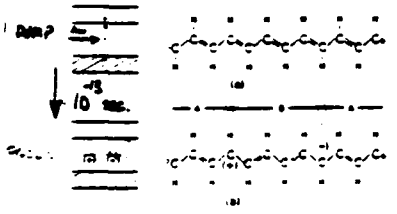
↳ SELF TRAPPED CHARGE IN CDW





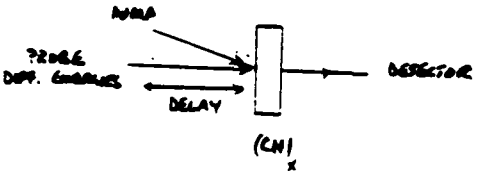


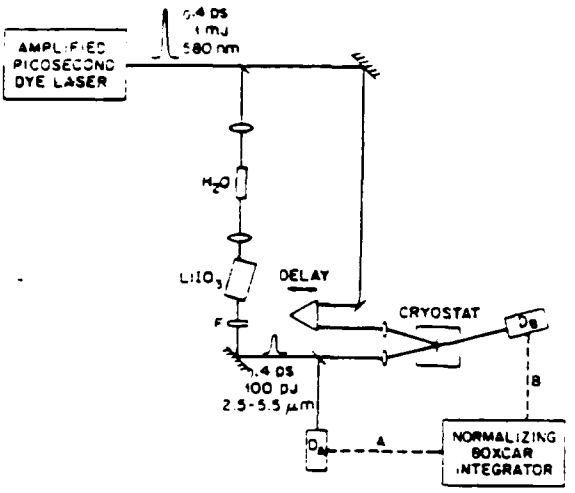
SU & SCHRIEFFER, PROC. NAT. ACAD. SCI 77, 5626 (80)

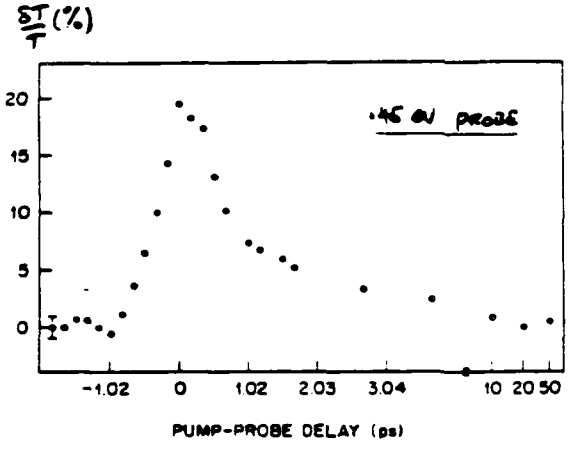


$\varepsilon_{el} > E_{ES}$ $\quad (\varepsilon_s = \frac{e\Delta}{\pi})$

$\tau \sim 1/\omega_{pl}$ $\quad (10^{-13}$ SEC)



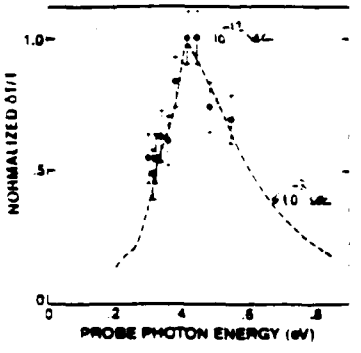


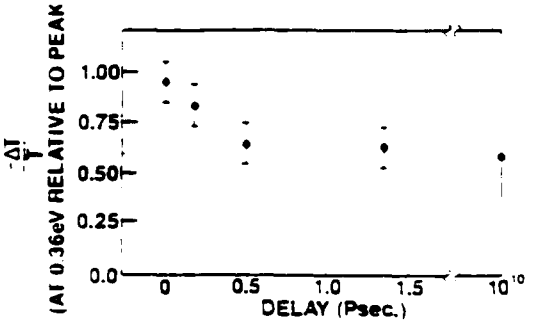


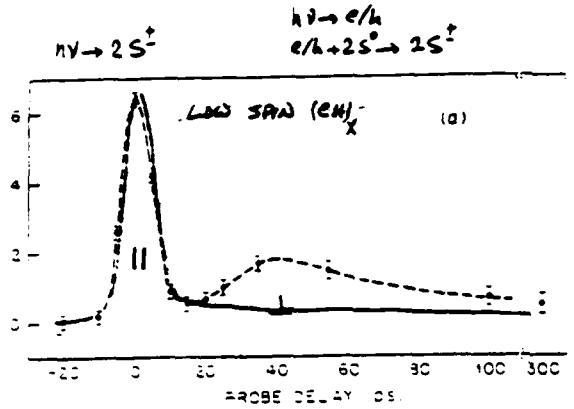
< 0.1 ps RISETIME

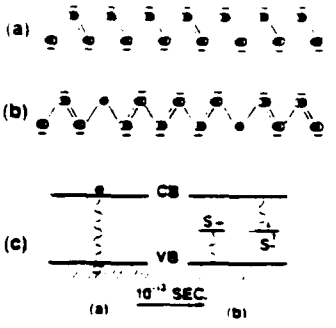
~ 0.5 ps LIFETIME

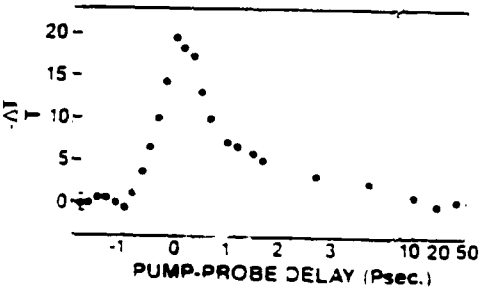
POWER DECAY (1.0 DIFF. ?)









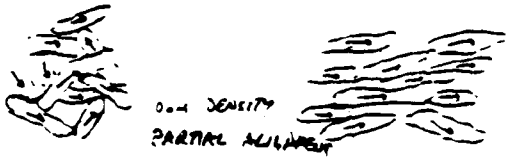


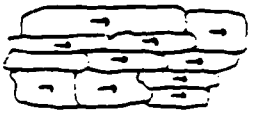
MAGNITUDE OF $\chi^{(3)}$

* ESR RESONANCE TRANSIENT (MW)

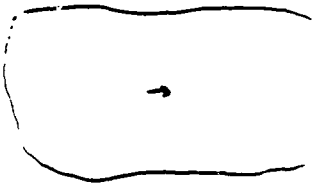
* POTENTIAL APPLICATIONS

SHIRAKAWA (CH)x





DURHAM (CH)x
100% ALIGNMENT
100% SPACE FILLING
MACROSCOPIC DOMAINS



WINNER'S (CH)x

* INTRINSIC ABSORPTION IS SMALL ~0.1-3 μ
* SCATTERING LOSS IS MORPHOLOGY DEPENDENT

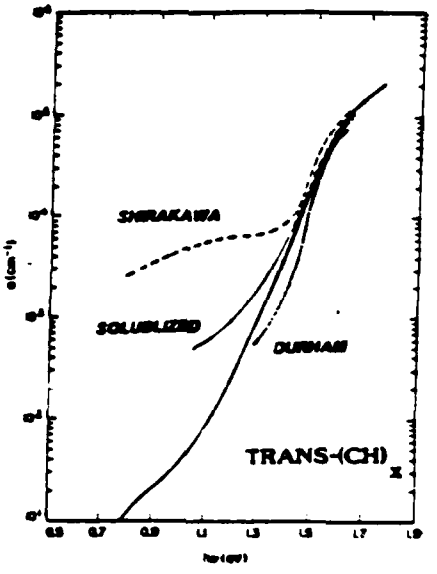
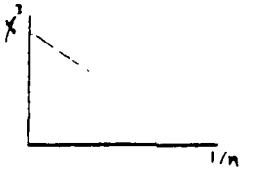


FIGURE OF MERIT

* $\chi^{(3)}/\alpha_{Total}$



FOR n LARGE DIFFERENTIAL GAIN IS VERY LARGE

* $\alpha_{TOTAL} = \alpha_{ABS} + \alpha_{SCATTERING}$

→ PROCESSABILITY ([illegible])
EASE OF FABRICATION

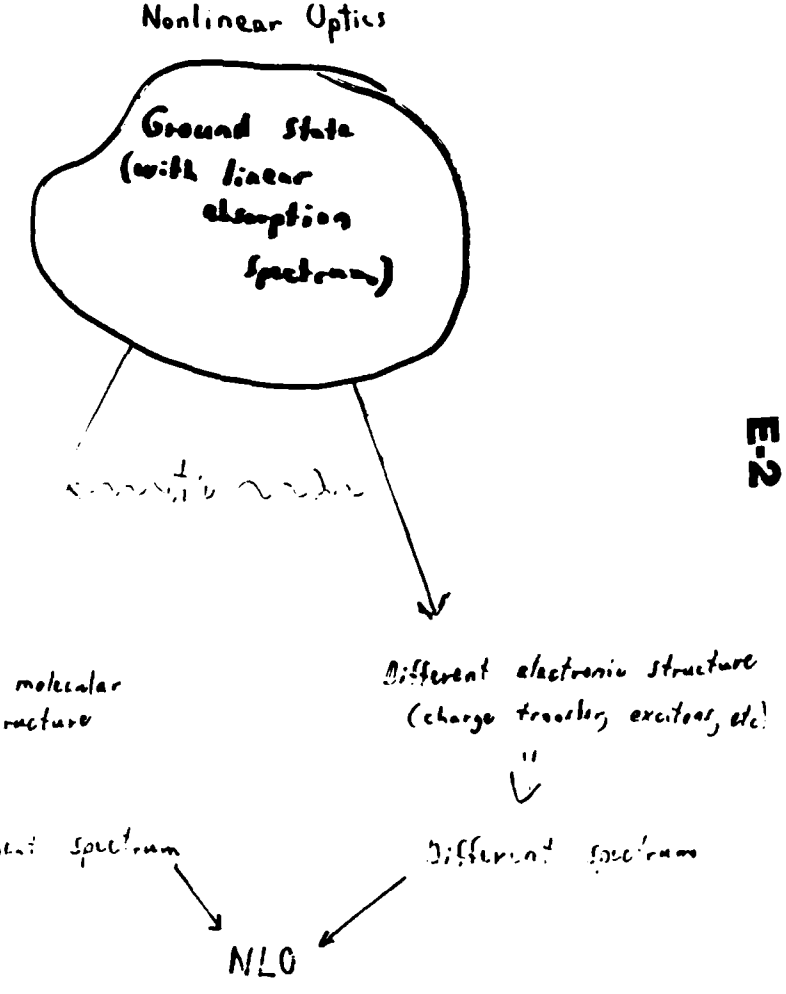
A. J. Heeger
University of California at Santa Barbara

ANISOTROPY OF THE THIRD ORDER NONLINEAR OPTICAL SUSCEPTIBILITY IN CONJUGATED POLYMERS

"Instantons" as the source of

Nonlinear Optical Properties

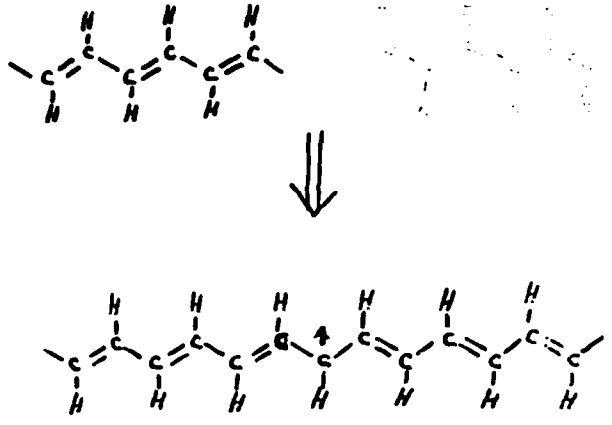
of Polyacetylene



Acknowledgement:
M. Sinclair
D. Moses
W.-P. Su

trans - $(CH)_x$

Broken symmetry with 2-fold degenerate ground state



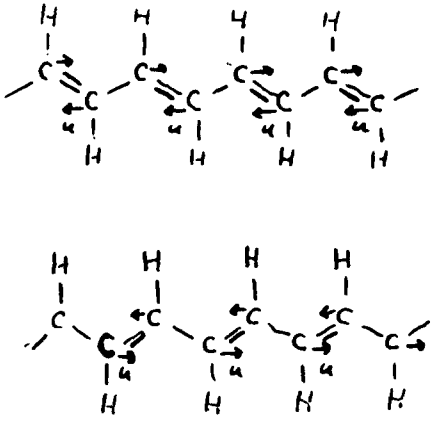
Bond-alternation domain wall or "Soliton"

? "particle" carrying structural information

p's:
localized non-bonding electronic state

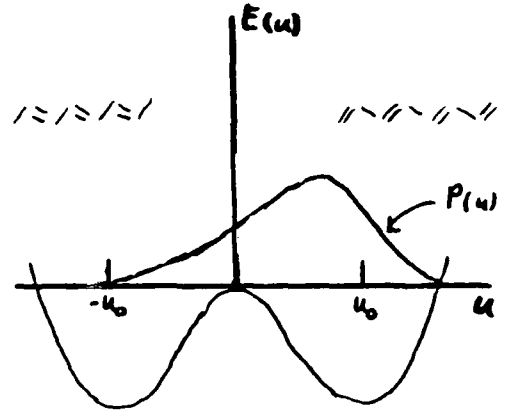
$m_s \sim 5\, m_e$

$\pm$trans - $(CH)_x$: two-fold degenerate ground state



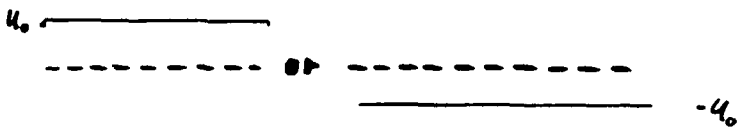
Quantum (zero point) fluctuations are important!

"Instantons" as the Source of $\chi^{(3)}_{\parallel}$ in Trans-$(CH)_x$

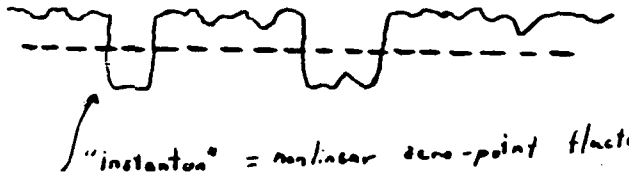


Order parameter $q = \pm(-1)^n u_n \overset{\text{(classical)}}{=} \pm u_0$

Classical:



Quantum:



"instanton" = nonlinear zero-point fluctuation

Instantons in polyacetylene

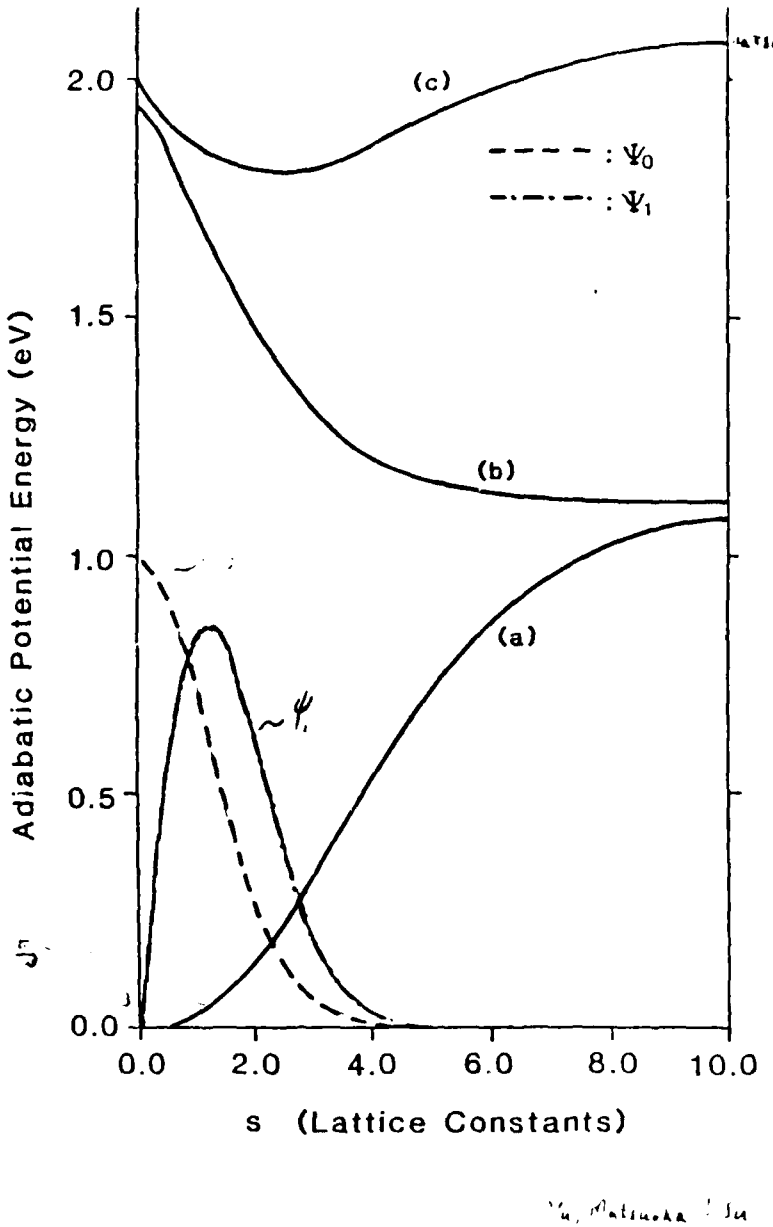
The effect of *nonlinear* ground state fluctuations on the photoproduction of charged solitons

Creation energy for soliton-antisoliton pair

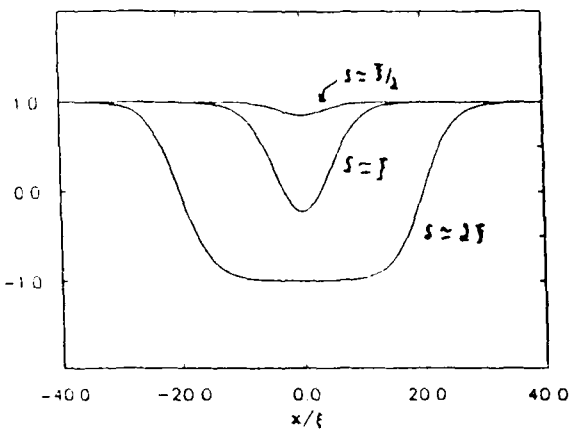
$$2E_s = \frac{2}{\pi} E_g < E_g$$

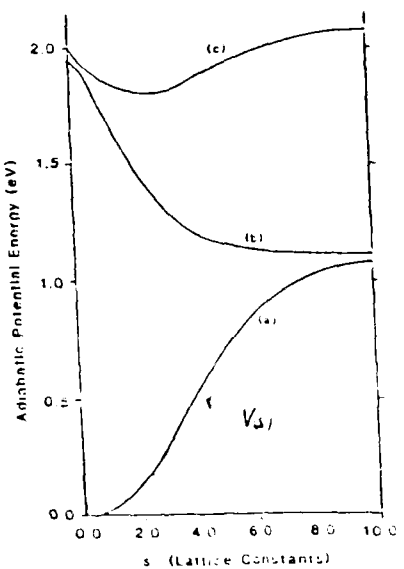
Can one get direct photogeneration of solitons for $\hbar\omega < E_g$?

Yes --- with help from ground state fluctuations !!



$\phi(x=na) = \phi_0\{1 - \tanh(2s/\xi)[\tanh(x-s/\xi) - \tanh(x+s/\xi)]\}$





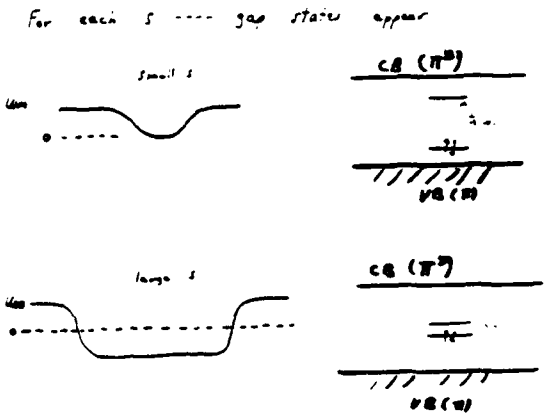
$U_{s1} = \frac{1}{2} m \omega^2 - V_{s1}$

& solve

straightforward [illegible] problem

E-5

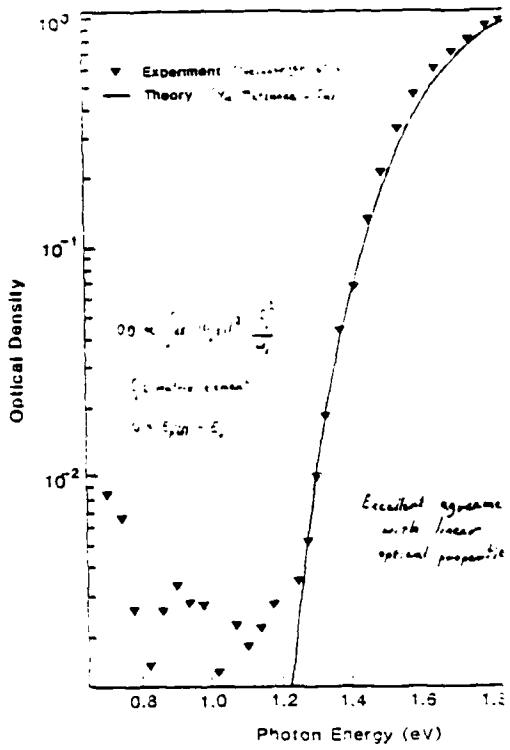
E-6



$$\Delta E = \frac{4}{\pi}\Delta + \hbar\omega_0(\omega)$$

$E_g = 2\Delta = 1.8 - 1.9\,eV$

$\frac{4}{\pi}\Delta \simeq 1.15\,eV$ (threshold)

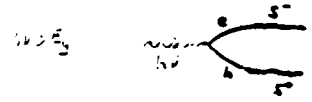


The connection to resonant

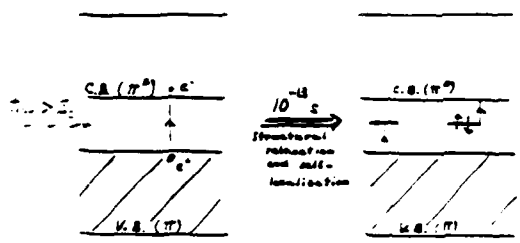
nonlinear optical properties

Soliton Photogeneration & Confinement in $(CH)_x$

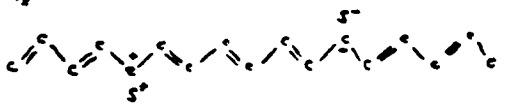
Dynamical calculations (Su & Schrieffer) show that after photogeneration of e-h pair, lattice distortion forms in very short time ($\sim 10^{-13}$ sec) leading to photogenerated S^+ and S^- pair



Photogeneration in the Continuum



Trans-$(CH)_x$



Two states are equivalent --- S^+ and S^- "free"

Sum Rule

$$\int_0^\infty \{\text{absorption}\}\, d\omega = \int_0^\infty \{\text{absorption}\}\, d\omega \Rightarrow \chi^{(3)} \simeq 5\times10^{-9}\ \text{esu}$$

Nonlinear Optics!

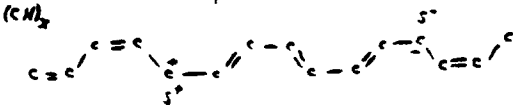
(resonant)

Index of refraction is different after absorption of $l^{\pm}$ photon

Resonant $\Delta\epsilon$ effects

Higher energy region

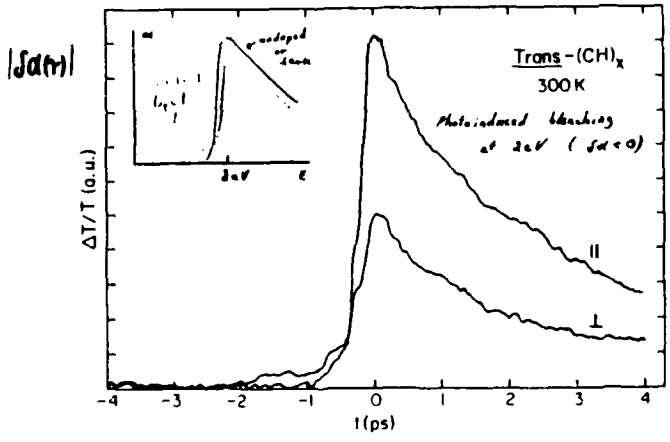
cis-$(CH)_x$



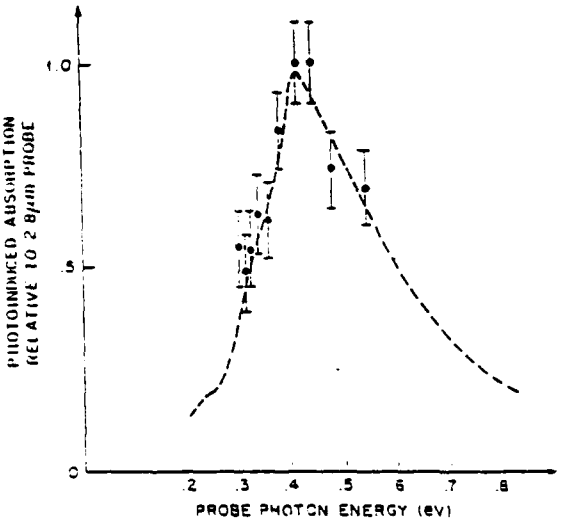
S^+ and S^- are "confined"

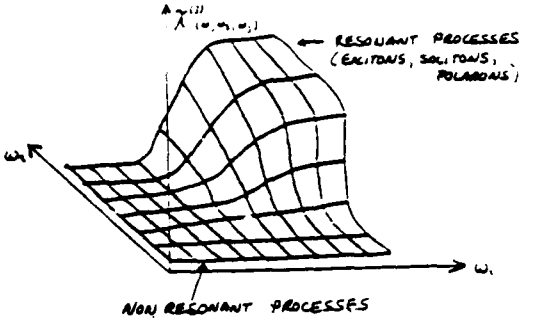
Vardeny, Strait, Moses, Chung & Heeger

PRL (1983)



Rubbery, Etemad et al





We have seen how solitons lead directly to resonant NLO

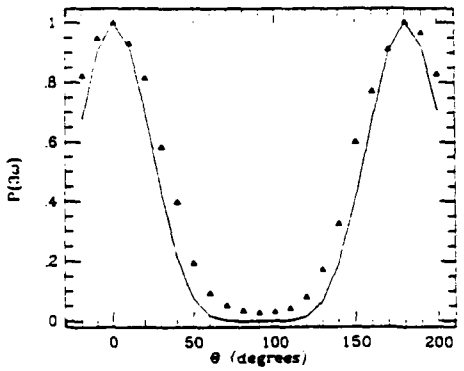
What about non-resonant NLO ?

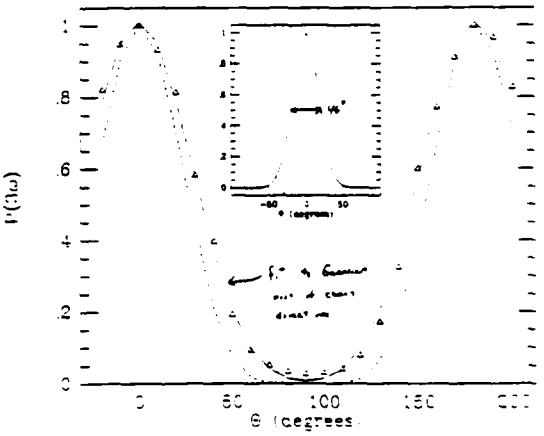
(... for $\hbar\omega < \frac{E_g}{2}$ ... we ... $\frac{E_g}{2}$

Yes ---- Instantons

THIRD HARMONIC GENERATION IN ORIENTED $\Sigma^{-}(CH)_x$

$$P(3\omega) \propto \chi^{(3)}_{\parallel} E^6_{\parallel} = \chi^{(3)}_{\parallel} E^6 \cos^6\theta$$





Alignment Direction

Polarization direction

$\chi^{(3)}_{\parallel}(3\omega;\omega,\omega,\omega) = (4 \pm 2) \times 10^{-10}$ e.s.u.

All nonlinearity associated with ...

Nonlinear $\chi^{(3)}(3\omega;\omega,\omega,\omega)$

Third order perturbation theory on the excited states of the system gives

$$\chi^{(3)} = N_0 \sum_{nmp} \langle g|r|n\rangle\langle n|r|m\rangle\langle m|r|p\rangle\langle p|r|g\rangle \times$$
$$\{(1/(E_{ng}-3\omega)(E_{mg}-2\omega)(E_{pg}-\omega) + 1/(E_{ng}+\omega)(E_{mg}-2\omega)(E_{pg}-\omega)$$
$$+ 1/(E_{ng}+\omega)(E_{mg}+2\omega)(E_{pg}-\omega) + 1/(E_{ng}+\omega)(E_{mg}+2\omega)(E_{pg}+3\omega)\}$$

where $E_{ng} = E_{s,n} - E_{s,g}$,

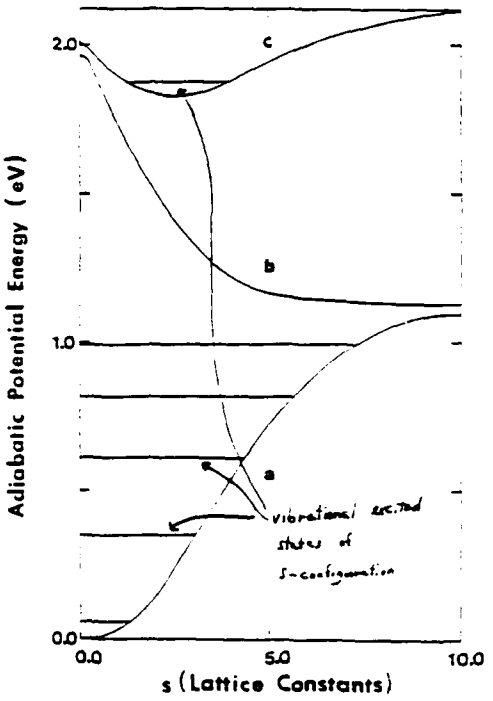
$E_{s,g}$ is the ground state energy

$E_{s,n}$ ($n = m$ or p) are the energies of excited states of the s-configurations

$\langle g|r|n\rangle$ are the dipole matrix elements

N_0 (= number density where $n_0 = L/2\pi$) is the unique space for soliton pairs on a chain of length L and ρ_c is the density of chains per unit area.

The sum is over charge excited states with symmetry opposite to n and m, i.e. all excited state with the same symmetry as g.



To estimate the magnitude of $\chi_s^{(3)}$ we consider the term in the full sum where the matrix elements go from $g \to E_{s,1}(s) \to n \to E_{s,1}(s) \to g$, i.e. we ignore the various vibrational states of the s-configuration and consider only the single commutation ($\chi_s^{(3)}{}_0$):

$$\chi_s^{(3)}{}_0 = N_0 \sum_{ss'} |\phi_0(s)|^2 |\phi_0(s')|^2 (|f_{s1}|^2 |f_{s1}|^2 / 2\omega) \times$$
$$[+1/(E_0-3\omega)(E_s-\omega) + 1/(E_0+\omega)(E_s-3\omega)].$$

For $3\omega = E_0$

$$\chi_s^{(3)}{}_0 = -4N_0 \sum_{ss'} |\phi_0(s)|^2 |\phi_0(s')|^2 (|f_{s1}|^2 |f_{s1}|^2 / E_0^2 E_s)$$

where f_s is the matrix element between the ground state with wave function $\phi_0(s)$ and the excited state with energy E_s relative to the ground state.

Since

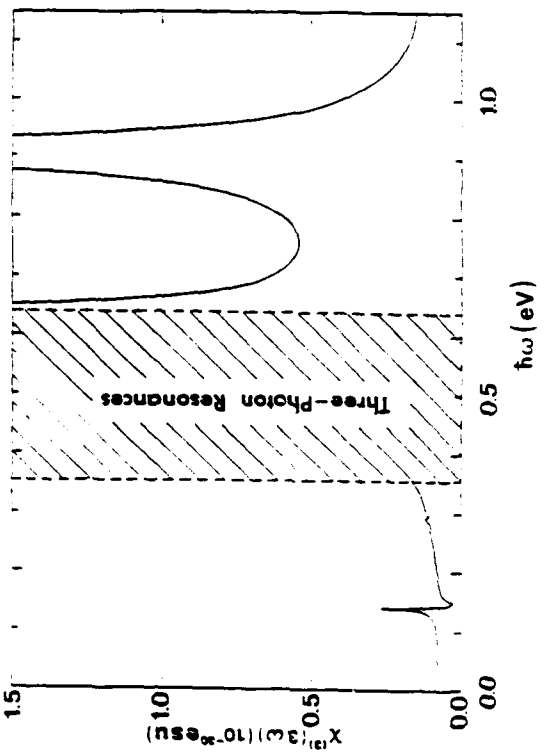
$$\alpha = N_0 \sum_{s,s'} |\phi_0(s)|^2 \alpha_{ss'}$$

is the linear term in the polarizability,

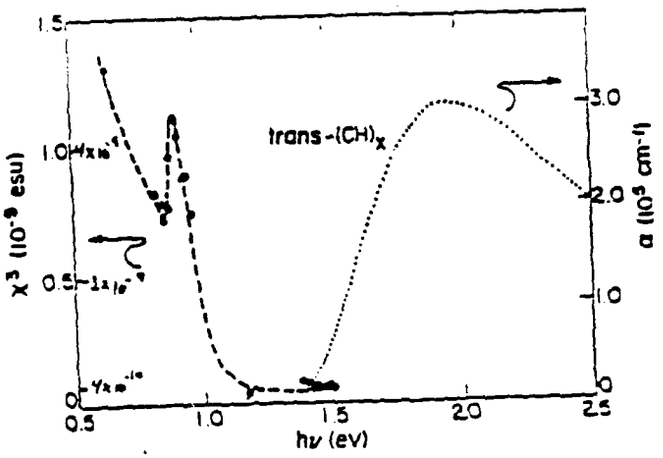
$$\chi_s^{(3)}{}_0 = -4\alpha \sum_{s,s'} |\phi_0(s)|^2 (\alpha_{ss'} E_s)$$

$$\chi_s^{(3)}{}_0 \sim (8\pi/a)(N_0 \rho_c)^{-1} \alpha^2 / E_0$$

$$\chi_s^{(3)}{}_0 \sim 3 \times 10^{-10} \text{ esu}$$



E-10

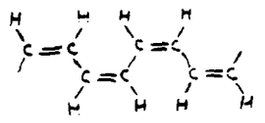


Kaiser, Stroud, Fission & Baker
Synth. Met. 17, 563 (1987)

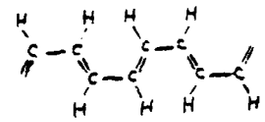
Symmetry Forbids Origin of $\chi^{(3)}$ Component

Measurements of [illegible] and Trans-(CH)$_x$

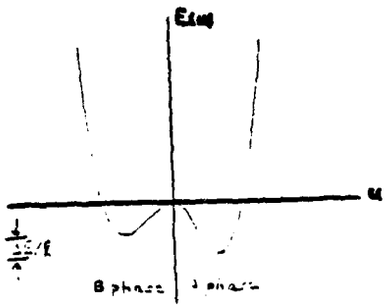
Not equivalent

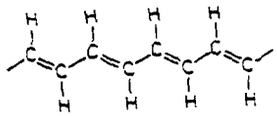


A phase

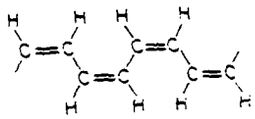


B phase





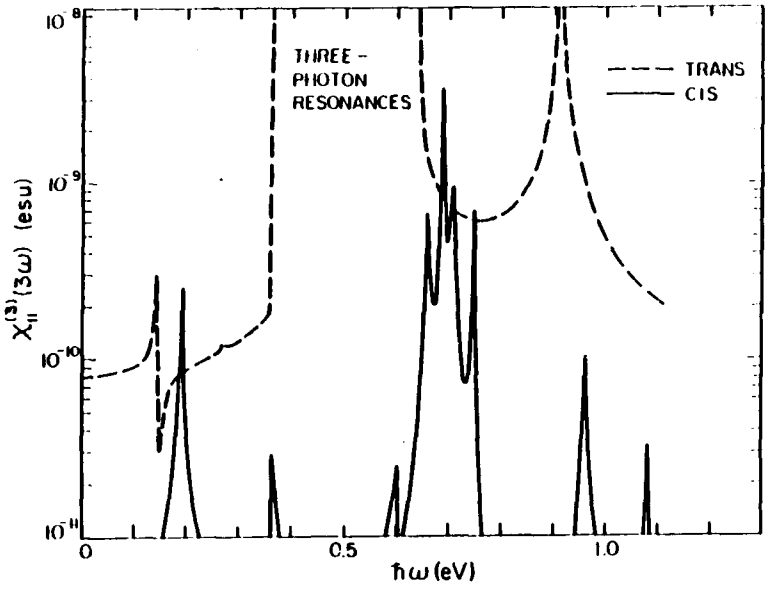
TRANS

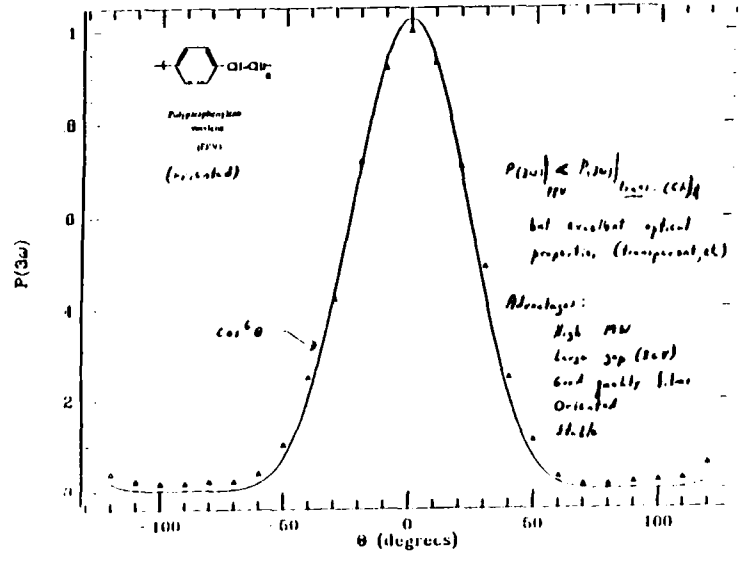


CIS

Result $\chi^{(3)}_{(xx)} < \frac{1}{c}$ [illegible]

Small number [illegible] $\chi^{(3)}$





Conclusions

1) Large $\chi^{(3)}_{//}$ are a general feature of conjugated polymers

2) Nonlinearity is associated with the π-electrons

3) At 1.06 μm $\chi^{(3)}_{(\omega,\omega,-\omega,\omega)}$ trans-$(CH)_x$ $\simeq$ $\chi^{(3)}_{(\omega,\omega,-\omega,\omega)}$ PDA

At longer wavelengths $\chi^{(3)}_{(\omega,\omega,-\omega,\omega)}$ trans-$(CH)_x$ is continuously larger by considerable factor

4) For polyacetylene $\chi^{(3)}_{trans} > 10\ \chi^{(3)}_{cis}$

5) Nonlinearity from rigid band structure is not dominant contribution [illegible] trans-$(CH)_x$ [illegible]

Questions:

1) Why is trans-$(CH)_x$ special?

2) How to connect measurement $\chi^{(3)}_{//}$ to known resonant properties?

K. D. Singer

AT&T

NONLINEAR OPTICS IN ORDERED MOLECULAR SYSTEMS

F-2

NONLINEAR OPTICS IN ORDERED MOLECULAR SYSTEMS

K.D. SINGER and M.G. KUZYK
AT&T Engineering Research Center, Princeton, NJ

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- NONLINEAR OPTICS IN MOLECULAR ENSEMBLES
- FILMS POLED UNDER UNIAXIAL STRESS
- NEW POLYMERS
  - MATERIALS
  - CORONA POLING
  - NONLINEAR OPTICAL PROPERTIES
  - MOLECULAR ORIENTATION DISTRIBUTION

MOLECULAR MATERIALS

- MACROSCOPIC POLARIZATION

$$P_i(t) = \chi_i^{(0)} + \chi_{ij}^{(1)}(t)E_j(t) + \chi_{ijk}^{(2)}(t)E_j(t)E_k(t) + \chi_{ijkl}^{(3)}(t)E_j(t)E_k(t)E_l(t) + \cdots$$

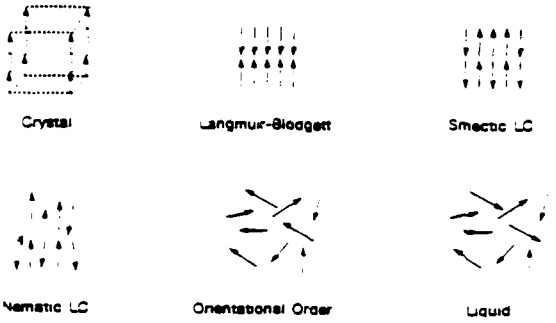
- MICROSCOPIC POLARIZATION

$$p_I(t) = \mu_I^{(0)} + \alpha_{IJ}(t)F_J(t) + \beta_{IJK}(t)F_J(t)F_K(t) + \gamma_{IJKL}(t)F_J(t)F_K(t)F_L(t) + \cdots$$

- VAN DER WAALS MATERIALS

$$P_I(t) = \frac{1}{V}\langle p_I(t)\rangle_i$$

MATERIAL CLASSES



MOLECULAR ORDER

- MOLECULES FIXED IN LATTICE

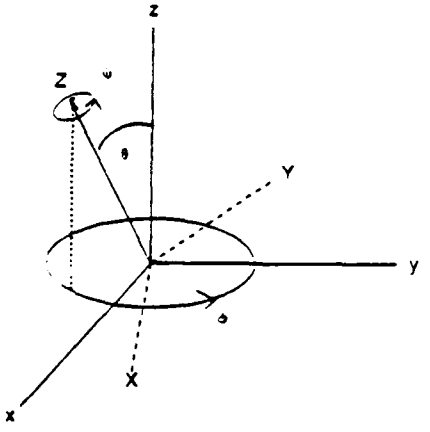
$$\chi^{(n)}_{ijkl\ldots} = N_u \sum_{I,J,K,L\ldots} \sum_{s=1}^{n} a_{iI(s)} a_{jJ(s)} a_{kK(s)} \cdots \xi^{*}_{IJKL\ldots}(s)$$

- THERMODYNAMIC ENSEMBLE

$$\chi^{(n)}_{ijkl\ldots} = N \langle \xi^{*}_{IJKL\ldots} \rangle_{ijkl\ldots}$$

$$\langle \xi^{*}_{IJKL\ldots} \rangle_{ijkl\ldots} = \int_0^{2\pi} d\phi \int_0^{\pi} \sin\theta d\theta \int_0^{2\pi} d\psi \xi^{*}_{IJKL\ldots} a_{iI} a_{jJ} a_{kK} \cdots G(\phi,\theta,\psi)$$

EULER ANGLES



SYMMETRY CLASSES

$\chi^{(2)}$ components for point group = mm

	1	2	3
1	0	0	$\chi^{(2)}_{311}$
2	0	0	$\chi^{(2)}_{322}$
3	0	0	$\chi^{(2)}_{333}$
4	0	$\chi^{(2)}_{223}$	0
5	$\chi^{(2)}_{113}$	0	0
6	0	0	0

$\chi^{(3)}$ components for point group = mmm

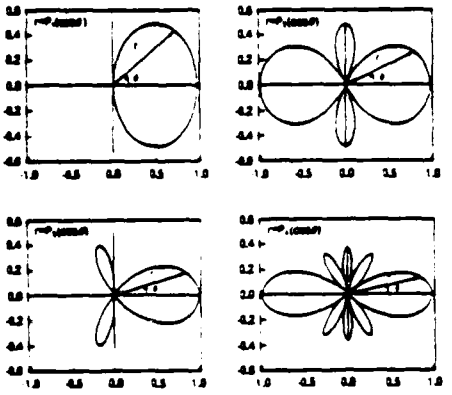
	1	2	3	4	5	6
1	$\chi^{(3)}_{1111}$	$\chi^{(3)}_{1122}$	$\chi^{(3)}_{1133}$	0	0	0
2	$\chi^{(3)}_{2211}$	$\chi^{(3)}_{2222}$	$\chi^{(3)}_{2233}$	0	0	0
3	$\chi^{(3)}_{3311}$	$\chi^{(3)}_{3322}$	$\chi^{(3)}_{3333}$	0	0	0
4	0	0	0	$\chi^{(3)}_{2323}$	0	0
5	0	0	0	0	$\chi^{(3)}_{1313}$	0
6	0	0	0	0	0	$\frac{1}{2}(\chi^{(3)}_{1111} - \chi^{(3)}_{1122})$

Row and column labels: 1 = 11; 2 = 22; 3 = 33; 4 = 23,32; 5 = 31,13; 6 = 12,21

DISTRIBUTION FUNCTION

$$G(\theta) = \sum_{l=0}^{\infty} \frac{(2l+1)}{2} A_l P_l(\cos\theta)$$

LEGENDRE POLYNOMIALS



SUSCEPTIBILITIES

$$\chi^{(2n)}_{ijkl\ldots} = \sum_{m=0}^{\infty} u^{(2m-1)}_{ijkl\ldots} \langle P_{2m-1} \rangle$$

$$\chi^{(2n-1)}_{ijkl\ldots} = \sum_{m=0}^{m-1} u^{(2m)}_{ijkl\ldots} \langle P_{2m} \rangle$$

- SECOND ORDER

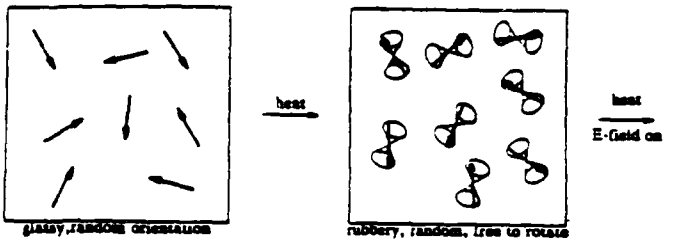
$$\chi^{(2)}_{333} = N\beta^{*}_{zzz} \left(\frac{3}{5} \langle P_1 \rangle + \frac{2}{5} \langle P_3 \rangle \right)$$

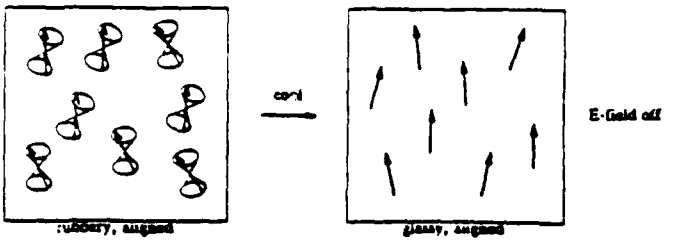
$$\chi^{(2)}_{113} = \chi^{(2)}_{131} = \chi^{(2)}_{311} = N\beta^{*}_{zzz} \left(\frac{1}{5} \langle P_1 \rangle - \frac{1}{5} \langle P_3 \rangle \right)$$

- THIRD ORDER

$$\chi^{(3)}_{3333} = N\gamma^{*}_{zzzz} \left(\frac{1}{5} + \frac{4}{7} \langle P_2 \rangle + \frac{8}{35} \langle P_4 \rangle \right)$$

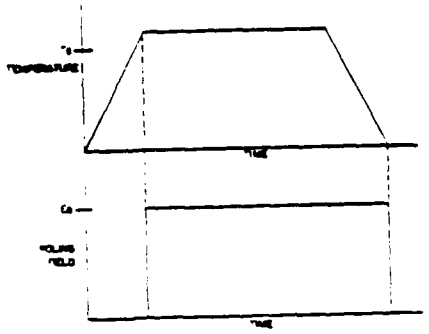
ELECTRIC FIELD POLING





F-5

POLED MATERIALS



$$G_u(\Omega, E_p) = \frac{\exp[-\frac{1}{kT}(\sum_v U_{uv} - \mathbf{m}_u^* \cdot \mathbf{E}_p)]}{\int d\Omega \exp[-\frac{1}{kT}(\sum_v U_{uv} - \mathbf{m}_u^* \cdot \mathbf{E}_p)]}$$

$$\chi_{ijk}^{(2)} = \nu_{ijk}^{(0)} \langle P_0 \rangle + \nu_{ijk}^{(2)} \langle P_2 \rangle + \nu_{ijk}^{(4)} \langle P_4 \rangle$$

POLING UNDER UNIAXIAL STRESS

- SECOND HARMONIC TENSOR PROPERTIES
- MOLECULAR DISTRIBUTION

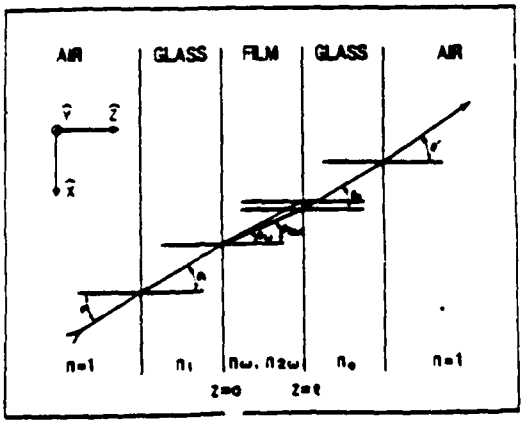
SECOND HARMONIC GENERATION

$$P_1^{(2)}(2\omega) = 2d_{31}(-2\omega;\omega,\omega)E_1(\omega)E_3(\omega)$$

$$P_2^{(2)}(2\omega) = 2d_{31}(-2\omega;\omega,\omega)E_2(\omega)E_3(\omega)$$

$$P_3^{(2)}(2\omega) = d_{31}(-2\omega;\omega,\omega)\left[E_1^2(\omega) + E_2^2(\omega)\right] + d_{33}(-2\omega;\omega,\omega)E_3^2(\omega)$$

EXPERIMENTAL GEOMETRY



SECOND HARMONIC INTENSITY

$$P_T = \frac{512\pi^3}{A}|d_{33}|^2 t_1^4 t_\omega^4 T_{2\omega} t_0^2 p^2(\theta) I_\omega^2 \left[\frac{1}{n_\omega^2 - n_{2\omega}^2}\right]^2 \sin^2\psi$$

- P-POLARIZED INCIDENT LIGHT

$$p(\theta) = (a\cos^2\theta_\omega - \sin^2\theta_\omega)\sin\theta_{2\omega} + 2a\cos\theta_\omega \sin\theta_\omega \cos\theta_{2\omega}$$

- S-POLARIZED INCIDENT LIGHT

$$p(\theta) = a\sin(\theta_{2\omega})$$

$$\text{where} \quad a = \frac{d_{31}}{d_{33}}$$

ORDERING ENERGY

$$G_u(\Omega) = \frac{\exp[-\frac{U}{kT}]}{\int d\Omega \exp[-\frac{U}{kT}]}$$

- ELECTRIC FIELD POLING

$U_E = m_u^* E_p$

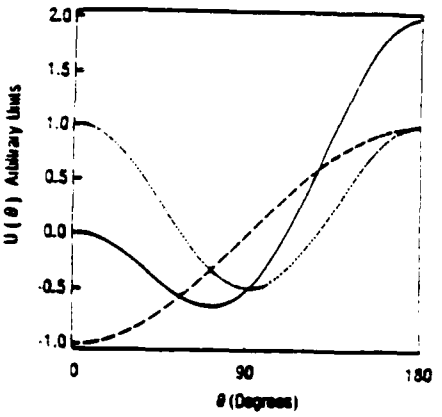
$$\chi^{(2)}_{333} = N\beta^*_{zzz}\frac{m_z^* E_p}{kT}\left(\frac{1}{5} + \frac{4}{7}\langle P_2\rangle + \frac{8}{35}\langle P_4\rangle\right)$$

$$\chi^{(2)}_{113} = \chi^{(2)}_{131} = \chi^{(2)}_{311} = N\beta^*_{zzz}\frac{m_z^* E_p}{kT}\left(\frac{1}{15} + \frac{1}{21}\langle P_2\rangle - \frac{4}{35}\langle P_4\rangle\right)$$

- UNIAXIAL STRESS

$U_T = U_P + U_E = bP_2(\cos\theta) - m^* E_p P_1(\cos\theta)$

ORDERING ENERGY

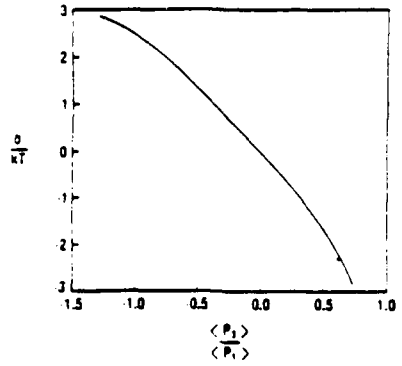


STRESS POTENTIAL

$$\frac{\exp\left[-\frac{(U_P - U_E)}{kT}\right]}{\left(\frac{m^* E}{kT}\right)} = a_1(\tfrac{b}{kT})P_1(\cos\theta) + a_3(\tfrac{b}{kT})P_3(\cos\theta)$$

$$\frac{\langle P_3\rangle}{\langle P_1\rangle} = \frac{3}{5}\frac{a_3}{a_1}$$

b = magnitude of stress potential



DISTRIBUTION FUNCTION

$$\langle P_1\rangle = \frac{2}{3}\frac{m^* E_p}{kT}\frac{a_1}{A_n}$$

$$\frac{\langle P_3\rangle}{\langle P_1\rangle} = \frac{1-3a}{1+2a}$$

$$\langle P_2\rangle = \frac{1}{2}\left(\frac{\langle P_1\rangle}{\left[\frac{m^* E_p}{3kT}\right]} - 1\right)$$

$$\langle P_4\rangle = \frac{1}{4}\left(\frac{\langle P_3\rangle}{\left[\frac{m^* E_p}{7kT}\right]} - 3\langle P_2\rangle\right)$$

FILMS POLED UNDER STRESS

- DISPERSE RED 1 DYE DISSOLVED IN PMMA

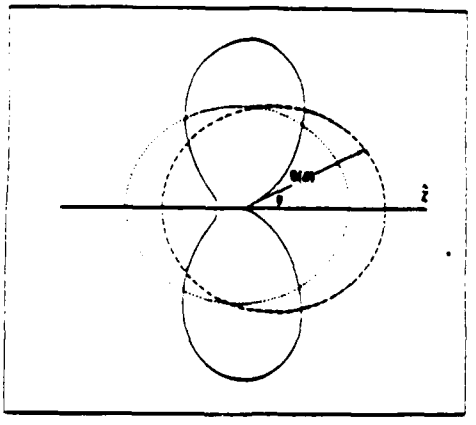
Film #	Dye Number Density N ($10^{20}/cm^3$)	Thickness ℓ (μm)	Poling Field E_p (MV/cm)	Stress σ ($dyne/cm^2 \times 10^7$)
1	2.42	4.0	0.60	0.00
2	1.08	4.9	0.25	3.71

- RESULTS

Film #	a	$\frac{\mu E_p}{kT}$	$\frac{b}{kT}$	$\langle P_1 \rangle$	$\langle P_2 \rangle$	$\langle P_3 \rangle$	$\langle P_4 \rangle$	Δn
1	0.33	0.50	0.00	0.16	-0.020	0.00	0.015	0.0014
2	0.7	0.20	1.2	0.041	-0.20	-0.019	-0.02	-0.0043

NEW MATERIALS

DISTRIBUTION FUNCTION



..... ISOTROPIC

------- POLED

——— STRESS + POLED

$r \propto d \propto N \beta \mu E_p$

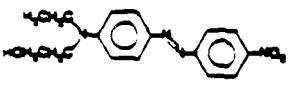
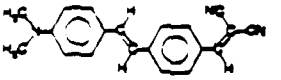
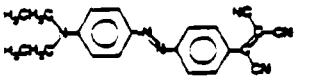
- MOLECULES
- CORONA POLING
- POLYMERS

MOLECULES

$\beta\mu$ MEASURED BY EFISH

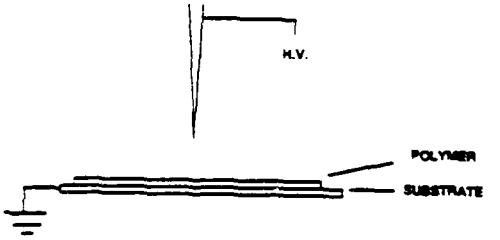
- DIRECT MEASUREMENT IN DIPOLAR SOLVENT, DMSO
- INFINITE DILUTION TECHNIQUE

RESULTS

Molecule		$\beta\mu$*
DR1		1090†
DCV		2860†
TCV		4110#

* $\beta\mu$ in $10^{-30} cm^5 D/esu$
† $\lambda = 1.358 \mu m$
# $\lambda = 1.58 \mu m$

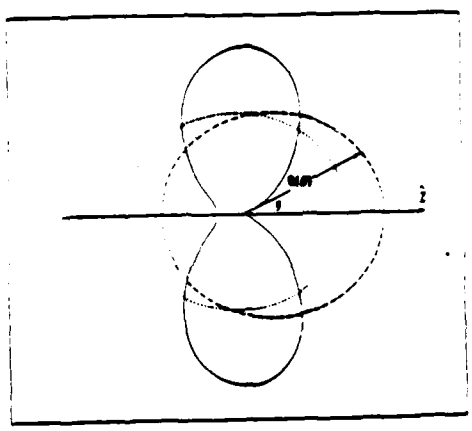
CORONA POLING



- NO ELECTRODE DEPOSITION
- HIGHER POLING FIELD

- RESTRICTED MOTION
  - REDUCES POSSIBLE SUSCEPTIBILITY
  - REDUCES DECAY MECHANISM
- CORONA POLING ALTERS MOLECULAR DISTRIBUTION

DISTRIBUTION FUNCTION



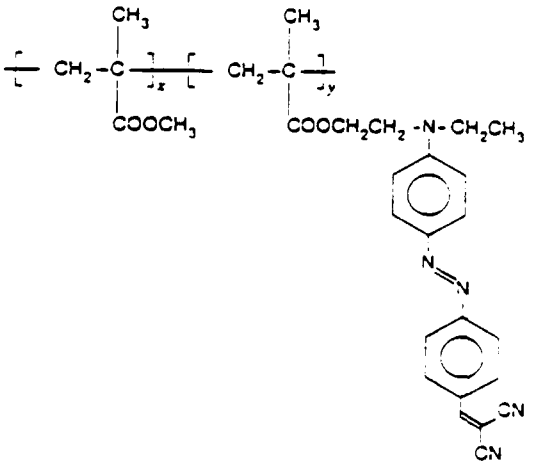
..... ISOTROPIC
------- ELECTRODE POLED
——— CORONA POLED

SUMMARY

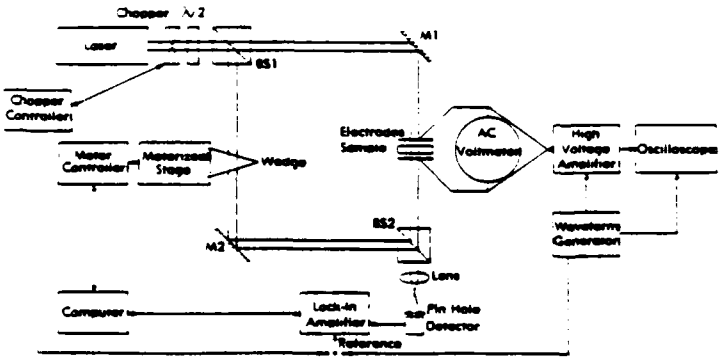
- NONLINEAR OPTICS CAN REVEAL MOLECULAR DISTRIBUTION
  - INTERNAL AND EXTERNAL FORCES
- CORONA POLING
- NEW MATERIALS

SIDE-CHAIN POLYMERS

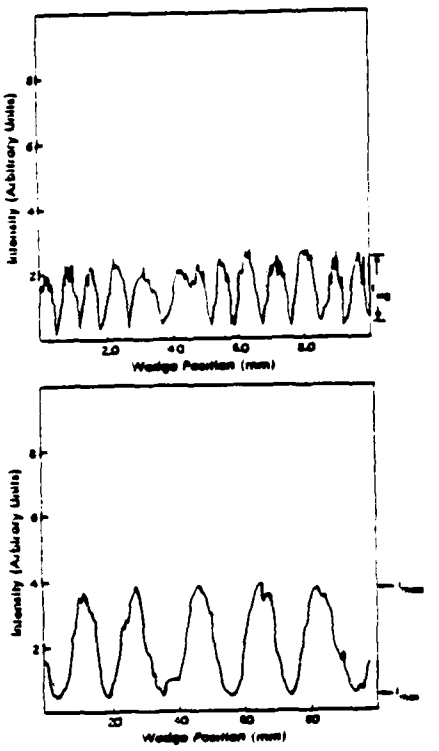
- HIGHER NUMBER DENSITY
- RESTRICTED MOTION
  - EFFECT ON POLING
  - EFFECT ON RELAXATION LIFETIME



ELECTRO-OPTIC MEASUREMENT



ELECTRO-OPTIC MEASUREMENT



RESULTS

MATERIAL	N	n	d_0	d_r	r_{ij}^0	r_{ij}
	(10^{20} cm^3)		(10^{-8} esu)	(10^{-8} esu)	(10^{-12} m/V)	(10^{-12} m/V)
DCV-MMA (corona)	~6	1.58 ($\lambda = .8$)	$d_{33} = 29$ $d_{31} = 20$	$d_{33} = 26$ $d_{31} = 18$	$r_{33}^0 = 9$ $r_{13}^0 = 6$	$r_{33} = 9$ $r_{13} = 6$
DCV/PMMA (corona)	2.3	1.53 ($\lambda = .8$)	$d_{33} = 34$ $d_{31} = 17$	$d_{33} = 9$ $d_{31} = 4.5$		
DR1/PMMA (corona)	2.3	1.52 ($\lambda = .8$)	$d_{33} = 13$ $d_{31} = 6$			
DR1/PMMA (electrode)	2.7	1.52 ($\lambda = .8$)	$d_{33} = 6$ $d_{31} = 2$			

H. Nakanishi

Research Institute
for Polymers and Textiles, Japan

SEVERAL SERIES OF NOVEL POLYDIACETYLENES FOR NONLINEAR OPTICS

G-2

Several Series of Novel Polydiacetylenes
for Nonliner Optics

by

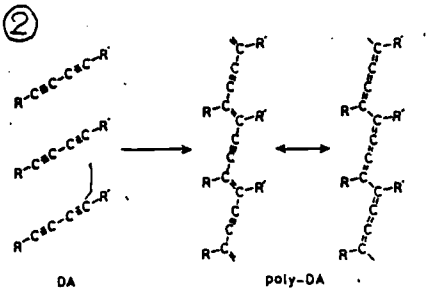
Hachiro NAKANISHI

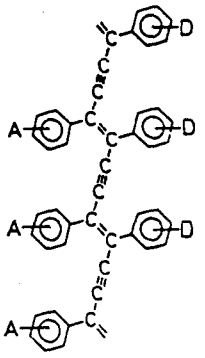
(Res.Inst.for Polymers & Textiles)

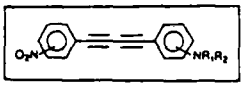
1. Significance of Crystal Engineering for Aromatic Substituted Polydiacetylenes (APDA)
2. APDAs by a Hydrogen-Bonding Effect
3. APDAs by a Bending Effect (I)
4. APDAs by a Bending Effect (II)
5. APDAs by an Anchor-Void Effect
6. APDAs by a Fluorine-Subsitution Effect
7. APDAs by Complex Effects
8. Preliminary Evaluation of $X^{(3)}$ of APDAs
9. Conclusion

Coworkers : H. Matsuda
S. Okada
M. Kato
S. Takaragi
M. Ohtsuka

②







ジアセチレン化合物および高分子化の3次の非線形感受率

化合物	結晶方向	$\chi^{(3)}$(10⁻¹² esu) 2.53 μm	1.90 μm
TCDUモノマー	ノ∥	—	1.3 ± 0.5
	ノ⊥	—	1.1 ± 0.5
TCDUポリマー	ノ∥(主結合方向)	270 ± 140	700 ± 350
	ノ⊥	< 4	< 7
PTSポリマー	ノ∥(主結合方向)	1650 ± 1000	8500 ± 5000
	ノ⊥	< 20	< 100
ゲルマニウム	(100)	4000 ± 2000 (10.6 μm)	
ガリウムヒ素	(100)	400 ± 200 (10.6 μm)	

C. Sauteret et al. (1976)

③

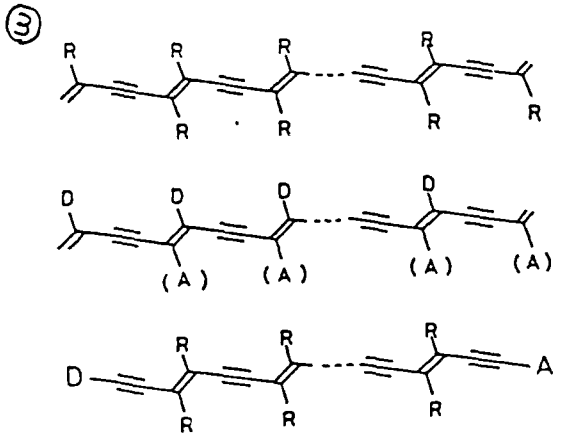


Fig. 1 Interesting polydiacetylene structures for NLO. (R=Ar)

④

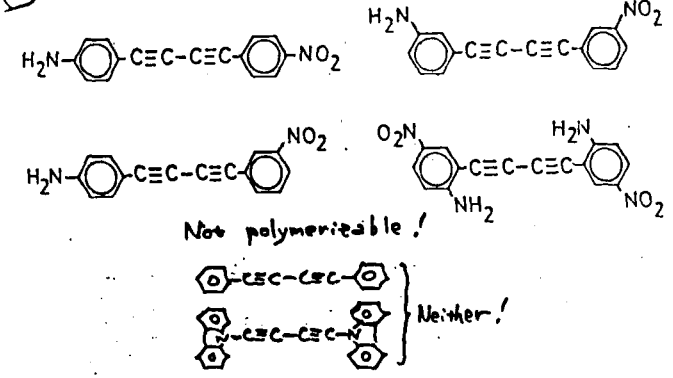
Bandwidths(BW), Bandgaps(Eg), and Ionization Potentials(IP) for Acetylenic(A) and Butatrienic(B) Polydiacetylenes By VEH Calculation.

Substituents		BW	Eg	IP
H	in A	3.972	2.596	5.338
C_6H_5	in A	1.116	1.769	4.903
CH_3	in A	3.265	2.449	5.039
H	in B	4.816	0.154	4.277
C_6H_5	in B	1.878	0.215	4.133
CH_3	in B	4.136	0.435	4.032

B.J.Orchard & S.K.Tripathy,Macromol.,19,1884(1986).

G-3

⑤



⑥

表7 Solid-State Photo-Reactivity of Derivatives of Diphenylbutadiynes as Dependent from Nature and Position of the Substituents in the Phenyl Rings[1]

	Substituents	Reactivity[2] % Yield	color[3]	Crystal Shape[4]	Solubility in DMFA[5]
I	H	no	–	needles	–
II	$-NO_2$	2.0	red	needles	yes
III	$-NO_2$	2.5	red	needles	yes
IV	$-NO_2$	no	–	needles	–
V	$-NH_2$	no	–	platelets	–
VI	$-NH_2$	no	–	platelets	–
VII	$-NH_2$	no	–	microcryst.	–
VIII	$-NH-\overset{O}{\overset{\|}{C}}-CH_3$	10	red-violet	needles	no[6]
IX	$-NH-\overset{O}{\overset{\|}{C}}-CH_3$	35	grass-blue	needles	yes
X	$-NH-\overset{O}{\overset{\|}{C}}-CH_2$	no	–	needles	–
XI	$-NH-\overset{O}{\overset{\|}{C}}-Ph$[7]	0.2	light purple	needles	yes
XII	$-NH-\overset{O}{\overset{\|}{C}}-Ph$	3.0	violet	needles	yes
XIII	$-NH-\overset{O}{\overset{\|}{C}}-Ph$	no	–	needles	–
XIV	$-NH-\overset{O}{\overset{\|}{C}}-NH-Ph$	4.0	light blue	elongated plates	yes
XV	$-NH-\overset{O}{\overset{\|}{C}}-NH-Ph$	13	green blue	elongated plates	no[6]
XVI	$-NH-\overset{O}{\overset{\|}{C}}-NH-Ph$	no	–	elongated plates	–

[1] General structure: H-C≡C-C≡C-R
[2] After 1 hour of irradiation of 25 °C crystals suspended in paraffin-water 1:10 (v/v)
[3] Of the mixtures of monomers and polymers as prepared
[4] Of the monomers and polymeric crystals
[5] Of the polymers in hexamethyl phosphoric triamide at 100°C
[6] Ph = phenyl-
[7] Soluble in conc. H_2SO_4

G. Wegner (1971)

⑦

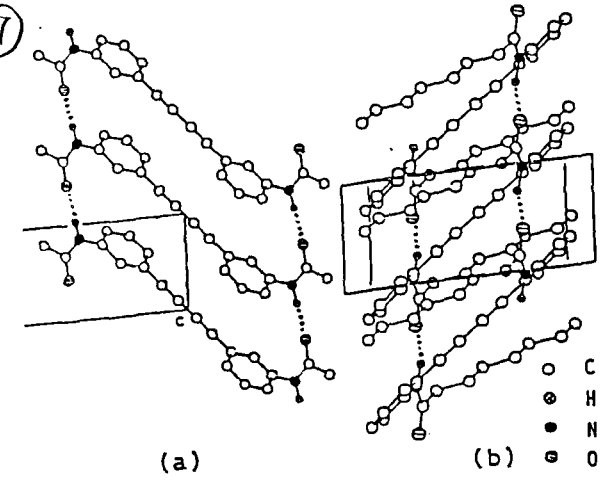
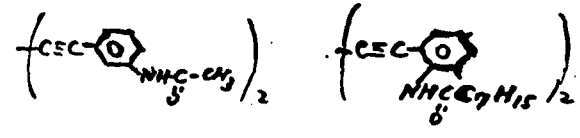


図2　2と3の結晶構造



⑧

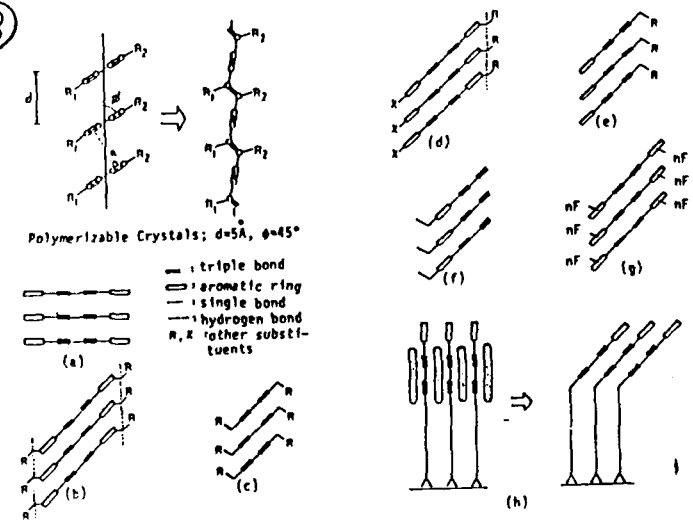


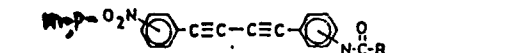
Fig. 2 Crystal engineering of polydiacetylenes with π-conjugation between main chain and

G-4

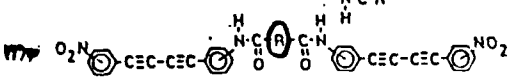
(9) 表 2　アミド基を持つ新規ジアセチレンの固相重合性

Structure	Substituent of -N-C-R (position (R) H O)		Reactivity	Polymer* Yield(%)
(3)	o	($-C_{17}H_{35}$)	+	13.4
	m	($-C_{17}H_{35}$)	+	8.9
	p	($-C_{17}H_{35}$)	-	
	m	($-C_7H_{14}COOH$)	+	13.8
	m	($-C_{18}H_{36}COOH$)	+	
(4)	m	(none)	-	
	m	($-C_4H_8-$)	+	
	m	($-C_7H_{14}-$)	-	
	m	($-C_8H_{16}-$)	+ +	58.8
	m	($-C_{18}H_{36}-$)	+ +	92.9

* ^{60}Co γ ray at the dose of ca. 100 MRad.
- stable, + reactive, + + highly reactive.

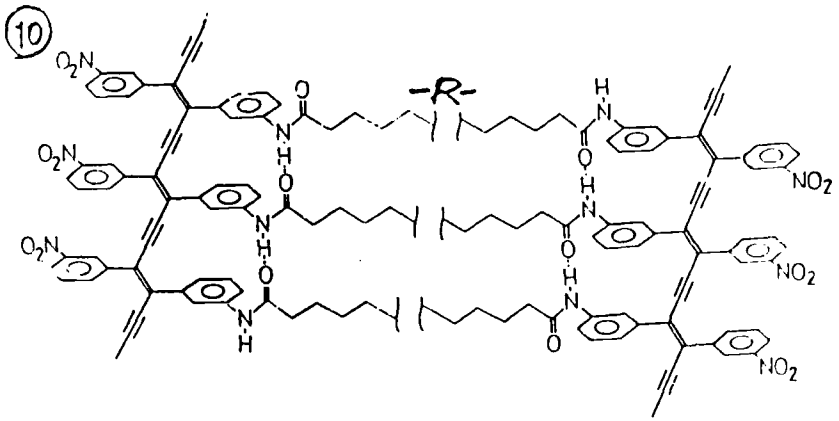


(3)



(4)

(10)



(11)

Table　Reactivity of 4-n

n	Reactivity	IR $\nu_{C=O}$ (cm^{-1})	mp (°C)
7	-	1672	208
8	++	1656	189
9	+	1667	155
10	++	1647	194
11	+	1661	159
18	+++	1658	175

(12)

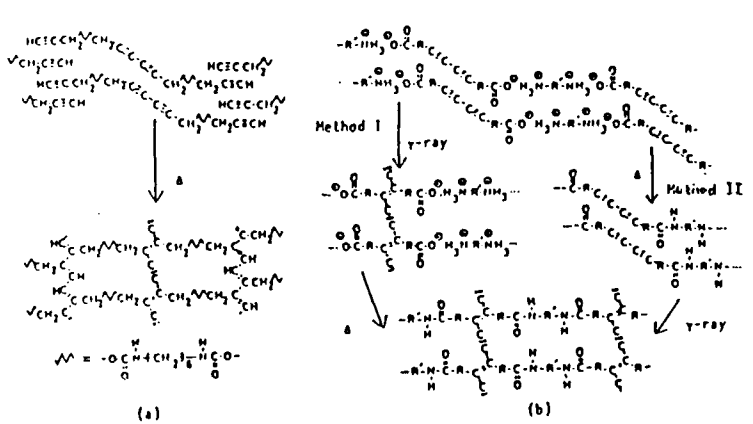
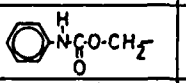
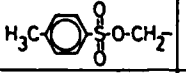
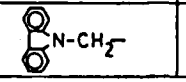


Figure 1. Schematic presentation of 2-D solid-state polymerization of diacetylene-acetylenes (a) and diacetylene nylon salts (b).

G-5

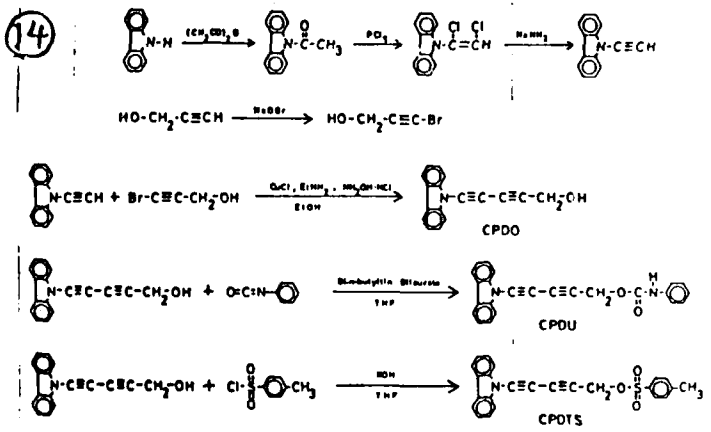
(13)

$R_1-C\equiv C-C\equiv C-R_2$

R_1 \ R_2	A	B	C	D	E	F	m.p./°C reactivity
A	86.0 –						
B	129 –	>240 –					
C HO-CH_2-	68.3 +	132 ++	113 +				
D 	70.8 +	160 ++	93.0 ++	145 +			
E 	64.8 –	111 ++	62.5 ++	114 +	96.0 ++		
F 	153 –		125 ++	112 ++	123 ++	>220 ++	

– stable, + reactive, ++ highly reactive

(14)



Scheme of synthetic procedures of CPDO and the derivatives.

(15)

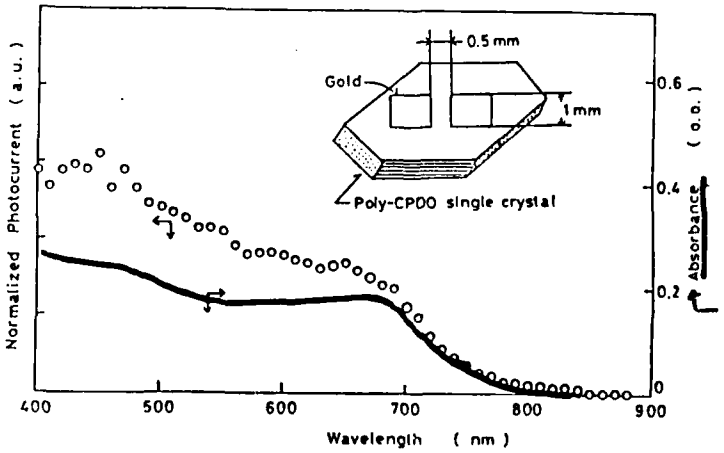


Fig. 7 Action spectrum of photocurrent (O) and absorption spectrum (——) of poly-CPDO.

(16)

Table 3 Band Gap Energies and Ionization Potentials of Polydiacetylenes

Polydiacetylene	Eg(eV)	I.P.(eV)
poly-PTS	2.1	(5.3)*
poly-DCHD	2.3	
poly-CPDO	1.6	4.4

* Calculated

(17)

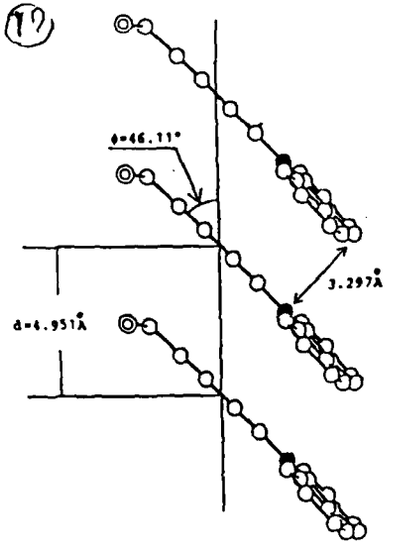


Table Crystallographic data of CPDO's.

	Monomer	Polymer
Formular	$C_{17}H_{11}NO$	$C_{17}H_{11}NO$
Mr	245.3	245.3
Crystal System	Monoclinic	Monoclinic
Space Group	$P2_1/a$	$P2_1/a$
a (Å)	16.269(3)	16.494(6)
b (Å)	4.951(1)	4.873(3)
c (Å)	17.360(4)	19.513(8)
β (°)	113.53(2)	124.27(3)
V ($Å^3$)	1280.4(5)	1296 (1)
Z	4	4
Dx(Mg m^{-3})	1.27_8	1.25_4
Dm(Mg m^{-3})	1.27	1.26

(18)

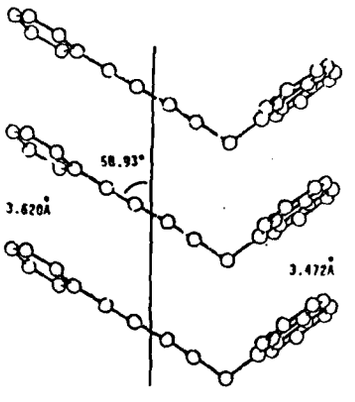
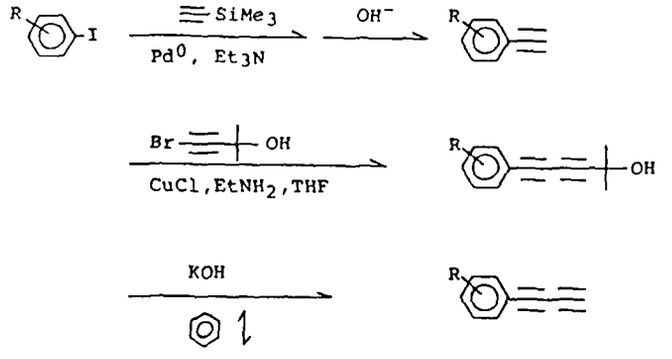


Table Crystallographic data

Formular	$C_{23}H_{15}N$
Mr	305.4
Crystal System	Monoclinic
Space Group	$P2_1/c$
a (Å)	13.180 (4)
b (Å)	4.296 (1)
c (Å)	28.776 (2)
β (°)	91.71 (3)
V ($Å^3$)	1628 (1)
Z	4
Dx(Mg m^{-3})	1.246
Dm(Mg M^{-3})	1.244
R	0.077

(19)



(20)

Table Solid state polymerizability of Phenylbutadiyne derivatives.

NO.	R	UV	γ	Δ	重合収率 (%)	[γ線量 MRad]
1	2-NO_2	O	O	O	95.6	[70.0]
2	3-NO_2	O	O	O	94.3	[25.5]
3	4-NO_2	×	×	O	——	[50.0]
4	2-NH_2	O	O	O	99.0	[70.0]
5	3-NH_2	O	O	O	100	[27.0]
7	2-NH_2 5-NO_2	O	O	O	100	[156.0]

O : active
× : inactive

(21)

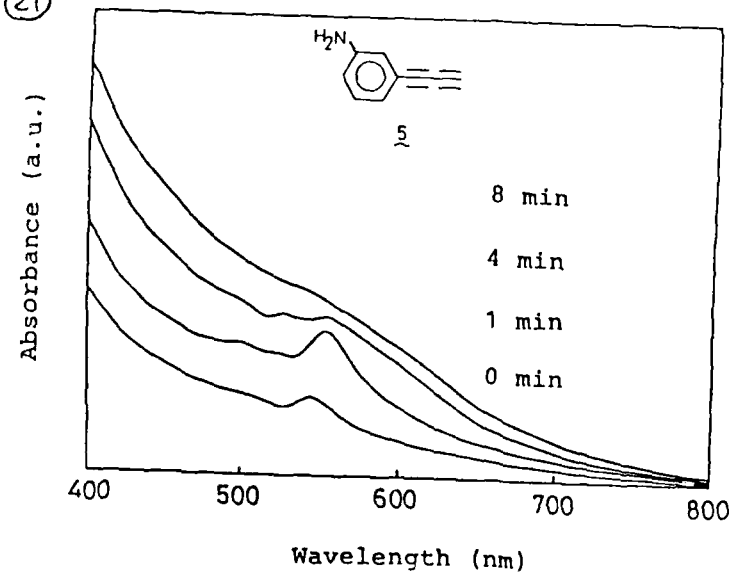
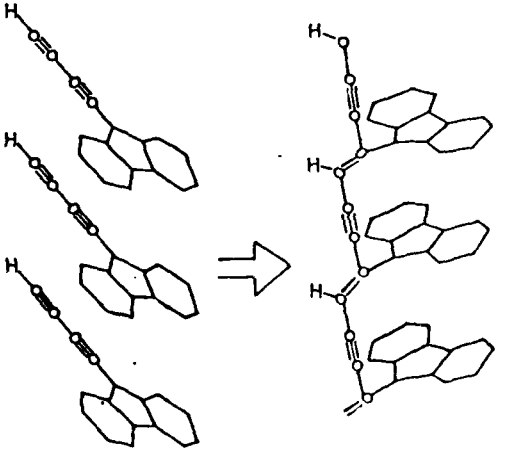


Fig. Absorption spectra of 5 with changing UV irradiation time.

(22)



(23)

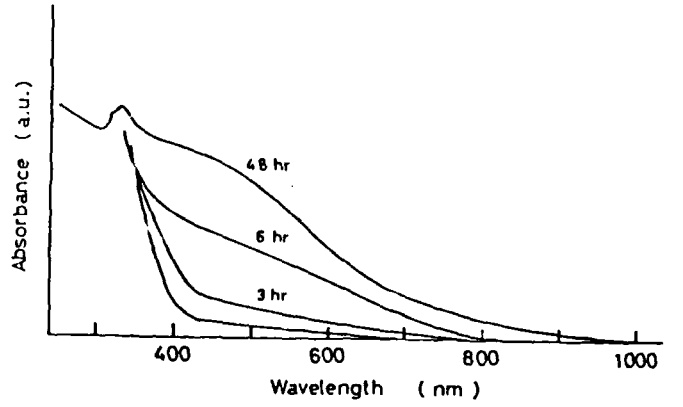


Figure Absorption spectra change of CBDy by heating at 50°C.

(24)

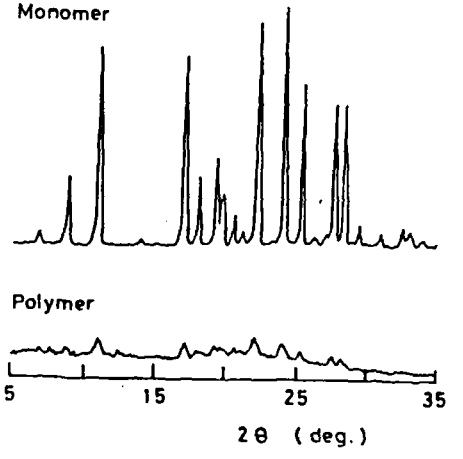
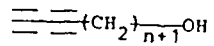
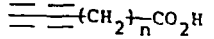


Figure X-ray powder diffraction patterns of CBDy.

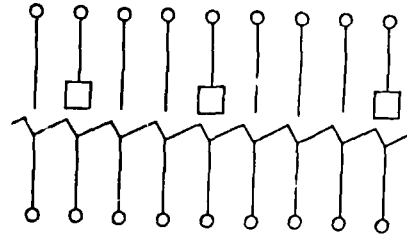
(25)



1-n (n=20,22)



2-n (n=20,22)



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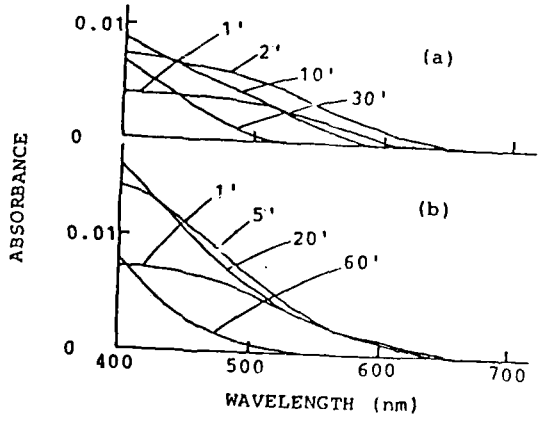
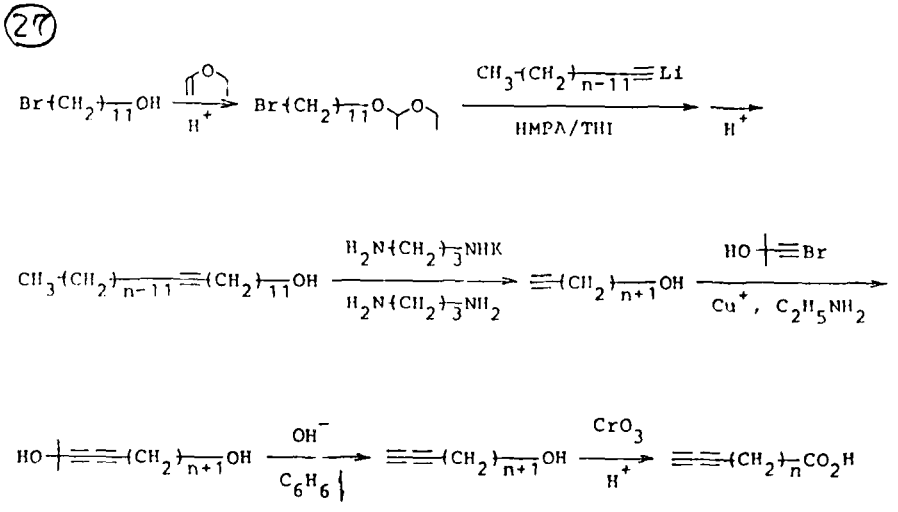
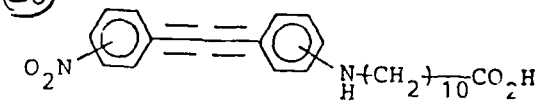


Fig. 4. Visible spectra of 20 layers of 1-20(a) and 2-20(b).

(27)

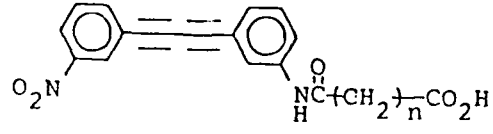


(28)



3-m (3,3'-substituted)

3-p (4,4'-substituted)



4-n (n=7,10)

(29)

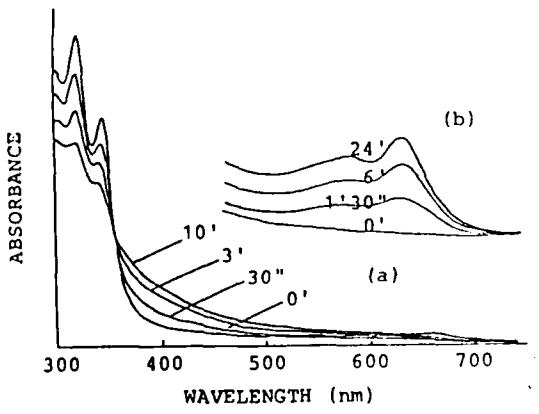
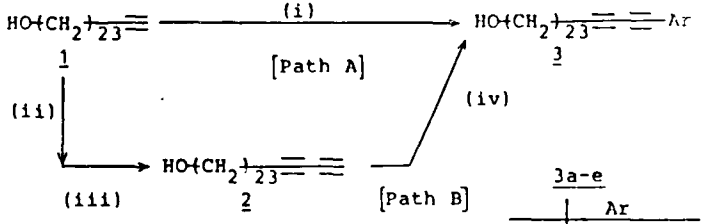


Fig. 8. UV-visible spectra of multilayers of 4-7(a) and 4-10(b).

(30)



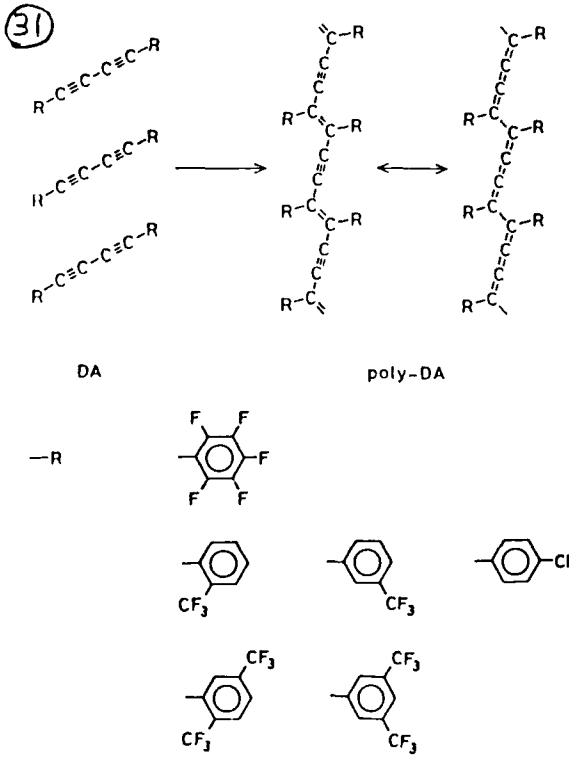
(i) Br—≡—Ph, Cu^+, amine

(ii) Br—≡—OH Cu^+, amine (iii) OH^-

(iv) Ar-I, $(PPh_3)_2PdCl_2$, Cu^+, amine

3a-e	Ar
3a	phenyl
3b	2-tolyl
3c	3-tolyl
3d	4-tolyl
3e	9-anthryl

(31)



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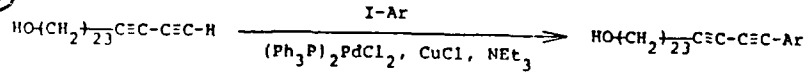


3 : Ar

3a : phenyl
3b : 2-tolyl
3c : 3-tolyl
3d : 4-tolyl
3e : 9-anthryl
3f : pentafluorophenyl
3g : 2-(trifluoromethyl)phenyl
3h : 3-(trifluoromethyl)phenyl
3i : 4-(trifluoromethyl)phenyl
3j : 2,5-bis(trifluoromethyl)phenyl
3k : 3,5-bis(trifluoromethyl)phenyl

(33)

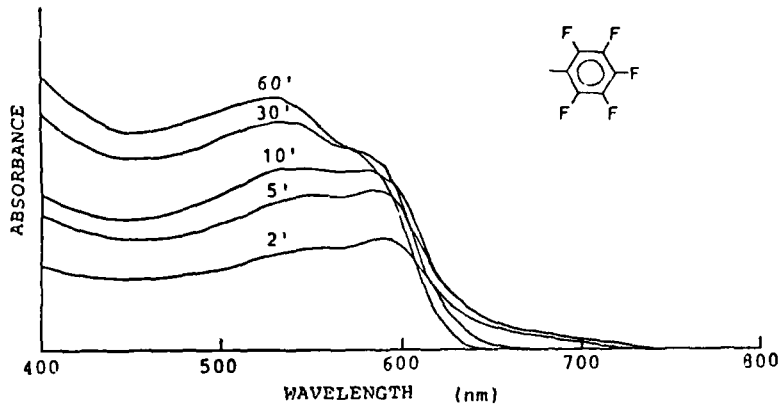


Fig. Absorption spectra of 3f dispersed in KBr with changing UV-irradiation time.

(34)

Table Polymer yield by γ-ray irradiation.

Substituents of phenyl group	γ-ray dose (Mrad)	Polymer yield (%)
——	19.7	2
pentafluoro	19.7	82
2-(trifluoromethyl)	100	11
3-(trifluoromethyl)	100	1>
4-(trifluoromethyl)	100	18
2,5-bis(trifluoromethyl)	50.3	98
3,5-bis(trifluoromethyl)	50.3	1>

(35)

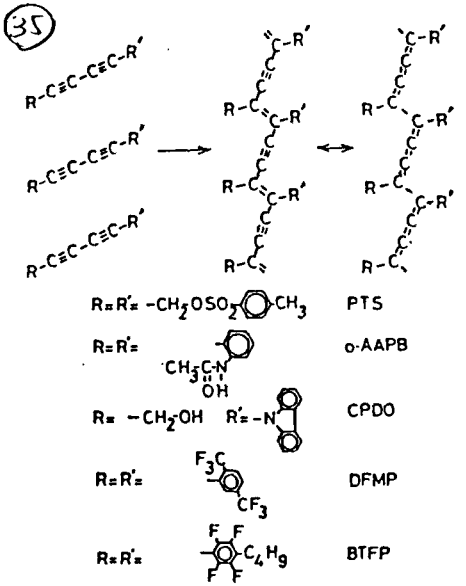


Fig. 1 Solid-state polymerization scheme and polydiacetylene derivatives.

(36)

Table 1 $\chi^{(3)}$ values of polydiacetylene thin films

Poly-DA	Thickness (μm)	$\chi^{(3)} \times 10^{11}$ (esu) Pumping Wavelength (μm) 1.83	1.88	1.94
DFMP	1.09	2.4	3.5	2.6
	0.98	3.7		2.4
BTFP	0.070	28	32	13
	0.054	26		15
PTS	1.35			1.1

Reference: fused quartz, $\chi^{(3)} = 3 \times 10^{-14}$esu at 1.89μm

F. Kajzar
CEN Saclay, France

RESONANCE EFFECTS IN CUBIC HYPERPOLARISABILITIES OF CONJUGATED POLYMERS

H-2

RESONANCE EFFECTS IN CUBIC HYPERPOLARISABILITIES OF CONJUGATED POLYMERS

François KAJZAR

Commissariat à l'Energie Atomique
Institut de Recherche Fondamentale et de Développement Industr
Division d'Electronique, de Technologie et d'Instrumentation
Département d'Electronique et d'Instrumentation Nucléaire
Laboratoire de Physique Electronique des Matériaux
CEN Saclay, 91191 GIF SUR YVETTE, France

- THIN FILM PREPARATION TECHNIQUES (polydiacetylenes)
- THIRD ORDER OPTICAL HYPERPOLARISABILITY DETERMINATION TECHNIQUES
  - Third Harmonic Generation
  - Electric Field Induced Second Harmonic Generation
- NONLINEAR SPECTROSCOPY IN PDA THIN FILMS
  - Multiphoton resonances
  - Two photon resonance ⇒ Kerr susceptibility ⇒ intensity dependent index of refraction
  - Temperature variation of cubic susceptibility
  - Nonlinear Optical Dichroism
- POLARISATION EFFECTS IN PDA THIN FILMS

PDA THIN FILM PREPARATION TECHNIQUES

- Langmuir - Blodgett technique
- Solution casting
- Dipping technique from a polymer solution
- Evaporation technique (sublimation ; ester)
- Shear technique (thin monocrystalline films

Any thin films (0.001 μm up a few tens of microns)

- Nonlinear optical properties characterization

$l \ll l_c$ $\quad l_c = \lambda/2(n_H - n_F)$

$\chi^{(n)} \propto \chi^{(1)n}$ (EFISH) (THG)

$I_{2\omega} \sim I^2 l_c^2$
$I_{3\omega} \sim I^3 l_c^3$ "phase matching"

- Nonlinear spectroscopy

harmonic light within absorption range

- Integrated optics
- Thin film devices

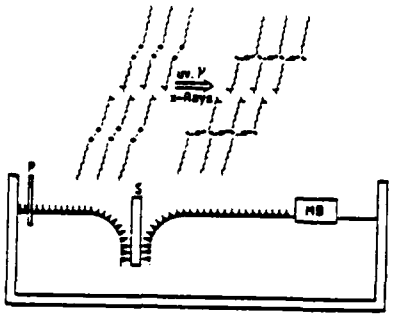
LANGMUIR- BLODGETT METHOD OF THIN FILM DEPOSITION

Diacetylene monomers :

$R_1 - C \equiv C - C \equiv C - R_2$

$R_1 = CH_2)_n COOH$ n=0, 8

$R_2 = CH_2)_m CH_3$ m=10.....15



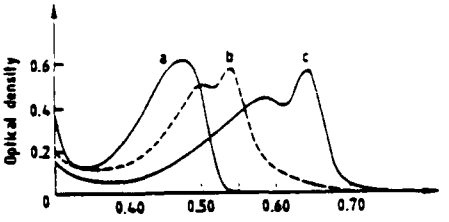
P-pressure sensor MB - mobile barrier S - substrat

Transfer layer by layer of monomer film

Polymerisation of monomer film by UV, γ, X-Ray radiation

Polymerisation of the monomer film on water subphase

Transfer of polymer monolayer ~30Å thick) on a substrat



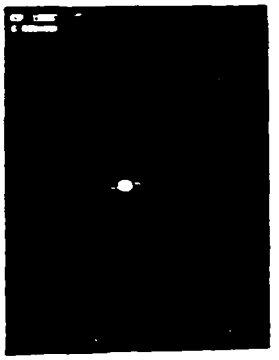
Optical absorption spectra of different diacetylene polymers:

a - yellow form (polymer solution amorphous phase)

b - red form (stable)

c - blue form

Electron micrograph of a 20,22-diacetylene monolayer



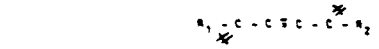
Electron diffraction pattern of a 22, 23-diacetylene monolayer

PRINCIPAL PROPERTIES OF LB FILMS

- Centrosymmetric thin films with controllable thickness - each layer ~ 30Å thick
- Thickness limited to a few thousand of Angstroms
- Two-dimensional order
- Films emanate from polycrystallites large light scattering

SOLUTION CASTING

Soluble polymers



3-BCMU $R_1=R_2=(CH_2)_3OCONHCH_2COOC_4H_9$

4-BCMU $R_1=R_2=(CH_2)_4OCONHCH_2COOC_4H_9$

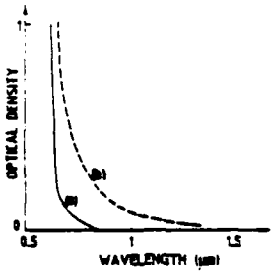
TS-12 $R_1=R_2=(CH_2)_4OSO_2C_6H_4CH_3$

Thin films with thickness varying from a few thousands Angstrom to a few tens of microns

Crystallites - large light scattering

Large surface roughness - light scattering by surface

Surface light scattering effects in solution cast 4-BCMU film (as formed).

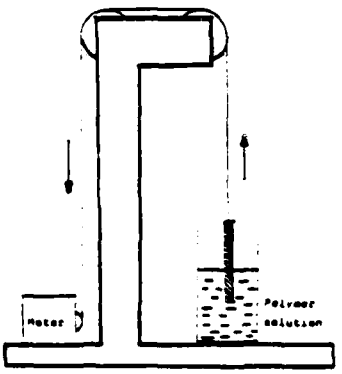


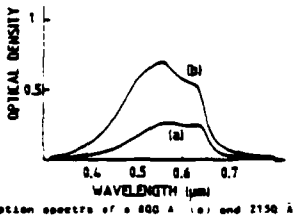
Tail of optical absorption spectrum of a 50 μm thick native 4-BCMU film (a) and after an annealing at 400° C under vacuum and a simultaneous cooling of a silica plate on free film face (b).

H-4

DIPPING TECHNIQUE

from a polymer solution





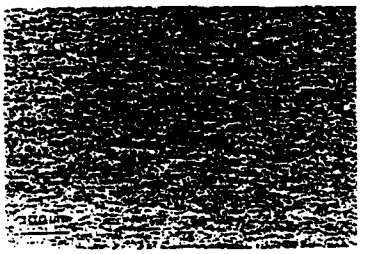
Mixed red + blue forms

Absorption spectra of a 800 Å (a) and 2150 Å (b) thick polymer films obtained by dipping technique from 3-OCHU solution in $CHCl_3$.

MONOMER EVAPORATION TECHNIQUE SUBLIMATION

High vacuum $\sim 10^{-6}$ Torr

Works for practically all DA monomers. Suitable in the case of monomers polymerising thermally like 3-5 BTS - 3DCH yields homogeneous thin films with thickness varying from a few hundreds to a few tens of microns.

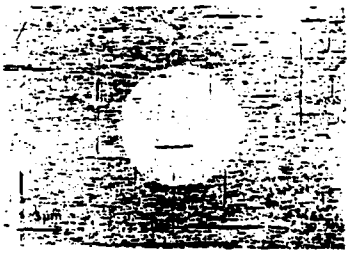


Electron micrograph of a poly-4DCH $R_1aR_2aCH_2{=}C_{1a}{-}C_{2a}{\equiv}C{-}R_3$ thin film showing an isotropic orientation of crystallites.

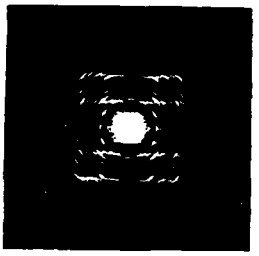
Light scattering by crystallites - this can be reduced by a cooling of substrate diminution of the crystallites size..

EPITAXY

KBr single crystal substrate

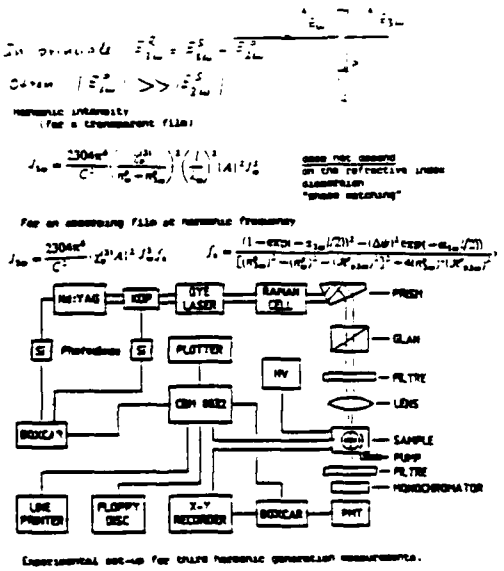


Electron micrograph of a bi-oriented 3DCH film ($250\,Å$) evaporated on KBr single crystal substrate

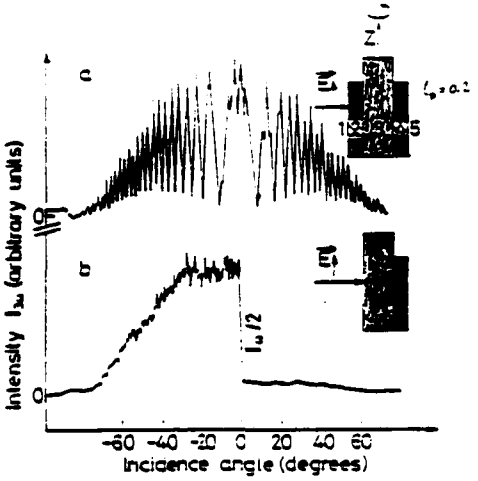


Electron diffraction of a central part of bi-oriented 250 Å thick 3-4DCH film

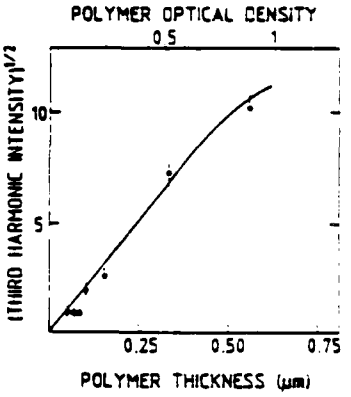
THIRD HARMONIC GENERATION EXPERIMENTS



Experimental set-up for third harmonic generation measurements.



Third harmonic intensity from an LB PDA film as function of rotation angle.



$\chi^{(3)}(-3\omega;\omega,\omega,\omega)$ phase determination

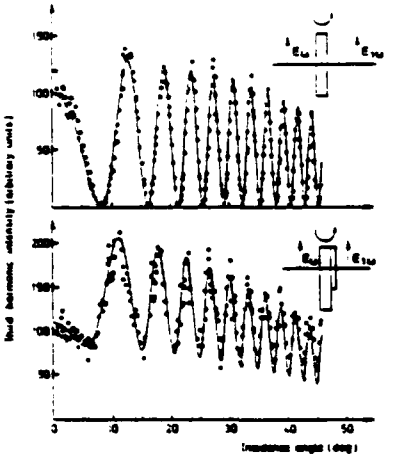


FIG. 4. Third harmonic intensity as function of incidence angle for (a) wave plate and (b) wave guide — polymer film as variable. Points represent measured values and solid lines the calculated ones with calculated values of refractive indices for wave.[1]

Kajzar, Messier, and Rosilio

J. Appl. Phys., Vol. 60, No. 9, 1 November 1986

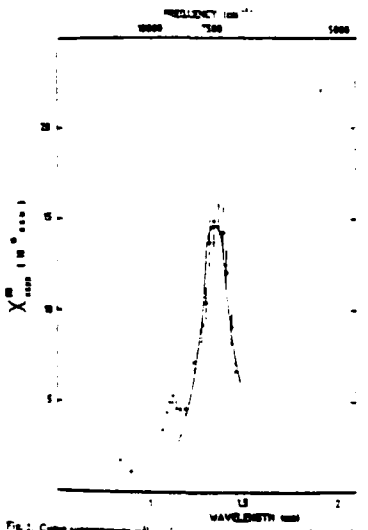


Fig. 1. Cubic susceptibility $\chi^{(3)}$ for ... dispersive and dynamic component, as a function of the wavelength. The dispersive one is a wave-shaped fit, as dynamic as the real.

H-6

ELECTRIC FIELD INDUCED OPTICAL SECOND HARMONIC GENERATION

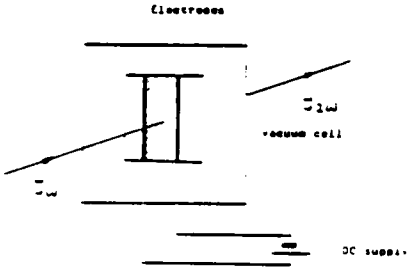
centrosymmetric - centrosymmetric structure

no second harmonic generation

by applying an external DC field

centrosymmetry broken

second harmonic generation

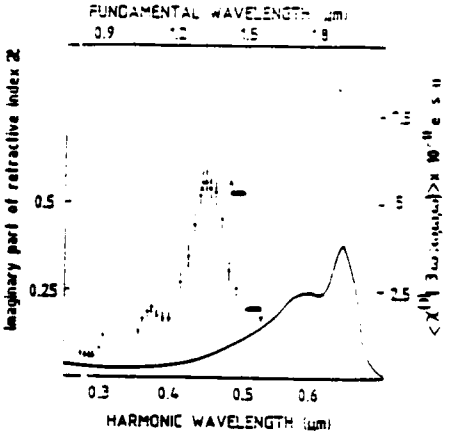


Comparison with a single crystal quartz standard (Q)

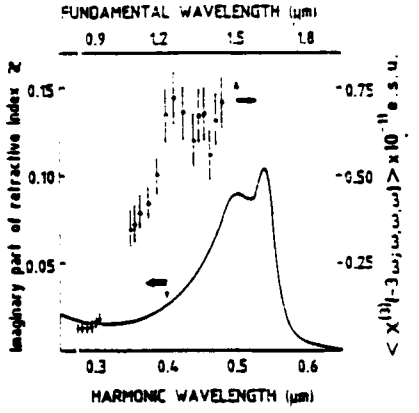
$$\langle \chi^{(3)}(-3\omega;\omega,\omega,0)\rangle = \frac{\gamma_{11}}{3\varepsilon_0 E_{dc}} \times \frac{3\varepsilon_0 + \chi^{(3)}_{1111}(-3\omega;\omega,\omega,0)E^2_{dc}}{3\varepsilon_0 + \chi^{(3)}_{1111}(-3\omega;\omega,\omega,0)E^2_{dc}} \cdot \frac{\varepsilon_{2\omega}}{\varepsilon_{2\omega}+2} \cdot \frac{\varepsilon_{\omega}+2}{\varepsilon_{\omega}+2} \cdot \frac{\varepsilon_{\omega}}{\varepsilon_0} \cdot \frac{\gamma_{11}}{\gamma_Q} \cdot \frac{\chi^{(3)}_{1111}(-3\omega;\omega,\omega,0)}{\chi^{(3)}_{1111}(-3\omega;\omega,\omega,0)}$$

(e.s.u.)

γ = polymer film

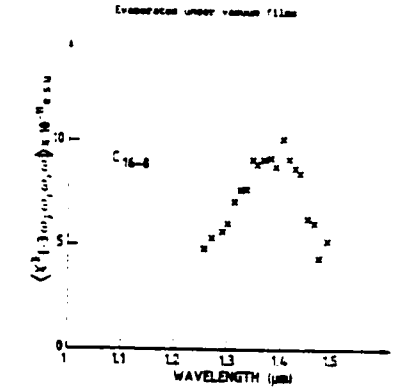


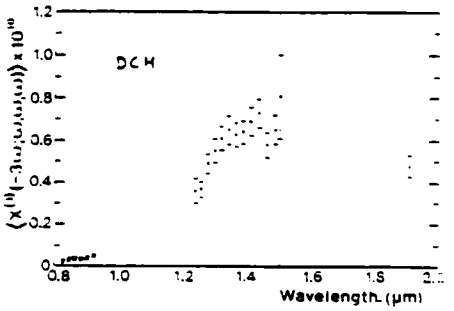
C_{16-8} LB film - blue form

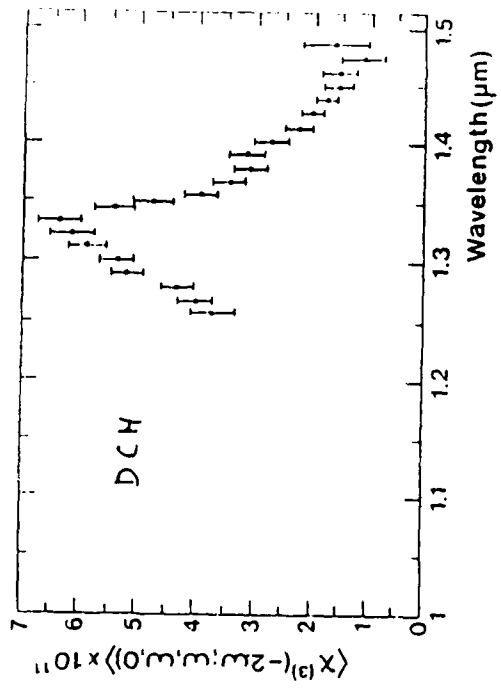


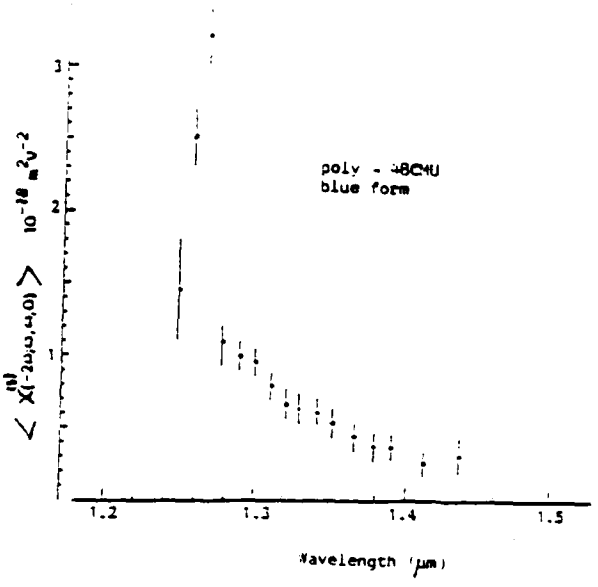
C_{16-8} LB film - red form

Evaporated under vacuum films

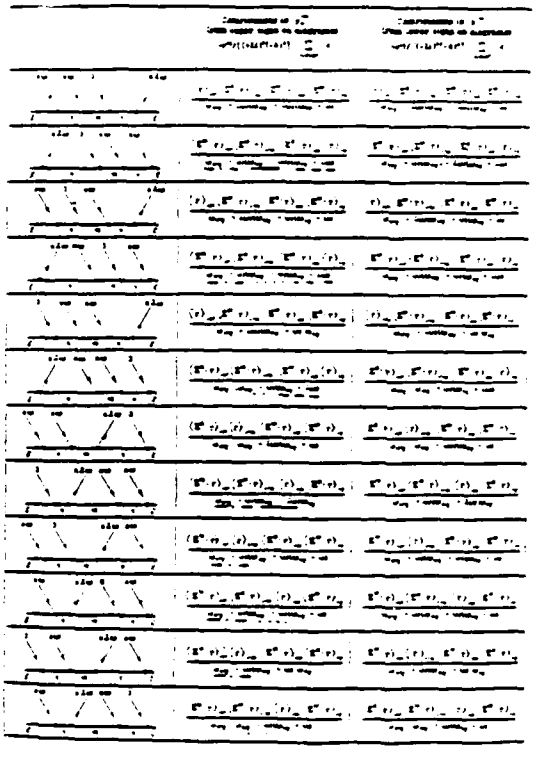








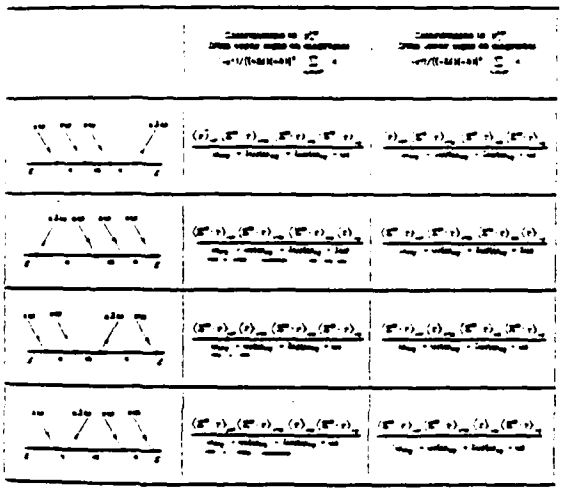
Tensor elements contributing to $\chi^{(3)}$(-2w;w,w,0) (EFISHG)



J. F. Ward, Rev. Mod. Phys., 37, (1965)

- two photon resonance with the same symmetry (as fundamental) level
- - - - - two photon resonance with opposite (to fundamental) symmetry level
- - - one photon resonance

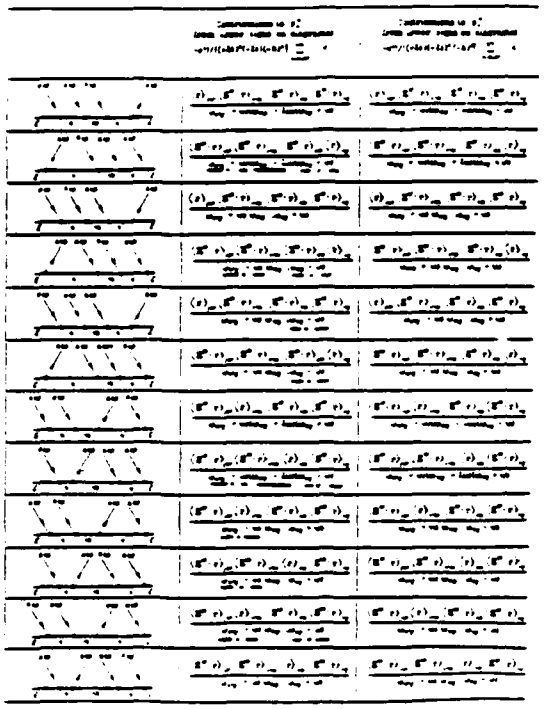
Tensor elements contributing to $\chi^{(3)}$(-3w;w,w,w) (THG)



J. F. Ward, Rev. Mod. Phys., 37, (1965)

- two photon resonance with a (same symmetry as fundamental) level
- - - - three photon resonance
- - - - one photon resonance

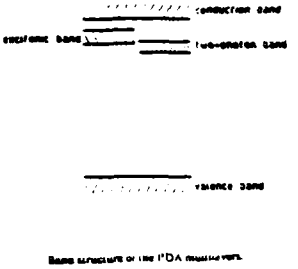
Tensor elements contributing to optical Kerr susceptibility $\chi^{(3)}(-\omega;\omega,\omega,-\omega)$



J.F. Ward, Rev. Mod. Phys. 37, 1 (1965)

—— - two photon resonance

- . - one photon resonance



Band structure of the PDA molecules

Intensity dependent index of refraction

$$n = n_0 + n_2 I^{\omega}$$

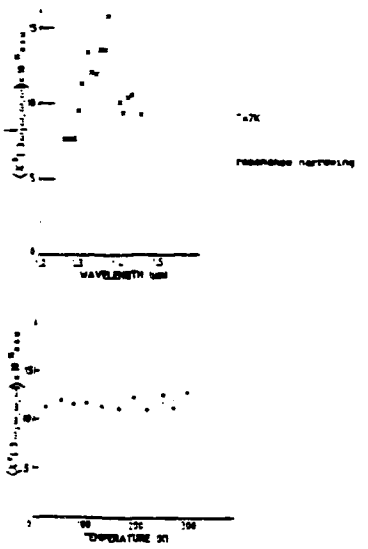
$$n_2 = 12\pi^2 \chi^{(3)}(-\omega;\omega,\omega,-\omega)/n_0^2 c$$

At two photon resonance - $\chi^{(3)}(-3\omega;\omega,\omega,-\omega)$ complex

↓

active optical bistability

Temperature variation of $\chi^{(3)}(-3\omega;\omega,\omega,\omega)$



Constancy of $\chi^{(3)}(-3\omega;\omega,\omega,\omega)$ vs temperature - electronic origin of cubic hyperpolarisability - crude space filling model - Schmitt-Rink et al Phys. Rev. B32, 1985

H-9

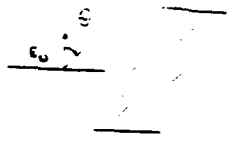
NONLINEAR OPTICAL DICHROISM

Enhanced $\chi^{(2)}$ [illegible] e.g. in direction of polymer chain

θ = angle between incident electric field and polymer chain

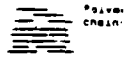
Harmonic intensity

$$I_{3\omega} \sim \cos^6\theta \; I_\omega^3$$



Evaporated oriented DCH thin film

Bi-axial orientation of polymer chains mutually perpendicular



In linear optics crossed polarizers, linear optical dichroism

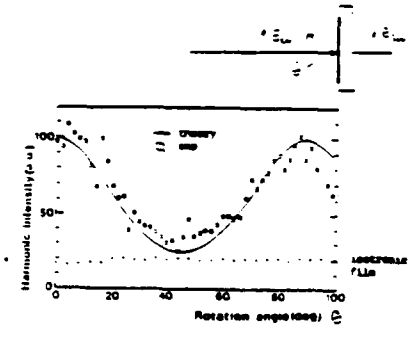
$I = I_\omega \cos^2\theta + \cos^2(90°-\theta) \; I_\omega = I_\omega$

In THG experiments

$E_{3\omega} = A(\cos^3\theta + \sin^3\theta) E^3_\omega$ harmonic field

$I_{3\omega} = E_{3\omega}^2 = A^2 \cos^6\theta + \sin^6\theta) I^3_\omega$ harmonic intensity

θ = angle between incident electric field and polymer chain

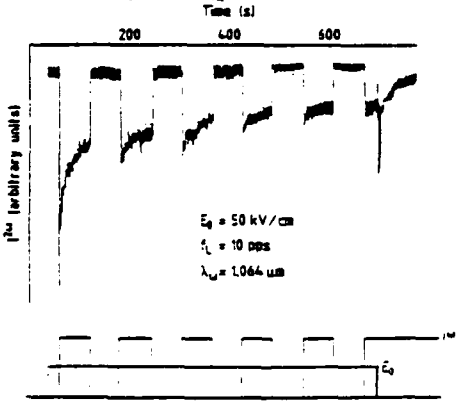


Third harmonic intensity from a bi-oriented 8-DCH thin film obtained by epitaxy on a <Br> single crystal substrate.

POLARIZATION EFFECTS

LB film

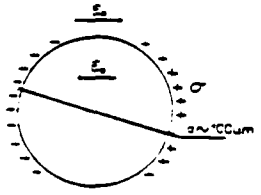
"Slow form" LB [illegible] $2 = (\varepsilon n_e)_\beta \cos\alpha d_{/\lambda}$ $2 - C - C \neq C - C -$ $2' = (\varepsilon n_e)_{or}$ C



Decrease of SH intensity due to an internal polarization

creation of e-h pairs and their separation in external DC field

H-10



Setting of the internal polarization by charge trapping at the laser spot boundaries.

CONCLUSIONS

ADVANTAGES

Large $\chi^{(3)}$ with fast response time : ps
Two photon resonance in telecommunications window : 1.3 - 1.6 µm
active optical bistability
logic systems
This film feasibility by different techniques
orientes this films
epitaxy
Optical gap and physico-chemical properties can be modified by a choice of side groups

PROBLEMS

Light scattering
amorphous thin films
Photodecomposition
Chemical stability : PTS
Blue-red transformation : in some cases

COWORKERS

Jean MESSIER - chief of the laboratory
Pierre-Alain CHOLLET
Dominique GREC
Jean-Michel MUNZI
Fabrice CHABRA - graduate student
Jacques BANIDE
Roger IRAS - technical staff
Andre LORIN

EXTERNAL COLLABORATIONS

Isabelle LEDOUX
Joseph ZYSS - CNET Bagneux
Alain BOUDET - CNRS Toulouse
Jacques LEMOIGNE
Anne THIERRY - CRM Strasbourg
Shahab ETEMAD - Bellcore
Lewis ROTHBERG - AT&T Murray Hill
Michel DUMONT
Jean-Claude LOULERGUE - Institut d'Optique Orsay
Yves LEVY
Gerhard WEGNER - MPI Mainz

Y. R. Shen

University of California at Berkeley

NONLINEAR OPTICAL MEASUREMENTS ON LIQUID CRYSTALS AND QUASI-LIQUID CRYSTALS

Optical Nonlinearities of Liquid Crystals and Quasi-Liquid Crystals

Motivation:

Liquid crystal molecules are highly nonlinear

Existence of many liquid crystals with different molecular structures

Dependence of nonlinearities on molecular structure

Gary Berkovic
Theo Rasing

Technique for measuring $\overleftrightarrow{\alpha}^{(2)}$

SHG from molecular monolayer spread on water

$$\chi^{(2)}_{ijk} = N L_{ii} L_{jj} L_{kk} \langle G^{\alpha\beta\gamma}_{ijk}(\Omega) \rangle \alpha^{(2)}_{\alpha\beta\gamma}$$

If $\Omega \equiv \theta$ and L's are known, then the n elements of $\overleftrightarrow{\alpha}^{(2)}$ can be deduced from measurements of $n+1$ independent components of $\overleftrightarrow{\chi}^{(2)}$.

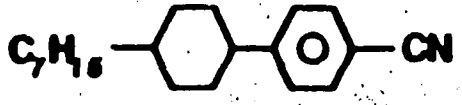
Advantages:

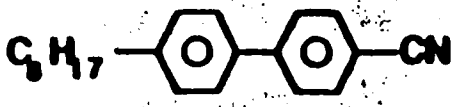
1. Molecular density can be a variable.
2. Local field effect could be less important.

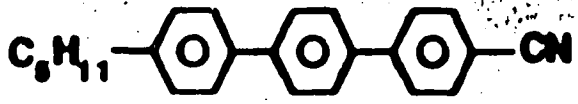
Disadvantages:

1. Not all molecules are spreadable on water.
2. Molecules could interact with water.

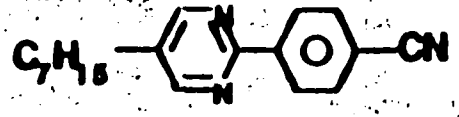
ALKYL-CYANO-(POLY)-PHENYLS

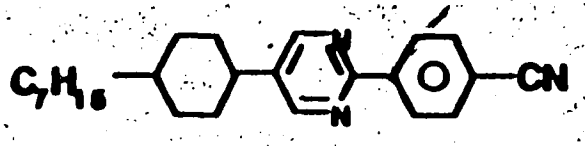
I 

II 

III 

ALKYL-CYANO-PHENYLPYRIMIDINES

IV 

V 

ALKOXY-CYANO-BIPHENYL

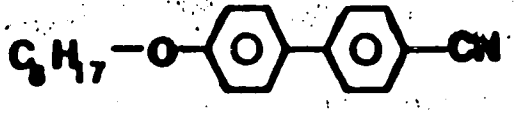
VI 

TABLE 1 Second order polarizabilities, $\alpha_{zzz}^{(2)}$, for molecules I - VI. θ_0 is the average orientation angle of the molecular long axis to the surface normal, as calculated from the SHG data.

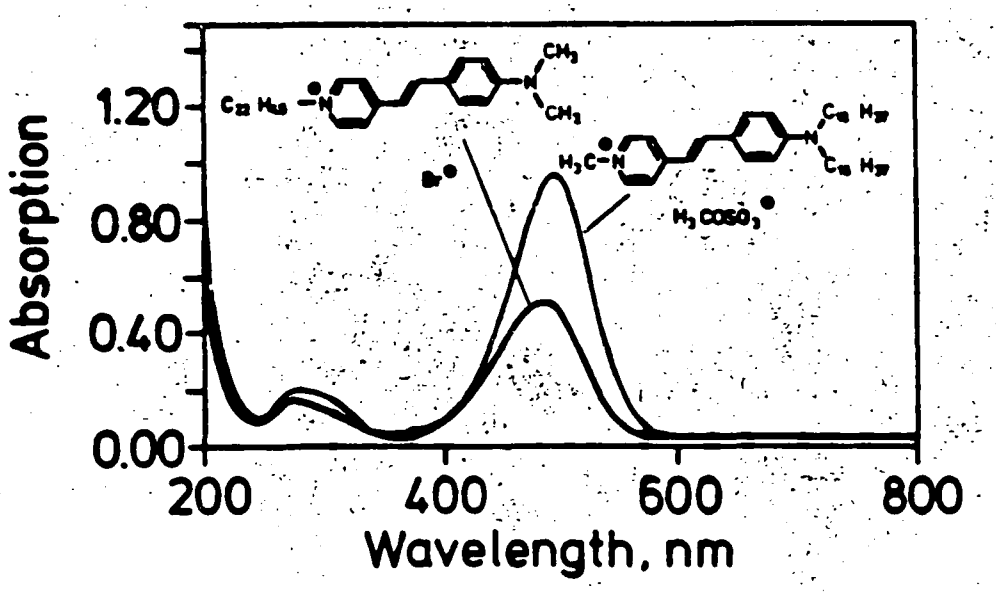
	$\lvert\alpha_{zzz}^{(2)}\rvert$ (10^{-30} esu)		θ_0 (°)
	at 2ω resonance	at 1.06 μm	
I	4	a	80 ± 10
II	25	3	71 ± 2
III	13	a	60 ± 2
IV	8	a	79 ± 3
V	8	a	82 ± 4
VI	40	5	78 ± 2

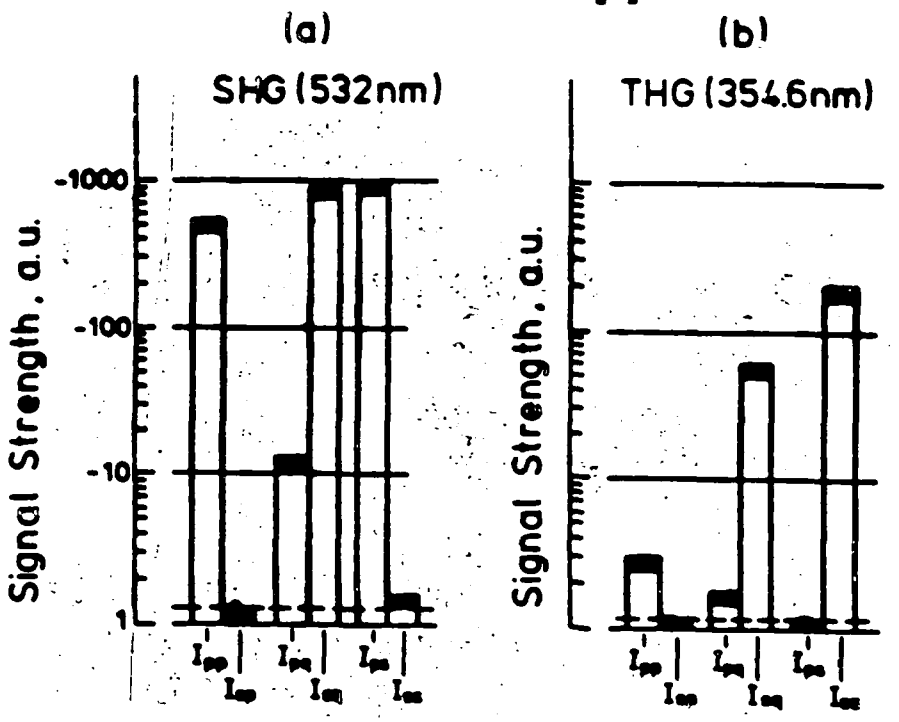
Results:

1. $\alpha^{(2)} \sim 10^{-29}$ esu
2. CN is a better electron donor than COOH.
3. Interruption of electron delocalization decreases $\alpha^{(2)}$
4. Triphenyl is worse than biphenyl presumably because of twist between phenyl rings.

Nonlinearities of Hemicyanine Dyes and the Environmental Effect

G. Marowsky
L. F. Chi
D. Mobius
R. Steinhoff
D. Dorsch
B. Rieger

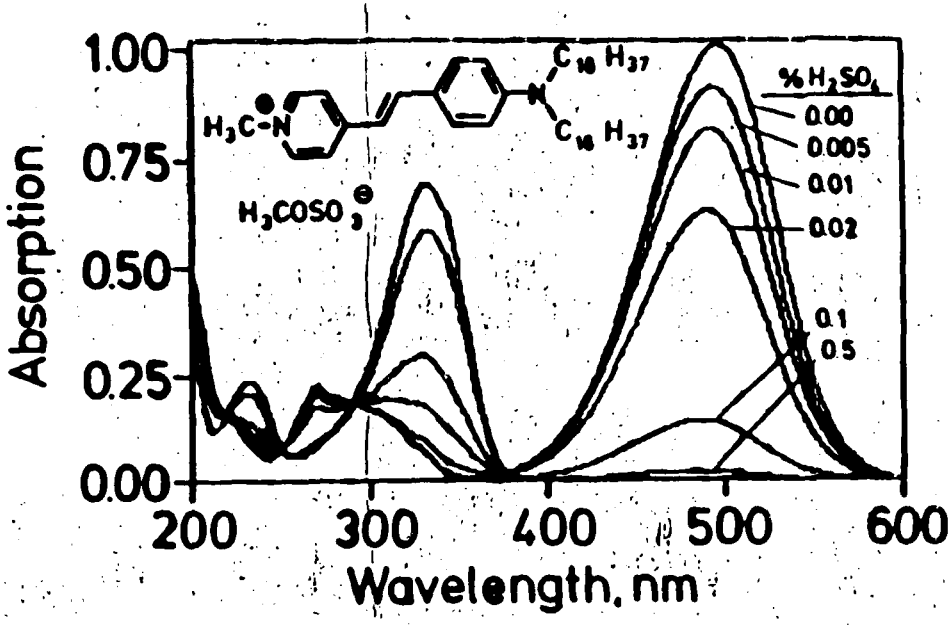




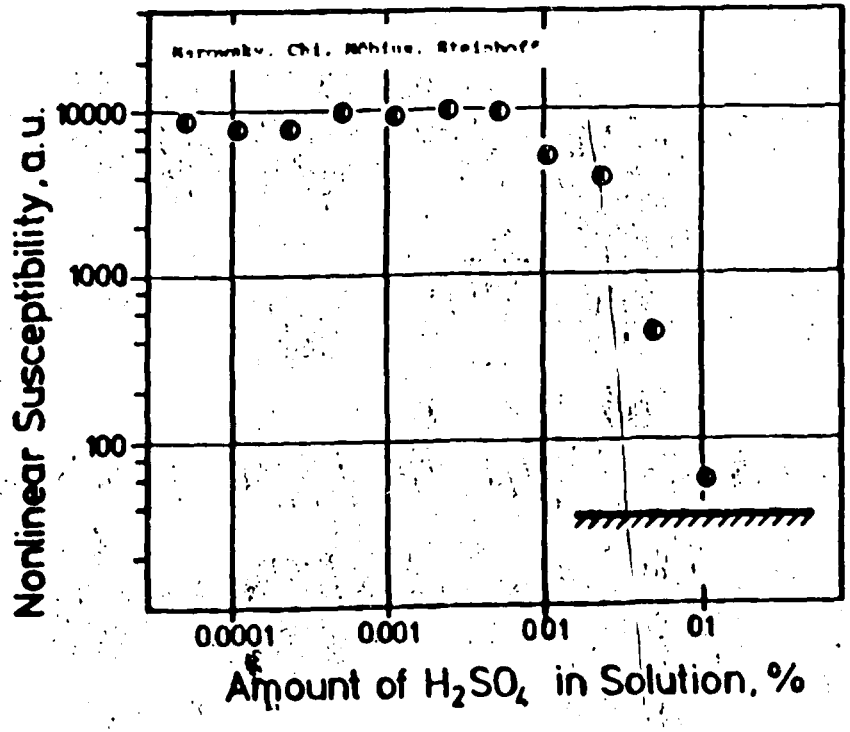
Marowsky, Chi, Möbius, Steinhoff, Shen, Dorsch, Rieger: Nonlinear Optical Properties ...

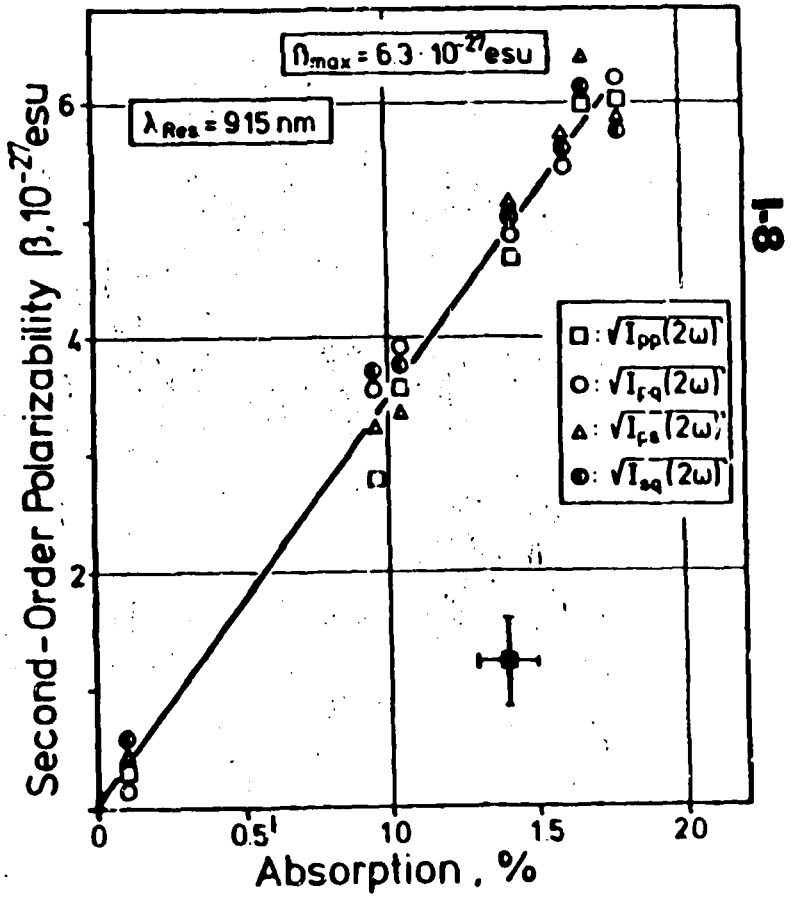
Effects of Protonation

1. Suppresses charge-transfer absorption
2. Drastically reduces $\chi^{(2)}$
3. $\chi^{(2)} \propto$ Charge-transfer absorption
   $\propto N_{\text{Unprotonated}}$
4. UV absorption band has little effect on $\chi^{(2)}$.



Marowsky, Chi, Möbius, Steinhoff, Shon, Dorsch, Rieger: Nonlinear Optical Properties ..





8-1

Poling
in
Quasi Liquid Crystal Films

H. Hsiung
T. Rasing
F.P. Shvartzman
I.R. Cabrera
V.A. Krongauz

Theory of Poling

Assume $\vec{\alpha}^{(2)}$ and $\vec{p}$ dominated by $\alpha^{(2)}_{zzz}$ and p_z. $\vec{E}$ along $\hat{x}$

$$\chi^{(2)}_{xxx} \propto \alpha^{(2)}_{zzz} \langle \cos^3\theta \rangle$$

$$\chi^{(2)}_{yyx} \propto \alpha^{(2)}_{zzz} [\langle \cos\theta \rangle - \langle \cos^3\theta \rangle]$$

$$\langle \cos^n\theta \rangle = \int_{-1}^{1} \cos^n\theta \, e^{-V/kT} d(\cos\theta) / Z$$

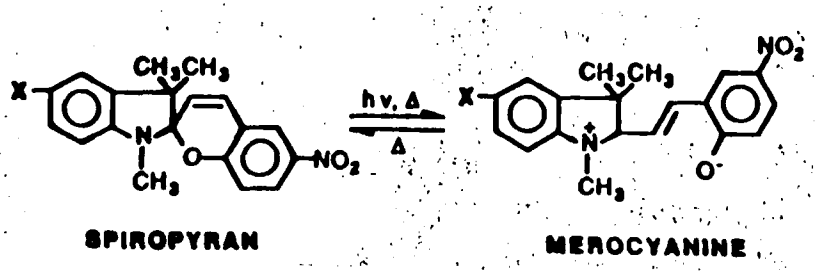
$$V = V_N - u\cos\theta - pE\cos\theta$$

$$V_N = -U_2 P_2(\cos\theta) - U_4 P_4(\cos^4\theta) -$$

$$\langle \cos^n\theta \rangle \cong \int_{-1}^{1} \cos^n\theta \left(1 + \frac{u + pE}{kT}\cos\theta\right)^{V_N/kT} \times d(\cos\theta) / Z_N$$

$$= \langle \cos^n\theta \rangle_0 \qquad n \text{ even}$$

$$= \frac{u + pE}{kT} \langle \cos^{n+1}\theta \rangle_0 \qquad n \text{ odd}$$



SPIROPYRAN MEROCYANINE

$\langle \cos^2\theta \rangle = \langle \cos^2\theta \rangle_0$ indep of E

$\langle P_2(\cos\theta) \rangle = \frac{1}{2}(3\langle \cos^2\theta \rangle - 1) = \langle P_2(\cos\theta) \rangle_0$

$\equiv S$

obtained from birefringence

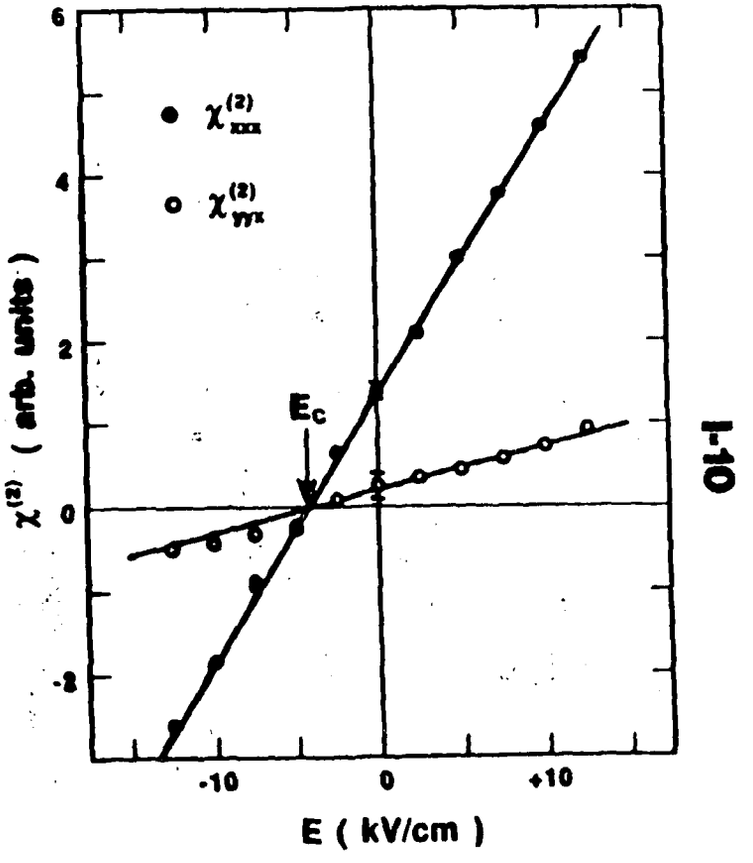
$\langle \cos\theta \rangle = \langle \cos^2\theta \rangle_0 \left(\frac{u + pE}{kT}\right)$

$\langle \cos^3\theta \rangle = \langle \cos^4\theta \rangle_0 \left(\frac{u + pE}{kT}\right)$

$\chi^{(2)}_{xxx} \propto \langle \cos^4\theta \rangle_0 \left(\frac{u + pE}{kT}\right)$

$\chi^{(2)}_{yyx} \propto [\langle \cos^2\theta \rangle_0 - \langle \cos^4\theta \rangle_0] \left(\frac{u + pE}{kT}\right)$

Measurements of $\chi^{(2)}_{xxx}$ and $\chi^{(2)}_{yyx}$ versus E allows the determination of $\langle \cos^4\theta \rangle_0$, u, and ϕ.



I-10

D. J. Gerbi

3M Co.

NONLINEAR OPTICAL EFFECTS IN CONJUGATED SYSTEMS

SECOND ORDER NONLINEAR OPTICAL EFFECTS IN CONJUGATED SYSTEMS

DIANA GERBI

G. T. BOYD

D. A. ENDER

R. M. HENRY

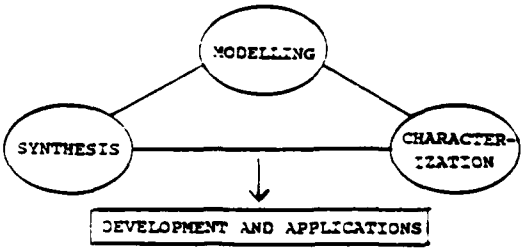
K. K. KAM

P. C. W. LEUNG

J. J. STOFKO

ADVANCED OPTICAL MATERIALS
SCIENCE RESEARCH LABORATORY
3M CORPORATE RESEARCH LABORATORIES

ADVANCED OPTICAL MATERIALS PROGRAM (ORGANIC BASED DEVICES)



- IDENTIFY CANDIDATE MATERIALS
- UNDERSTAND AND MAINTAIN MOLECULAR ORDER
- DETERMINE APPLICATIONS OF MATERIALS. FEASIBILITY IN DEVICES

$\underline{X^{(2)}}$

OPTICAL COMMUNICATIONS

FIBER OPTICS LAB
TELCOMM
3M DORRAN
EOTEC

SENSORS

FIBER OPTICS LAB

$\underline{X^{(3)}}$

OPTICAL SIGNAL PROCESSING

INFORMATION AND IMAGING TECHNOLOGIES

OPTICAL SIGNAL PROCESSING
OPTICAL SENSOR PROTECTION

APOSR

OUTLINE

I. REVIEW OF SECOND ORDER NONLINEAR OPTICS, CHARACTERIZATION METHODS AND DEVICE CONFIGURATIONS

II. ADVANTAGES OF ORGANIC NONLINEAR OPTICAL MATERIALS

III. MATERIALS PROCESSING/APPLICATIONS

IV. ELECTRO-OPTIC MATERIALS - CRYSTALS AND POLED POLYMER SYSTEMS

MACROSCOPIC POLARIZATION:

$$P_i = P_{i_0} + \chi^{(1)}_{ij} E_j + \chi^{(2)}_{ijk} E_j E_k + \chi^{(3)}_{ijkl} E_j E_k E_l \cdots$$

MICROSCOPIC POLARIZATION:

$$p_j = p_{j_0} + \alpha_{jk} E_k + \beta_{jkl} E_k E_l + \gamma_{jklm} E_k E_l E_m \cdots$$

REVIEW OF SECOND ORDER NONLINEAR OPTICAL EFFECTS

ELECTRO-OPTIC EFFECT:

Index of refraction changes with applied voltage

$$n = n_o + \Delta n(E)$$

$$\Delta n \propto \chi^{(2)}$$

SUM FREQUENCY GENERATION:

Output frequency = sum of input frequencies

$$w(out) = w_1 + w_2$$

SHG: $I(2w) \propto [\chi^{(2)}]^2 [I(w)]^2$

DIFFERENCE FREQUENCY GENERATION:

Output frequency = difference of input frequencies

$$w(out) = w_1 - w_2$$

CHARACTERIZATION METHODS
FOR
SECOND ORDER NONLINEAR OPTICAL MATERIALS

POWDER SHG

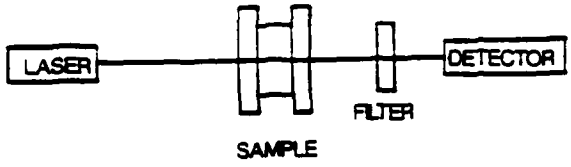
SINGLE CRYSTAL SHG

EFISH

POLYMER POLING

ELECTRO-OPTIC EFFECT

POWDER SHG



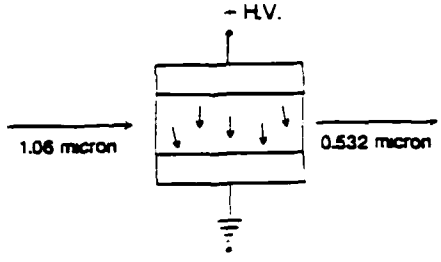
$$\eta = \frac{I(2w)sample}{I(2w)urea}$$

MATERIAL FORM: MICROCRYSTALLINE POWDER

ADVANTAGES: USEFUL FOR SCREENING

DISADVANTAGES: CANNOT RESOLVE MICRO- AND MACROSCOPIC CONTRIBUTIONS TO NONLINEARITY

EFISH

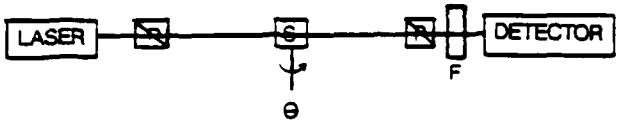


MATERIAL FORM: SOLUTION (LOW POLARITY SOLVENTS)

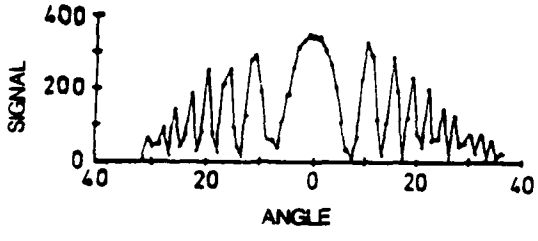
ADVANTAGES: OBTAIN MOLECULAR PROPERTIES. COMPARISONS

DISADVANTAGES: MOLECULAR PROPERTIES ARE SUBJECT TO ENVIRONMENT

SINGLE CRYSTAL SHG



MAKER FRINGE



MATERIAL FORM: LARGE SINGLE CRYSTAL (mm to cm)

ADVANTAGES: MEASURES TENSOR ELEMENTS $x^{(2)}_{ijk}$

DISADVANTAGES: REQUIRES CRYSTAL ORIENTATION, INDICES OF REFRACTION, POLISHING

POLYMER POLING

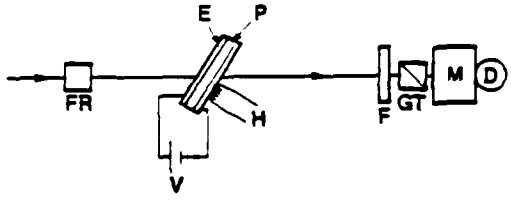


Figure 2. Experimental set-up for thin film SHG measurements using Fresnel rhomb FR, transparent electrodes E, polymer film P, poling voltage V, heater H, laser filter F, Glan-Thompson prism GT, monochromator M and detector D.

MATERIAL FORM: POLYMER SYSTEM

ADVANTAGES: REAL LIFE ENVIRONMENT, EASY SIGNAL DISCRIMINATION

DISADVANTAGE: NOT A DIRECT MEASUREMENT FOR E-O

ELECTRO-OPTIC EFFECT

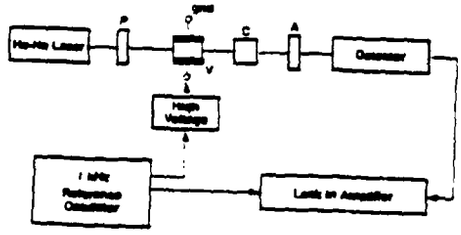


Figure 1. Experimental set-up for electro-optic measurements using polarizer P, analyzer A, and Babinet-Soleil compensator C.

MATERIAL FORM: POLYMER SYSTEMS, CRYSTALS

ADVANTAGES: DIRECT MEASUREMENT (DEVICE FORM)

DISADVANTAGES: LESS SENSITIVE THAN SHG
NOT AN IN-SITU TEST
CRYSTALLOGRAPHIC ORIENTATION FOR CRYSTALS

ADVANTAGES OF ORGANIC MATERIALS

- SYNTHETIC TAILORABILITY VIA DELOCALIZATION/SUBSTITUENTS
- SUBPICOSECOND RESPONSE TIMES
- TRANSPARENCY
- MECHANICAL AND STRUCTURAL STABILITY
- HIGH RADIATION DAMAGE THRESHOLD
- ENVIRONMENTAL STABILITY
- PROCESSABILITY
- ROOM TEMPERATURE OPERATION OF DEVICES

MATERIALS PROCESSING

SPIN-COATED POLYMERS

e.g. CHANNEL WAVEGUIDES

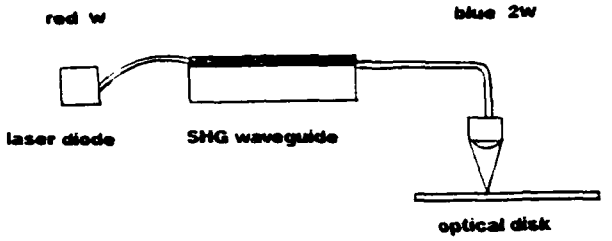
- REQUIRES LOW LOSS (<1 dB/cm)
- REPRODUCIBLE, WELL-KNOWN TECHNIQUES AVAILABLE
- INDUCE ORDER RATHER THAN RELY ON CRYSTAL PACKING

CRYSTALS

e.g. BULK CRYSTALS
CHANNEL WAVEGUIDES
VAPOR DEPOSITED FILMS

- REQUIRES LOW LOSS (<1 dB/cm)
- BULK CRYSTALS MUST BE DURABLE ENOUGH FOR CUTTING AND POLISHING
- COMPLETE CRYSTALLOGRAPHIC ORIENTATION IS REQUIRED
- PRINCIPAL OPTIC INDICES AND AXES RELATIVE TO EXTERNAL MORPHOLOGY MUST BE DETERMINED

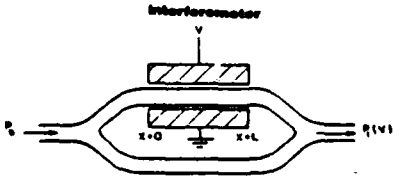
SECOND HARMONIC GENERATION APPLICATIONS



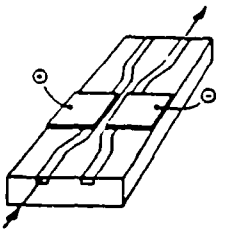
doubling optical frequency gives 4x storage density

APPLICATIONS – ELECTRO-OPTIC EFFECT

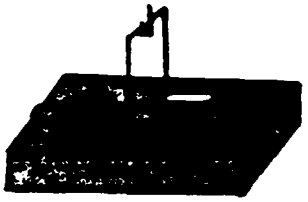
modulator



directional coupler



ELECTRO-OPTIC PHASE SHIFTER



MODULATOR, GYRO

* COMPARE $LiNbO_3$

λ = 850 nm

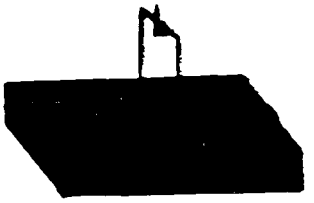
Insertion loss 6dB

BW = 3 GHz

V_π = 5V (4 cm)

Room Temperature

ELECTRO-OPTIC PHASE SHIFTER



[illegible]

$$\chi_{33}^{(2)} = \frac{\lambda n_e d}{2V_\pi L}$$

$\chi_{33}^{(2)} \approx 3 \times 10^{-7}$ esu $\approx 30 \cdot \chi^{(2)}$ (urea)

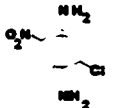
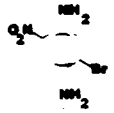
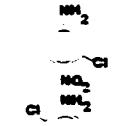
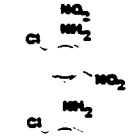
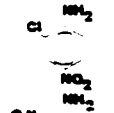
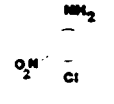
[illegible]

$\chi^{(2)} = c\, N \mu\beta\, E$ N = 1 Molar

E = 0.4 MV/cm

$\Rightarrow \mu\beta \sim 50 \cdot \mu\beta$ (DNA)

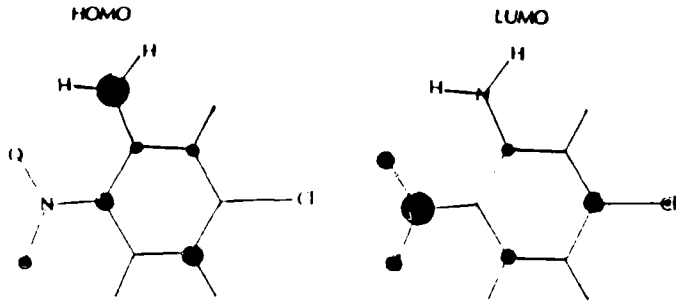
$A < 0.1$/cm (1 dB/cm)

HALONITROANILINES	RELATIVE EFFICIENCY (UREA)	μ (DEBYE
	20	4.471
	≤0.001	—
	≤0.001	9.466
	≤0.001	4.433
	2	7.722
	0.03	5.281
	≤0.001	8.023

MATERIAL	SPACE GROUP	a	b	c	α	β	γ	Z
5-chloro-2-nitroaniline (phase I)	$Pna2_1$	30.844 Å	3.852 Å	6.004 Å	90°	90°	90°	4
5-bromo-2-nitroaniline (5-chloro-2-nitroaniline) (phase II)	$P\bar{1}$	7.344	7.844	7.091	97.95	116.69	83.23	2
2-chloro-4-nitroaniline*	$Pna2_1$	11.25	16.85	3.87	90	90	90	4
3-chloro-4-nitroaniline	$P2_1/C$	3.813	12.531	14.467	90	91.20	90	4

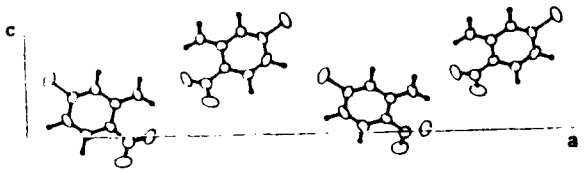
* A. T. McPhil and G. A. Sim, J. Chem. Soc., 227 (1965)

MOLECULAR MODELLING



$\beta \propto$ difference in ground state and excited state dipole moments

5-CHLORO-2-NITROANILINE



a = 30.844 Å
b = 3.852
c = 6.004

SPACE GROUP
$Pna2_1$

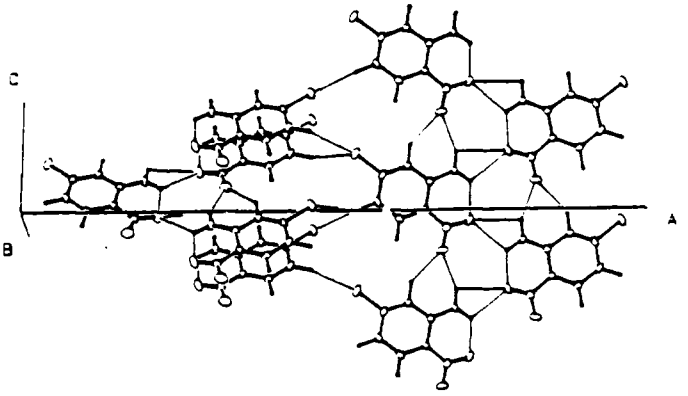


Figure 4. An illustration of the crystal structure of 5-chloro-2-nitroaniline. Significant intra- and intermolecular hydrogen bonding indicated by thin lines.

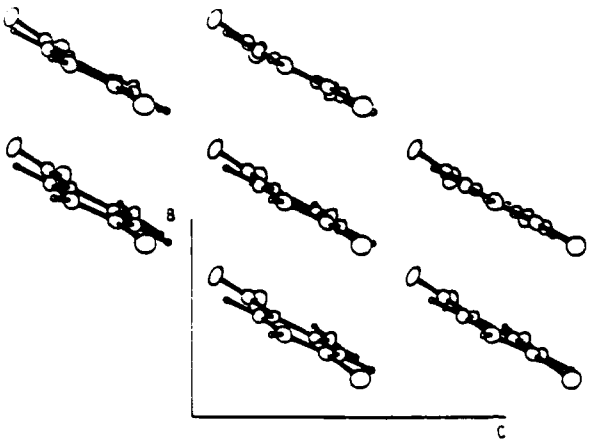


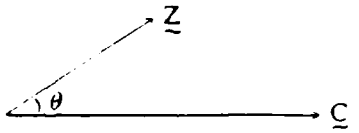
Figure 5. A projection of the ribbon-like packing structure of 5-chloro-2-nitroaniline. Molecules in each row are connected by significant intermolecular hydrogen bonding.

5-CHLORO-2-NITROANILINE

SPACE GROUP $Pna2_1$

polarization axis ∥ C-axis

$P \propto \chi(333) \propto \beta(zzz)\cos^3\theta$



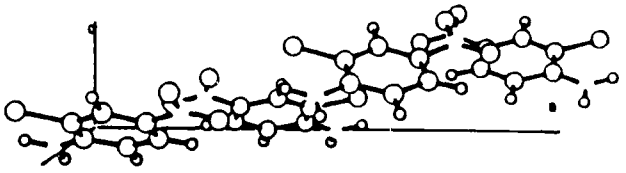
$\underset{\sim}{Z}$ ∥ polarization axis of molecule

$\underset{\sim}{C}$ ∥ polarization of crystal

$\underset{\sim}{Z} \cdot \underset{\sim}{C} = \cos\theta = 0.906$

SHG PACKING EFFICIENCY ≈ 0.74

2-CHLORO-4-NITROANILINE



ELECTRODE CONFIGURATION
FOR MEASURING E-O EFFECT

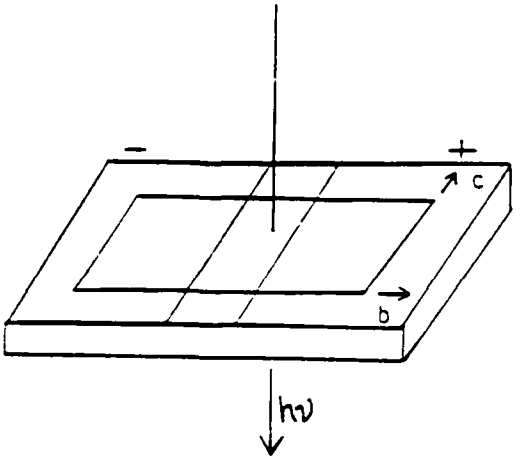
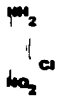
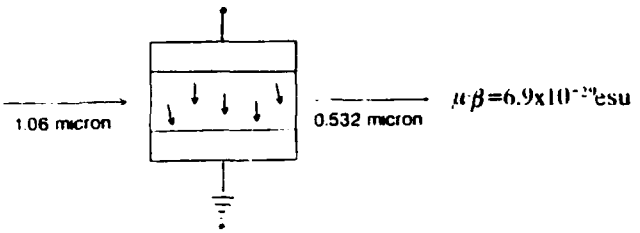


FIGURE OF MERIT = $\frac{1}{2} n_1^3 r_{13} - n_2^3 r_{23} = 18$ pm/v

$E^{DC} = \hat{y}$

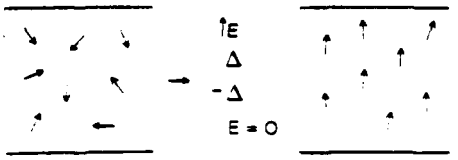
EFISH on 3-CHLORO-4-NITROANILINE





SHG STUDIES OF POLED POLYMERS

PRINCIPLE OF POLING GUEST/HOST SYSTEMS

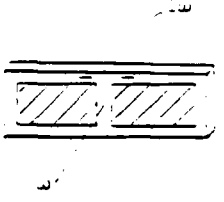


INVESTIGATE:

- Extent of ordering
- In-situ β
- Poling dynamics

CONDITIONS FOR POLING

3-CHLORO-4-NITROANILINE IN PMMA



- 0.7 M in PMMA (10% by wt)
- E = 6 x 10^4 V/cm
- T = 110° C

RESULTS OF POLING EXPERIMENTS

- CALCULATED β AGREES WITH MEASURED
- OBSERVED DECREASE OF $\chi^{(2)}$ WITH TIME

CONDITIONS	$\chi^{(2)}$ (esu)
E, 110° C	1 X 10^{-10}
E, RT	1 X 10^{-10}
E = 0 (30 sec), RT	0.5 X 10^{-10}
E = 0 (65 hr), RT	0.39 X 10^{-10}

POLED POLYMER SYSTEMS FOR ELECTRO-OPTIC EFFECT

GUEST	$\mu\cdot\beta$ (x 10^{-28} D-esu) at 1.58 microns	A/molar 810 nm	1000 nm	1300 nm	1500 nm
3MX-40	37	84	51	30	27
3MX-3	19	1.5	0.13	0.09	0.1
3MX-36	18	0.6	0.3	0.3	0.3
3MX-2	15	0.5	0.6	0.6	0.6
3MX-1	11	0.07	0.06	0.05	0.07
3MX-8	10	0.03	0.04	0.04	0.04

G. R. Meredith
E. I. Dupont DeNemours and Co.

OPTICAL NONLINEARITY: MOLECULES, ASSEMBLIES AND WAVE PHENOMENA

G. Khanarian
Hoechst-Celanese

CHARACTERIZATION OF POLYMERIC NONLINEAR OPTICAL MATERIALS

L-2

Characterization of Nonlinear Optical Organic Materials

G. Khanarian
Hoechst Celanese Corporation
Summit, New Jersey 07901

ACS Workshop
Virginia Beach, May, 1988

T CHE
R DEMARTINO
D HAAS
T LESLIE
H MAN
J. STAMATOFF
C TENG
H YOON

OUTLINE

- Molecular Miller's Rule
- Polymer Structure and
- Measurement of by Second Harmonic Generation
- Measurement of by the Pockels Effect
- Results for MNA/PMMA
- MNA/PMMA/Sol-Gel Glasses - Role of Molecul Motion
- Langmuir Blodgett Films - Role of Internal Optical Field
- Application to Devices

Schematic

Materials Development

- Design of organic molecules (Intuition, computer modeling and quantum mechanics)
- ↓ Synthesis
- ↓ Characterization (Optical, electro-optical...) (Solvato-chromism) (Structure/property algorithm)
- ↓ Formulation of polymeric systems (Guest-host, single component LCs) (Tractability, amphiphilicity)
- ↓ Fabrication (Thin films, 3D articles)
- ↓ Fabrication to critical standards (Dimensions & relation to activity, shape, size...)

Device Design and Evaluation

- ↓ Conversion to device format
- ↓ Evaluation of device

L-3

BASIC PHYSICS

MOLECULAR

$$p = \mu_0 + \alpha E + \beta E^2 + \gamma E^3$$

MATERIAL

$$P = \chi^{(1)} E + \chi^{(2)} E^2 + \chi^{(3)} E^3$$

$$\frac{d^2r}{dt^2} + 2\gamma \frac{dr}{dt} + \omega_0^2 r - \xi r^3 = -\frac{e}{m} E$$

$$\chi^{(1)}(\omega_\sigma) = \frac{Ne^2}{m} \frac{1}{\omega_0^2 - 2i\gamma\omega_\sigma - \omega_\sigma^2}$$

$$\chi^{(3)}(\omega_\sigma, \omega_m) = -\frac{m\xi}{Ne^4} [\chi^{(1)}(\omega_\sigma)][\chi^{(1)}(\omega_m)][\chi^{(1)}(\omega_\sigma + \omega_m)]$$

ANHARMONIC OSCILLATOR MODEL

$$\delta_{zzz} = \frac{-m\xi}{Ne^4} e^3_{zz}$$

m mass of electron

e charge of electron

N oscillator strength

ξ anharmonic constant

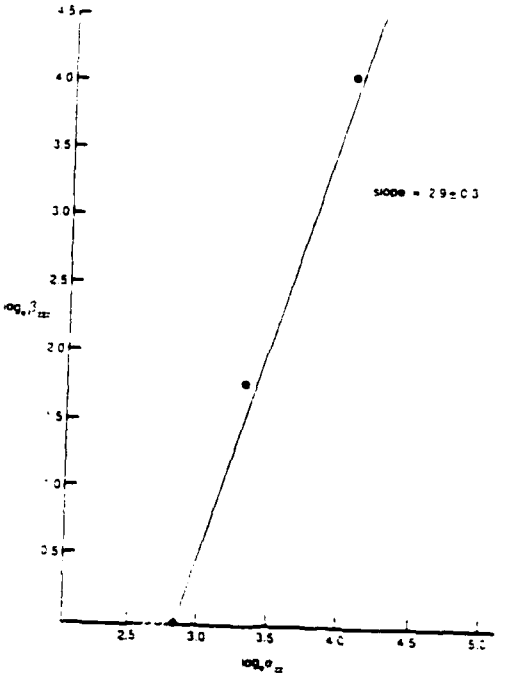
$$= \frac{1}{L^{12}}$$

ω angular frequency

L length of molecule

$\frac{m\xi}{Ne^4}$	Exp. (10^{-36} esu)	Theory (10^{-36} esu)
	1	3.0

$\log_e \beta_{zzz}$ versus $\log_e \alpha_{zz}$
Verification of molecular Miller's Rule



$$[illegible] = \frac{[illegible]}{[illegible]}$$

- [illegible] = molecular weight
- [illegible] = refractive index
- [illegible] = wavelength of light
- [illegible] = dielectric constant
- [illegible] = density
- [illegible] = Kerr constant
- [illegible] = molar Kerr constant

$$[illegible] = [illegible] + [illegible] + [illegible] + [illegible] + [illegible]$$

$$[illegible] = [illegible] - [illegible]$$

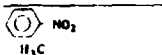
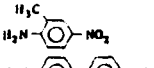
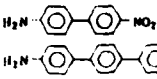
$$[illegible] = [illegible] + [illegible] + [illegible] + [illegible]$$

$$[illegible] = [illegible] + [illegible] + [illegible]$$ (1st hyperpolarizability)

- [illegible] = mean 2nd hyperpolarizability
- [illegible] = Avogadro's number
- [illegible] = Boltzmann's constant
- [illegible] = temperature
- [illegible] = mean polarizability
- [illegible] = dipole moment

TABLE I

Molar Kerr constants ${}_mK$ (x 10 ^{6} esu), linear polarizability α_{zz} (x 10 ^{24} esu) and β_{zzz} (x 10 ^{30} esu)

Compound	${}_mK$	α_{zz}	β_{zzz}
	0.985	13.2	1.0
	6.850	18.7	5.7
	14.5	29.5	20
	16.9	39.6	51

${}_mK$ values are at 0.633 μm α_{zz} has been deduced from equation 3, and literature values for the dipole moment μ_z and the average polarizability. α_{zz} values reported above are at 1.9 μm. A dispersion formula has been used to go from 0.633 to 1.91 μm. β_{zzz} are also at 1.91 μm.

$\chi^{(2)}$ OF POLED FLEXIBLE DIPOLAR POLYMERS

Types of Molecular Packing

Packing	Type	Order	Magnitude
	Non-centric	Second	Moderate
	Non-centric	Second	Strong
	Centric	Third	Strong
	Centric	Third	Weak

- Theory same as for efish

− +
——→ Direction of dipole moment

- Exact calculations can be done for single chains - Flory Theory

L-5

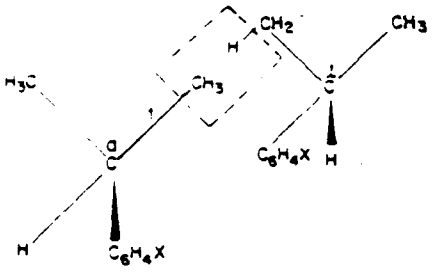


FIG. 2. Designation of bonds of PPNS, $X = NO_2$.

TABLE II. $(\mu \cdot \beta)/x$ ($\times 10^{-48}$ cm^4) and $\langle \mu^2 \rangle / X$ ($\times 10^{-36}$ SC^2 cm^2) of poly(*p*-nitrostyrene) vs tacticity p_r, $T = 298$ K, $x = 200$ repeat units.

P_r	$\frac{(\mu \cdot \beta)}{x}$	$\langle \mu^2 \rangle / x$
0.0 (isotactic)	21.5	10.7
0.2	16.6	8.27
0.4	16.3	8.12
0.6	16.8	8.36
0.8	16.4	8.17
1.0 (syndiotactic)	12.5	6.23

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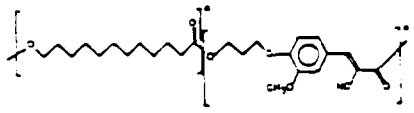


Table 2: Average Monomer Susceptibilities for Various Molecular Weight Copolymers.

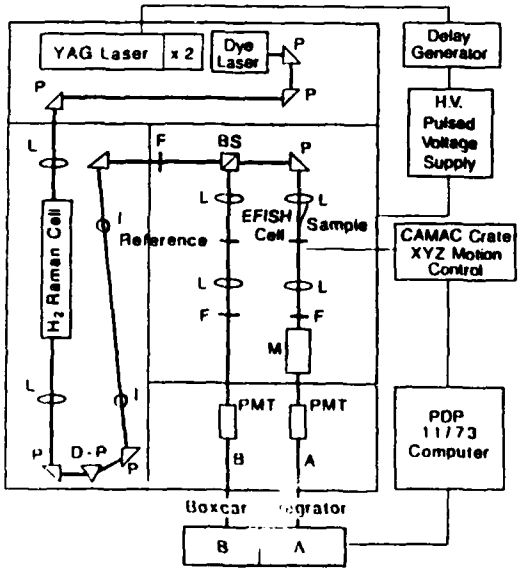
Molecular Weight,[a] $\bar{M}_n$	Calculated Number of Monomer Units, n	$M_z B_z / n$ (10^{-48} esu)	Enhancement Factor, G
NLO chromophore[b]	—	57	—
17,000	37	830	15
70,000	152	1140	20

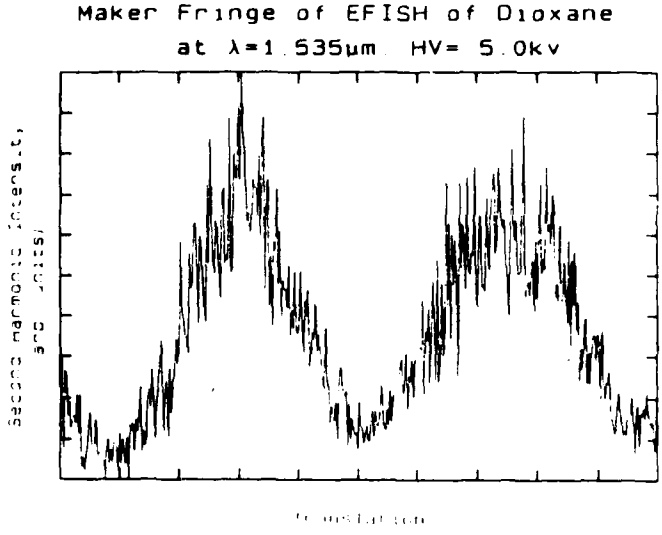
[a] Determined by GPC relative to polystyrene.

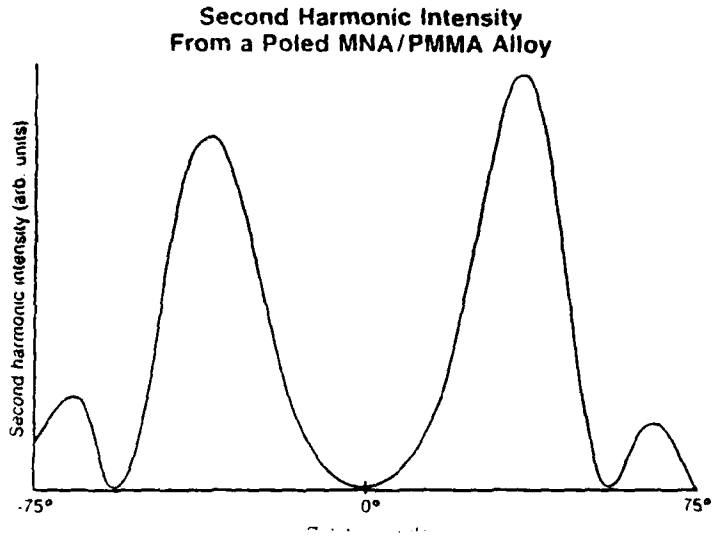
[b] Structure II from Table 1.

C. S. Willand, S. E. Feth, M. Scozzafava, and D. J. Williams
Corporate Research Laboratories, Eastman Kodak Company, Rochester, N. Y.

G. D. Green,* J. I. Weinschenk, III, H. K. Hall, Jr., and J. E. Mulvaney
C. S. Marvel Laboratories, Department of Chemistry, University of Arizona, Tucson, Az.







SECOND HARMONIC GENERATION FROM POLED POLYMERS

The second harmonic intensity is given by

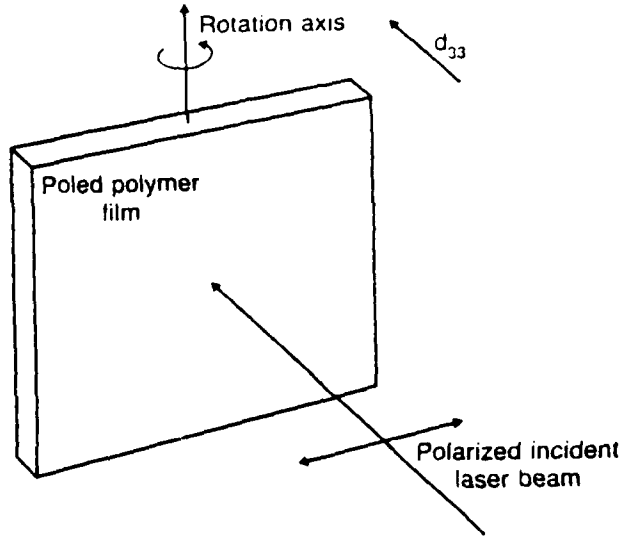
$$\frac{I(2\omega)}{I(\omega)^2} \propto t^2 T d_{ij}^2 p^2 l_c^2 \sin^2\left(\frac{\pi}{2}\frac{L}{l_c}\frac{n}{(n^2-\sin^2\theta)^{1/2}}\right)$$

t, T	Fresnel transmission factors
d	Second harmonic coefficient
p	Projection factor of d tensor onto optical electric field
l_c	Coherence length
n	Refractive index
L	Thickness of sample
θ	Angle of rotation

$x^{(2)}(-2\omega; \omega, \omega) = 2d$

When $\theta = 0$, $p = 0$ and there is no component of d along E, and there is no second harmonic observed

The Maker fringe arises from an interference between the fundamental beam and generated harmonic wave



THEORY OF MEASUREMENT FOR POCKELS AND KERR EFFECT

The birefringence Δn induced in a Kerr cell is:

$$\Delta n = \lambda B E^2$$

and in a Pockel cell:

$$\Delta n = 1/2\ n^3 E$$

The birefringence results in a retardation Γ

$$\Gamma = \frac{2\pi \Delta n l}{\lambda}$$

In the small angle approximation, Equation 4 becomes:

$$\frac{I}{I_o} = \frac{1}{2}[1 + \Gamma]$$

A sinusoidal voltage is applied across the electro-optic cell

$$V = V_0 \sin \omega t$$

Substituting Equation 7 into Equation 5

$$\frac{I}{I_o} = \frac{1}{2} + \frac{\Gamma_{Kerr}}{2} + \frac{\Gamma_{Pockel} \sin \omega t}{2} - \frac{\Gamma_{Kerr} \cos 2\omega t}{2}$$

POCKELS EFFECT

The optical retardation is

$$\Gamma = \frac{2\pi}{\lambda} l \Delta n$$

- l Optical path length
- Δn Induced birefringence
- λ Wavelength of light

The induced birefringence

$$\Delta n = \frac{1}{2}(n_1^3 r_{11} - n_1^3 r_{11}) E$$

- r Pockels constant
- n Refractive index
- E Applied electric field

For poled materials

$$r_{11} \cong \frac{r_{33}}{3}$$

This result is obtained from a thermodynamic model for poling

- Boltzmann statistics

The apparent angular dependence of the Pockels effect arises from change of optical path length

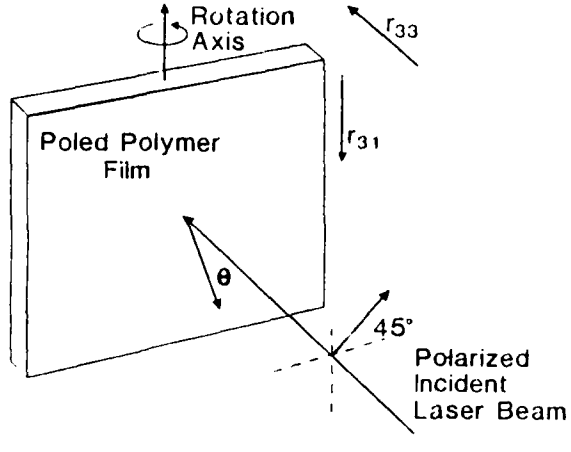
$$\frac{d}{\cos\theta}$$

where d is the thickness of the sample

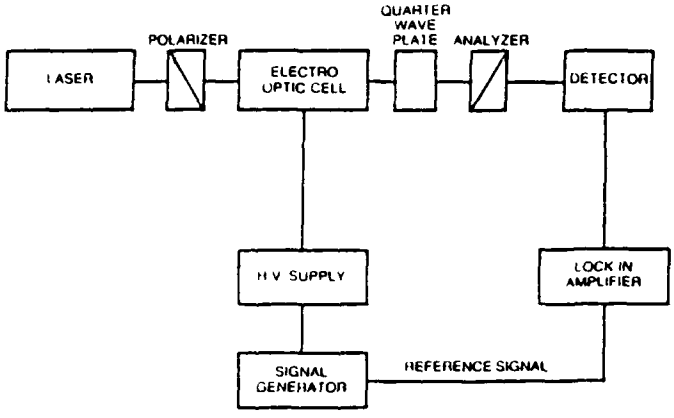
The analyzing light beam sees a different birefringence as a function of angle

$$\Delta n(\theta) = \Delta n(\theta = 90°) \sin^2\theta$$

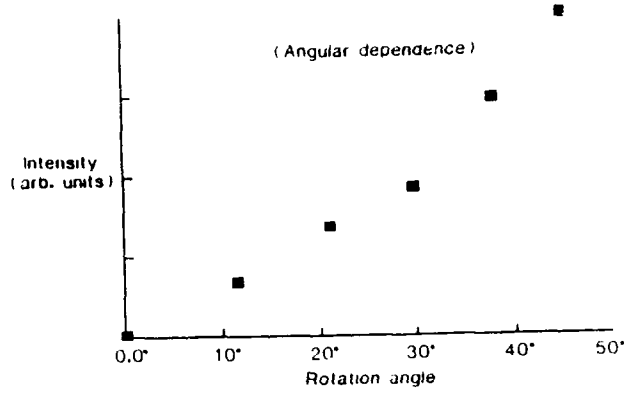
θ is the angle between the normal axis of sample and the light beam



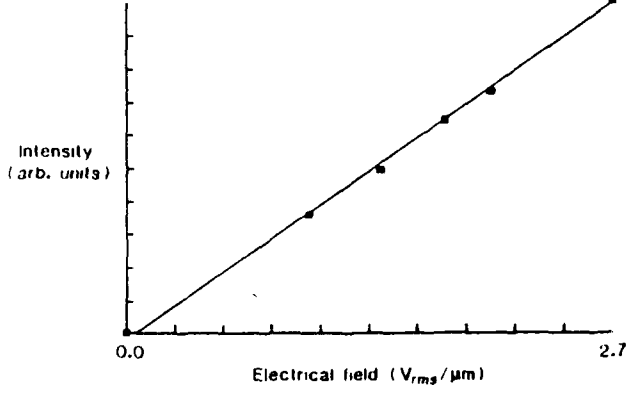
SCHEMATIC OF ELECTROOPTIC APPARATUS



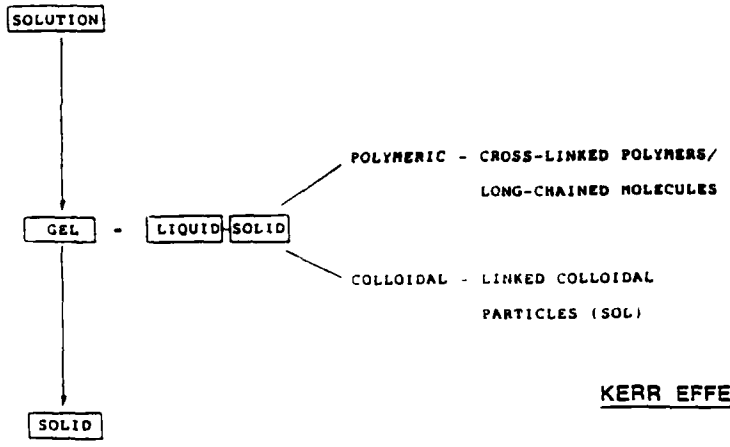
Pockels Effect from Poled MNA/PMMA Sample



Pockels Linear Electro-optic Effect From a $X^{(2)}$ Polymer



SOL-GEL TECHNOLOGY



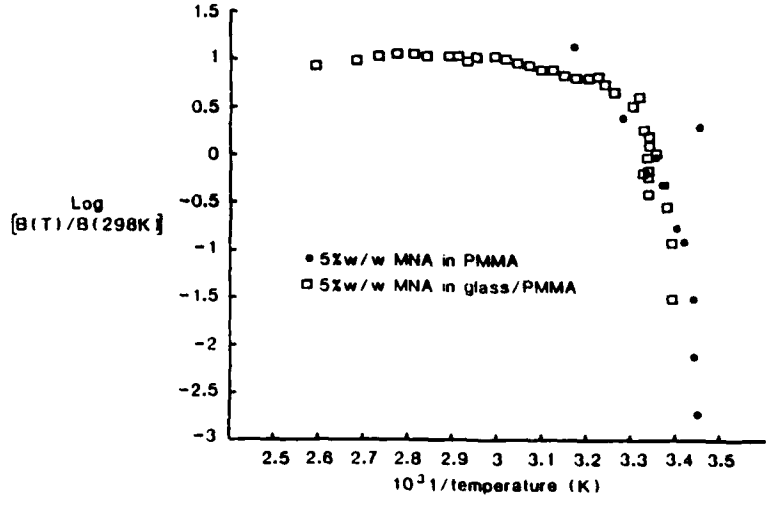
KERR EFFECT OF SOL-GEL GLASS

MNA added to sol-gel glass

PMMA is added to sol gel glass to give mechanical strength

Slab was cut and polished for electro-optic measurement

Arrhenius Plot of Kerr Constant for MNA Optical Composites



THERMODYNAMIC MODEL

Assume that nonlinear optical molecules are distributed orientationally according to Boltzmann statistics.

$$\chi^{(3)}_{zzzz}(-2\omega;\omega,\omega) = Nf^4\beta \frac{\epsilon(n^2+2)}{n^2+2\epsilon} \frac{\mu E}{5kT}$$

N	number density
f	internal field
β	hyperpolarizability
μ	dipole moment
E	poling field
k	Boltzmann constant
T	temperature
ϵ	dielectric constant
n	*refractive index*

RESULTS

Sample	$\chi^{(3)}(-2\omega;\omega,\omega)$	$\chi^{(3)}(-\omega;\omega,0)$	$\chi^{(3)}$(calc)
10% MNA/PMMA	1.6	1.5	0.6

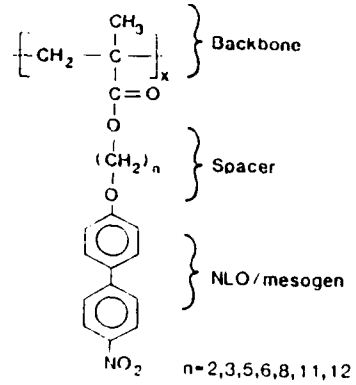
All $\chi^{(3)}$ values are $\times 10^{-9}$ esu and are at 1.06 μm

$\chi^{(3)}(-2\omega;\omega,\omega)$ measured at 1.06 μm

$\chi^{(3)}(-\omega;\omega,0)$ measured at 0.63 μm and a dispersion relation was used to obtain values at 1.06 μm

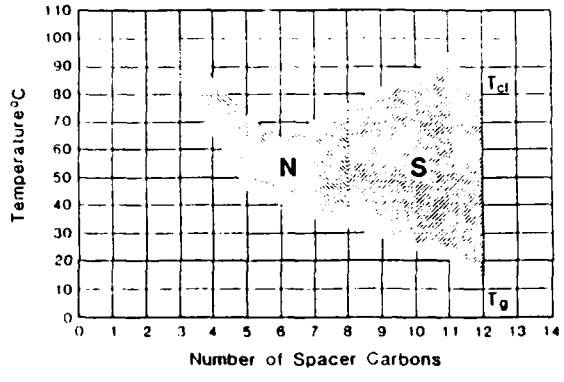
$\chi^{(3)}$(calc) used the thermodynamic model

NLO Side Chain Polymers First Generation



n=2,3,5,6,8,11,12

Dependence of Glass and Clearing Temperatures on Carbon Spacer Length



NLO Polymer Properties

$\chi^{(2)}$ at 1.3 μm	> 50 pm/V
r (calculated)	> 14 pm/V
n (1.3 μm)	1.57
ε (DC)	3.5
ε (n^2)	2.6
waveguide loss at 1.3 μm	0.9 dB/cm

Spin coatable from common solvents

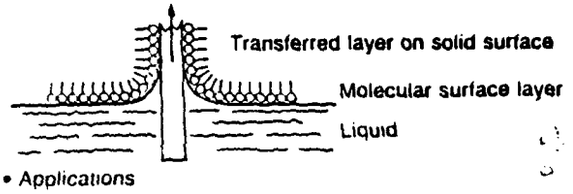
Poled for application
Stable (< 10% loss) at > 50°C for 5 years

LANGMUIR BLODGETT FILMS

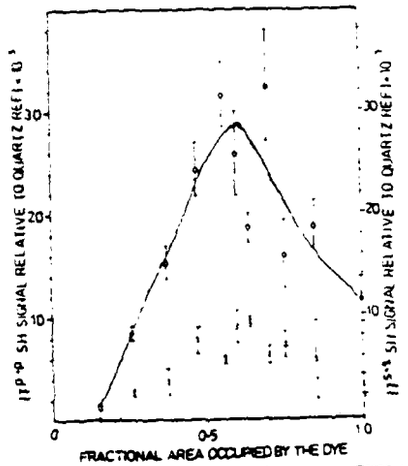
- 2D Material
- Orientation of Molecules by Surface
- Useful for Fundamental Studies of:
  - Interaction of radiation with molecules (spectroscopy)
  - Tilt angles
  - Hyperpolarizability
  - Molecule/surface interactions
  - Interaction between layers
  - Local optical electric field effects

Langmuir-Blodgett Film (LBF) Formation

- Is the deposition on a surface of a single molecular layer at a highly ordered state
- Sequential deposition leads to periodically structured films
- It is done by transfer of a compressed molecular surface layer on a liquid onto a solid surface by dipping



- Applications
  - — Nonlinear optics: Bistable switches; Thin film SH and TH generation
  - — Electro-optics: Thin film light modulator
  - — Integrated optics: Planar dielectric wave guides



g. 5. Plot of the second-harmonic (SH) signals $I^{2\omega,p}$ (○) and $I^{2\omega,s}$ (×) relative to the quartz reference slab versus the area fraction ccupied by the dye in the mixed monolayer.

[illegible] ET AL. 1987, VOL. [illegible]

Local Optical Electric Field

$$p_z = \mu_z + \alpha_{zz} F_z + (\beta_{zzz}) F_z^2 + (\gamma_{zzzz}) F_z^3$$

$$F_z = E_z + \sum_i T_{zz}^{ij} p_z$$

$$T_{zz}^{ij} = \frac{-1}{r_{ij}^3}$$

μ, α, β and γ are the dipole moments and polarizabilities

Z axis is normal to glass surface

Linear Mean Field Approximation

* Neglect fluctuation in dipole moment
* Assume that linear polarizability alone changes local dynamic optical field.

$$\sum_i T^{ij} = \rho \int_a^\infty \frac{2\pi r dr}{r^3}$$

$$= \frac{2\pi\rho}{a}$$

ρ = surface density of dipoles

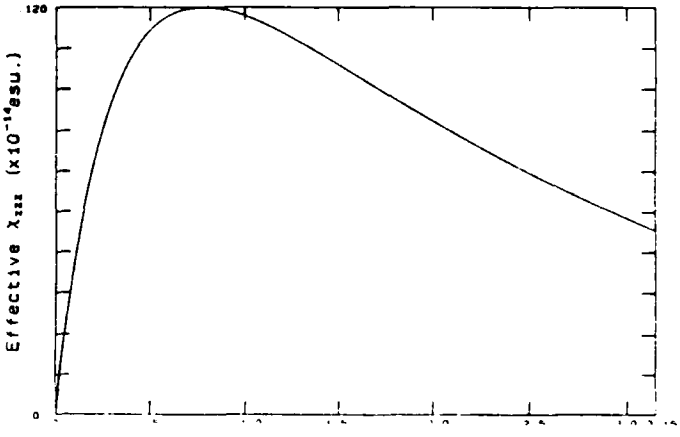
a = radius of nonlinear optical molecule

Results for the nonlinear susceptibility

$$\chi_{zzz} = \frac{3a}{2\pi\alpha_{zz}} \frac{x}{(1+x)^2} - \frac{3\gamma\mu a}{2\pi\alpha_{zz}^2} \frac{x^2}{(1+x)^2}$$

$$x = \frac{2\pi\alpha_{zz}\rho}{a}$$

Variation of effective χ_{zzz} of a Langmuir Blodgett Film versus normalized concentration of active nonlinear optical molecule



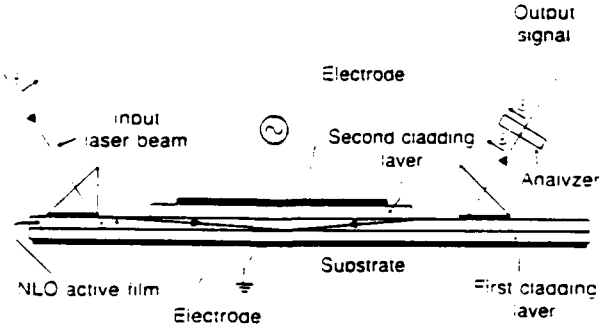
CLASSES OF ORGANIC NLO DEVICES

- Electro-Optic Devices
  - Control of light with electronics
  - Based on the second order NLO susceptibility $\chi^{(2)}$
  - Applications: Hybrid optical processing and optical communications
- All Optical Devices
  - Control of light with light
  - Based on the third order NLO susceptibility $\chi^{(3)}$
  - Applications: All optical computing and ultra-fast optical communications

POLYMER GUIDE FABRICATION PROCESS

COMPONENTS

- Spin Coating (thin film formation)
- Buffer Layer and Substrate Materials
- Patterning
- Metallizing
- Beam Coupling



TE Polarization
TM Polarization

MODULATOR RESULTS

MATERIAL	LENGTH (CM.)	V_π (V)	λ (nm)	F_{MAX} (MHz)	r_{33} (pm/V)
PMMA: pNA	1.0	450	633	30	.5
HCC #0520	1.0	45	633	0.5	3.5
HCC #1622	2.0	30	830	10*	3.75
HCC #1238	1.5	4.0	830	1	20

$$r_{33} = \frac{3 \lambda G}{2n^3 L V_\pi \Gamma}$$

$\Gamma \approx .85$ to $.95$ for these structures

OTHER MATERIAL PROPERTIES

> N FROM 1.51 TO 1.66

> ε (100 KHZ) ≈ 3.8

SUMMARY

- Organic NLO research at HCC has developed outstanding NLO and EO polymers
- These materials, additionally, exhibit combination of excellent performance characteristics and fabrication properties for NLO and EO devices
- Initiative to develop a series of important NLO devices has been undertaken at HCC
- Fabrication science and technology for the materials is a key component of the initiative

T. Richardson

University of Oxford, U. K.

PREPARATION AND CHARACTERIZATION OF ORGANO-TRANSITION METAL LANGMUIR-BLODGETT FILMS

M-2

THE PREPARATION AND CHARACTERISATION OF ORGANO-TRANSITION METAL LANGMUIR-BLODGETT FILMS

T. RICHARDSON, G.G.ROBERTS
UNIVERSITY OF OXFORD
DEPARTMENT OF ENGINEERING SCIENCE
PARKS ROAD, OXFORD, OX1 3PJ, ENGLAND

M.E.C. POLYKRA, S.G. DAVIES
DYSON PERRINS LABORATORIES
UNIVERSITY OF OXFORD
SOUTH PARKS ROAD, OXFORD, OX1 3QY, ENGLAND

A SERIES OF NOVEL RUTHENIUM COMPOUNDS HAVE BEEN DEVELOPED FOR USE WITH THE LANGMUIR-BLODGETT DEPOSITION TECHNIQUE. COMPLEXING OF A π- (RUTHENIUM (CYCLOPENTADIENYL-BIS TRIPHENYLPHOSPHINE)) HEAD GROUP TO A CYANOTERPHENYL LIQUID CRYSTAL MOLECULE HAS BEEN SHOWN TO INCREASE THE SECOND-ORDER NON-LINEAR OPTICAL HYPERPOLARIZABILITY AND FURTHERMORE INDUCE MULTILAYER FORMATION. OPTICAL ABSORPTION DATA HAVE REVEALED THE EXCELLENT REPRODUCIBILITY OF SUCCESSIVE MONOLAYER TRANSFER. SECOND HARMONIC GENERATION HAS BEEN OBSERVED AND THE EFFECT HAS BEEN INCREASED BY INCORPORATING UNSUBSTITUTED LIQUID CRYSTAL MOLECULES INTO THE VOIDS BETWEEN THE TERPHENYL CHAINS OF ADJACENT RUTHENIUM SUBSTITUTED MOLECULES. WE HAVE FURTHER OPTIMISED THE NON-LINEAR RESPONSE BY SYSTEMATICALLY VARYING THE ELECTRON-RELEASING CHEMICAL GROUP AND THE CONJUGATION WITHIN THE MOLECULE.

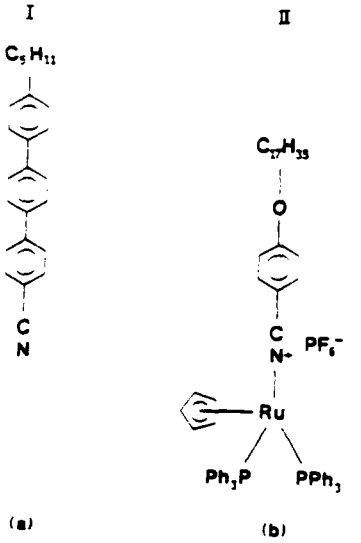


FIGURE 1

(A) A TYPICAL CYANO-TERPHENYL MOLECULE (I).

(B) THE $(C_5H_5)Ru(PPh_3)_2$ SUBSTITUTED MOLECULE POSSESSES A LARGER SECOND-ORDER NON-LINEAR OPTICAL HYPERPOLARIZABILITY THAN COMPOUND I.

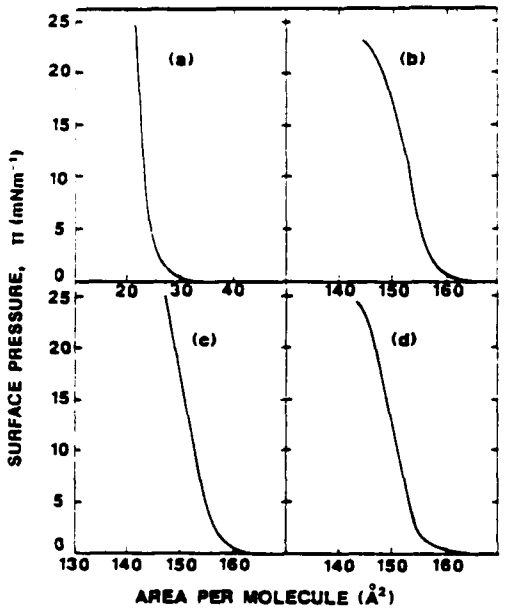


FIGURE 2

THE BEHAVIOUR OFMOLECULES OF COMPLEX I AND II UNDERGOING COMPRESSION ON THE WATER SURFACE. (A) COMPLEX I AT PH 5.8, (B, C AND D) COMPLEX II AT PH 3.8, 5.8 AND 8.7 RESPECTIVELY. THE MOLECULAR AREAS AT RELATIVELY HIGH SURFACE PRESSURE (20 MNM⁻¹) CORRESPOND ACCURATELY TO THE MEASURED CROSS-SECTIONAL AREA OF THE RUTHENIUM HEAD GROUP.

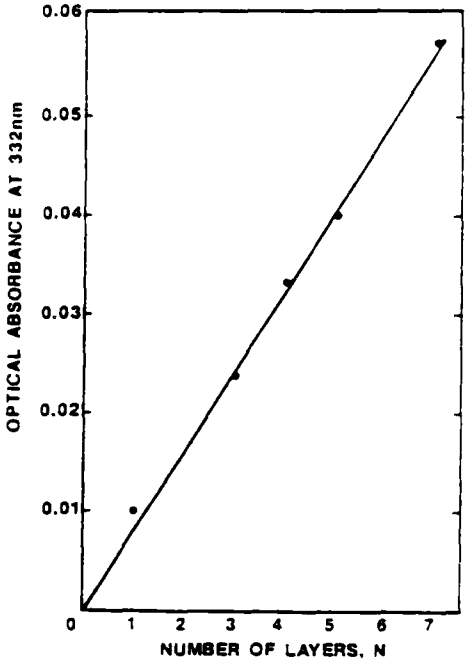


FIGURE 3

OPTICAL ABSORPTION VERSUS THE NUMBER OF TRANSFERRED MONOLAYERS. THE LINEAR RELATIONSHIP INDICATES THE REPRODUCIBILITY OF SUCCESSIVE MONOLAYER DEPOSITION.

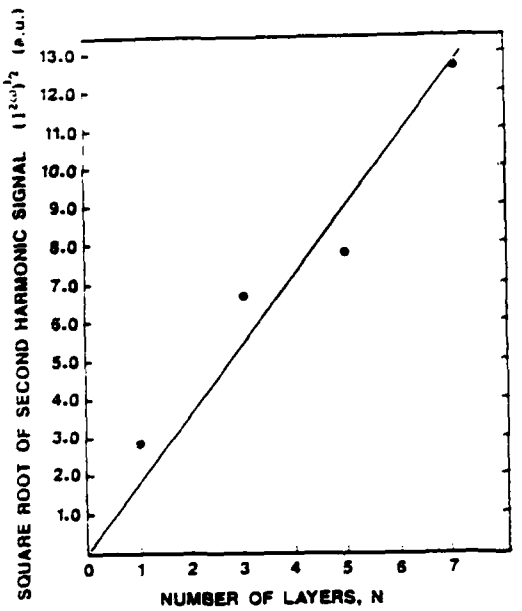
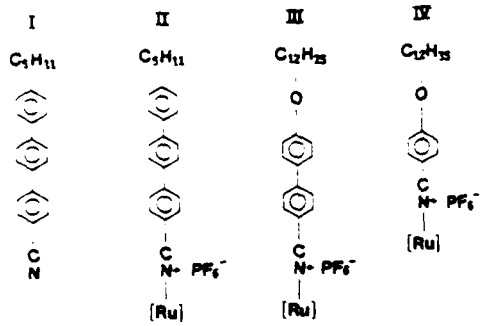


FIGURE 4

THE RELATIONSHIP BETWEEN THE SQUARE ROOT OF THE SECOND HARMONIC GENERATION SIGNAL AND STRENGTH THE THICKNESS OF THE FILM. THE APPROXIMATELY LINEAR RELATIONSHIP IMPLIES THE UNIDIRECTIONAL ALIGNMENT OF THE MOLECULES.



COMPLEX	SHG SIGNAL NORMALIZED TO II
II	1.0
II/1	1.5
III	11.0
IV	77.0

FIGURE 6

OPTIMISATION OF NON-LINEAR RESPONSE. THE SECOND HARMONIC SIGNAL IS HIGHLY DEPENDENT UPON THE ELECTRON DONOR AND THE DEGREE OF CONJUGATION.

(a) NO INCORPORATION

(b) INCORPORATED CTP MOLECULES

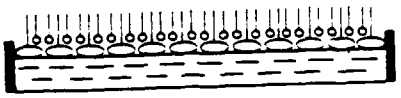


FIGURE 5

HIGH PACKING DENSITY STRUCTURES.

(A) THE LIQUID CRYSTAL MOLECULES MAY REMAIN ON THE WATER SURFACE,
OR
(B) THEY MAY BE INCORPORATED INTO THE MATRIX FORMED BY THE RUTHENIUM SUBSTITUTED MOLECULES.

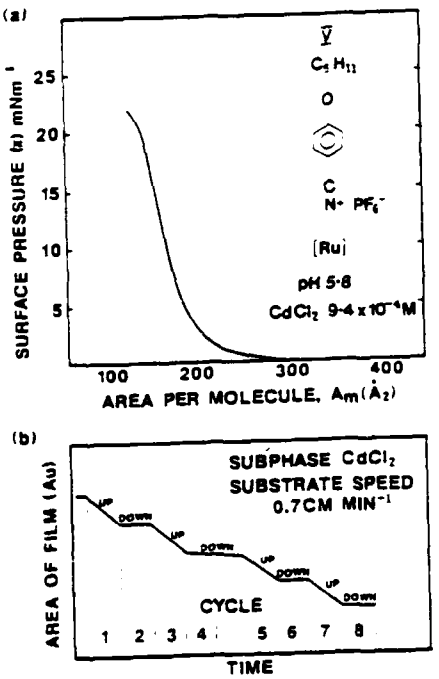


FIGURE 7

OPTIMISATION OF THE CARBON CHAIN LENGTH:-

(A) II VS.Am PLOT FOR COMPLEX V, SHOWN IN INSERT

(B) THE Z-TYPE DEPOSITION OF COMPLEX V. HIGHER RATES OF DEPOSITION ARE POSSIBLE WITH $CdCl_2$ IN THE SUBPHASE.

S. K. Tripathy
University of Lowell

OPTICAL PROPERTIES OF ORGANIZED ASSEMBLIES

OPTICAL PROPERTIES OF MOLECULAR ASSEMBLIES

SUKANT TRIPATHY
UNIVERSITY OF LOWELL
LOWELL, MA 01854

- Selected conjugated molecular and Macromolecular systems
- Organized mono and multilayer assemblies
- Characterization of microstructure and morphology
- Measurement and anticipation of electronic and optical properties

Selection of materials

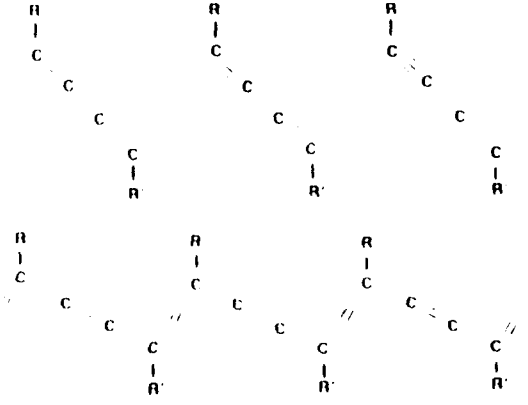
1. **Linked donor-acceptor molecules.**

   anticipated large 2nd order effects.
   example MNA

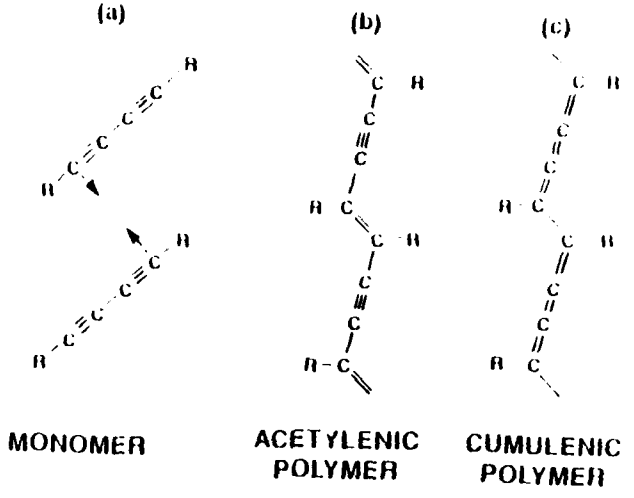
2. **Polymers with delocalized backbone electronic structure.**

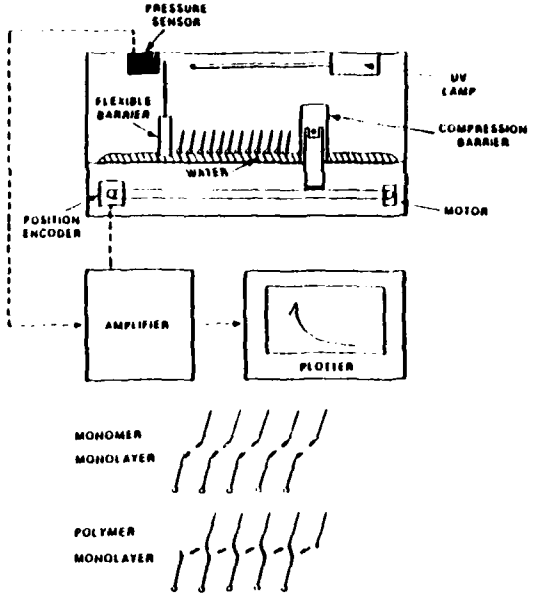
   anticipated large 3rd order susceptibilities.
   example Polydiacetylenes

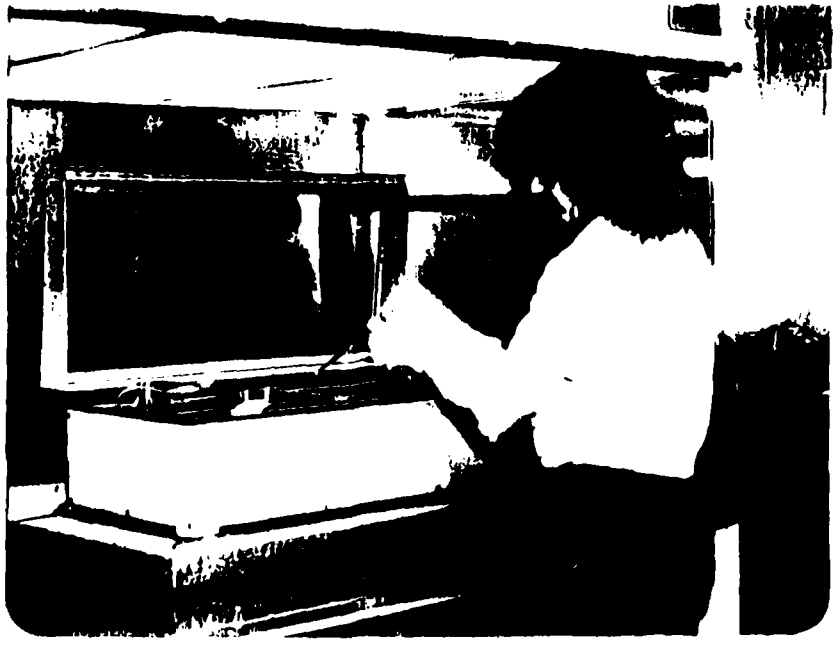
POLYDIACETYLENES

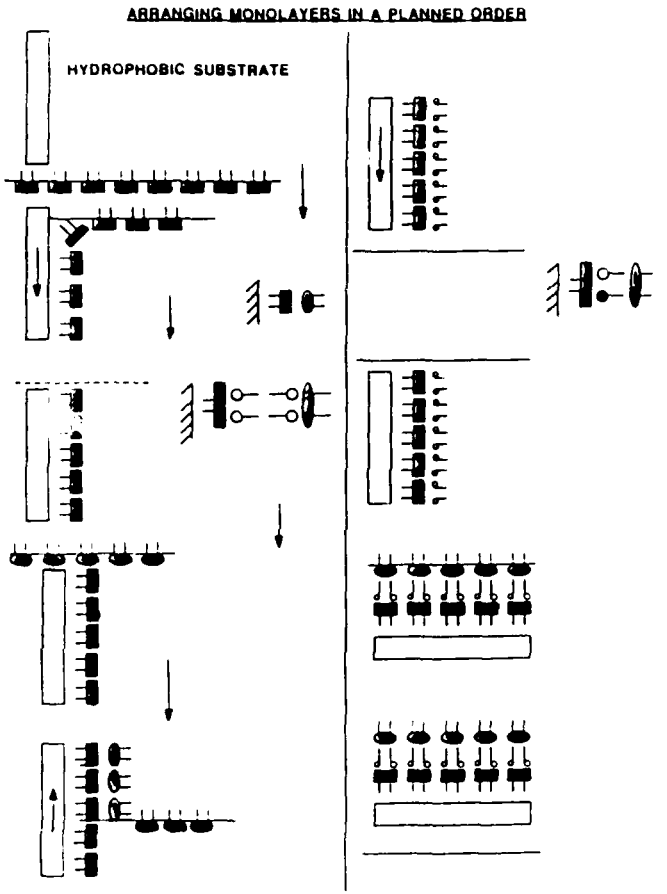


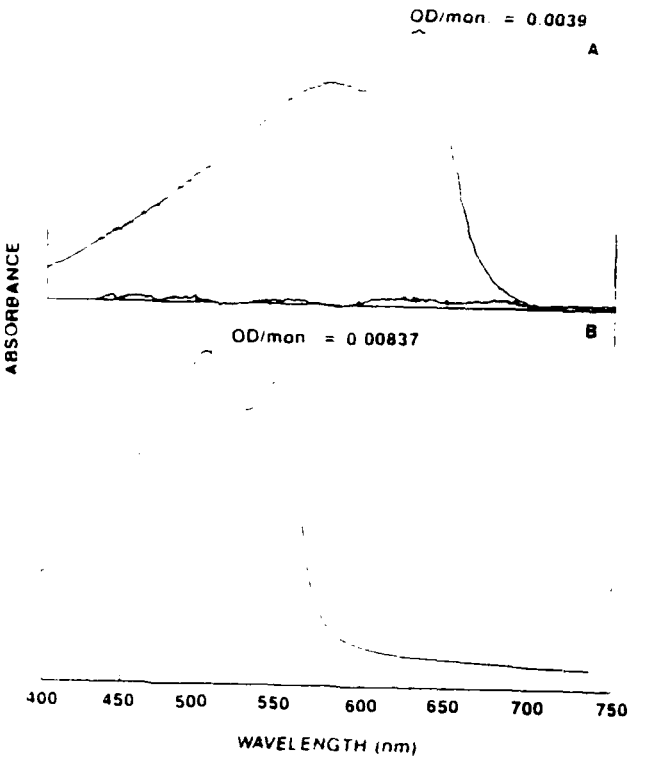
- Backbone Responsible for the Optical and the Nonlinear Optical Properties
- The Side Groups Provide a Handle for Fabrication and Structure Control

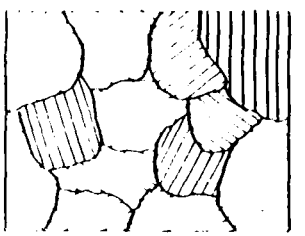

(a)
(b)
(c)
MONOMER
ACETYLENIC POLYMER
CUMULENIC POLYMER


PRESSURE SENSOR
UV LAMP
FLEXIBLE BARRIER
COMPRESSION BARRIER
WATER
MOTOR
POSITION ENCODER
AMPLIFIER
PLOTTER
MONOMER MONOLAYER
POLYMER MONOLAYER

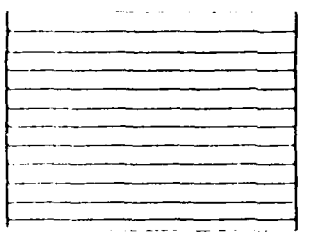






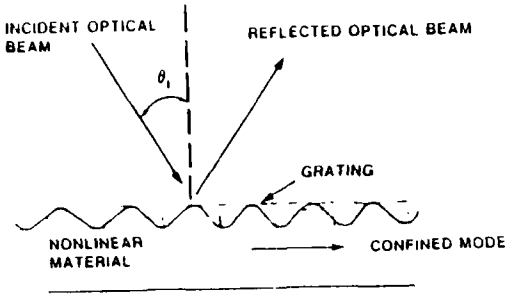


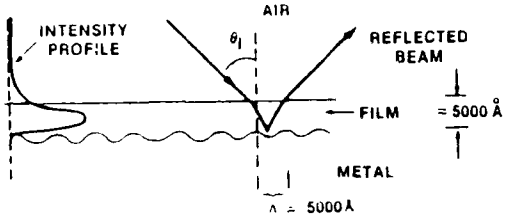
POLY CRYSTALLINE

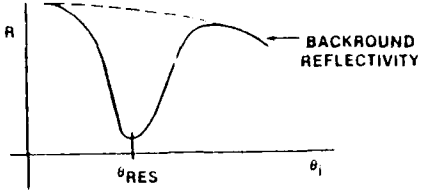


ORIENTED SINGLE CRYSTALLINE

N-4

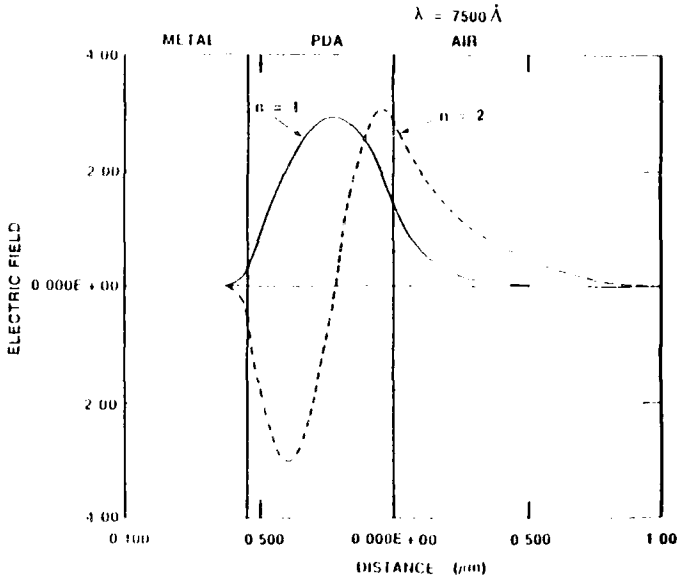


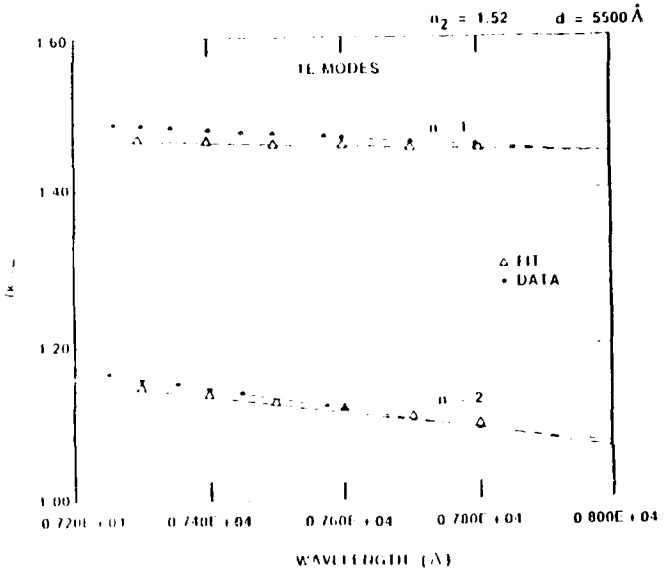


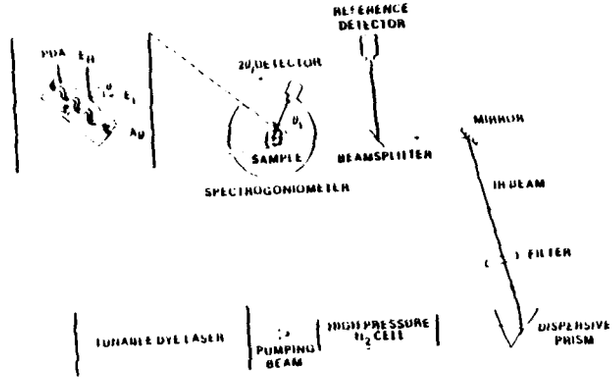


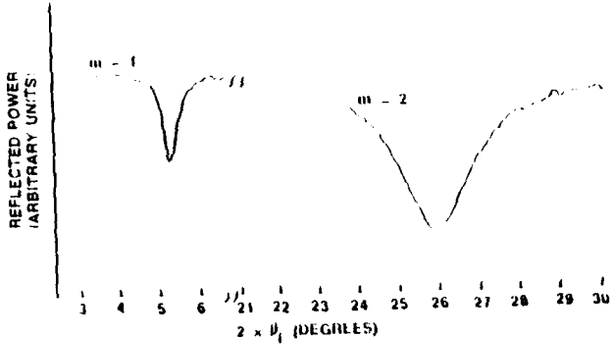
$$n_g = \lambda_0/\Lambda \pm \sin(\theta_{RES})$$

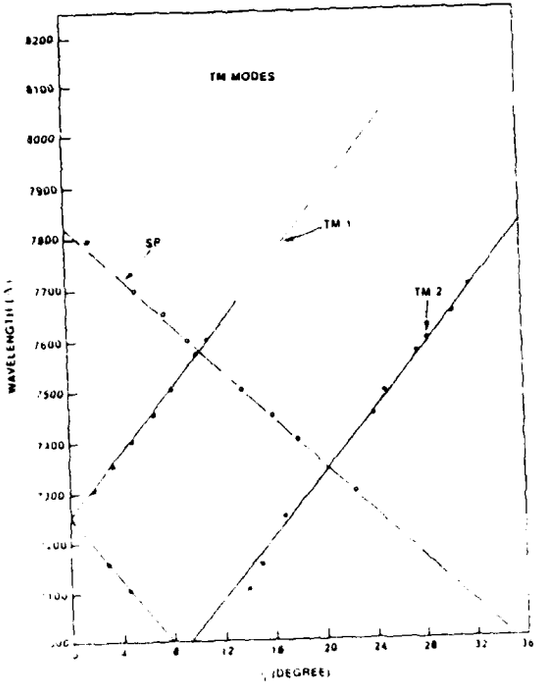
$$(n_g = k_g/k_0)$$

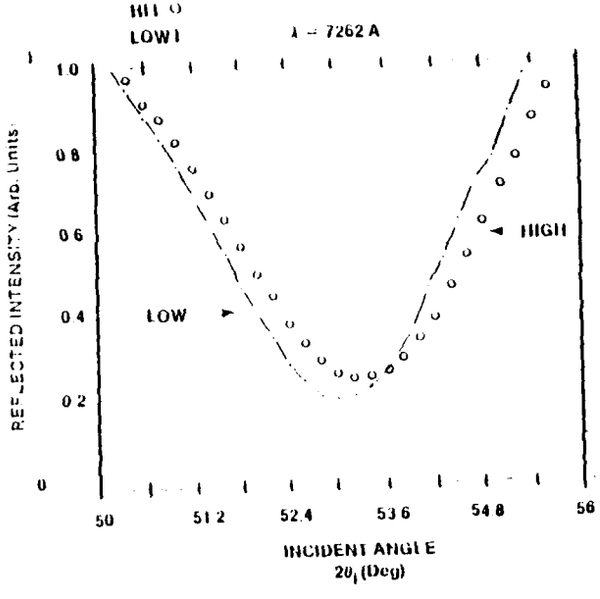




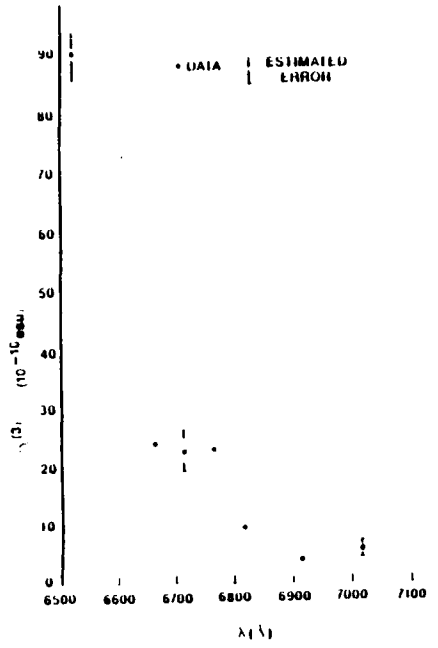

REFERENCE DETECTOR
$2\theta_i$ DETECTOR
SAMPLE
BEAMSPLITTER
SPECTROGONIOMETER
MIRROR
IR BEAM
FILTER
DISPERSIVE PRISM
TUNABLE DYE LASER
PUMPING BEAM
HIGH PRESSURE H_2 CELL


REFLECTED POWER (ARBITRARY UNITS)
m = 1
m = 2
1 4 5 6 21 22 23 24 25 26 27 28 29 30
$2 \times \theta_i$ (DEGREES)


TM MODES
TM 1
TM 2
SP
8200
8100
8000
7900
7800
7700
7600
7500
7400
7300
7200
7100
4 8 12 16 20 24 28 32 36
(DEGREE)


LOW1
λ = 7262 A
REFLECTED INTENSITY (Arb. Units)
1.0
0.8
0.6
0.4
0.2
0
LOW
HIGH
50 51.2 52.4 53.6 54.8 56
INCIDENT ANGLE
$2\theta_i$ (Deg)

N-6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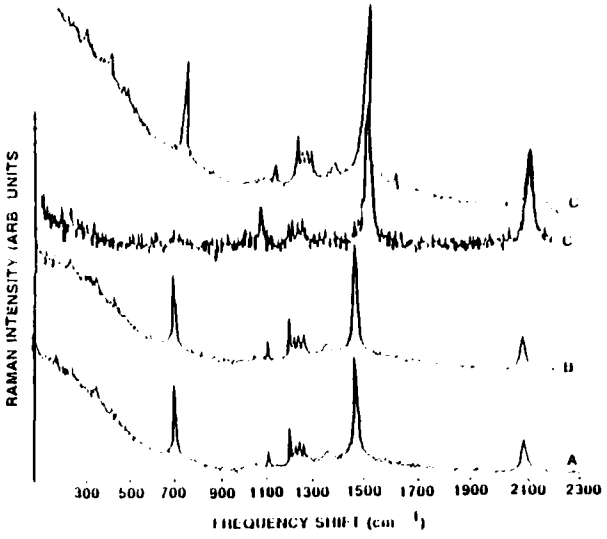
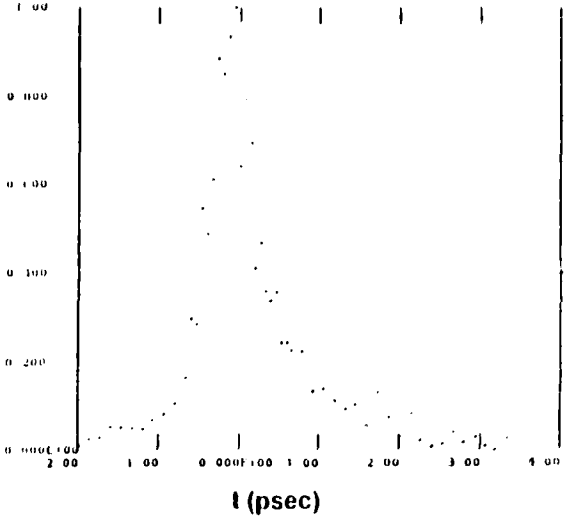
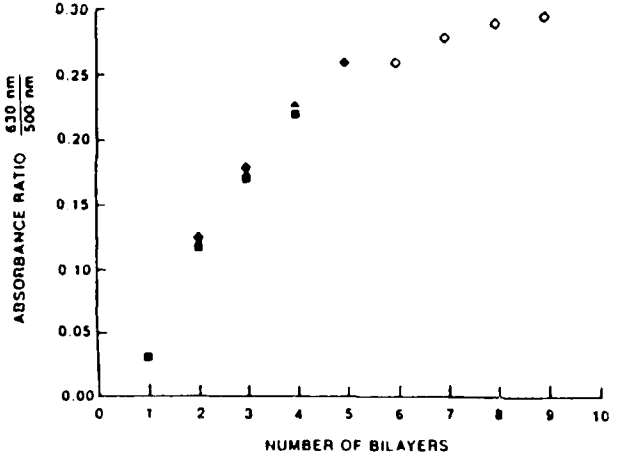
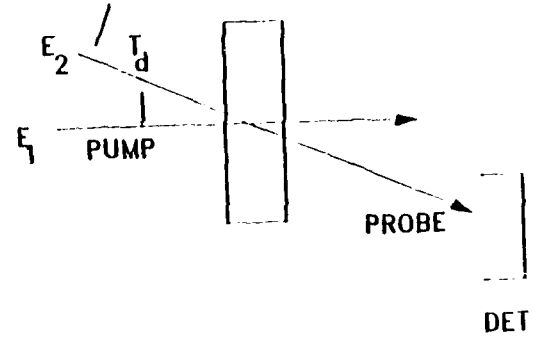
ESTIMATED ERROR
6500
6600
6700
6800
6900
7000
7100

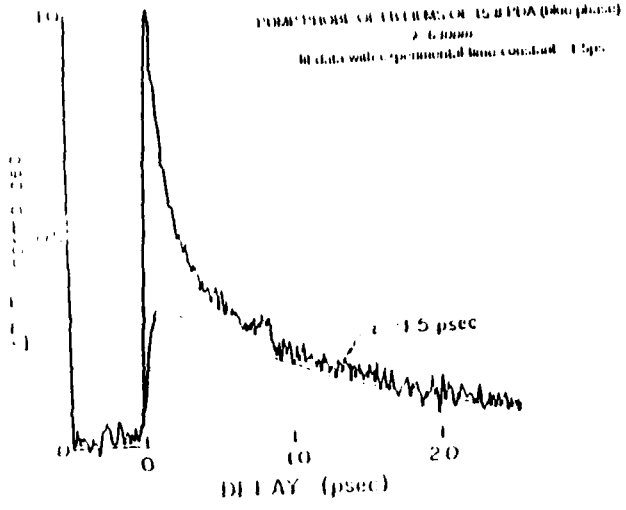

RAMAN INTENSITY (ARB UNITS
C
B
A
300 500 700 900 1100 1300 1500 1700 1900 2100 2300
FREQUENCY SHIFT (cm⁻¹)


t (psec)

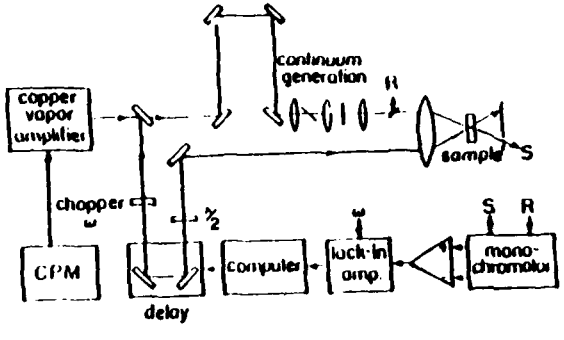

ABSORBANCE RATIO 630 nm / 500 nm
0.30
0.25
0.20
0.15
0.10
0.05
0.00
0 1 2 3 4 5 6 7 8 9 10
NUMBER OF BILAYERS

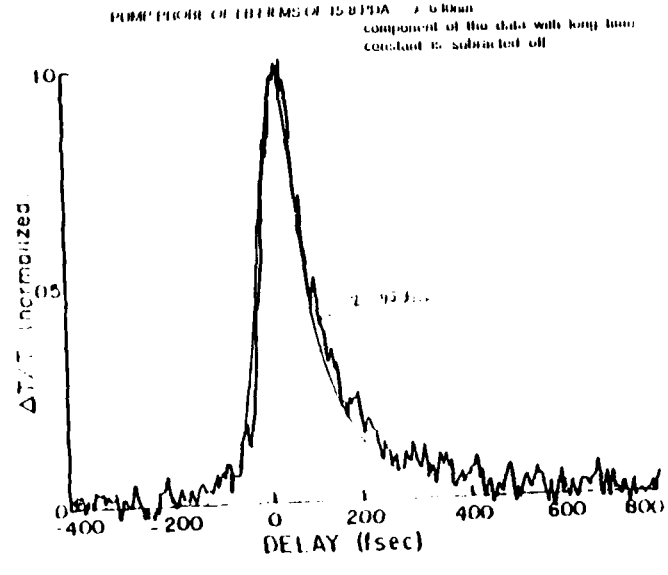
PUMP–PROBE: SATURATED ABSORPTION

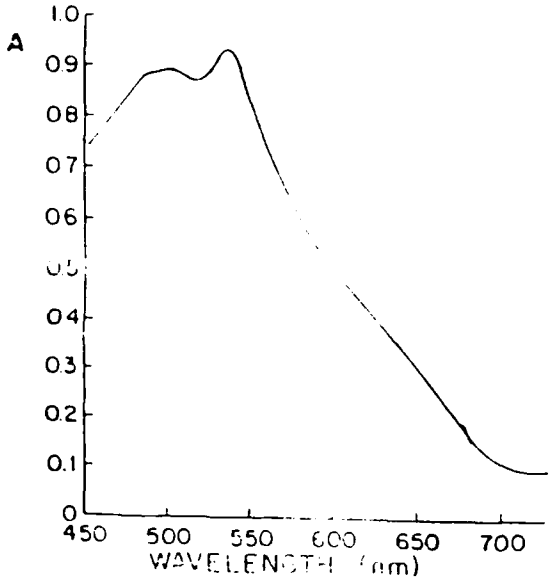




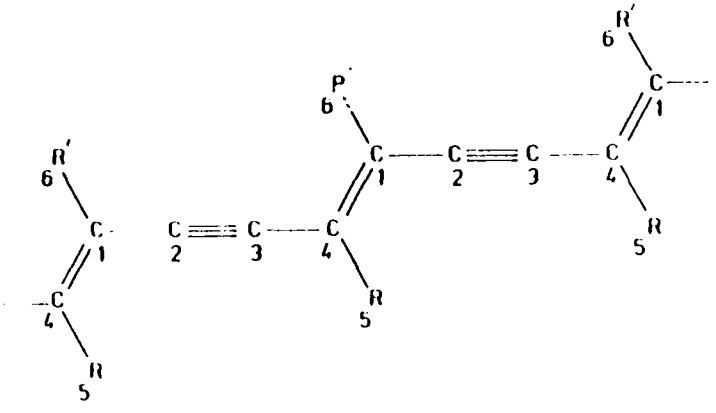
EXPERIMENTAL SCHEMATIC







LINEAR ABSORPTION SPECTRUM OF LASER-INDUCED RED PHASE LB FILMS OF PDA 15-8



Structure of the polydiacetylene backbone. The numbers label the carbon atoms on the backbone and the single masses representing the sidegroups R and R' in the vibrational model

SCF ab initio Hartree Rock

Semi empirical (EH)

VEH gives ab initio quality results

σ and π bonds treated equally

MNDO - Excellent geometry all electrons.

	ΔH_f	Etot
PDA	498.6	-106275.8
PBT		-106159.7

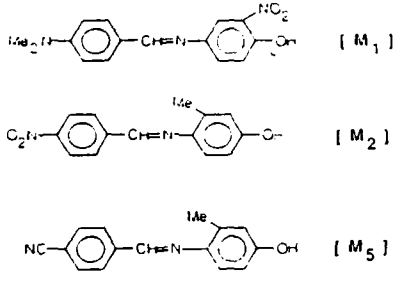
Δ/rep. = 14.5 Kcals/Mole

BANDGAP OF PDA AS A FUNCTION OF NONPLANARITY

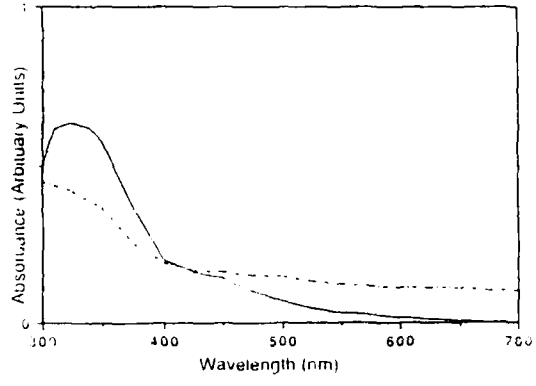
	0°	5°	10°	15°	20°
eV	2.596	2.558	2.585	2.612	2.721
cm^{-1}	20938	20631	20850	21070	21947
nm	478	485	480	475	456

EFFECT OF SUBSTITUENTS ON PDA ELECTRONIC STRUCTURE

	BW	E_g	E_{ip}
PDA	3.972 (32043)	2.596 (20938)	5.338 (43056)
t_2^- PDA	1.115 (8998)	1.769 (14266)	4.903 (39544)
$(CH_3)_2^-$ PDA	3.265 (26337)	2.449 (19753)	5.039 (40642)

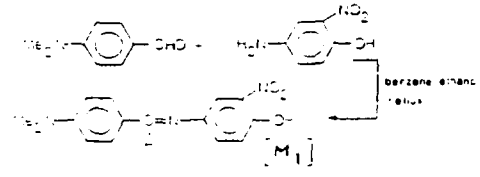


Molecular Structures of Some Representative Molecules

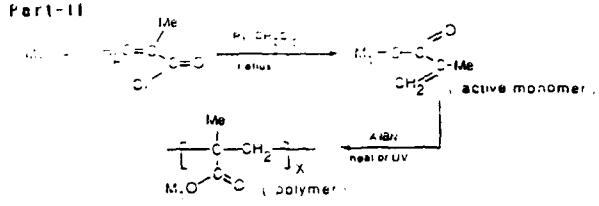


Visible Spectra of Partially Oxidized *Polypyrrole in Solution*

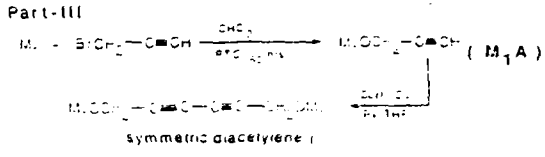
Part-I

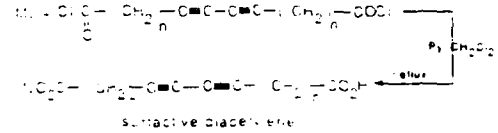


Part-II



Part-III

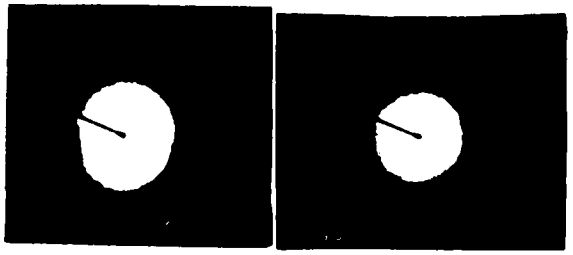




Synthetic Scheme

N-10

TEM MICROGRAPH OF A POLYPYRROLE MONOLAYER



PYRROLE: HDP=500: 1

d_1=2.58A

d_2=1.55A

d_3=1.33A

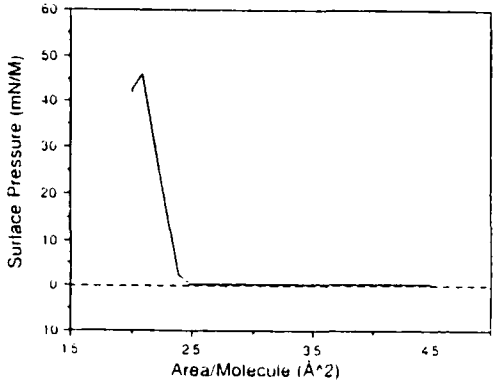
d_4=1.01A

d_5=0.90A

POLYPYRROLE

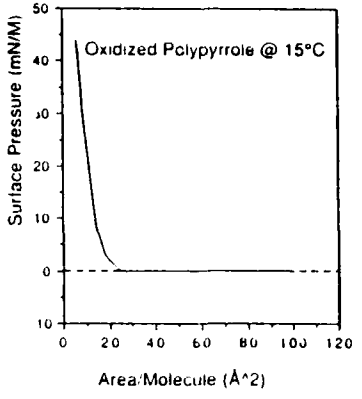
d_1=2.54A

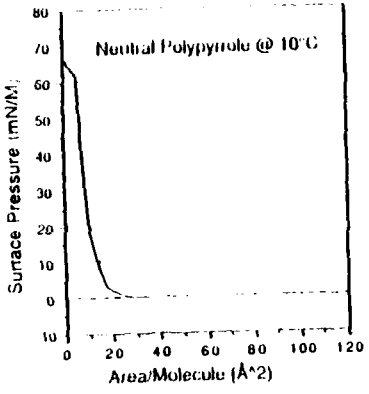
d_2=1.55A

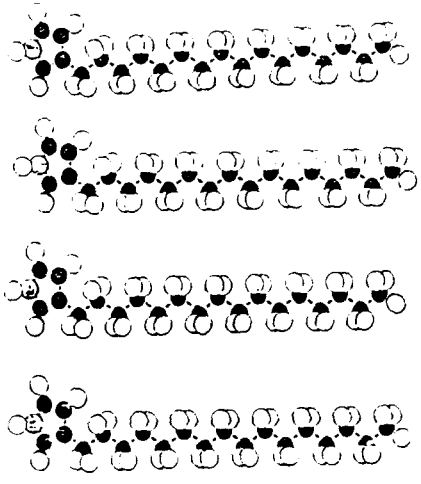


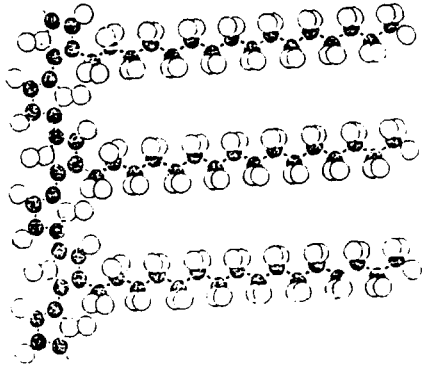
Isotherms of 3-Hexadecyl Pyrrole

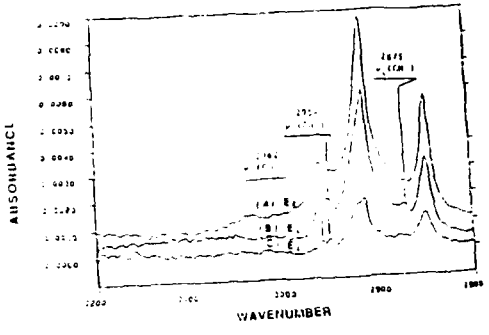
(mixed monolayers with pyrrole monomer)









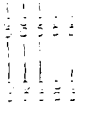


IR SPECTRA OF $C_{18}H_{33}$ PYRROLE LB FILMS IN THE C-H STRETCHING REGION

(A) TRANSMISSION OF 5 MONOLAYERS ON ZnSe

(B) GIR OF 5 MONOLAYERS ON Pt

(C) GIR OF 1 MONOLAYER ON Pt



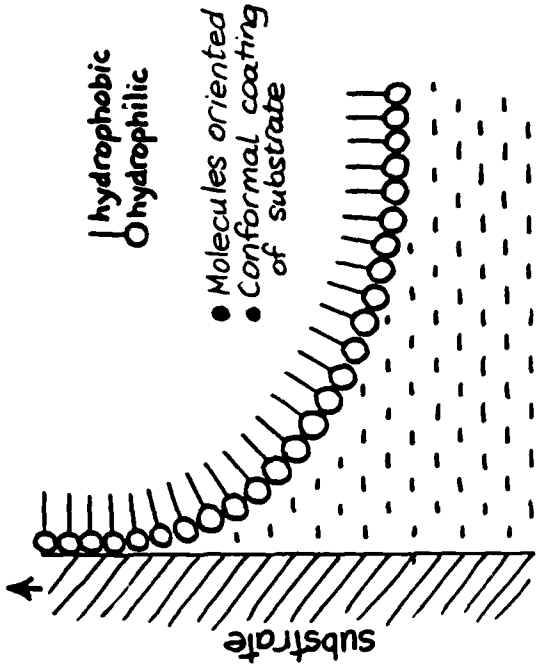
I. Peterson
GEC Research, Ltd., Great Britain

THE NONLINEAR OPTICS OF LANGMUIR-BLODGETT FILMS

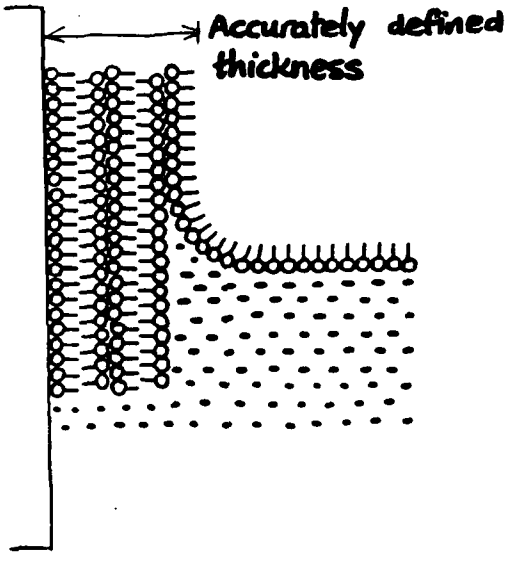
THE NONLINEAR OPTICS OF LANGMUIR-BLODGETT FILMS

Theoretical advantages:

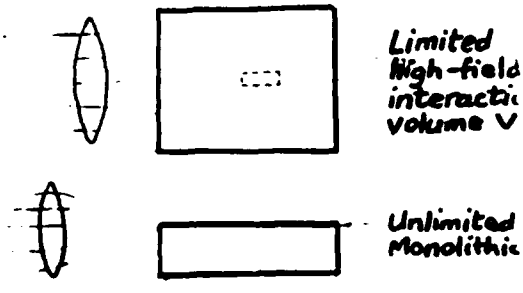
- Good geometry
- Chromophore alignment
- Dense packing



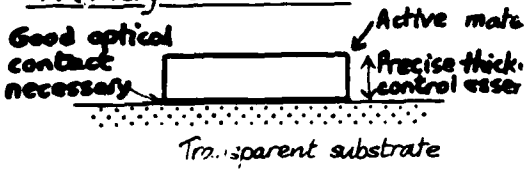
Building up thick films



Geometry



Overlay structure



SECOND-ORDER EFFECTS

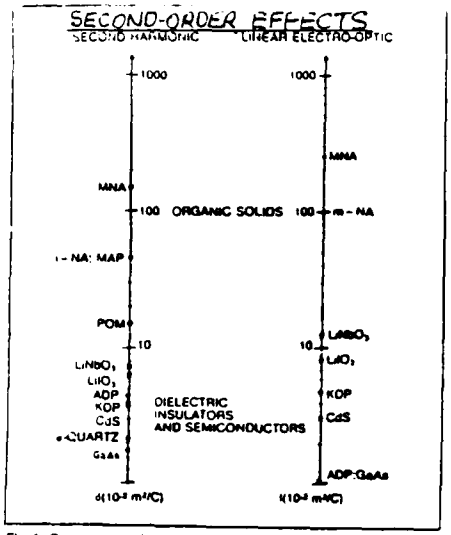
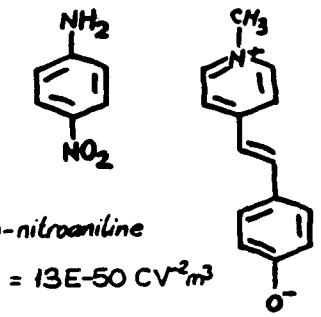


Fig. 1. Comparison of nonlinear optical figures of merit for organic and inorganic solids. (d is measured at 1.05 μm; χ is the strain-free quantity measured at 0.633 μm, except for GaAs where it is measured at 0.9 μm)

IFGarito & KDSinger
Laser Focus 80(1982) 59

WHAT MOLECULE?



p-nitroaniline
β = 13E-50 $CV^{-2}m^3$

'Gedye'
merocyanine
β = 370E-50 $CV^{-2}m^3$

$\frac{\beta}{\xi_0 V}$ 65 pm/V 1100 pm/V

cf $LiNbO_3$ $\chi^{(2)}_{SHG}$ = 10 pm/V

Two-state Approximation

$$\beta = \frac{3e^2\hbar^2}{2m} \cdot \frac{W_0}{(W_0^2 - 4W^2)(W_0^2 - W^2)} \cdot f\Delta\mu$$

W_0	State transition energy
W	Photon energy $\hbar\omega$
f	Oscillator strength
$\Delta\mu$	Dipole moment difference

The best materials have

- Long-wavelength absorption
- Strong absorption
- Charge transfer

Ian Girling
Graham Cross
John Earls
} GEC Hirst Researc

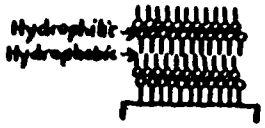
JOERS (LB nonlinear opt

Durham	Mike Petty
Lancaster	Richard Tredgold
Hull	George Gray
Plessey	Jack Brettle
British Telecom	Roger Heckingbott

My new address.....

Institut für phys. Chemie
Universität Mainz FRG

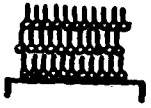
Y-type film



Stable but $\chi^{(2)}$-inactive

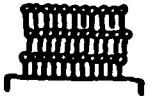
X- and Z-type films

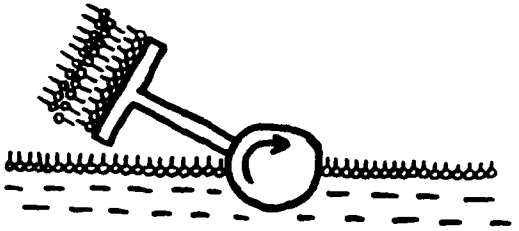
X



$\chi^{(2)}$-active but unstable

Z





Deposition of $\chi^{(2)}$-active

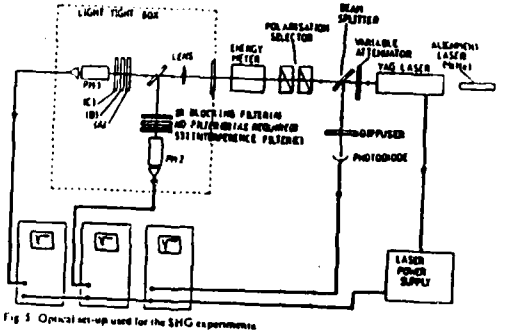
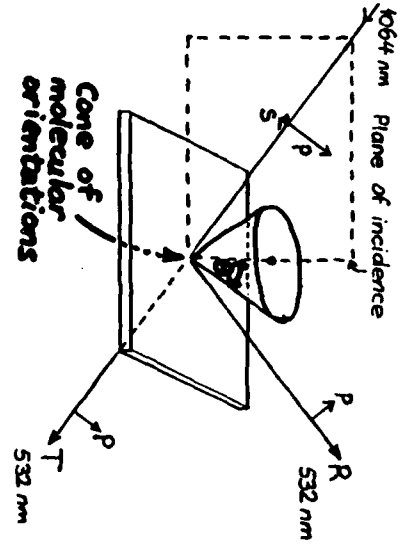


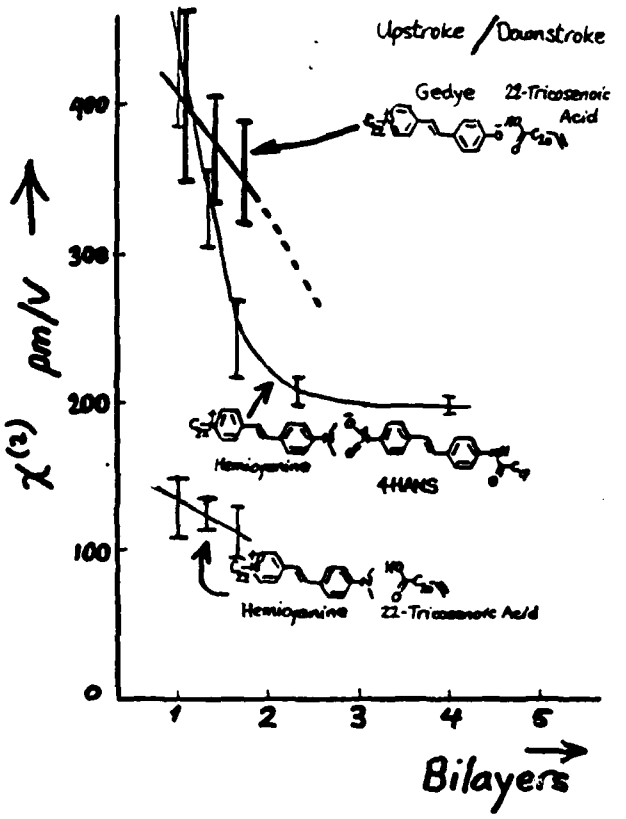
Fig. 1. Optical set-up used for the SHG experiments

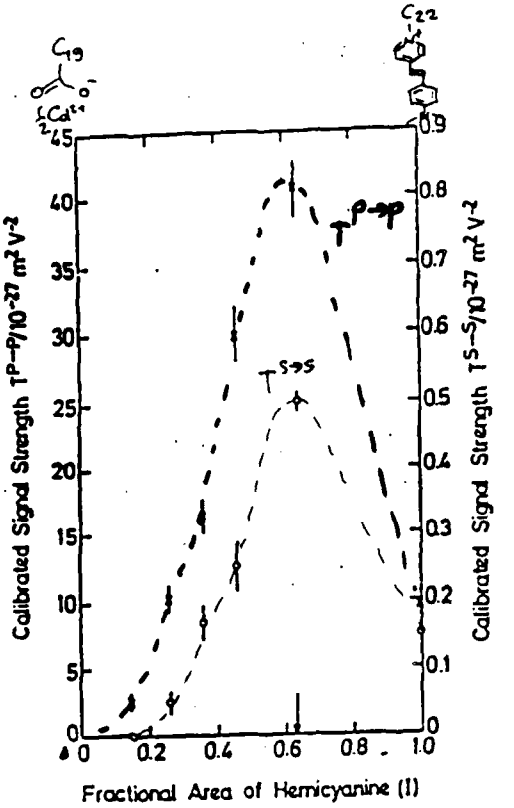
Second Harmonic Generation

GEDYE MEROCYANINE MONOLAYERS

	$\chi^{(2)}$(pm/v)	θ°
Low π	250	15
High π	1300	9



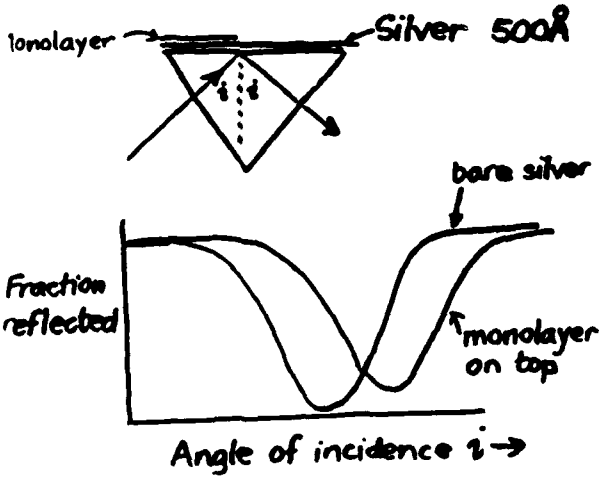




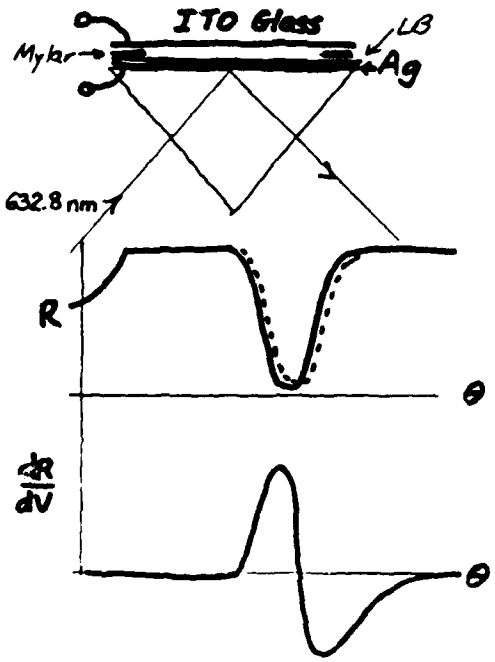
4 $T^{p\to p}$(x) and $T^{s\to s}$(o) second harmonic signal (10^{-27} m^2V^{-2}) from mixed monolayer

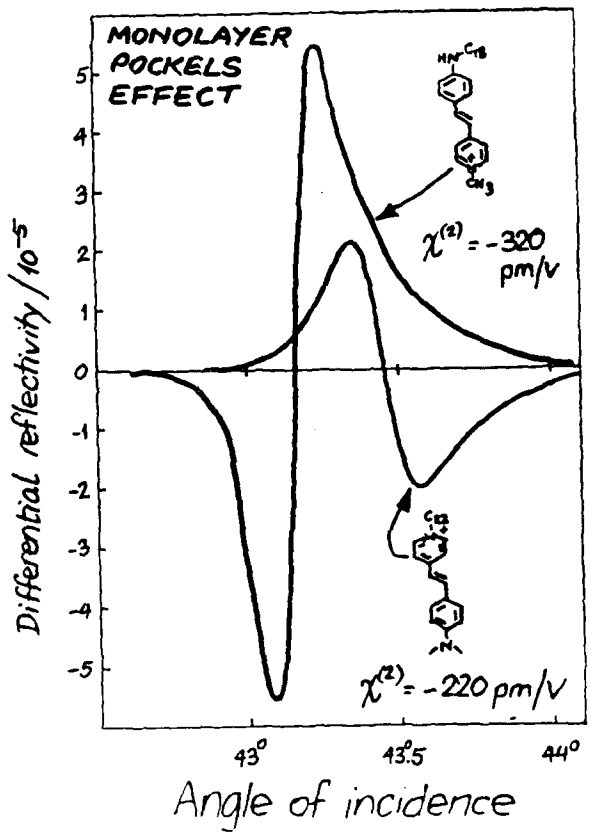
Measurement of refractive index

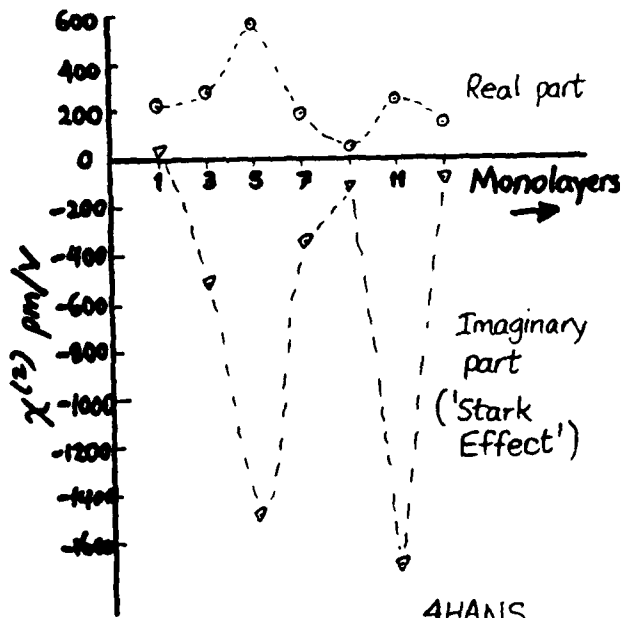
Surface plasmon Attenuated Total Reflection



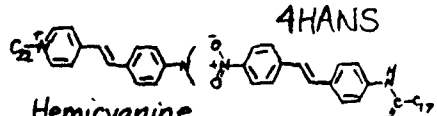
Pockels-ATR Technique



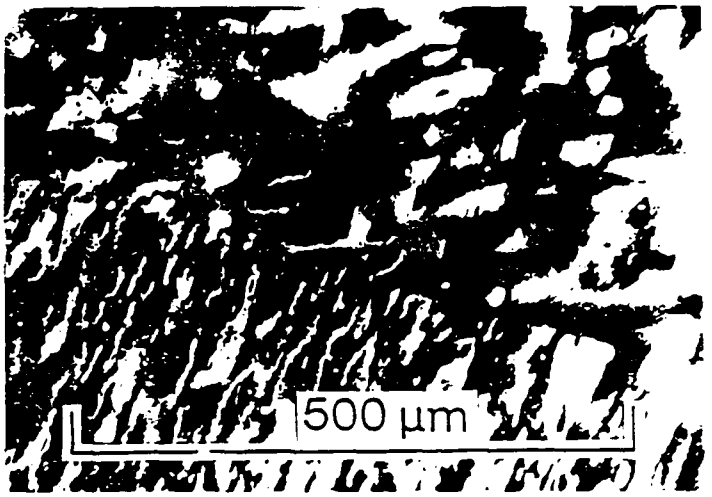


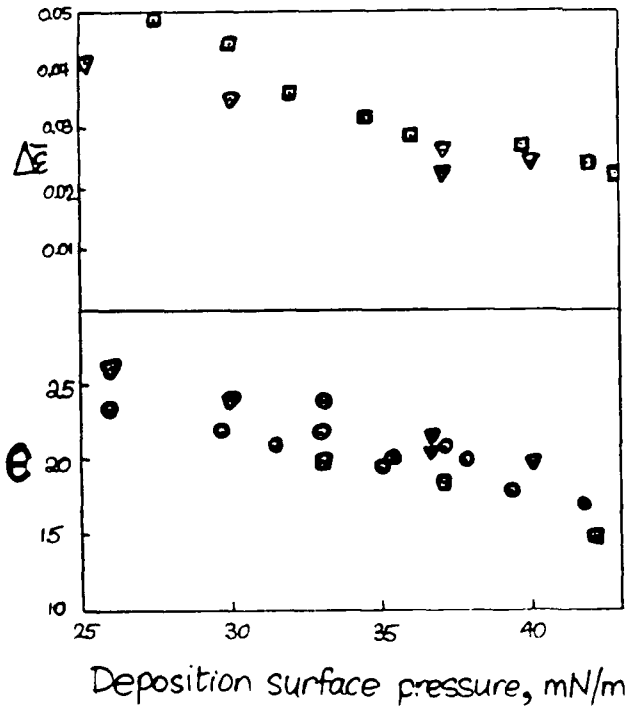


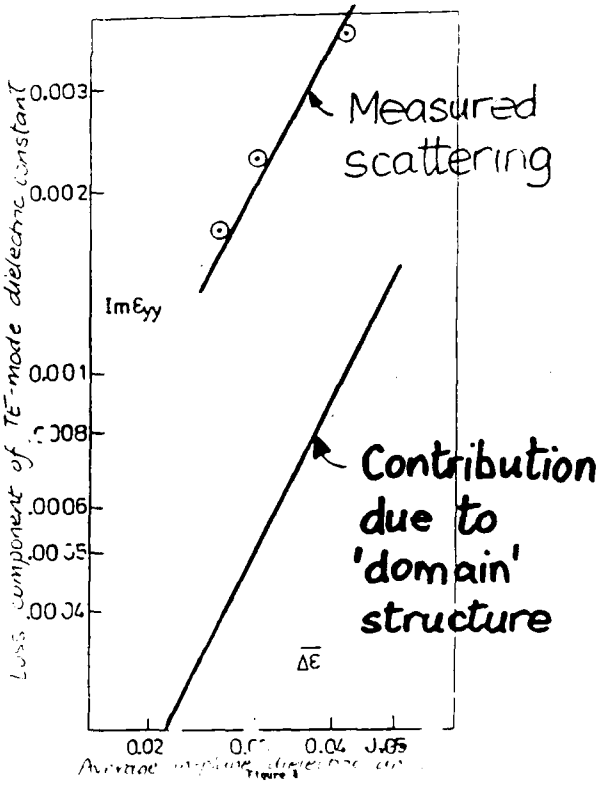
4HANS



Hemicyanine (Upstroke) (Downstroke)


500 µm


0.05
0.04
0.03
0.02
0.01
Δε̄
25
20
15
10
ε
25
30
35
40
Deposition surface pressure, mN/m


Measured scattering
Imε_yy
0.003
0.002
0.001
.0008
.0006
.0005
.0004
Loss component of TE-mode dielectric constant
Contribution due to 'domain' structure
Δε̄
0.02
0.04
0.05

R. S. Lytel
Lockheed Research and Development

ADVANCES IN ORGANIC ELECTRO-OPTIC DEVICES

R&DD ORGANICS

LOCKHEED

ADVANCES IN ORGANIC ELECTRO-OPTIC DEVICES

MAY 19, 1988

R. LYTEL

Lockheed Research and Development Division
LOCKHEED MISSILES AND SPACE COMPANY, INC.
3251 Hanover St. Palo Alto, California 94304

R&DD ORGANICS 3/88

ACKNOWLEDGEMENTS

LOCKHEED

DARPA
* J. NEFF

AFOSR
* D. ULRICH

AFWAL/AFML
* P. LANE

U.S. ARMY
* E. SHARP
* W. ELSER

U. PENN
* A.F. GARITO

HOECHST CELANESE
* J. STAMATOFF
* D. DEMARTINO
* H. YOKIN

U.S. MISS
* A. GRIFFIN

R&DD ORGANICS 3/88 THE LOCKHEED ORGANIC DEVICES GROUP LOCKHEED

SYNTHESIS

S. ERMER
M. STILLER

ANALYSIS

S. KWIATKOWSKI
G.F. LIPSCOMB
R. LYTEL
D. SWANSON
A. TICKNOR

GRATINGS/FILTERS

M. STILLER
B. SULLIVAN

CHARACTERIZATION

J. ALTMAN
K. ARON
P. ELIZONDO
G. HANSEN
G.F. LIPSCOMB
R. STONE

WAVEGUIDES

G.F. LIPSCOMB
R. LYTEL
M. STILLER
J. THACKARA
A. TICKNOR

SPATIAL LIGHT MODULATORS

D. ARMITAGE
W. EADES
M. STILLER
J. THACKARA

R&DD ORGANICS 3/88 MAJOR BENEFITS OF NONLINEAR ORGANIC/POLYMERIC MATERIALS LOCKHEED

* ORGANIC/POLYMERIC MATERIALS OFFER UNIQUE OPTICAL AND STRUCTURAL FEATURES FOR DEVICE APPLICATIONS

* MOLECULAR PROPERTIES CAN BE ENGINEERED TO ACHIEVE DESIRED MACROSCOPIC PROPERTIES

STRUCTURAL	OPTICAL
* MOLECULAR ENGINEERING	* LARGE, NONRESONANT RESPONSE
* THIN FILMS AND BULK CRYSTALS	* LOW DC DIELECTRIC CONSTANTS
* ROOM TEMPERATURE OPERATION	* FAST NLO RESPONSE
* CHEMICAL/STRUCTURAL STABILITY	* HIGH OPTICAL DAMAGE THRESHOLD
* INTERNAL GRATINGS/STRUCTURE	* BROADBAND
* ARCHITECTURAL FLEXIBILITY	* LOW ABSORPTION

P-3

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ORGANIC MATERIALS IN INTEGRATED OPTICS

LOCKHEED

- CURRENT TECHNOLOGY: $TiLiNbO_3$
  - Materials Dev. Began in 1960s
- r = 32 pm/V
  - Larger Modulating Voltage
  - Little Improvement Expected
- LIMITED FABRICABILITY
  - 1000°C Processing
  - Depth Limited to 5 μm
  - Low Index Change Δn
  - Loss > 0.1 dB/cm
  - Optical Damage (Photorefractor)
- LARGE DIELECTRIC CONSTANT (28)
  - Longer Time Constants = RC
  - Large Velocity Mismatch in Traveling Wave Modulator
- MASS PRODUCTION DIFFICULT

- PROPERTIES OF POLYMERIC ORGANIC E-O MATERIALS
  - Materials Dev. Began 1975
- r = 14-53 pm/V (poled films*)
  - Lower Modulating Voltage
  - Potentially Much Larger r
- FLEXIBLE FABRICATION
  - Low Temperature Processing
  - Flexible Dimensions
  - Controllable Index Change Δn
  - Loss < 0.8 dB/cm**
  - High Optical Damage Threshold
- LOW DIELECTRIC CONSTANT (4)
  - Shorter Time Constants = RC
  - Smaller Velocity Mismatch
- POTENTIAL FOR MASS PRODUCTION

* See Proc. Materials Research Society, Boston, MA (12/87)
** Current Lockheed/Hoechst Celanese Result

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ORGANIC MATERIALS IN OTHER DEVICES

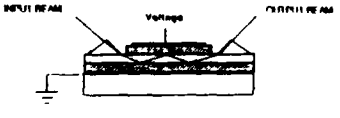
LOCKHEED

ELECTRO-OPTIC DEVICES	ALL-OPTICAL DEVICES
* SPATIAL LIGHT MODULATORS, TUNABLE FILTERS, SHUTTERS	* ETALON SWITCHES, ALL-OPTICAL FILTERS, NONLINEAR WAVEGUIDE DEVICES
* MATERIALS WITH LARGE r AND LOW DIELECTRIC CONSTANTS EXIST AND ARE AVAILABLE	* NONRESONANT NONLINEARITIES ARE STILL FAR TOO SMALL FOR MICRON-SIZED DEVICES; RESONANT MATERIALS REQUIRED
* FABRICATION UNDERWAY IN THIS PROJECT	* NONRESONANT MATERIALS NEARLY ADEQUATE FOR GUIDED WAVE DEVICES

R&DD ORGANICS 3/88

ORGANIC E-O THIN-FILM WAVEGUIDE MODULATORS

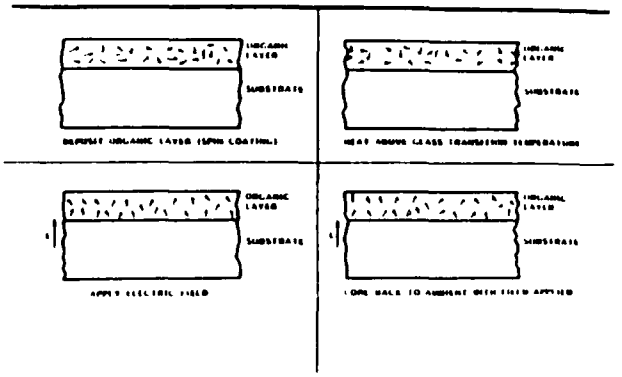
LOCKHEED



	BUFFER LAYERS	POLYMERS
COPPER	POLYSILOXANE RESIN	MNA/PMMA
ALUMINUM	UV CURABLE COATINGS	PC69
GOLD	SILICON DIOXIDE	C-22
ITO	2 COMPONENT EPOXY	HCC-1237 (new)

* TYPICAL LAYER THICKNESS OF ORDER 2 MICRONS
* POLING ACCOMPLISHED PRIOR TO FINAL ASSEMBLY

POLED ORGANIC E-O LAYER PREPARATION



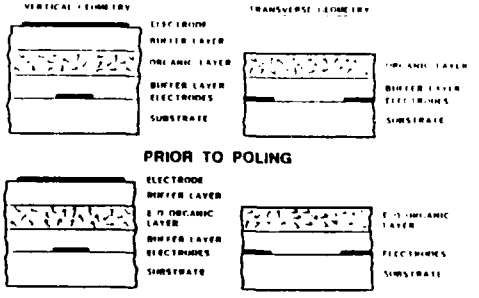
H&UU ORGANICS 3/88 POLED POLYMER FILMS AND SLAB WAVEGUIDE MODULATORS LOCKHEED

(wavelength = 0.83 μm)	PC6S	C-22
E-O COEFFICIENT (pm/V)	2.8	14.0
TM REFRACTIVE INDEX (POLED)	1.7	1.58
TM INDEX DIFFERENCE (POLED-UNPOLED)	0.06	0.005
WG LENGTH (cm)	1.8	2.5
MEASURED LOSS (dB/cm)	3.4	0.8
HALF-WAVE VOLTAGE (volts)	48	7

H&UU ORGANICS 3/88 FABRICATION OF CHANNEL WAVEGUIDES BY SELECTIVE POLING LOCKHEED

- SINGLE POLARIZATION BURIED CHANNEL WAVEGUIDES CAN BE FABRICATED BY SELECTIVE ELECTRIC FIELD POLING IN THIN FILM POLYMERS USING VERTICAL OR TRANSVERSE ELECTRODES
- POLING PRODUCES HIGHER INDEX, E-O CHANNELS BURIED IN SURROUNDING, UNPOLED, LOWER INDEX POLYMER
- WAVEGUIDE PATTERN DEFINED BY PHOTOLITHOGRAPHY
- RELATIVELY LOW TEMPERATURE PROCESSING, 100-200 C
- FLEXIBLE DIMENSIONS IN HEIGHT AND WIDTH, 1-100 MICRONS
- VARIABLE INDEX DIFFERENCE $\Delta n = 0.001$-0.05
- CAN MODE MATCH TO STANDARD SINGLE MODE FIBER
- CONCEPT PROVED IN DEVICE STRUCTURES: MACH-ZEHNDER INTERFEROMETER COUPLER, TRAVELING WAVE MODULATOR

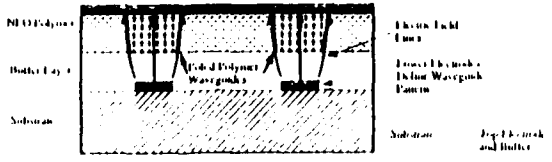
H&UU ORGANICS 3/88 VERTICAL AND TRANSVERSE POLING OF GLASSY POLYMER FILMS/WAVEGUIDES LOCKHEED



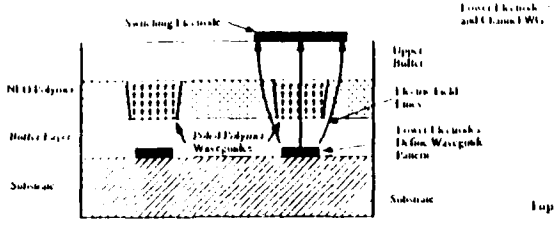
ORGANICS
3/88

INTEGRATED OPTIC MODULATOR FABRICATION

LOCKHEED



Fabrication of Poled Polymer Waveguide Structure



Optical Modulation By Electro-Optic Modulation

Top View of Modulator

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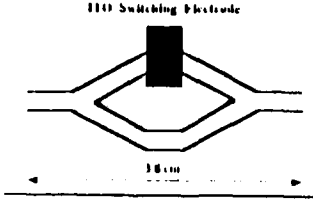
FABRICATION AND OPERATION OF A SELECTIVELY-POLED M-Z INTERFEROMETER



- POLED PC6S, 90°C, 5 MIN, 100 V/μm
- GOLD POLING ELECTRODE ON PC6S, REMOVED AFTER POLING
- 3° BRANCH ANGLE
- 780 nm LIGHT, TM MODE CONFINED
- GUIDE DIMENSIONS 2 x 7 μm

Device Structure After Poling Completed

INPUT Y-BRANCH

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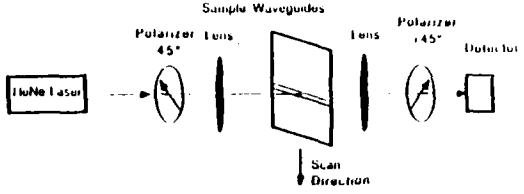
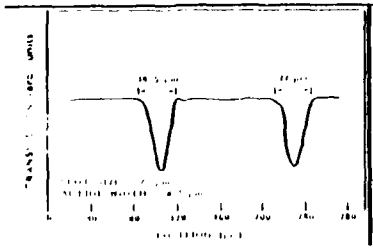
CHANNEL BOUNDARY IN SELECTIVELY-POLED GUIDES





- Test of the Extent of Poling Beyond the Electrode Boundaries
- Sample Placed at 45° Between Crossed Polarizers
- Focused HeNe Spot Scanned Across Poled Waveguide Regions
- Poling Induced Birefringence at the Guide Boundary Would Cause Increased Signal
- Metallic Poling Electrode Blocks Beam and Causes a Dip in the Background Signal
- Poling Sharply Confined to the Electroded Region

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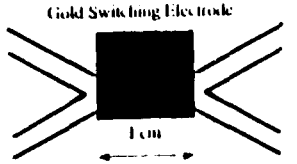
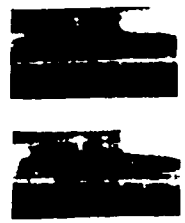
FABRICATION AND OPERATION OF A SELECTIVELY-POLED DIRECTIONAL COUPLER



- POLED @ 22, 105° C, 15 MIN, 90 V/μm
- 3° COUPLING ANGLE
- 830 nm LIGHT, TM MODE CONFINED
- INPUT/OUTPUT GUIDES 2 x 7 μm
- COMMON GUIDE 2 x 13 μm

Device Structure After Poling Completed

gold switching electrode
3 μm polysiloxane buffer
2 μm C 22 F O polymer
3 μm UV curable coating
patterned aluminum electrode
glass substrate



a) BAR STATE (120 V)

b) CROSS STATE (65 V)

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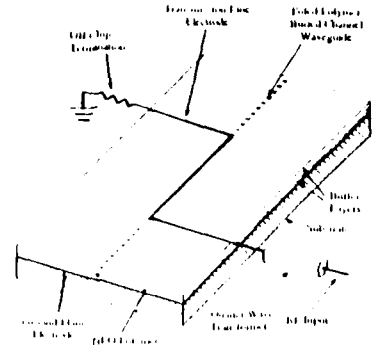
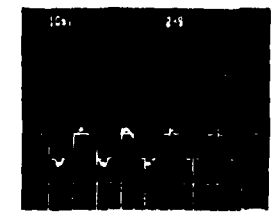
TRAVELING WAVE INTEGRATED OPTIC PHASE MODULATOR



- POLED @ 22 CHANNEL (100V/μm)
- ACTIVE PATH LENGTH 4 cm
- WAVELENGTH 830 nm
- DEVICE IMPEDANCE 9.5 ohms
- DRIVE SIGNAL 0.5 W (applied through transformer, 1/4 wave @ 250 Mhz)



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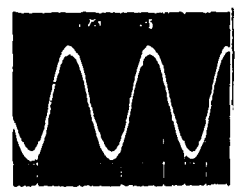
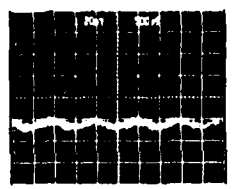
TRAVELING WAVE MODULATORS

- PHASE MODULATOR IN ONE ARM OF A MACH-ZEHNDER INTERFEROMETER
- CALCULATED MODULATION DEPTH USING MEASURED AT LOW FREQUENCY EQUALS MEASURED MODULATION DEPTH AT HIGH FREQUENCY
- IMPEDANCE MATCHED, 9.5 Ω



270 MHz

- PHASE MODULATOR IN ONE ARM OF A MACH-ZEHNDER INTERFEROMETER
- RESPONSE SMALL DUE TO IMPEDANCE MISMATCH BUT
- CLEAR GHz MODULATION IS OBSERVABLE



1 GHz

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SIGNIFICANCE OF ORGANIC E-O WAVEGUIDE RESEARCH

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CRITICAL RESULTS	IMPLICATIONS
• POLED POLYMER WAVEGUIDE FAB IS CHEAP, FAST, AND SIMPLE	• MASS PRODUCTION POSSIBLE
• PATTERNS DETERMINED BY ORDINARY PHOTOLITHOGRAPHY	• COMPLEX DEVICES ON A CHIP
• E O COEFFICIENTS NEARING LITHIUM NIOBATE LEVELS	• LOW DRIVING VOLTAGES COMPATIBLE WITH FET
• DIELECTRIC CONSTANTS ARE 7-10 TIMES SMALLER THAN INORGANICS	• FASTER RESPONSE TIMES AND HIGHER SENSITIVITY
• MODULATION TO 1.3 GHz SHOWN, TO >2 GHz ACHIEVABLE	• HIGH SPEED SWITCHING AND INTERCONNECTION
• DEVICES BUILT AND OPERATED: INTERFEROMETERS, COUPLERS, AND TWO PHASE MODULATORS	• PROOF OF CONCEPT COMPLETE; CAN MOVE TO COMPLEX DEVICE FABRICATION

B. K. Nayar

British Telecom Research Laboratories, U. K.

ORGANIC NONLINEAR OPTICAL DEVICES AND MATERIAL CONSIDERATIONS

ORGANIC NONLINEAR OPTICAL DEVICES AND MATERIAL CONSIDERATIONS

B K NAYAR

British Telecom Research Laboratories
Martlesham Heath
Ipswich
Suffolk IP5 7RE
United Kingdom

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BTRL

K I WHITE
R KASHYAP
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B J McARDLE
H MORRISON
E A SHEPHERD
C S YOON

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OUTLINE

1. Review of device requirements for optical signal processing
2. Why organics?
3. Bulk devices
4. Guided wave devices
5. Crystal cored fibres
6. Material requirements dictated by the device design
7. Review of the present status

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NON-LINEAR OPTICAL PROCESSES

$$P_i = \epsilon_0 \left[\chi_{ij}^{(1)} E_j + \chi_{ijk}^{(2)} E_j E_k + \chi_{ijkl}^{(3)} E_j E_k E_l + \ldots \right]$$

- $\chi_{ij}^{(1)}$ — Linear susceptibility
- $\chi_{ijk}^{(2)}, \chi_{ijkl}^{(3)}, \ldots$ — Non-linear susceptibilities

$\chi_{ijk}^{(2)} = 0$ in centrosymmetric media

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NONLINEAR OPTICAL DEVICES FOR SIGNAL PROCESSING

- Amplitude/Phase Modulators
- Switching Matrices
- Bistable Elements
- Frequency Convertors
- Tunable Sources
- Amplifiers
- Real-time phase conjugators

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WHY ORGANIC MATERIALS?

- Large optical nolinearities
- Fast response times
- High optical damage thresholds
- Large birefringence
- Material optimisation using "Molecular Engineering"

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DISADVANTAGES OF ORGANIC MATERIALS

- Low melting points
- Mechanically weak
- Susceptible to chemical attack
- Complex transmission spectra
- Health hazards

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MATERIAL SYSTEMS

SINGLE CRYSTAL	• Bulk
	• Thin film
	-planar
	-overlays
	• Confined growth
	-channels
	-fibres
POLYMER FILMS	• LC polymers
	• Guest-host polymers
	• LB films

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BULK ORGANIC DEVICES

DEVICE TYPE	MATERIALS
SHG	DAN, mNA, MBA-NP, MAP, NPP, POM, Urea
SFG	Urea
OPA	POM, NPP
OPE	POM
OPO	Urea

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BULK MBA-NP CRYSTAL GROWTH

- Material Purification
  - column chromatography
  - successive recrysatallisations
- Selection of perfect seeds
  - X-ray topography
- Solution growth by temperature lowering of a seeded saturated methanol solution

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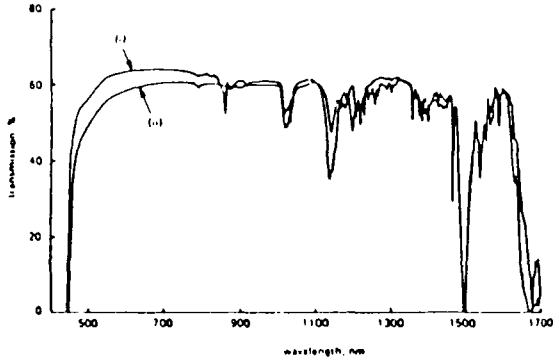
MBA-NP CRYSTAL TRANSMISSION SPECTRA

Crystal Cut: (001); Propagation: [001]

Input Polarisation: (i) [100] and (ii) [010]



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MBA-NP SHG RESULTS

- Large single crystal growth
  - $5x3x3\ cm^3$
- Type I Phase-Matched SHG
  - $d_{eff} = 3.4x10^{-12}\ m/V$
- $d_{22} = 25x10^{-12}\ m/V$

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ADVANTAGES OF GUIDED WAVE NONLINEAR INTERACTIONS

- Semiconductor laser powers adequate
- Long interaction lengths
- Phase-matching using modal dispersion
- Ease of coupling to optical fibres

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ACTIVE WAVEGUIDE TYPES

- PLANAR
  - — Two-dimensional eg slab
  - — Three-dimensional eg channel
- FIBRE
  - — Polished/D-shaped fibres with overlays
  - — Crystal cored fibres
  - — Doped fibres

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ACTIVE WAVEGUIDE DEVICE TYPES

- Waveguide
- Directional Coupler
- Waveguide Interferometers
  - — Mach-Zehnder, Ring Resonator etc
- Waveguide Fabry-Perot

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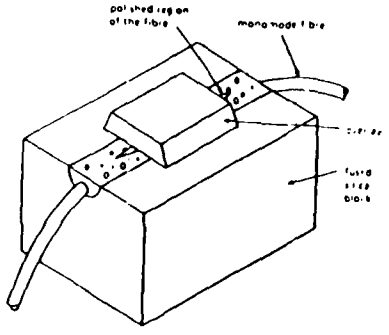
POLISHED / D-SHAPED FIBRES WITH NONLINEAR OVERLAYS



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- Evanescent mode field interacts with the Nonlinear Overlay eg
  - — Change in the overlay index can be used to modulate Amplitude or Phase of the fibre mode

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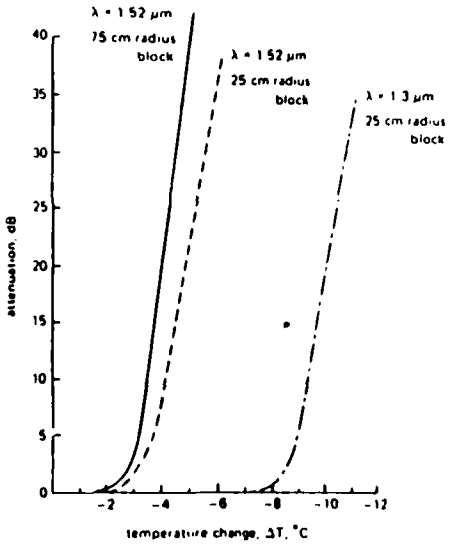
ATTENUATION OF A POLISHED FIBRE WITH A REDUCTION IN THE OIL OVERLAY TEMPERATURE ie INCREASE IN INDEX

$$\frac{dn_D}{dT} = -3.7\times10^{-4}\ ^\circ C$$



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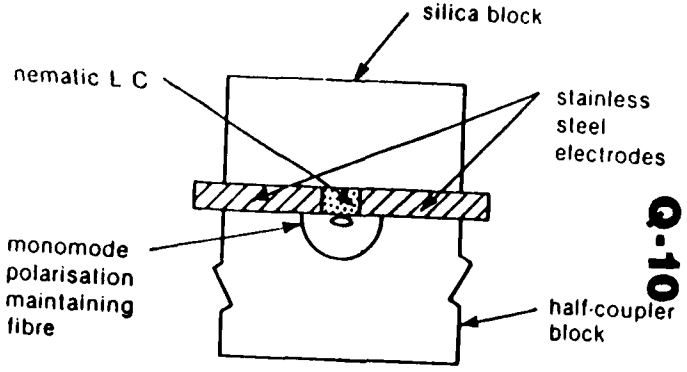
SCHEMATIC OF A FIBRE E-O MODULATOR WITH A NEMATIC LC OVERLAY



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CHARACTERISTICS OF A FIBRE E-O AMPLITUDE MODULATOR WITH A NEMATIC LIQUID CRYSTAL OVERLAY

- Insertion Loss
  - — Horz Pol: 1.2dB and Vert Pol: 0.5dB
- Modulation Depth (Vert Pol): >30dB
- Switching Voltage: 5V
- Switching Field Strength: 0.2V/μm
- Response Times: $\tau_r = 2.5$ms and $\tau_f = 160$ms

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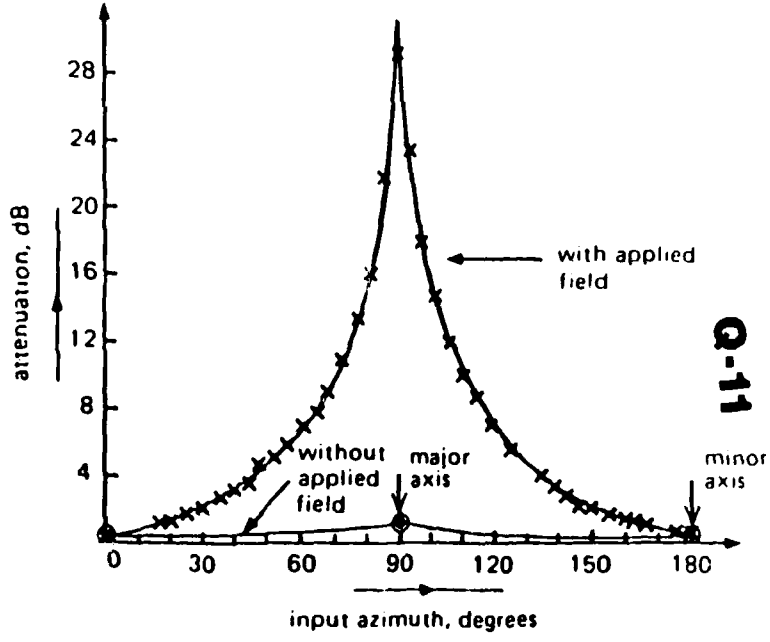
EXTINCTION RATIO OF A LC FIBRE MODULATOR WITH INPUT AZIMUTH ANGLE



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WHY CRYSTAL CORED FIBRES?

- Peak intensity in the core
- Good geometrical uniformity
- Large choice of cladding glasses
- Encapsulation of crystal core
- In-line fibre device

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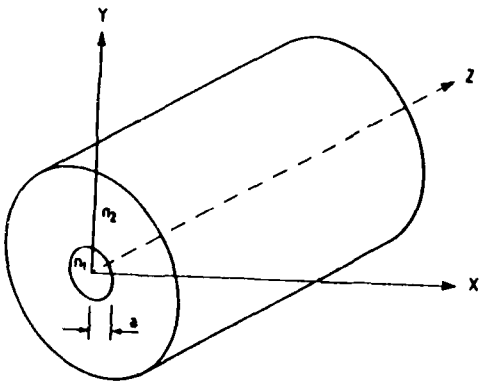
CRYSTAL CORED FIBRES

- Cylindrical waveguiding structure



- For optical guidance $n_1 > n_2$
- Applications: Three-wave and Four-wave mixing processes

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FABRICATION PROCESS

- Selection of suitable cladding glass

  — $\Delta n = n_c - n_{cl} < 0.05$

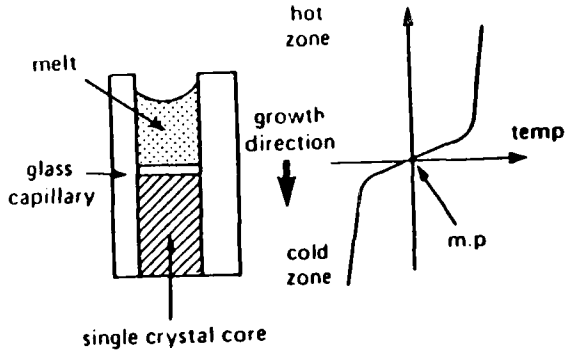
- Drawing of small bore capillaries

  — Bore diameter = 2 to 10μm

- Capillaries filled with the crystal melt

- Growth of single orientated crystal

CRYSTAL CORED FIBRE FABRICATION



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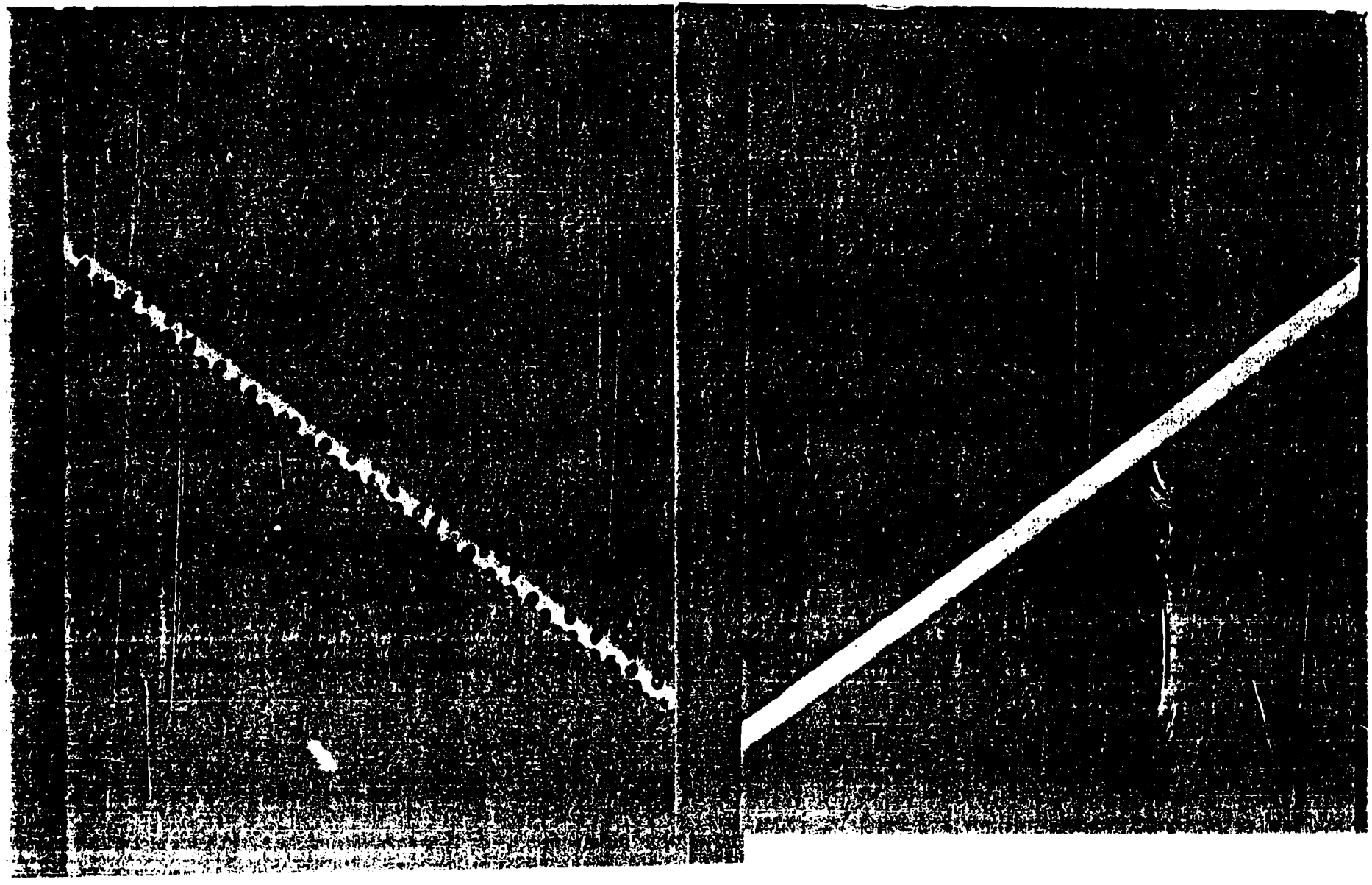
Defects In CCFs

SINGLE CRYSTAL CORE



FACTORS INFLUENCING DEFECT FREE CRYSTAL GROWTH

- Material Purity
- Adsorbed Oxygen
- Bubbles
- Temperature Gradient
- Growth Rate
- Vibration

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MATERIAL REQUIREMENTS FOR GROWTH IN GLASS CAPILLARIES

- Chemical stability
- Low melting point
- Optically transparent
- Refractive index < 2.0
- Non-centrosymmetric crystal
- Large transverse nonlinear coefficient

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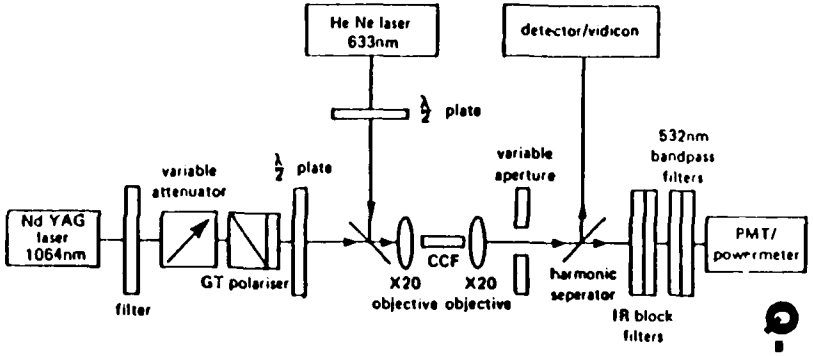
ASSESSMENT OF CCFs

- Polarising Microscope
  - — Crossed Polars
    - * Uniformity of orientation, defects/voids
  - — Parallel Polars
    - * Defects/Voids
- X-ray Diffraction
  - * Crystal Orientation
- Optical Transmission

EXPERIMENTAL SET-UP FOR OPTICAL CHARACTERISATION OF CCFs



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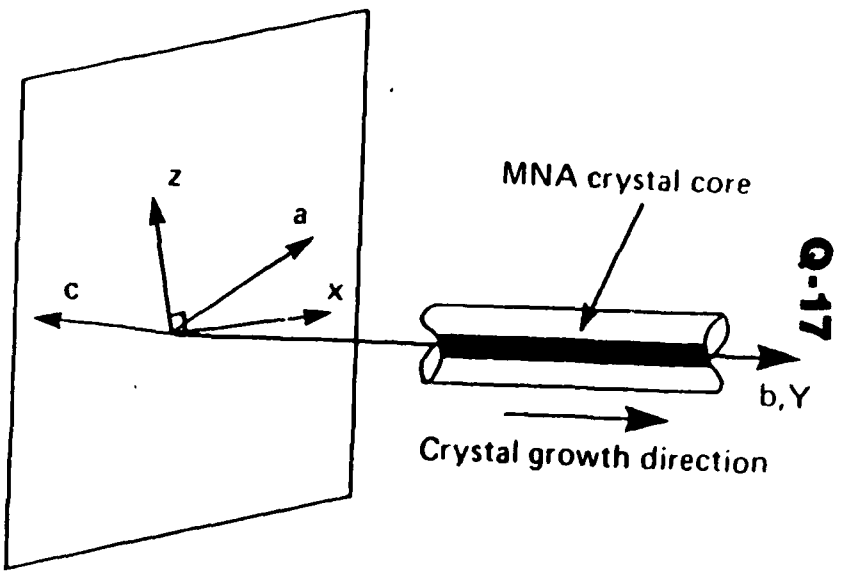
SUMMARY OF SHG EXPERIMENTS IN CCFs

Reference	Core
Nayar (1982&1983)	benzil
Vidakovic et al (1984)	NPP
Umegaki et al (1985)	MNA
Umegaki et al (1986)	MNA
Tomaru et al (1986)	DAN
Holdcroft et al (1987)	MNA
Nayar et al (1987)	acetamide, MNA
Vidakovic et al (1987)	NPAN
Holdcroft et al (1988)	DAN
Kerkoc et al (1988)	DAN

MNA CRYSTAL ORIENTATION IN CCFs



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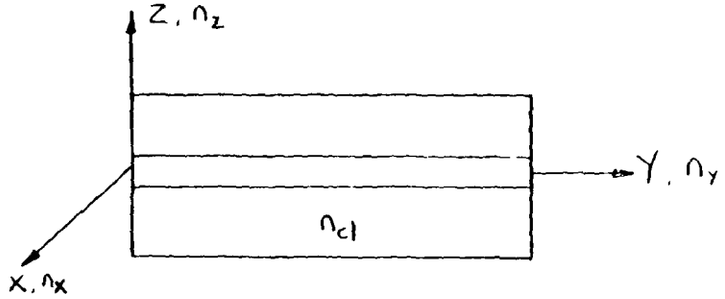
MNA CORED SILICA FIBRE POLARISER



- Refractive Indices of MNA:
  n_x (633nm) = 1.8 and n_z (589nm) = 1.453

- Silica Cladding, n_{cl} (589nm) = 1.458

- Hence transmission of *only* x-polarised light

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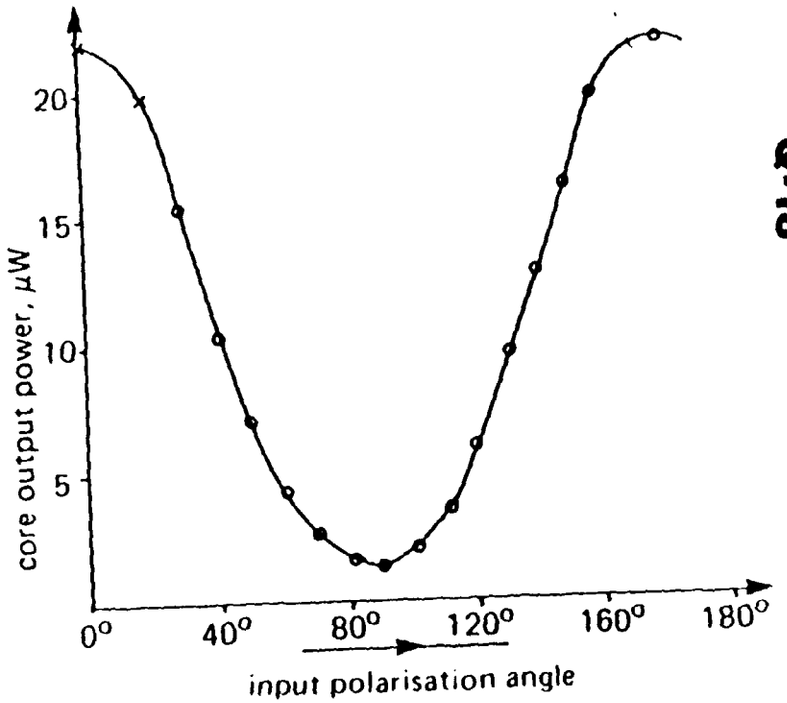
POLARISATION TRANSMISSION CHARACTERISTIC OF A MNA CORED SILICA FIBRE

Wavelength: 633nm; Extinction Ratio: 12.8dB



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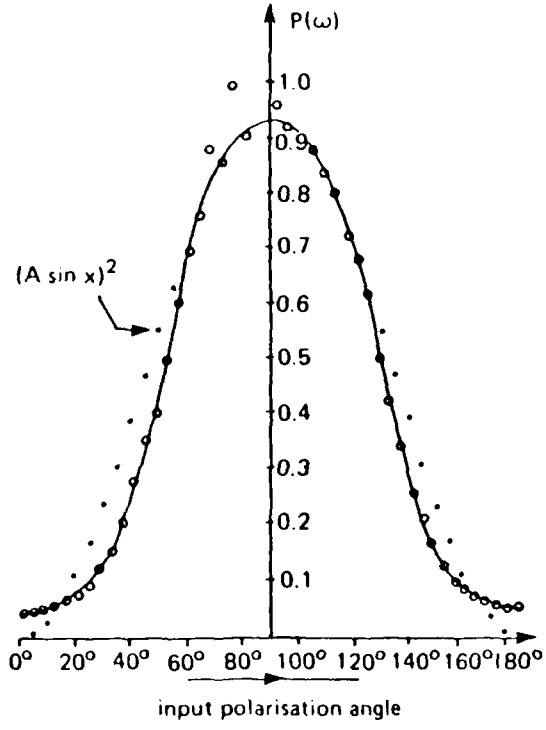
SH POWER CHARACTERISTIC OF A MNA CCF AS A FUNCTION OF INPUT POLARISATION



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CCF INSERTION LOSSES

CRYSTAL CORE	LOSS, dB/cm
acetamide	1.1
benzil	<2.0
DAN	10
MNA	20
NPP	High

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SUMMARY OF CCF SHG RESULTS

$\lambda_f = 1064$nm; Length = 10-15mm; Core dia. = 6-10μm

Average $P_f = 10$mW; Peak $P_f = 50$W

Material	Transmission, %	Efficiency, %
Acetamide	5	$0.25\text{-}1\times10^{-6}$
DAN	0.5	2×10^{-3}
MNA	0.2-0.6	$0.2\text{-}4\times10^{-5}$

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LATEST BTRL SHG RESULTS FOR DAN IN SILICA CCFs

$\lambda_f = 1064$nm; P_f (avg) = 1mW; P_f (peak) = 10W

Pulse Width = 200ns; Rep Rate = 500Hz

Fibre length = 10-15mm; Core dia = 6μm

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Publication	Throughput,%	Efficiency,%
CLEO'88	5-15	1-1.5

Ref: G E Holdcroft et al, paper WM55

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PRESENT STATUS OF SHG IN CCFs

- Typical conversion efficiencies $< 0.1\%$

DUE TO

- Unsuitable crystal orientation
- Low transmission
  - — Poor crystal end quality
  - — Voids and defects
- Un-optimised waveguide design
  - — Lack of data on optical properties

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DEVICE DESIGN REQUIREMENTS

- Bulk refractive indices
- Effective mode refractive indices
- Uniformity of guiding region dimensions and index difference
- Low waveguide attenuation
- Optical damage and intensity dependent index change

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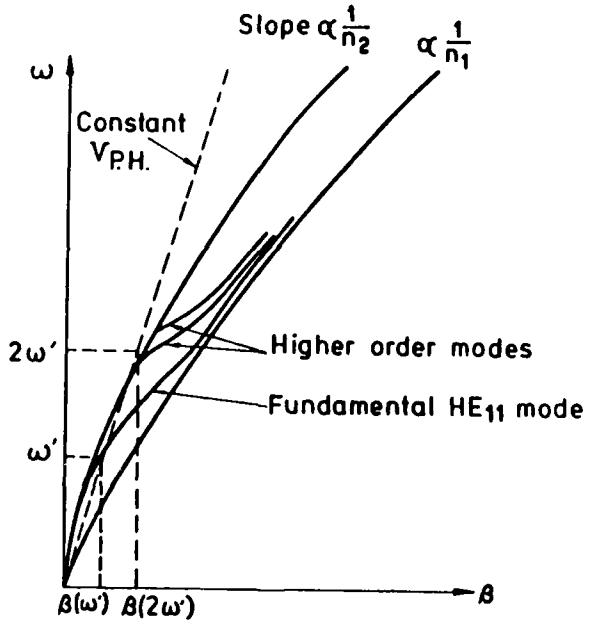
PHASE-MATCHING IN WAVEGUIDES

- Different mode orders
  - same or orthogonal polarisations
- Same order mode (orthogonal polarisations)
  - birefringent core material
  - elliptical core shape
- Hence require cladding glass of appropriate index and dispersion

PHASE-MATCHING FOR RADIATION SHG



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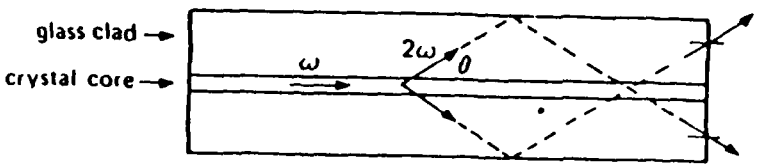
RADIATION SHG IN CCFs

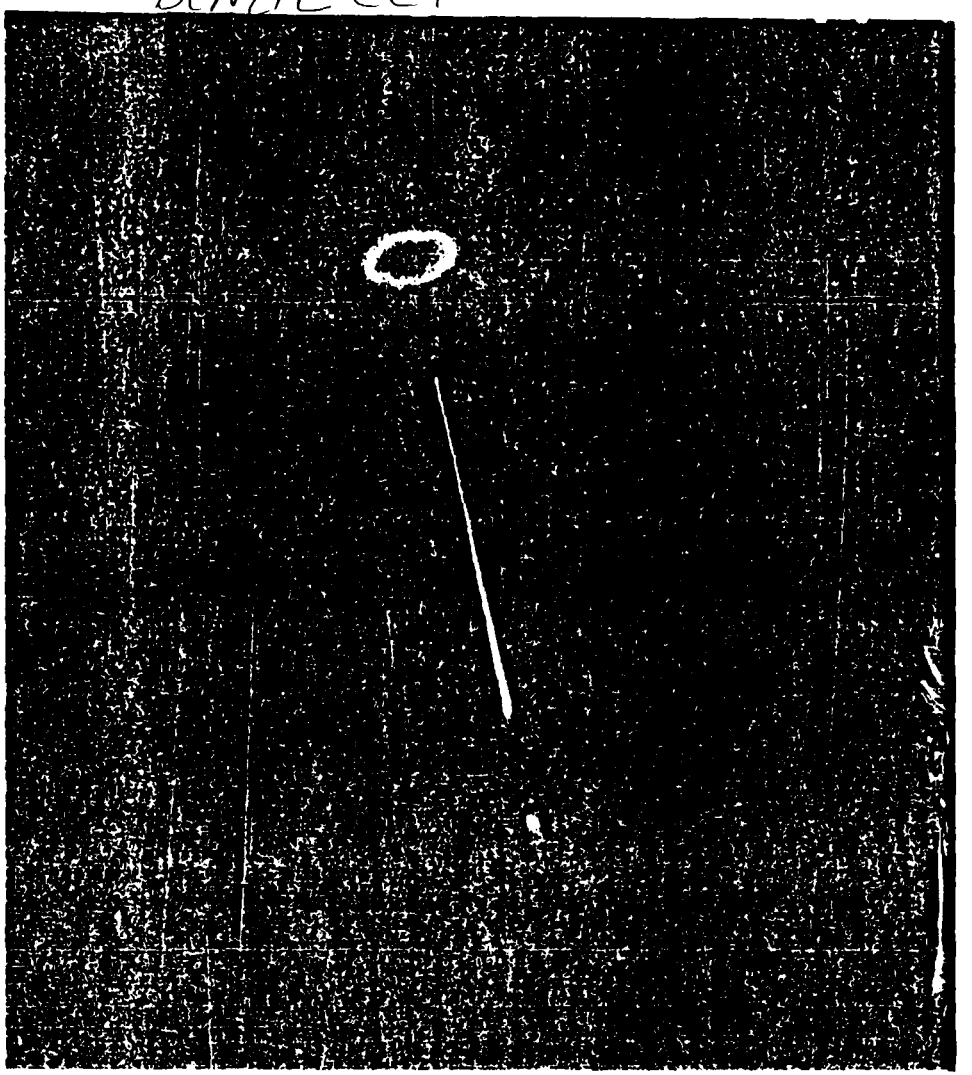


$$\cos\theta = \frac{n_e^{(\omega)}}{n_{cl}^{(2\omega)}}$$

$$\delta n = n_{cl}^{2\omega} - n_{cl}^{\omega} \geq \left[n_e^{\omega} - n_{cl}^{\omega} \right]$$

- **Advantage: Relaxed phase-matching constraints on guide dimensions and dispersion**
- **Disadvantage: Efficiency α Fibre length**

RADIATION FILED SHG IN A BENZIL CCF



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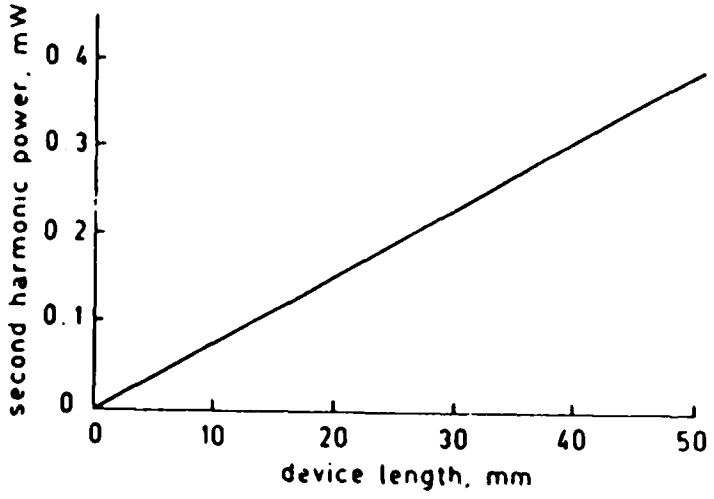
EFFICIENCY OF RADIATION SHG

$P_f = 10mW$; $\lambda_f = 1.5\mu m$; $d = 250pm/V$; $n = 1.65$



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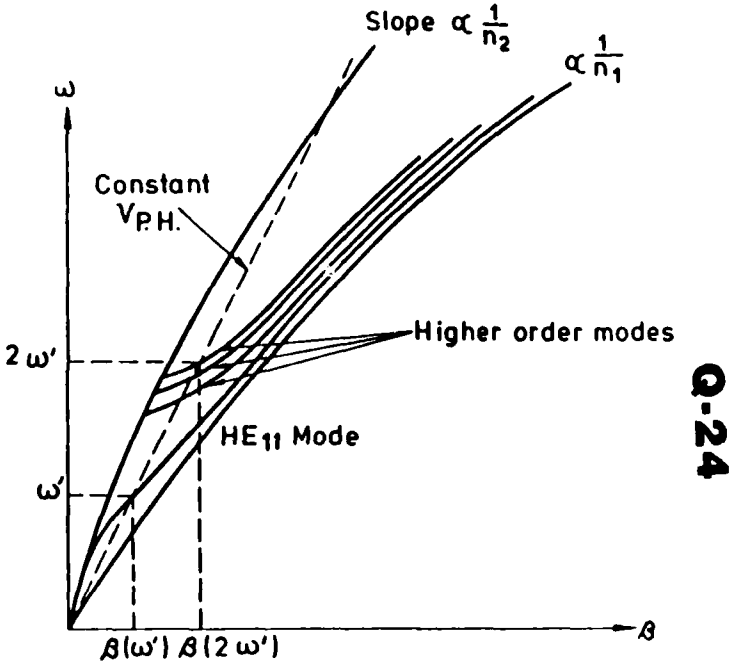
PHASE-MATCHING FOR GUIDED WAVE SHG



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PHASE-MATCHED SHG IN WAVEGUIDES

- **PUMP DEPLETION**

$$\eta = \tanh^2 \left[\kappa \sqrt{P_m^{(\omega)}}\, L \right]$$

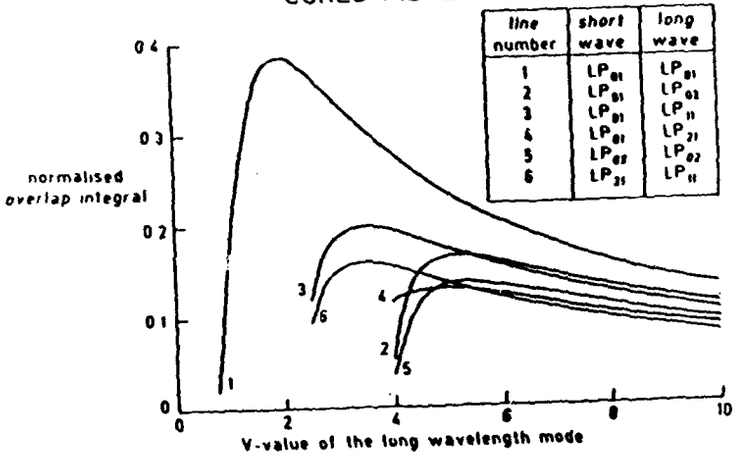
where

$$\kappa = \frac{\omega}{2} \epsilon_0 d_{im} \int_{-\infty}^{\infty} \int_{-\infty}^{\infty} E_\nu^{(\omega)} E_\nu^{(\omega)} . E_\mu^{(2\omega)} \, dx \, dy$$

- **For efficient SHG require optimistation of the "overlap integral".**

  - **Hence waveguide design**

NORMALISED FIELD OVERLAP INTEGRAL IN A CRYSTAL CORED FIBRE



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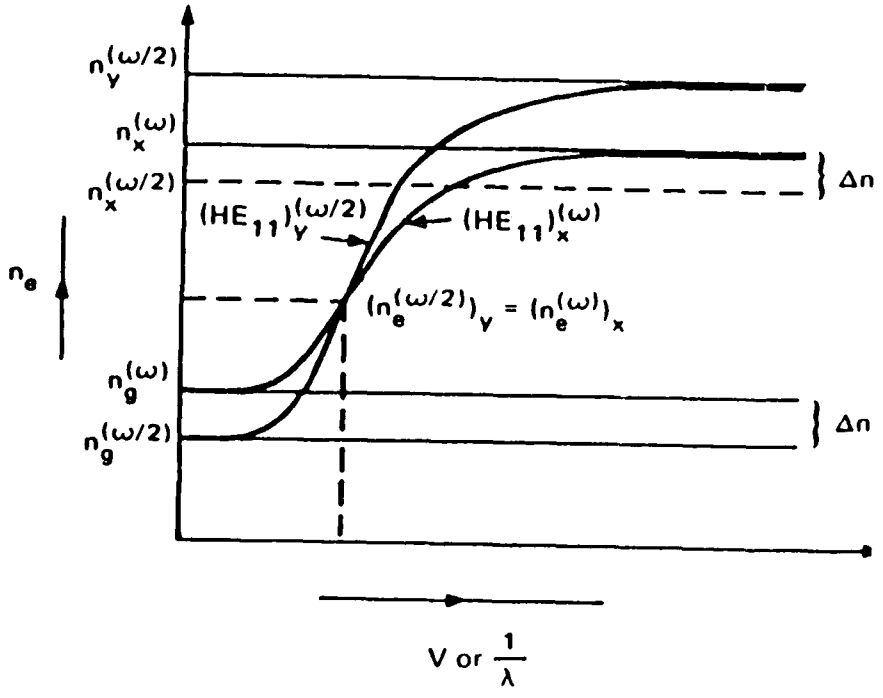
SH PHASE-MATCHING BETWEEN THE LOWEST ORDER ORTHOGONAL MODES



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SH POLARISATION

$$\begin{bmatrix} P_x \\ P_y \\ P_z \end{bmatrix}_{2\omega} = \epsilon_0 \begin{bmatrix} d_{11} & d_{12} & d_{13} & d_{14} & d_{15} & d_{16} \\ d_{21} & d_{22} & d_{23} & d_{24} & d_{25} & d_{26} \\ d_{31} & d_{32} & d_{33} & d_{34} & d_{35} & d_{36} \end{bmatrix} \begin{bmatrix} E_x^2 \\ E_y^2 \\ E_z^2 \\ 2E_yE_z \\ 2E_zE_x \\ 2E_xE_y \end{bmatrix}_{\omega}$$

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USEFUL CRYSTAL CLASSES FOR PM-SHG BETWEEN LOWEST ORDER ORTHOGONAL MODES

CRYSTAL SYSTEM	CLASS	COMMENTS
Triclinic	1	Any orientation
Monoclinic	*m*, 2	Specific orientation & index requirements
Orthorhombic	mm2	As above
Tetragonal	4, 4	z-axis transverse & -ve uniaxial
Trigonal	3, 3m	As above
Hexagonal	6, 6mm	As above

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GUIDED WAVE SHG IN A SUITABLY ORIENTATED mNA CCF

- Require: Y-axis parallel to the fibre axis

Wavelength, nm	Refractive Index
532	$n_z = 1.7006$
1064	$n_z = 1.6320$
1064	$n_x = 1.7196$

- PM between lowest order orthogonal modes with $n_g = 1.66$ and $\Delta n_g = 0.0245$

Calculated 10% SHG efficiency with $P_{in} = 1mW$; L= 25mm; Core dia $= 1.1\mu m$

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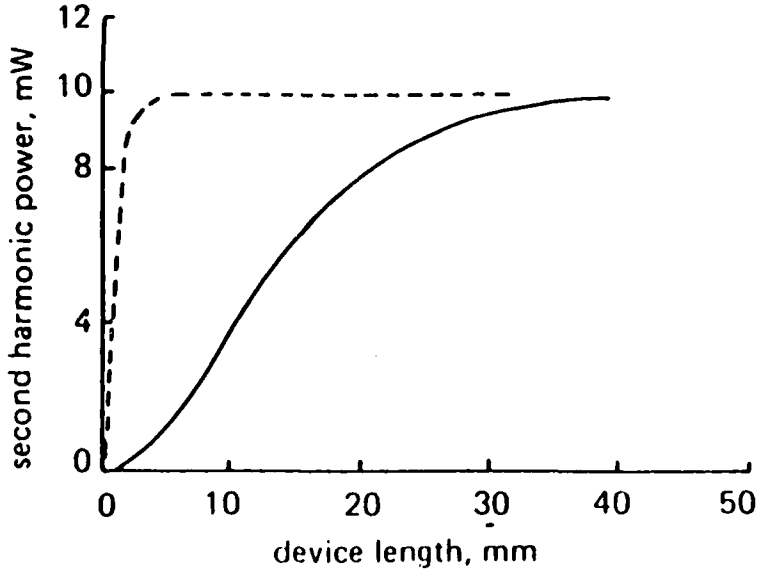
SHG OUTPUT FOR THE LP_{01} MODE IN A CRYSTAL CORED FIBRE

Fundamental Power: 10mW

$V = 2.0$; $\lambda_f = 1500$nm; $\Delta = 0.1$; $n = 1.65$

d(------) $= 250$pm/V; d(——) $= 20$pm/V



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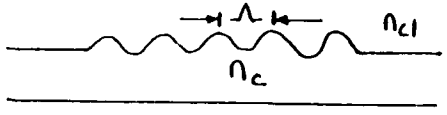
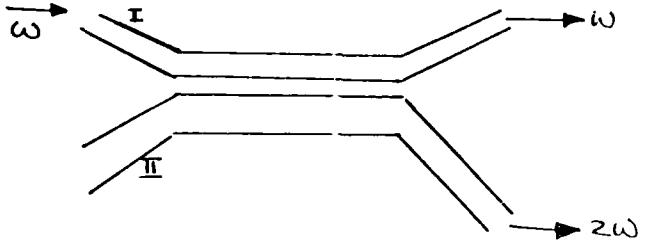
PHASE-MATCHING SCHEMES FOR GUIDED WAVE INTERACTIONS

- **Electro-optic/Temperature tuning**
- **Grating structures**



$$\Delta\beta = \beta^{(2\omega)} - 2\beta^{(\omega)} = \frac{2\pi}{\Lambda}$$

- **Coupled waveguides**



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ADVANTAGES OF CCF OPTICAL PARAMETRIC AMPLIFIER

- Independent of modulation format
- Independent of data bit rate
- Redundancy in pump lasers
- In-line device

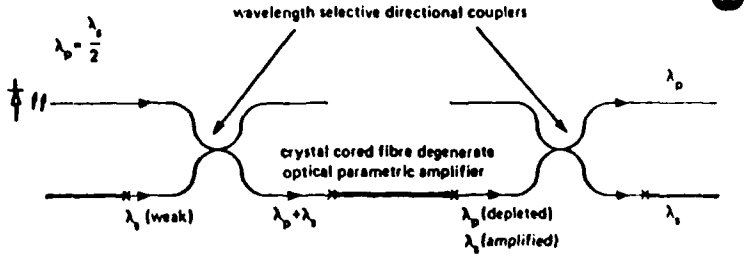
A CCF ALL OPTICAL AMPLIFIER

GAIN = 40dB

With

$P_p = 10mW$; $d_{eff} = 250 \times 10^{-12} m/V$

V-value = 2.0; $\Delta = 0.1$; L=10mm



Q-29

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CONCLUSIONS

Semiconductor diode pumped nonlinear devices are feasible

CCF DEVICE REQUIREMENTS

- Higher transmission
  - — Defect/void free crystal growth
  - — Better end preparation
- Efficient device designs
- New materials

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R-1

M. Thakur

AT&T

TOWARDS NONLINEAR OPTICAL APPLICATIONS OF POLYDIACETYLENES

R-2

TOWARD NONLINEAR OPTICAL APPLICATIONS OF POLYDIACETYLENES

M. THAKUR
AT&T BELL LABORATORIES

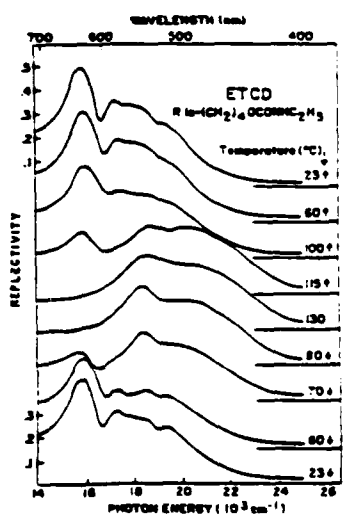
B. I. GREENE
J. ORENSTEIN
K. TAI
G. C. CHI
K. J. O'BRIEN
Y. SHANI
M. GOMEZ
H. TANAKA
A. TONELLI

TOPICS

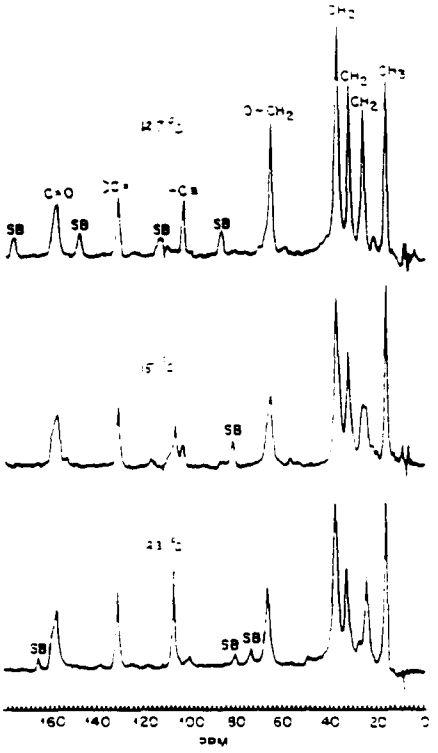
- MATERIALS ASSESSMENT
- GROWTH OF THIN SINGLE CRYSTAL FILMS
- FABRICATION OF DEVICE STRUCTURES
- DEMONSTRATION OF CHANNEL WAVEGUIDING
- INTENSITY DEPENDENT PHASE-MODULATION

IMPORTANT PARAMETERS FOR MATERIALS SELECTION

- EXTENT OF CONVERSION (MONOMER → POLYMER)
- EXTENT OF CONJUGATION (PLANARITY)
- THERMAL STABILITY (THERMOCHROMISM)
- SOLUBILITY
- EASE OF CRYSTALLIZATION



R-3



^{13}C Chemical Shifts of Polydiacetylenes

^{13}C, ppm vs. TMS

	C=O	≫C=	-C≡	α-CH_2	β-CH_2, γ-CH_2
ETCD (blue)	157.5	131.6	107.4	37.3	24.5
PTS-6 (blue)	—	131.3	107.1	—	—
PTS-12 (blue)	—	131.0	106	—	—
TCDU (blue)	—	—	107.3	—	—
ETCD (red)	158.3	132.0	103.6	37.8	26.4
TCDU (red)	155.8	131.5	102.9	37.9, 32.3	25.9, 21.8, 28.0, 30.8
ETCD (melt)	158.1	130.8	102.5	37.3	27.2

CONCLUSIONS FROM NMR STUDIES

- **THE CONJUGATION LENGTH IS DETERMINED BY THE EXTENT OF PLANARITY OF THE CHAIN-BACKBONE.**
- **INCREASE OF CHAIN LENGTH DOES NOT GUARANTEE INCREASE OF CONJUGATION LENGTH.**
- **THE ACETYLENIC FORM IS PREDOMINANT IN POLYDIACETYLENES INDEPENDENT OF PHASES.**

R-4

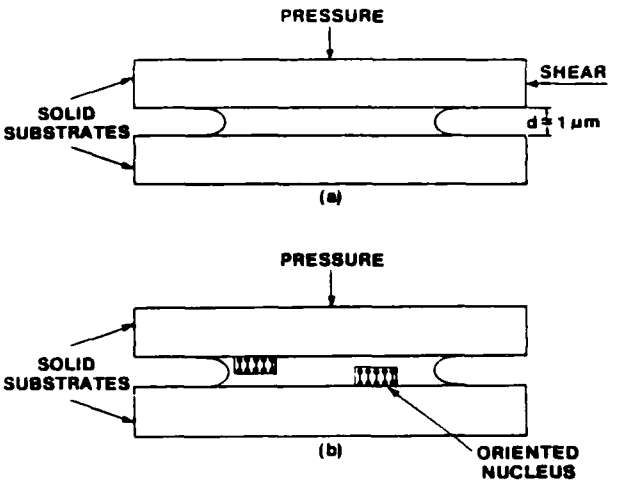
GROWTH OF SINGLE THIN FILM CRYSTALS

- THE SHEAR METHOD

  ORIENTATIONAL PRINCIPLES
  REQUIREMENTS ON MOLECULAR SHAPE
  GROWTH PARAMETERS
  CONTROL OF THICKNESS
  OPTICAL QUALITY OF FILMS

- COMPARISON WITH THE L-B METHOD

- ASSESSMENT OF APPLICABILITY



SPREADING COEFFICIENT

$$S_{B/A} = \gamma_A - \gamma_B - \gamma_{AB}$$

$$= W_{AB} - W_{BB}$$

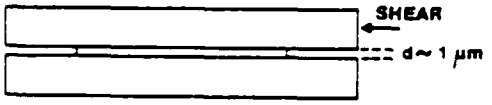
γ = SURFACE TENSION
W_{AB} = WORK OF ADHESION
W_{BB} = WORK OF COHESION

FOR SPONTANEOUS SPREADING

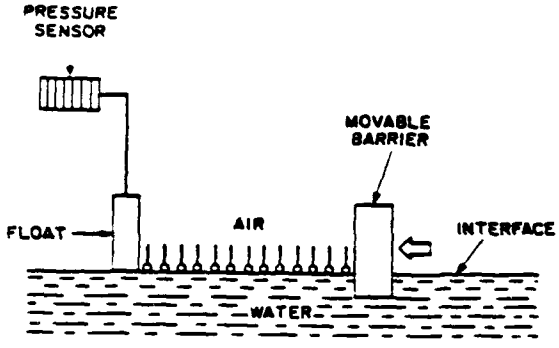
$$S_{B/A} > 0$$

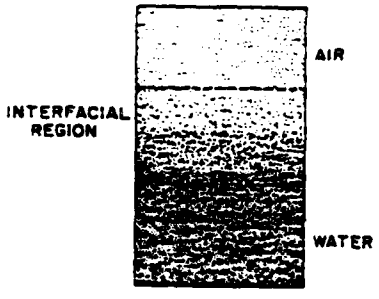
COMPARISON OF THE CALCULATED MOLECULAR LENGTHS WITH THE OBSERVED d-SPACINGS

MATERIALS	CALCULATED LENGTH L (Å)	COMPENSATED LENGTH $L\sin\phi$ (Å)	d-SPACINGS OF 1ST ORDER REFLECTIONS (Å)
RC ≡ C — C ≡ CR WITH R			
1. — CH_2 OH	~8.1	8.1	8.05
2. — $(CH_2)_4$ OCONH C_2H_5	~17.9	17.9	17.87
3. — $(CH_2)_4$ OCO NH C_6H_5	~19.5	19.5	18.94
4. — CH_2 OSO_2 C_6 H_4 CH_3	~14.8	12.9	12.87
5. — (CH_2) OCO NH $CH_2COOC_4H_9$	~26.9	26.9	26.80
NH_2–⟨⟩–C ≡ N	~8.0	8.0	8.40
HO, HO, N–⟨⟩–NO_2	~10.5	10.5	10.05



TOTAL SHEAR $T = T_{cap} + T_{ext}$
LATERAL PRESSURE $P \sim 10^7$ DYNES/cm^2
EQUILIBRIUM SPREADING PRESSURE OF A MONOLAYER
$P_{mono} \sim 10^7$ DYNES/cm^2





COMPARISON OF THE L-B AND THE SHEAR METHOD

- POLAR INTERACTIONS HAVE IMPORTANT ROLES IN BOTH THE METHODS.
- IN THE L-B TECHNIQUE A LIQUID IS USED AS THE SUBSTRATE. IN THE SHEAR METHOD SOLID SUBSTRATES ARE UTILIZED.
- THE L-B METHOD APPLIES TO AMPHIPHILIC MOLECULES ONLY. THE SHEAR METHOD IS APPLICABLE TO A BROADER RANGE OF MOLECULES.
- THE L-B METHOD PROVIDES ORDER ALONG ONE DIRECTION ONLY. THE SHEAR METHOD LEADS TO 3-D ORGANIZATION.
- THE L-B FILMS HAVE MICRO-DOMAIN MORPHOLOGY (POOR OPTICAL QUALITY). THE SHEAR-GROWN FILMS ARE UNIFORM SINGLE CRYSTALS (EXCELLENT OPTICAL QUALITY).

INTENSITY DEPENDENT PHASE MODULATION

$$n = n_0 + n_2 I$$

$$\Delta\phi = \frac{2\pi}{\lambda} n_2 I L \,, \quad L = \text{LENGTH OF PROPAGATION}$$

$\Delta\phi$ = PHASE SHIFT

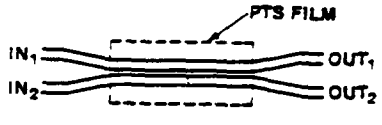
FOR $\lambda \sim 0.8$ TO $2.0\,\mu$

n_2 OF PTS $\sim 7 \times 10^{-6}$ cm^2/MW (HERMANN AND SMITH, 1980)

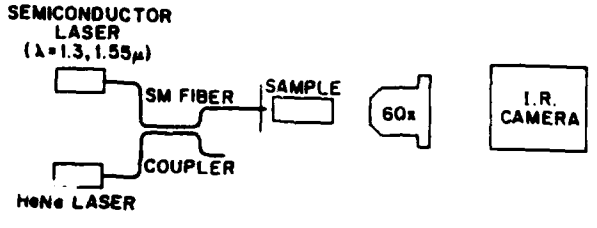
IF OPTICAL PULSES ($\lambda \sim 1\,\mu$) OF PEAK POWER $\sim$ 500 mW ARE FOCUSSED ON A CROSS-SECTION $\sim 1\,\mu$m^2

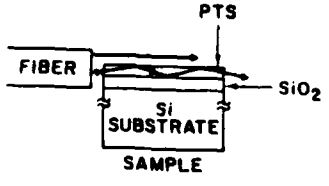
$\Delta\phi \longrightarrow \pi$

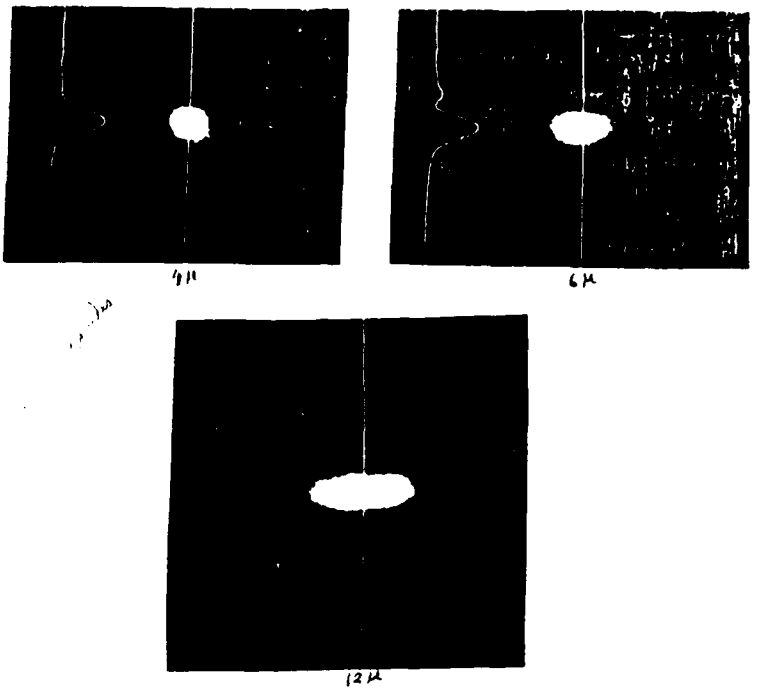
FOR L $\sim$ 1.4 mm.



WITH SUBPICOSECOND PULSES
ENERGY REQUIREMENT < 1 pj/bit.
THE DATA-RATE THAT THE DEVICE COULD HANDLE $\sim$ 1 THz
NONABSORPTIVE $\longrightarrow$ NO THERMAL DAMAGE.







SUMMARY

- A COMPARATIVE EVALUATION IS MADE FOR DIFFERENT POLYDIACETYLENES IN RELATION TO NLO DEVICE APPLICATIONS.
- C^{13} – NMR RESULTS SHOW THAT THE CONJUGATION LENGTH IS DETERMINED BY THE EXTENT OF PLANARITY OF THE CHAIN BACKBONE AND NOT BY THE CHAIN LENGTH.
- THE ORIENTATIONAL PRINCIPLES OF THE SHEAR METHOD ARE DISCUSSED IN COMPARISON WITH THE L-B TECHNIQUE.

SUMMARY (Cont.)

- THE SUPERIORITY OF THE SHEAR METHOD IN PROVIDING GOOD OPTICAL QUALITY SINGLE CRYSTAL FILMS OF CONTROLLED THICKNESS AND ORIENTATION IS DEMONSTRATED WITH MANY EXAMPLES.
- CHANNEL WAVEGUIDING IS DEMONSTRATED (PROPAGATION > 5 mm) FOR SHEAR-GROWN PTS FILMS.
- PRELIMINARY RESULTS OF INTENSITY DEPENDENT PHASE CHANGE IN PTS WAVEGUIDES ARE DISCUSSED.

D. Haarer
Universitat Bayreuth, West Germany

HIGH RESOLUTION LASER SPECTROSCOPY IN POLYMERS

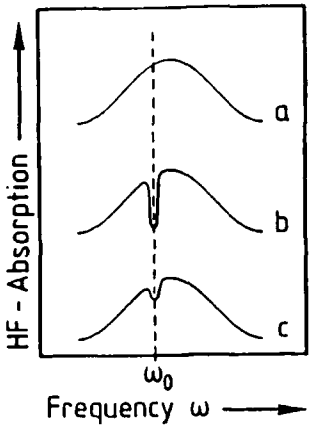


Fig.3.1. Local saturation of an NMR line at the frequency ω_0 (a) before, (b) during, and (c) after irradiation at ω_0 [3.1]

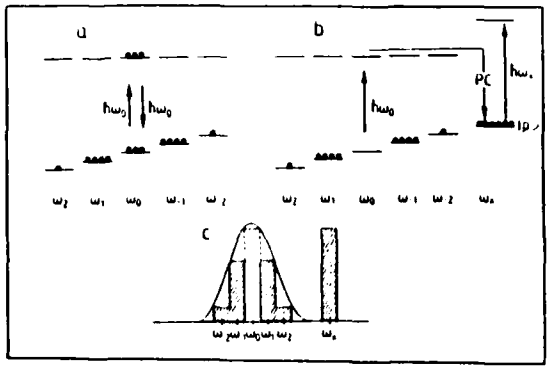


Fig.3.2. (a)Radiation saturation of an ensemble of five optical two-level systems at the center frequency ω_0. (b) *Photochemical bleaching of an ensemble of five* two-level systems at the center frequency ω_0. Creation of a photoproduct state absorbing at the frequency ω_a. (c) Absorption after photochemical bleaching as described in Fig 3.2b. The photoproduct shows up at the frequency ω_a

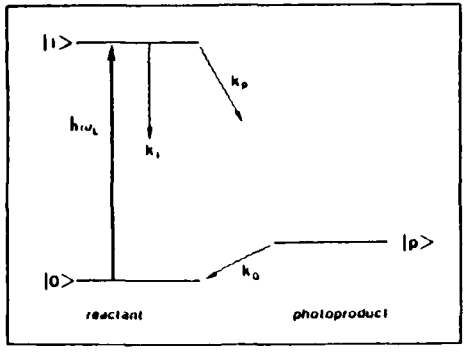


Fig.3.3. Three-level system with the reactant levels |0) and |1) and the photoproduct level |p). K_1, K_p and K_0 are the decay rate constants of the various states. ω_L is the hole-burning frequency

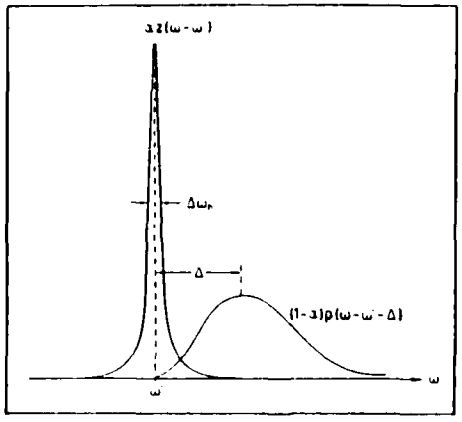


Fig.3.4. General lineshape function of an electronic excitation of a guest molecule in a solid host matrix: Schematic view of a zero-phonon line and its phonon sideband. The phonon sideband has an intensity of $(1-\alpha)$ and is displaced by the lineshift parameter Δ. The latter corresponds to half the "Stokes shift"

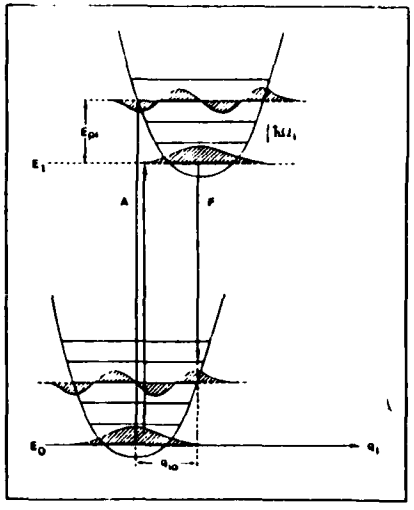


Fig.3.5. Energy diagram for interpreting phonon side-band spectra in terms of the excited state displacement q_{10}. The phonon frequency is Ω_1. The figure shows a zero-phonon and a three-phonon transition in absorption (A) and emission (F), respectively

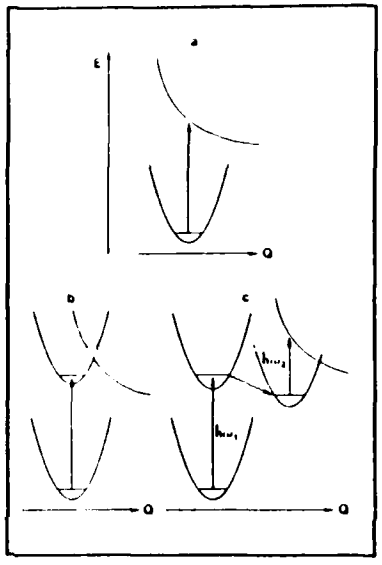


Fig.3.6a-c. Photochemical reaction schemes plotted as a function of one configurational coordinate Q. (a) Repulsive exciplex-like state. (b) Level-crossing from a "quasi-stable" excited state. (c) Two-photon reaction with photon energies $\hbar\omega_1$ and $\hbar\omega_2$. The level which absorbs the photon $\hbar\omega_2$ is a long-lived intermediate state

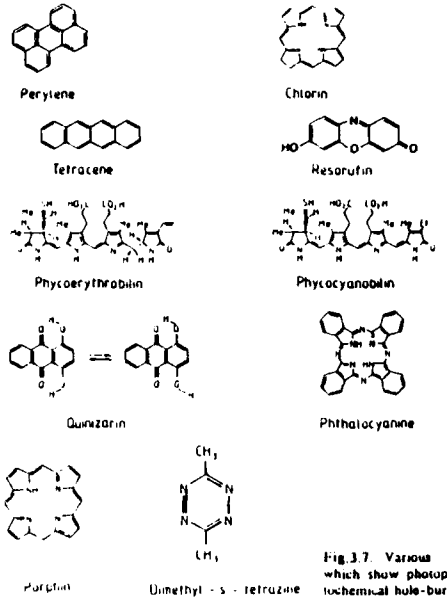


Fig.3.7. Various dye molecules which show photophysical and photochemical hole-burning

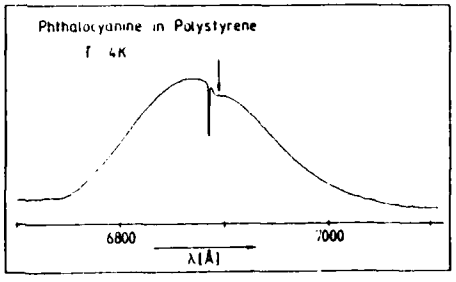


Fig.3.8. Experimental hole spectrum of phthalocyanine in polystyrene at 4 K. The pseudo-phonon wing is marked by the wavy arrow

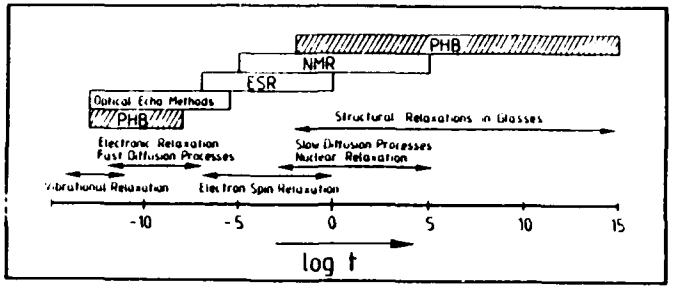


Fig.3.9. Logarithmic scale of relaxation times and of methods of measuring characteristic time constants. Hole-burning is especially well suited for very short and very long relaxation times (see text)

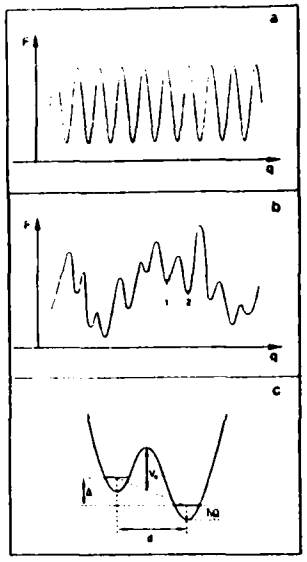


Fig.3.10. (a) Periodic potential of a crystalline solid. (b) Potential along a fictitious coordinate q of a glass: Note the lack of periodicity. (c) Idealized two level scheme with the two parameters Δ and V_0 (see text). The oscillators in the two wells are separated by the distance d and have a zero-point frequency on the order of Ω

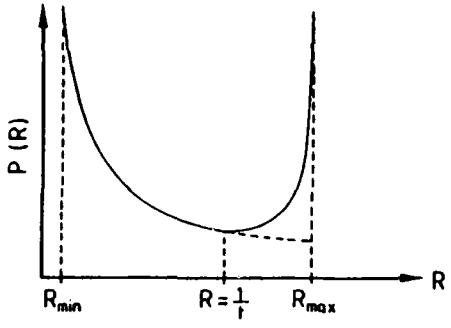


Fig.3.11. Rate distribution as calculated by *Jäckle* [3.98]. For the definition of the two limiting rates R_{min} and R_{max} see text

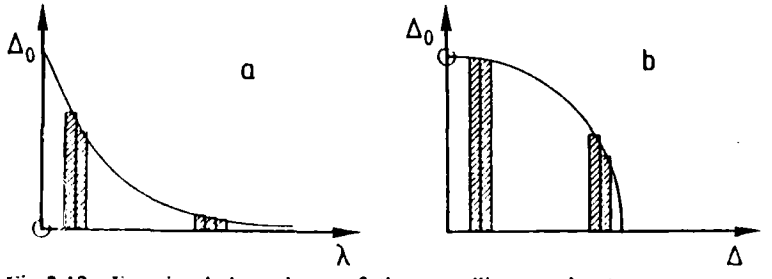


Fig.3.12. Functional dependence of the tunnelling matrix element Δ_0 on the TLS-parameters λ (Fig.3.12a) and Δ (Fig.3.12b) (see text)

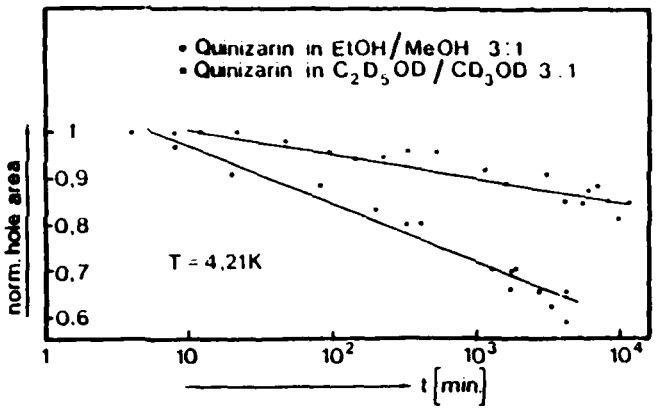


Fig.3.13. Time decay of the area of photochemical holes of quinizarin in alcohol glass for deuterated (*squares*) and protonated systems (*dots*)

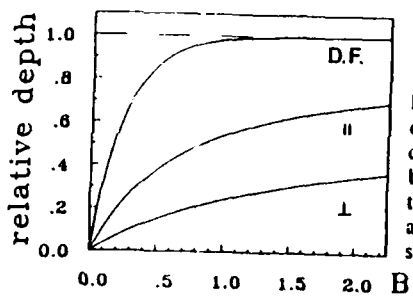


Fig.3.15. Dependence of the relative depth of a photochemical hole *on the irradiated light* dose B. The upper curve shows the maximally bleached *distribution function* with a polarization factor of unity. The two curves with parallel and perpendicular polarization are also shown [3.40]

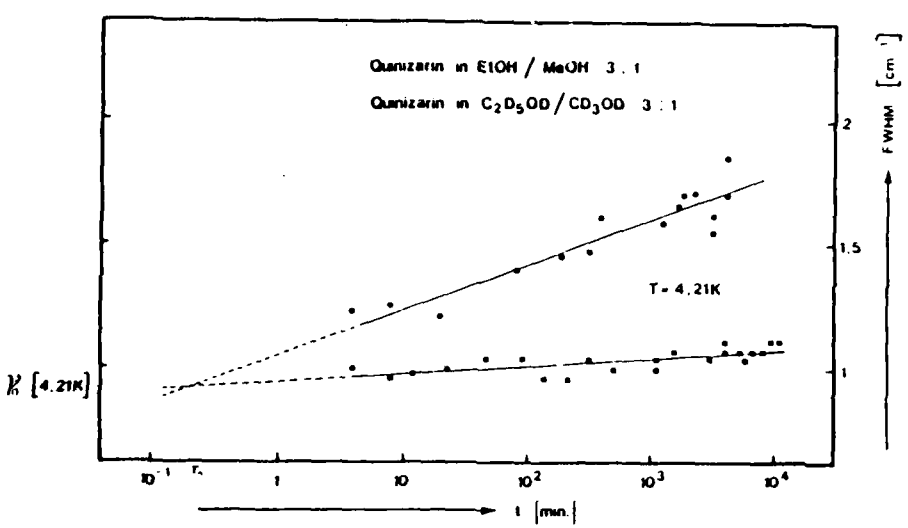


Fig.3.14. Line broadening of the photochemical holes of quinizarin in alcohol glass for deuterated (*squares*) and protonated systems (*dots*)

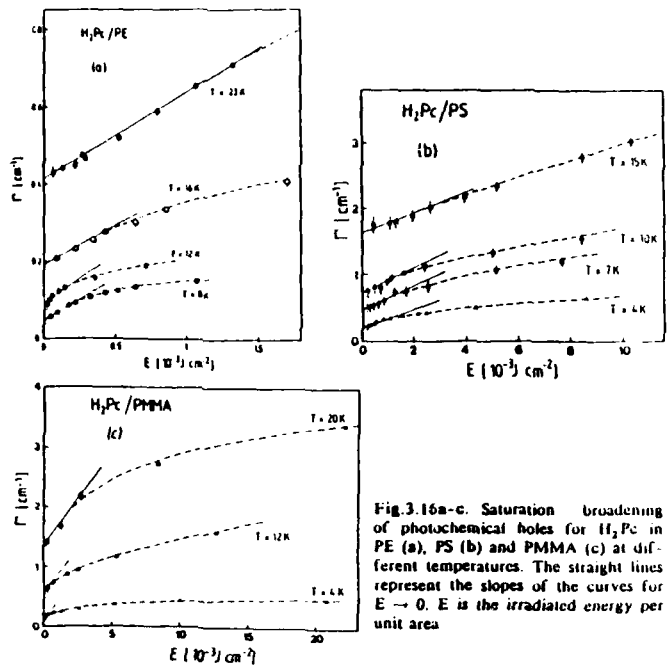


Fig.3.16a-c. Saturation broadening of photochemical holes for H_2Pc in PE (a), PS (b) and PMMA (c) at different temperatures. The straight lines represent the slopes of the curves for $E \rightarrow 0$. E is the irradiated energy per unit area

S-5

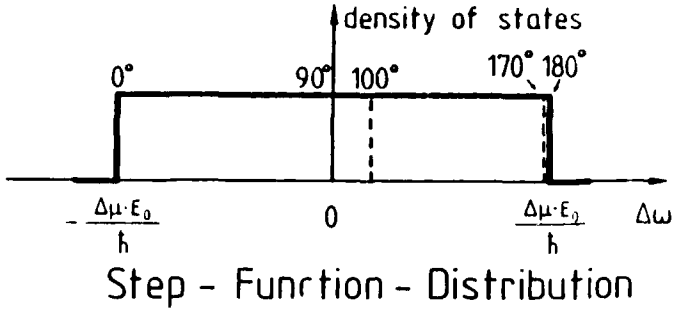


Fig.3.17. Distribution function of the absorption frequencies of guest molecules in an electric field E_0. All molecules absorb at the 0-frequency for E = 0; they have identical dipole moment changes $\Delta\mu$ but are oriented randomly with respect to the external E-field. The numbers indicate the orientation angles for some representative frequency shifts

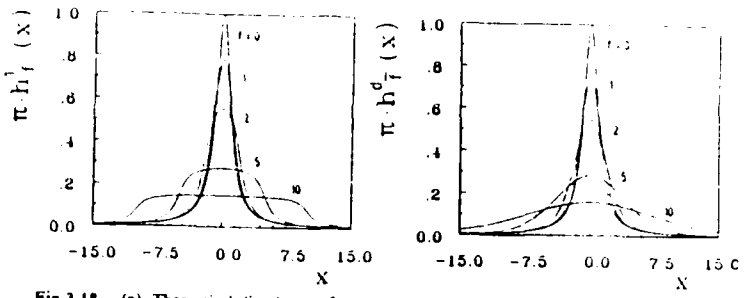


Fig.3.18. (a) Theoretical lineshape of a spectral hole for different external field strengths f. All absorbers have the same $\Delta\mu$ value. For a field value of f = 1, the Stark broadening equals the linewidth. (b) The same calculations as a) with a Gaussian distribution of $\Delta\mu$ values

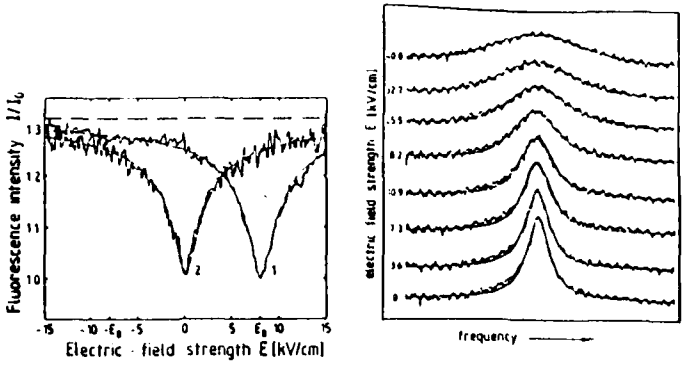


Fig.3.19. Fluorescence excitation spectra of two holes. One spectrum was burned at E = 0 and one was burned at the field E_B [3.123]

Fig.3.20. Measured and calculated hole profiles for the system Zn-TBP $(C_6H_4CH_3)_4$ in polyvinylbutyral (see [3.124]). Here the average change in dipole moment is $\Delta\mu$ = 0.174 Debye units

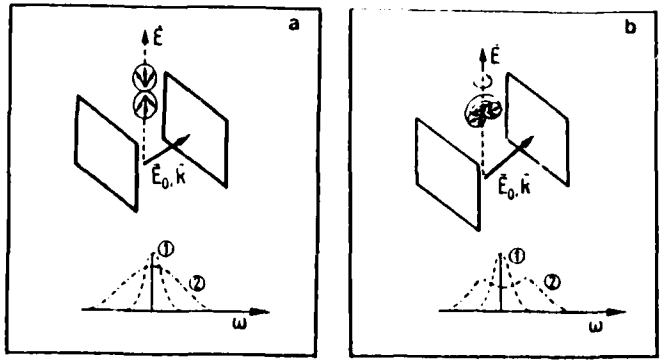


Fig.3.21. Dipolar $\Delta\mu$ configurations for $\Delta\mu$ parallel (a) and perpendicular (b) to the transition dipole moment. E_0 is the electric field strength and k is the wave vector of the incident light

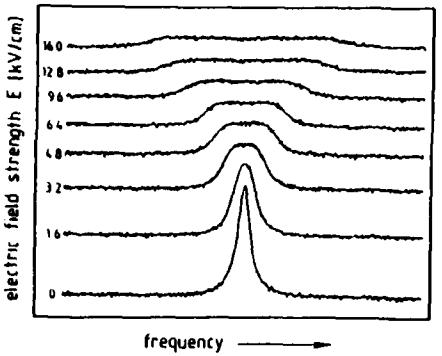


Fig.3.22. Measured and calculated hole profiles for H_2Ch in polyvinylbutyral [3.124]. Here the calculated $\Delta\mu$ value is $\Delta\mu$ = 0.214 Debye units

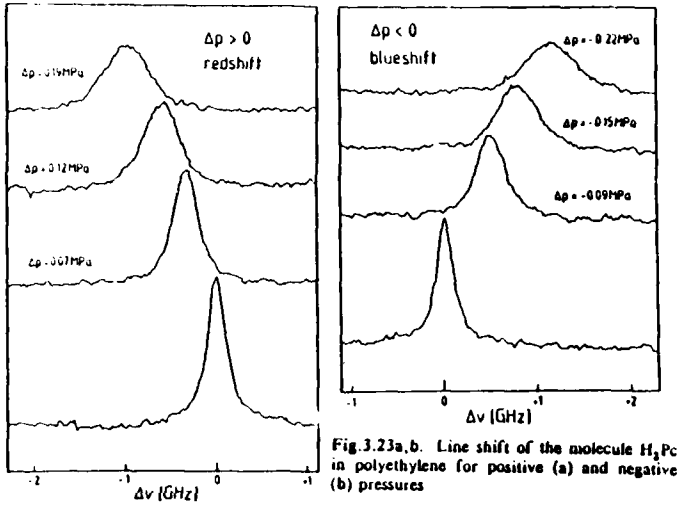


Fig.3.23a,b. Line shift of the molecule H_2Pc in polyethylene for positive (a) and negative (b) pressures

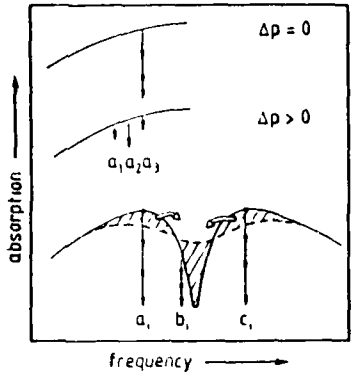


Fig.3.25. Line broadening of sites which had been site-selected at $\Delta p = 0$ and which drift apart at higher pressures $\Delta p \neq 0$. At higher pressures the frequency range of the absorbers extends from a_1 to a_2. The lower part of the figure shows the line broadening for various sets of molecules a_i, b_i and c_i

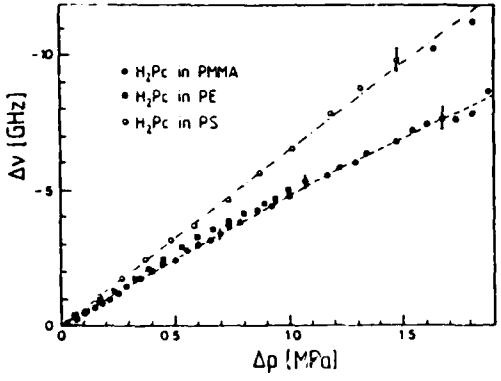


Fig.3.24. Line shifts of H_2Pc in PS, PE and PMMA in the low pressure regime

POSTER SESSION ABSTRACTS

Optical Kerr Measurements on some Ferrocene Derivatives.

C.S.Winter, J.D.Rush and S.N.Oliver.

British Telecom Research Labs.,
Martlesham Heath,
Ipswich IP5 7RE,
England.

We report here preliminary results from a study of the third order non-linearities in a range of organo-metallic compounds. These initial measurements have been carried out carried using the optical power limiter technique developed by Soileau *et al* [1], where the critical power for self-focusing is measured and used to calculate n_2. The materials measured were solutions of ferrocene in ethanol, varying from 10^{18} to 10^{19} molecules/cc and a liquid ferrocene derivative, bis(trimethylsilyl)ferrocene. A value of γ for ferrocene of 4.1×10^{-34} esu was found for the solution studies, in good agreement with that measured for the liquid derivative of 4.6×10^{-34} esu . The experiments were carried out at 1.06 μm with 10 ns pulses. We are currently repeating the measurements using other techniques and shorter pulses to distinguish the various possible contributions to the observed n_2.

(1) M.J.Soileau, W.E.Williams and E.W.Van Stryland;IEEE J Quant Elect.,QE-19,(1983),731.

Theoretical models for the second hyperpolarizability of novel conjugated polymers

David N. Beratan
Jet Propulsion Laboratory
California Institute of Technology
Pasadena, CA 91109

Theoretical models will be presented for the chain length dependence of the second electronic hyperpolarizability of simple polyenes, simple polyynes, and more complicated unsaturated organic materials. The hyperpolarizability of conjugated polymers which incorporate novel localized electronic states will be described as well. These materials present the possibility of achieving enhanced hyperpolarizabilities due to mixing of appropriate "gap states" with the delocalized states of the conjugated polymer. They also present the possibility of designing materials with "switchable" hyperpolarizabilities.

NONLINEAR OPTICAL PROPERTIES OF TRANSITION METAL POLY-YNES

E.A. Chauchard, M.P. Cockerham, P.L. Porter, S. Guha, C.C. Frazier
Martin Marietta Laboratories
1450 South Rolling Road
(301) 247-0700

Data from third harmonic generation (with a 1.06-μm fundamental), power limiting and four-wave mixing measurements of solutions and films of transition metal poly-ynes were used to verify that these compounds have large third-order optical susceptibilities. The large third-order nonlinearities observed in four-wave mixing studies of metal poly-yne solutions may originate, in part, from contributions from the real and imaginary components of intense two-photon absorptions associated with the metal-organic compounds. We will discuss our latest four wave mixing experiments and the direct observation of two-photon absorption in metal poly-ynes.

We will also discuss the correlation of polymer chain length and structure with third-order hyperpolarizability per repeat unit for several metal polymers and oligomers.

REVERSE SATURABLE ABSORBERS: INDANTHRONE AND ITS DERIVATIVES

R. S. Potember, R. C. Hoffman, and K. A. Stetyick
Johns Hopkins University Applied Physics Laboratory
Johns Hopkins Road
Laurel, MD 20707-6099

Indanthrone has been shown to exhibit the phenomenon of reverse saturable absorption.[1] The wavelengths at which indanthrone behaves in this fashion can be changed by structural modification of the indanthrone chromophore. The derivatives which have been synthesized have been shown to be more efficient reverse saturable absorbers than the parent chromophore.

It is advantageous to extend the range of nonlinear behavior to any desired portion of the spectrum, and this is best accomplished by substitution on the aromatic portion of the indanthrone molecule. We have demonstrated that oxidized indanthrone, monochloroindanthrone and an oligomer of indanthrone are more efficient saturable absorbers than the parent. Oxidized and monochloro-indanthrone exhibit reverse saturable absorption at both 1064 nm and 532 nm, whereas indanthrone itself exhibits the phenomenon at 532 nm only. The oligomer, which consists of three anthraquinone units, has proved to be an efficient reverse saturable absorber at 1064 nm as well as at 532 nm.

[1]C. R. Giuliano and L. D. Hess, IEEE J. Quantum Elec. QE-3, 338 (1966).

This work was supported in part by the Dept. of the Navy under Contract No. N00039-87-C-5301.

THE PREPARATION AND CHARACTERIZATION OF POLYMERIC MATERIALS WITH ENHANCED SECOND ORDER NONLINEARITIES. M.L. Schilling, H.E. Katz, D.I. Cox, AT&T Bell Laboratories, Murray Hill, NJ 07920.

We have recently introduced a new class of organic materials for second order nonlinear optics, consisting of poled films of dye-containing polymers. In the past year, some uncommon functional groups (di- and tricyanovinyl) have been shown to enhance the molecular susceptibilities of the nonlinear moieties when used instead of their more usual counterparts. Dyes with enhanced nonlinearities by virtue of the cyanovinyl substituents have been exploited in the preparation of bulk materials with some of the highest second order susceptibilities yet reported.

The synthesis of conformationally defined dye aggregates, whose subunit dipoles are constrained to be additive, is in progress. These dyes can then be incorporated into polymeric materials, taking advantage of their enhanced effective dipole moments for increased orientation in poling experiments. We will report some of the new synthetic organic chemistry that has been utilized in preparing our latest electro-optical materials.

Second Harmonic Generation in Doped Glassy Polymer Films as a Function of Physical Aging

Hilary L. Hampsch[a], Jian Yang[b], George K. Wong[b],
and John. M. Torkelson[a,c]*

[a] Department of Materials Science and Engineering
[b] Department of Physics and Astronomy
[c] Department of Chemical Engineering
and the Materials Research Center
Northwestern University
Evanston, Illinois

March 31, 1988

ABSTRACT

The temporal stability of second harmonic generation (SHG) intensity is measured in poly(methyl methacrylate) (PMMA) and bisphenol-A-polycarbonate (PC) doped with nonlinear optical dyes in electric field poled films. Doped PC films show slower SHG decay than doped PMMA films at times less than 8 hours. In PC+DANS films aged 10 hours at 25°C, there is no SHG decay over the first 8 hours, whereas in PMMA+DANS aged at 25°C and at 60°C the effect is much smaller. Two dopants show the effect of size on SHG decay, with the larger dopant showing increased temporal stability. Good agreement is obtained when decay curves are fit using a Williams-Watts stretched exponential.

* to whom correspondence should be addressed

ELECTRO-OPTIC, POLYMER CLAD, E-FIELD SENSOR

L. MICHAEL HAYDEN
GERALD F. SAUTER

UNISYS CORPORATION, CSD, St. Paul, MN, 55164

Abstract

There is a military need for sensor systems that combine high sensitivity, immunity to EMI/RFI, large bandwidth, and low power and cost. The hybridization of present day electronic components with optical components offers the promise of sensor systems that meet these requirements.

Unisys has been developing a PVDF-coated fiber optic, electric field sensor and now has expanded its program to include nonlinear organic polymers as cladding and waveguide material. This paper will report on progress using Guest/Host (GH) polymers as cladding material.

The concept of an all dielectric high frequency sensor is demonstrated. The sensor consists of a Ag^{+} exchange waveguide coated with a GH nonlinear polymer glass. The sensor is incorporated into one arm of a Mach-Zender interferometer and exhibits a figure of merit of 4 microradians/volt/meter/meter. The frequency response is flat from DC to our current instrumentation limit of 5 MHz.

This sensor design was chosen primarily as a vehicle that would allow an easy method to test and verify design parameters for fiber sensor systems. These parameters include index and depth of guide vs. index, thickness and E-O coefficients of the cladding. We will present a comparison of the results of this sensor with those from the PVDF sensor program.

MOLECULAR CONFORMATION AND THE STABILITY OF TICT STATE IN P,P'-DISUBSTITUTE-1,6-DIPHENYL-1,3,5-HEXATRIENES

C.T. Lin, H.W. Guan, R. K. McCoy and C. W. Spangler
Department of Chemistry
Northern Illinois University
DeKalb, IL 60115

ABSTRACT

The p,p'-disubstituted linear diphenyl polyenes are expected to have a high optical nonlinear susceptibility because of its large permanent dipole moment induced by the substituents. The photophysical properties for a series of p,p'-disubstituted-1,6-diphenyl-1,3,5-hexatrienes (referred as D,A-DPH) are investigated, where D and A are the electron-donating and - accepting groups of $-OCH_3$, $-N(CH_3)_2$ and $-NO_2$. In all solvents used, a dual fluorescence is observed for D,A-DPH containing the internal rotation groups of $-N(CH_3)_2$ and/or $-NO_2$, suggesting that the "a*" fluorescence (the locally excited state gives the normal "b*" fluorescence) is originated from a twisted intramolecular change transfer (TICT) state. The stability of TICT state is sensitive to the D and A substituents and their relative twisting angles. The observed results provide the evidence of the π-electron distortion and thus the enhancement of optical nonlinearity in this class of molecules.

Second and Third – Order Nonlinear Optical Properties of End – Capped Acetylenic Oligomers

Joseph W. Perry, Albert E. Stiegman, Seth R. Marder and Daniel R. Coulter

Jet Propulsion Laboratory, California Institute of Technology
4800 Oak Grove Drive, Pasadena, CA 91109

We have been investigating the second and third – order nonlinear optical properties of a variety of acetylenic oligomers. A series of symmetric acetylenic oligomers of the form

$$R-(C\equiv C)_n-R \qquad I$$

have been investigated for third – order nonlinear susceptibility. A series of new compounds of the form

$$D-(C\equiv C)_n-A \qquad II$$

where D and A are electron donor and acceptor groups, respectively, have been synthesized and investigated for second – order nonlinearity. Third – order nonlinear susceptibilities of series I molecules in solution have been measured using third harmonic generation (THG). THG susceptibilities at 1064 nm have been determined for various oligomer lengths and end – capping groups. X(3) increases with length and varies with the nature of the end – group. Series II compounds have been screened for second harmonic gener – ation by using the Kurtz powder method. Several samples show SHG efficien – cies comparable to urea. Characterization of molecular hyperpolarizabilities for the series is in progress.

Optical Field Induced Scattering in Polymer Dispersed Liquid Crystal Films

P. Palffy-Muhoray, Michael A. Lee and J.L. West
Liquid Crystal Institute
Kent State University
Kent, OH 44242

ABSTRACT

We report observations of optical field induced scattering in polymer dispersed liquid crystal films due to reorientation of the liquid crystal molecules by the optical field of a CW argon ion laser. These composite materials consist of nearly spherical liquid crystal droplets dispersed in a polymer binder. As previously reported [1,2,3], films of these materials may be switched from an opaque scattering state to a clear transparent state by application of a d.c. or low frequency a.c. electric field. An applied low frequency electric field is used to align the liquid crystal in an orientation such that the refractive index of the liquid crystal within the droplet is matched with that of the polymer binder. If a sufficiently intense optical field is applied to the transparent film, it will reorient the liquid crystal director, and give rise to a refractive index mismatch and hence scattering.

1. J.W. Doane, N.A. Vaz, B.-G. Wu and S. Zumer, App. Phys. Lett. 48, 269 (1986).

2. J.L West, Mol. Cryst. Liq. Cryst. (in press).

3. S. Zumer and J.W. Doane, Phys. Rev. A 34, 3373 (1986).

FABRICATION OF WAVEGUIDE STRUCTURES FROM SOLUBLE POLYDIACETYLENES. **G.L. Baker, N.E. Schlotter, J.L. Jackel, P. Townsend, S.Etemad, Bell Communications Research, Red Bank NJ 07701.**

Thin waveguide structures were fabricated from spun films of poly(3-BCMU) and poly(4-BCMU) by two separate processes. In the first, micron-sized features were patterned in polydiacetylene films using deep-UV lithography. This multilayer process utilizes a novel silicon-substituted polyacetylene as the resist layer, and can be used to generate sub-micron sized features in thick (>1μm) polydiacetylene films.

In the second method, composite waveguides were fabricated from a patterned glass substrate and an overlayer of the polydiacetylene. These composite structures are relatively simple to prepare and are mechanically robust. Guides constructed as described above performed well with minimal losses and single-moded behavior at laser wavelengths of 1-1.5 μm.

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